

**DECLARATION OF DEBABANI CHOUDHURY, PH.D.  
CONCERNING PAPERS PUBLISHED AT IMS 2010**

I, Debabani Choudhury, declare as follows:

1. I am currently employed by Intel Corporation as a Principal Engineer. I have worked at Intel for more than 12 years.

2. I am a Fellow of the Institute of Electrical and Electronics Engineers (IEEE). IEEE is the largest professional organization in the world for electrical engineers. I was elected as an IEEE Fellow for my contributions to millimeter-wave enabling technologies.

3. I have served on the Steering Committees and Technical Program Committees for several IEEE conferences, including IEEE International Microwave Symposium (IMS), IEEE Antenna and Propagation Symposium (AP-S), and IEEE Radio and Wireless Symposium (RWS). I am also a member and Past Chair of the IEEE Microwave Theory and Techniques (MTT) MTT-20 Wireless Communications Committee. In addition, I have served as an editor for multiple journals, including *Proceedings of IEEE*, *IEEE Transactions on Microwave Theory and Techniques (T-MTT)*, and multiple special issues of the *IEEE Microwave Magazine*. My own papers have also been published in IEEE journals.

4. I am submitting this declaration in my capacity as an Intel employee, not in any official capacity on behalf of IEEE.

5. I earned my Bachelor of Technology degree in Electronics and Communication Engineering from the Institute of Radio Physics and Electronics at the University of Calcutta in Kolkata, India in 1984. I earned my Doctor of Philosophy degree in Electrical Engineering from the Indian Institute of Technology Bombay (IITB) in Mumbai, India in 1991.

6. A copy of my current curriculum vitae is attached hereto as Attachment A.

7. This declaration concerns a paper entitled "Envelope Tracking Power Amplifier Robust to Battery Depletion," authored by Dr. Jinsung Choi of the Pohang University of Science

and Technology in Pohang, South Korea (the “Choi 2010 paper”), a true and accurate copy of which is submitted as Attachment B to this declaration.

8. In 2010, I attended and had an official role at the IEEE International Microwave Symposium (“IMS”). The IMS 2010 conference was held in Anaheim, California between May 23 and May 28, 2010. For the conference, I was, among other things, the chair for Publications, and the co-chair of the subcommittee for Millimeter-Wave and THz Components and Technologies within the IMS Technical Program Review Committee (TPRC).

9. IMS is the leading international conference on microwave/radio frequency (RF) theory and practice. The conference consists of a full week of events, including technical paper presentations, workshops, and tutorials, as well as playing host to a large commercial exhibition. The details of the IMS 2010 conference are listed in an IMS 2010 Program Book available at [https://mtt-archives.org/Chapter\\_E\\_Publications\\_and\\_Publicity/IMS2010\\_Reports/program\\_book\\_2010.pdf](https://mtt-archives.org/Chapter_E_Publications_and_Publicity/IMS2010_Reports/program_book_2010.pdf) (“Program Book”), a true and accurate copy of which is submitted as Attachment C to this declaration.

10. The IMS conference involves the presentation of papers on, among other things, RF circuit and power supply design, and it always draws many electrical engineers with multiple years’ experience in those areas. IMS 2010 was no exception: it was attended by many leading engineers in those fields, including industry leaders and academics from the largest and most prestigious electronics and semiconductor companies and universities in the world. At the time of the conference, for example, I worked at Intel, had a doctorate in electrical engineering, and had decades of experience in RF design.

11. The IMS 2010 conference was both well-advertised and well-attended. For example, the online webpage publicizing the IMS 2010 conference stated that IMS 2010 is “the premier annual international meeting for technologists involved in all aspects of microwave theory and practice.” *See 2010 International Microwave Symposium, About the Symposium* (Feb. 23, 2010 archived version), *available at* <https://web.archive.org/web/20100223070645/http://www.ims2010.org:80/about.html> (accessed January 31, 2018), a true and accurate copy of which is submitted as Attachment D to this declaration.

12. Based on my experience working on the IMS 2010 conference, and my own personal attendance at that conference, I know that more than 1,800 people attended IMS 2010.

13. As reflected in the symposium’s technical program, IMS 2010 included a specific session on “Power Amplifier Circuits.” *See Attachment C (Program Book)*, at 40. Papers presented during this session represented the state of the art in power amplifier circuits at that time, and would have been of interest to academic and industry leaders in the field of power amplifiers seeking to learn about new developments in the field.

14. The Choi 2010 paper was announced in the Program Book for the IMS 2010 conference. *Attachment C (Program Book)*, at 40. On information and belief, Dr. Jinsung Choi presented the Choi 2010 paper at the IMS 2010 conference as Paper ID WEPF-5, during the Power Amplifier Circuits, Interactive Forum session WEPF held on Wednesday, May 26, 2010.

15. The IMS 2010 conference in general, and the Power Amplifier Circuits session in particular, were open to the public. Anyone willing to pay the registration fee was permitted to attend, with IEEE members paying a discounted rate. No confidentiality restrictions of any kind were imposed on attendees at IMS 2010, and attendees were free to (and indeed encouraged to)

disseminate and discuss papers and other technical material presented during the conference openly.

16. PDF versions of the papers presented at the conference were available at computer terminals stationed throughout the conference space. A person who wanted a hard copy of a particular paper could use the printers at those computer terminals to print a copy. The IMS Program Book (Attachment C) refers to these computer terminals on page 5 (“Print on Demand”).

17. Over 2,000 identical USB drives were created before the 2010 conference began, each containing a copy in PDF format of every paper presented at the conference—including the Choi 2010 paper attached hereto as Attachment B.

18. My official role at the IMS 2010 conference included not only the roles identified above but also the preparation of the Symposium Proceedings USB drives containing the conference papers. As shown in the Program Book for the IMS 2010 conference, I was the chairman of the “Proceedings USB” subcommittee:

**Proceedings USB**  
Debabani Choudhury, Chairman  
Weiheng Chang

Attachment C (Program Book), at 59.

19. All the IMS 2010 papers were available to the IMS Technical Paper Review Committee (TPRC) members no later than December 2009. The IMS 2010 published papers were selected by TPRC members on Sunday, January 10, 2010 at a TPRC meeting in New Orleans, Louisiana.

20. To permit sufficient time to prepare the USB drives in advance of the conference, we required final manuscripts of accepted papers to be submitted on or before March 4, 2010. I recall the publications committee receiving these papers, and, over the ensuing weeks, committee members participated in organizing the papers (including Choi 2010) for publication to symposium participants on the USB drives, with the help of an external USB vendor.

21. Copies of the USB drive containing these papers (including Choi 2010) were then created at my direction, and these copies were distributed to conference attendees when they checked in at our conference location the Anaheim Convention Center in Anaheim, California.

22. Participants typically want a USB drive containing the papers and therefore register to receive one. Based on my personal attendance at and involvement with the conference, I know that a significant share of the USB drives (more than 1,500) were distributed to participants at the conference.

23. Because each of the USB drives contained the Choi 2010 paper, more than 1,500 people, all of whom attended the IMS 2010 conference, received the Choi 2010 paper no later than May 28, 2010.

24. There were no confidentiality restrictions placed on any of the papers contained on the USB drives, and the purpose of distributing the USB drives to attendees was to promote the further dissemination of these papers to the interested public.

25. I have been in possession of the USB drive that I received at the start of the IMS 2010 conference on or about May 23, 2010. My USB drive is identical to the USB drives given to IMS 2010 conference registrants.

26. The copy of Choi 2010 that is attached hereto as Attachment B is a true and accurate copy of this paper contained on the USB drive that I received at the IMS 2010

conference on or about May 23, 2010. Attachment B is thus identical to the copy of the Choi 2010 paper on each of the identical USB drives distributed to registrants at the IMS 2010 conference.

27. Other than my ordinary employment relationship with Intel Corporation, I am not receiving any compensation for my declaration or testimony in this matter.

28. I declare that all statements made herein of my own knowledge are true; that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like are punishable by fine or imprisonment, or both.

Signed: Debabani Choudhury

Dated: June 19, 2018

## **ATTACHMENT A**



DEBABANI CHOUDHURY, PhD.  
Principal Engineer, Intel Labs  
e-mail: debabani.choudhury@intel.com

**SUMMARY OF PROFESSIONAL EXPERIENCE:**

Broad range of technical/technical-management experience in RF/microwave, mm-wave/THz technologies, 5G hardware, wireless platform implementation, vehicular embedded RF/mmW research.

Proficient in the field of subsystem/circuit/device design, development, integration, and testing. Technologies include but not limited to 5G, RF-circuit/system design/integration, mm-wave imaging, smart-antennas, active and passive components, antenna/array integrated sub-systems, RF-modules/packaging, flexible-electronics, 3D-integration, interconnects, RFICs/MMICs, RF-MEMs, III-V devices, III-V fabrication, MMICs, meta-materials, FSS/EBGs, wireless-power, sensors/networks, quasi-optics, vehicular.

**EMPLOYMENT HISTORY:**

**INTEL CORPORATION (2006- to date)**

Principal Engineer - Intel Labs

- Leading 5G and vehicular antenna integrated system research and defining long-term strategy at Intel Labs.
- Led a diverse team of technologists to demonstrate Intel's first 73GHz E2E link demo with direct conversion approach.
- Defined 60GHz modular antenna array (MAA) front-end modules project and led a team of technologists from various Intel BUs to demonstrate MAA front-end modules for 60GHz wireless, backhaul and hybrid beamforming applications.
- Demonstrated smartphone integrated antenna POCs for LTE-A type applications. Collaborated with BUs for FFRD demonstration.
- Coordinated completion of an antenna/Front-End Module project with external vendors using organic-based low-cost embedded passives in a small-form-factor. Achieved smallest form factor with desirable performance of front-ends (FEMs) and integrated antennas.
- Initiated 60GHz hardware research at Intel for future platform-specific applications and generated IPs on integrated package/RFIC/antennas based on various usage models. Collaborated with product team members to generate initial WPAN ideas for Intel products.
- Taken strategy, management and leadership courses from Intel University and Stanford Graduate School of Business (GSB).
- Created multiple Intel research projects with different universities.
- Invited to DARPA Workshops on mm-wave silicon-based architectures
- Supervising SRC/Intel funded university research efforts on RFICs, mm-wave phased arrays, MIMO-based mm-wave imaging and THz electronics.

- Served on the distinguished panel of US National Science Foundation (NSF) Engineering Advisory Committee to evaluate funding to US universities.

**HRL LABORATORIES, (former HUGHES RESEARCH LABORATORIES), CA**  
(1996- 2006)

Senior Staff Scientist

- Led several programs on sub-system integration, circuit and III-V semiconductor device development to successful completion.
- Worked on several different semiconductor device technologies such as, InP HEMT, InP HBT, SiGe, RF MEMs, InP Gunn diode, varactor, etc. Developed antennas, active devices, MMICs and integration techniques for imaging and automotive applications.
- Developed new RFIC/MMIC architectures for mm- and higher frequencies. Introduced new ideas to multi-gigabit IC design approach and packaging.
- Invited to multiple DARPA workshops, influenced DARPA BAA solicitation/topics and was involved in writing DARPA proposals on mm-wave/THz imaging approaches
- InP HBT/HEMT-based IC projects included high frequency device modeling, interconnects and IC packaging, 1-300+ GHz ICs, 40+ Gb/s ICs, etc. Demonstrated a packaged HBT-IC design with a **world record BW of 1-70+ GHz**.
- Demonstrated **largest bandwidth active amplifiers** using HBT-IC process technology.
- Was responsible for several programs related to design and demonstration of RF Micro-Electro-Mechanical (MEM) switches, phase shifters, filters, resonators, beam switched-antennas/arrays and other components. Implemented novel ideas and monolithic integration of MEMs switches on InP and GaAs MMICs.
- Research/development included flexible electronics, wafer-scale packaging of MMICs and MEMs, 3D-package with heterogeneous device integration.
- Investigated Rotman lens and 3D-imaging designs with flexible electronics
- Developed low-cost Gunn devices for mm-wave oscillator application including a novel Gunn Device processing technique for 77GHz and 140GHz automotive applications.
- Experienced on antenna array, Frequency Selective Surfaces (FSS), meta-materials, resonator/filters, requiring extensive 3D EM design efforts.
- Designed beam-steerer and spatial power combiners based on planar and waveguide technologies.
- Developed automotive-embedded antennas and MMICs for 77GHz auto-radar.
- Developed antenna-embedded rectifier circuits/arrays for wireless power.
- Received new inventor award at HRL for generating IPs to impact the future product oriented research.

**Millivision and Millitech Corporation, MA (1994 - 1996)**

Senior Technical Staff

- Led an effort for the design and development quasi-optical and wave-processing (WP)-MMICs for imaging applications. Projects included mm-wave beam-forming and beam-steering imagers and sub mm wave (-upto 800GHz) circuits/components.

- Guided a technical team to develop design, fabrication and testing methodologies for dual-polarized electronic beam steering and demonstrated **world's first** dual-polarized quasi-optical monolithic beam steering array for mm-wave imaging. Projects included semiconductor processing and testing of circuits and systems.
- Experience in developing folded lens and optics based compact mm-wave handheld passive imager.
- Was instrumental in the co-design and development of antenna and RF front ends of focal plane array heterodyne receivers for passive mm-wave imaging systems at 94GHz. Investigated focal plane array based 140GHz design also.

### **NASA/JET PROPULSION LABORATORY, Caltech, CA (1991- 1994)**

Researcher

- As a JPL researcher, worked on the submm-wave/THz heterodyne receiver development effort for earth remote sensing and astrophysics applications.
- Was responsible for the development of sub-millimeter-wave, solid-state local oscillator sources for space applications. Was involved in all aspects of the submillimeter-wave frequency multiplier program; -starting from design of multiplier circuits to the design, fabrication, characterization of novel varactor devices as well as assembly/testing of the solid state multipliers.
- Collaborated on multiple quasi-optical circuit designs and demonstration
- Led an effort on the development of innovative planar varactor diode frequency multipliers and THz waveguide circuitry. Created numerous new concepts on device and circuits for THz and received multiple NASA recognition/awards.

### **INDIAN INSTITUTE OF TECHNOLOGY, India (1987 - 1991)**

Project Engineer, Advanced Center for Research in Electronics (ACRE)

- ∞ Was responsible for designing and fabricating monolithic and hybrid microwave integrated circuits. Developed novel method of selective electrolessplating for MIC applications and a CAD package for designing MIC components.
- ∞ Was In-Charge of the CAD/CAM lab. at defense research center ACRE.

### **ELECTRICAL ENGINEERING DEPARMENT, IIT, BOMBAY, INDIA**

Research Scholar (1987-1990), (received Ph.D degree in 1991)

- ∞ Developed a Finite Element package for analyzing transmission lines
- ∞ Worked on Monolithic Microwave Integrated Circuit (MMIC) /passive structures.

### **EDUCATION:**

Ph.D (1991) Electrical Engineering, Indian Institute of Technology (IIT), Mumbai India. The thesis is entitled "Experimental and finite element studies on monolithic microwave integrated circuit transmission lines".

M.Tech (1986) Electronics and Comm. Engineering, Institute of Radio Physics & Electronics, Calcutta University, Kolkata, India.

B.Tech (1984) Electronics and Comm. Engineering, Institute of Radio Physics & Electronics, Calcutta University, Kolkata, India.

### **PATENTS/PUBLICATIONS/PRESENTATIONS:**

- 25+ patents/patent applications. Several invention disclosures.
- Published numerous articles in refereed journals and conferences.
- Several invited talks in workshops, Conferences and Universities.

### **PROFESSIONAL ACTIVITIES:**

- Elected 2011 IEEE Fellow.
- Invited speaker at many IEEE conferences, Workshops/Summits and Universities at US and abroad.
- Served as Industry Advisor for multiple university Post-graduate theses.
- Reviewed NSF funded proposals and Impacted DARPA BAAs.
- Served on the distinguished panel of NSF Committee of Visitors (COV).
- Industry liaison of SRC funded university programs.
- Co-Editor for 2013 Proceedings of IEEE issue on Wireless Power Technologies and Applications.
- Co-Editor, IEEE Transactions on Microwave Theory and Techniques Special Issue on 5G Technologies, 2017.
- Editor, Microwave magazine Special Issue on RWW11, RWW12
- Editor, Microwave magazine Special Issue on 5G Technologies, 2017 and Full-Duplex in 2018.
- Multiple IEEE MTT-S Technical Co-ordination Committee (TCC) member:
  - MTT-20 on Wireless Communications
  - MTT-26 on Wireless Power and Energy Conversion
  - MTT-6 on Microwave and Millimeter Wave ICs
  - MTT-27 on Wireless Enabled Automotive & Vehicular Applications
- Elected and served three years as Chair of IEEE MTT-S TCC committee MTT-20 on Wireless Communications.
- Served as elected Co-Chair for two IEEE MTT-S Committees (MTT-20 and MTT-26) for three years.
- Technical Program Committee (TPC) Co-Chair for 2013 IEEE Radio and Wireless Symposium.
- Chair, 2017 and 2018 IEEE 5G Summit
- Technical Program Committee (TPC) member for IEEE International Microwave Symposium since 2001 .
- Technical program reviewer and TPC member/Session Organizer for IEEE Antennas and Propagation Symposium (APS).
- TPC Member for SPIE Int. Symp. on Microelectronics, MEMs & Nanotech. Since 2006.
- TPC member and subcommittee chair for IEEE Radio & Wireless Symposium
- Served as Co-Chair for IEEE IMS symposium subcommittees.
- Technical session chairs for IEEE-IMS, IEEE-APS, IEEE RWS .
- IEEE MTT-S Steering Comm member in 1999,2001,2005,2007,2008,2010.

- Served as Plenary, Panel, Focused session and Registration Chair for RWW.
- Publications Chair for multiple IEEE IMS Symposiums: IMS2005, IMS2007, IMS2008 and IMS2010; CDROM Editor for IMS1999 and IMS2001.
- TPC and organizing committee member for several International conferences supported by MTT-S and AP-S societies (European Microwave Conference (EuMC), Asia Pacific Microwave Conference (APMC), ICMIM, Wireless Power Transfer Conference (WPTC) AEMC/IAW, IMWS-IWPT, RFIDTA and so on.
- Multiple IEEE IMS Workshop, focused session and panel organizer.
- 2013 IEEE Wireless Industry Day (WID) speaker.
- 2018 IEEE Communications Future Summit speaker.
- Reviewer of several IEEE Transactions/Journals.
- Editorial board member of CUP Wireless Power Journal.

**ATTACHMENT B**

# Envelope Tracking Power Amplifier Robust to Battery Depletion

Jinsung Choi, Dongsu Kim, Daehyun Kang, Jungmin Park, Boshi Jin, and Bumman Kim

Department of Electrical Engineering, Pohang University of Science and Technology,  
Gyeongbuk, Republic of Korea  
*jinsungc@ieee.org*

**Abstract**—A wideband envelope tracking power amplifier, which is robust to battery depletion, is introduced. An integrated boost converter keeps a stable operation of the PA supply modulator. Even at the battery depletion from 4.2V to 2.8V, there is no significant degradation of output power and linearity in the power amplifier. Moreover, the efficiency degradation by the additional regulator is minimized for the novel supply modulator architecture proposed in this work. The fabricated 2.535GHz envelope tracking power amplifier presents max/min power-added efficiencies of 32.3/26.2% for 10MHz BW 3GPP LTE standard along the battery voltage from 4.2V to 2.8V.

## I. INTRODUCTION

As the wireless communication systems evolve, the peak-to-average power ratio (PAPR) of the signal increases. For 2G and 3G systems such as CDMA, EDGE, and WCDMA, the PAPRs of the signals are around 3.5dB as depicted in Fig. 1. For the next generation communication systems such as 3GPP LTE and Mobile-WiMAX, however, an orthogonal frequency-division multiplexing (OFDM) is employed for a wideband communication, which results in higher PAPR around 8–10dB. In the case, an efficiency of a radio frequency (RF) power amplifier (PA) is so low that the efficiency improvement technique is required. The envelope tracking (ET) technique is one of the best way achieving a high efficiency. Because the supply of the RF PA is modulated according to the instantaneously transmitted power level, the power dissipated as a heat is minimized. Ideally, it is the optimum PA architecture with assumption of high efficiency supply modulator. In [1], the low drop-out (LDO) regulator is employed as a supply modulator. It operates over a wide bandwidth, but efficiency of the LDO is not high enough for high PAPR signals. The switching mode power supply such as a buck converter shows a high efficiency, but the switching frequency is limited by the switching loss so that wide bandwidth capability can not be fulfilled [2].

At the same time, due to battery depletion, the performances of PAs such as output power and efficiency are degraded as shown in Fig. 2-a and Fig. 3. In the envelope tracking power amplifier, the battery is directly coupled to the PA supply modulator as illustrated in Fig. 2-b. Therefore, the supply voltage of the PA depends on the topology of the supply modulator. For the step-down converter such as the LDO and the buck converter, the output voltage swings are limited by the minimum battery voltage, as there is always a voltage drop across the transistor between the battery and the load. To prevent the degradation of the output power, a boost converter,

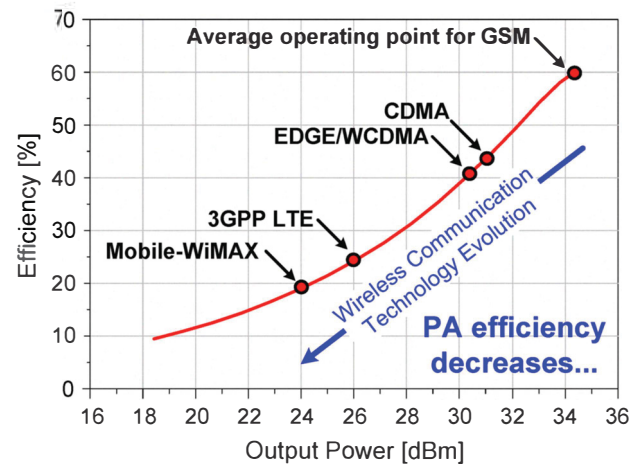


Fig. 1. Efficiencies of PA for various applications

whose output voltage is always higher than the input voltage, can be utilized [3]. However, drawback of employing the boost converter is that it is not possible to deliver the load voltage lower than the battery voltage. As the efficiency improvement at a low power region becomes very important, a good low voltage operation of the PA should be achieved. Therefore, the buck-boost converter taking advantage of the buck and boost converters is suitable for the application [4].

Still, the power converters mentioned above are not the best solution for the modern PA applications. It works well for average power tracking of the PA, but the instantaneous bias modulation is impossible due to the bandwidth limitation of the switching mode power supply. As the PAPR increases, the efficiency at the specific average power level is so low that the instantaneous bias modulation is essential.

In this paper, a new supply modulator architecture employing a hybrid switching amplifier and a boost converter is proposed. The hybrid switching amplifier (HSA) combines the advantage of the LDO and buck converter and simultaneously achieves high efficiency and linearity [5]-[8]. By boosting up the supply voltage of the linear amplifier to 5V regardless of the battery voltage variation, while that of the buck converter is still coupled to the battery in the HSA, the supply modulator dynamically regulates the PA with the peak voltage of 4.5V. The implemented 2.535GHz ET PA delivers the output power of 25.8dBm with the maximum PAE of 32.3% for 10MHz

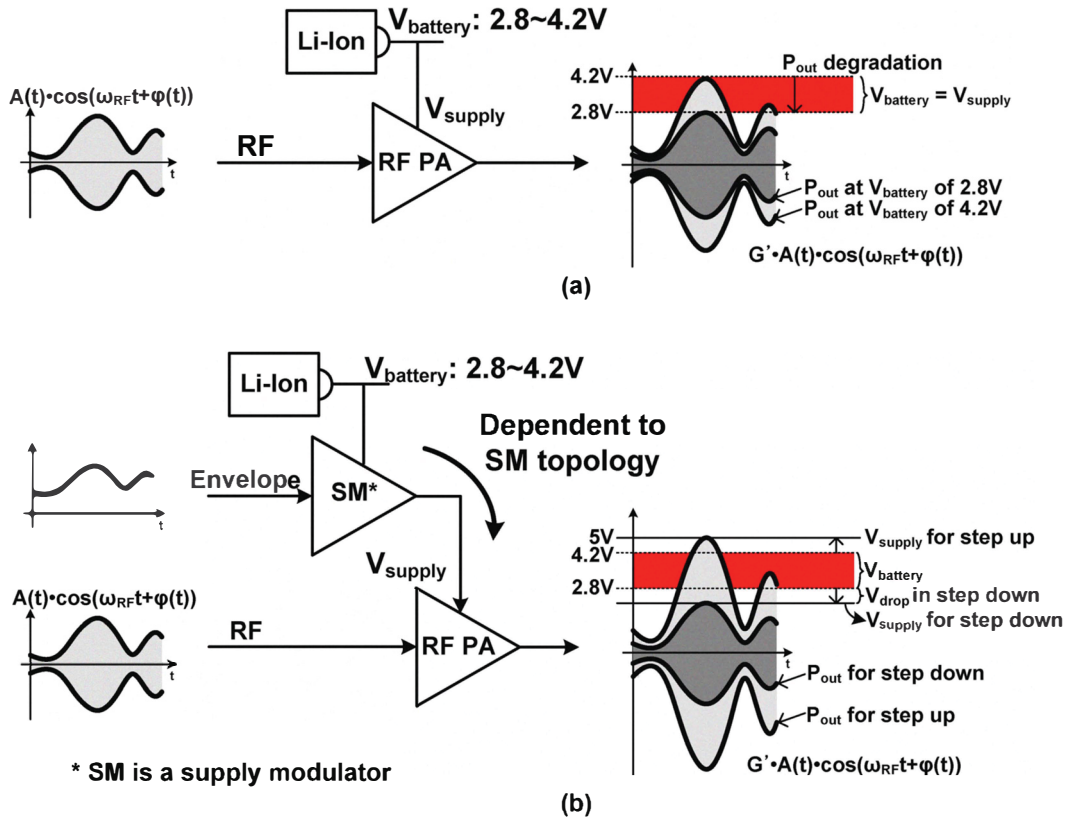


Fig. 2. Battery depletion in (a) general power amplifiers and (b) envelope tracking power amplifiers. In the general PA, the output power is degraded according to the battery depletion. In the ET PA, however, the supply voltage of the PA is coupled to the supply modulator so that it depends on the topology of the supply modulator. With the step-down supply modulator, the regulated supply voltage of RF PA is always lower than the minimum battery voltage, while it is always higher than the maximum battery voltage with the step-up supply modulator.

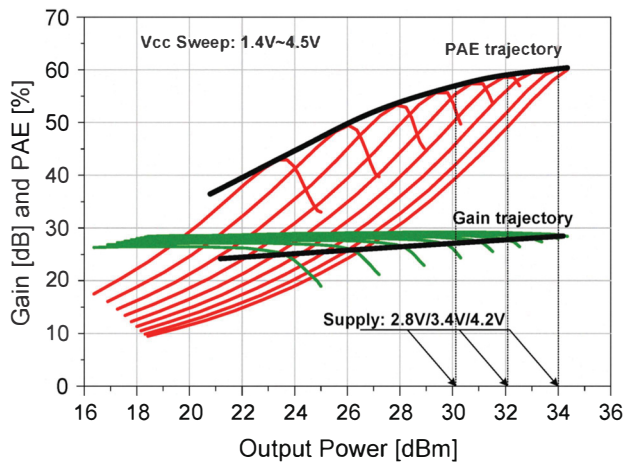


Fig. 3. Simulation results of RF PA: PAE and gain with the supply voltage from 1.4V to 4.5V.

BW 3GPP LTE standard. Thanks to the robust performance of the proposed architecture, there is no degradation of the output power, gain, and linearity with only a slight decrease in efficiency [9].

## II. DESIGN OF ET PA ROBUST TO BATTERY DEPLETION

In the HSA, as shown in Fig. 4, the LDO operates as an independent voltage source with a low output impedance, while the switching buck converter roles as a dependent current source with a high output impedance and supplies most of the current needed at the output. The current sensing unit detects the current flowing from the linear amplifier to the output and it changes the state of the switching amplifier according to the magnitude and polarity of the sensed current. For the control of the switching buck converter, the self-oscillating architecture through the hysteretic operation is employed. Compared with pulse-width modulation, it shows the reduced switching frequency resulting in low switching loss. This is advantageous in the wideband application such as WiMAX and 3GPP LTE.

As the load voltage is regulated by the linear amplifier, boosting up the supply voltage of the linear amplifier results in a stable supply voltage to the RF PA regardless of the battery depletion. Thus, the additional 5V boost converter, whose input range is from 2.8V to 4.2V, is coupled to the supply of the linear amplifier, while that of the switching amplifier is directly connected to the battery as illustrated in Fig. 5. Even though the  $V_{Load}$  in Fig. 5 is instantaneously higher than the battery voltage, the current through the inductor does not flow



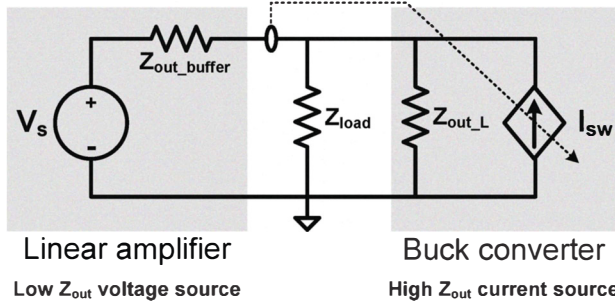


Fig. 4. Simplified block diagram of a hybrid switching amplifier.

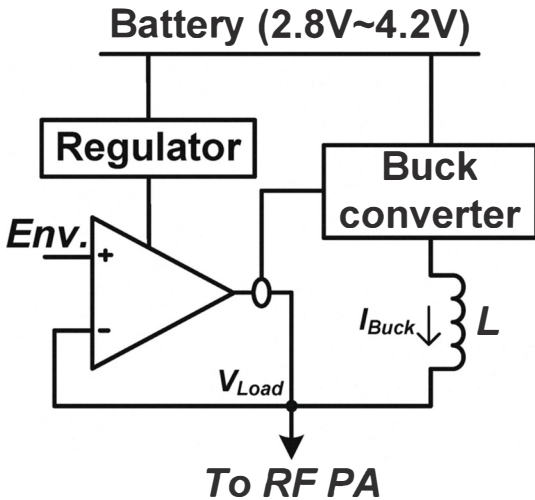


Fig. 5. Battery-to-5V boosting PA supply modulator.

in an opposite direction because the output impedance of the switching buck converter is high enough.

In the proposed architecture, the efficiency degradation by the additional boost converter is not serious because the load current provided by the linear amplifier is about 30% of the overall load current. Assuming that  $\eta_{linear}/\eta_{boost}/\eta_{switch}$  of each block are 50%, 90% and 90%, respectively, the efficiency of the proposed supply modulator is 76.5%, while that of the conventional HSA without the boost converter is 78%. When the boost converter regulates the whole HSA, the supplies of linear amplifier and switching amplifier together, the efficiency drops to 70.2%. There is a 6.3% efficiency improvement of the supply modulator while achieving the robust operation against the battery depletion.

As the supply voltage of the modulator is boosted up to the 5V, considering the 0.5V drop across the modulator, the PA now operates with 4.5V supply voltage. In this case, to meet the 2W output power level, the maximum current of the power cell is 1A while it is 1.6A for the PA with the supply voltage of 3V. It stands for the 1.6 times smaller cell size, and directly results in smaller die size and routing loss, which means the lower cost and higher efficiency. To cover the 3GPP LTE band VII, the PA is designed to operate at 2.535GHz with 70MHz channel bandwidth. With the class-AB bias condition,

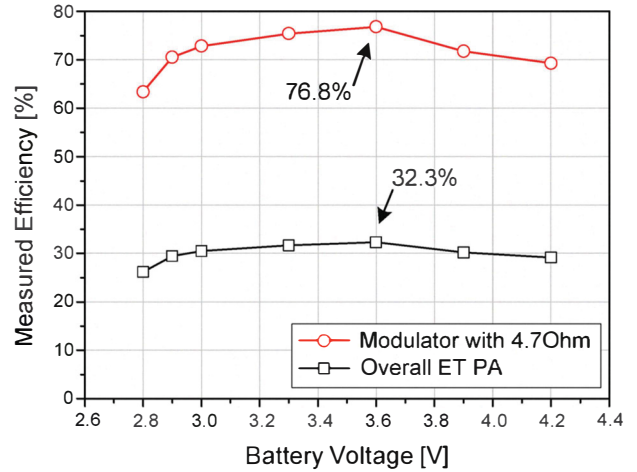


Fig. 6. Measured efficiencies of the 5V boosting envelope tracking PA for 3GPP LTE application.

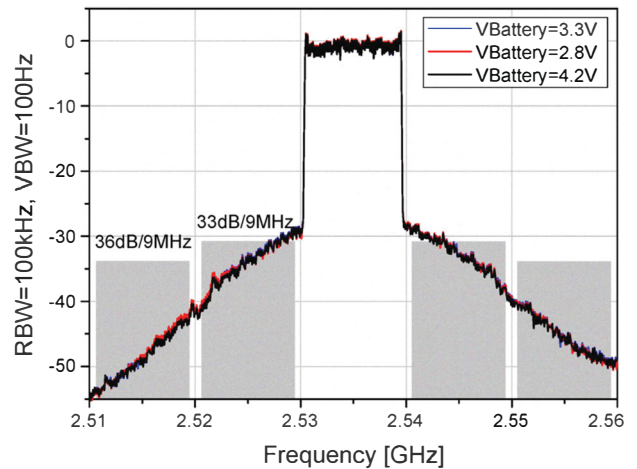


Fig. 7. Measured spectra of the 5V boosting envelope tracking PA for 3GPP LTE application.

the designed two-stage PA delivers 34dBm output power with the 60% PAE.

### III. MEASUREMENT RESULTS

The fabricated supply modulator delivers 4.5V peak voltage 10MHz 3GPP LTE envelope signal to the 4.7Ohm load with the maximum efficiency of 76.8%. The LTE envelope signal is shaped for the linear operation of the RF PA [8]. With 2.535GHz class-AB HBT PA, the ET PA presents the maximum PAE of 32.3% at the average output power of 25.8dBm for 3GPP LTE. The worst-case efficiency of 26.2% is obtained at the supply voltage of 2.8V. The efficiencies over the battery voltage from 4.2V to 2.8V are presented in Fig. 6. The output spectra of the ET PA with various battery voltages are shown in Fig. 7. They satisfy the spectrum emission mask, and there is no degradation of the output power and the linearity according to the battery voltage variation from 4.2V to 2.8V. The proposed supply modulator is fabricated in 0.18um CMOS process with 3.3V compatible I/O devices. The die micrograph

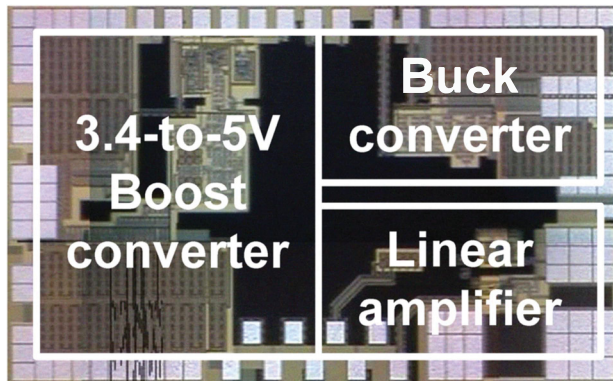


Fig. 8. Microphotograph of the fabricated boosting supply modulator.

of the chip is shown in Fig. 4. The area including all pads is  $2.6 \times 1.7 \text{ mm}^2$ .

#### IV. CONCLUSIONS

The voltage-boosting hybrid switching supply modulator is proposed and designed using the TSMC 0.18 $\mu\text{m}$  CMOS technology. It enables the high voltage operation of the RF PA resulting in the overall performance enhancement over the broad operating frequency range. The fabricated chip is composed of the battery-to-5V boost converter, the linear class-AB amplifier and the highly efficient buck converter. The supply voltage of the linear amplifier is boosted to 5V, and it enables the RF PA operating with the maximum 4.5V supply voltage regardless of the battery depletion. For 10MHz BW 3GPP LTE shaped envelope signal, it provides the maximum output voltage of 4.5V to the 4.7 $\Omega$  resistive load with 76.8% efficiency. With the 2.535GHz class-AB PA, it shows the overall PAE of 32.3% at the output power of 25.8dBm. For the additional boost converter, the proposed supply modulator presents the robust performance over the battery voltage variation while the efficiency degradation is minimized.

#### V. ACKNOWLEDGEMENT

This work was supported by ETRI SoC Industry Promotion Center, Human Resource Development Project for IT SoC Architect, by WCU (World Class University) program through the Korea Science and Engineering Foundation funded by the Ministry of Education, Science and Technology (Project No. R31-2008-000-10100-0), and supported by the Ministry of Knowledge Economy, Korea, under the ITRC (Information Technology Research Center) support program supervised by the IITA (Institute of Information Technology Advancement) (IITA-2009-C1090-0902-0037).

#### REFERENCES

[1] P. Raynaert and S. Steyaert, "A 1.75-GHz polar modulated CMOS RF power amplifier for GSM-EDGE," *IEEE J. Solid-State Circuits*, vol. 40, no. 12, pp. 2598–2608, Dec. 2005.

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## **ATTACHMENT C**



2010

IEEE MTT-S  
INTERNATIONAL



IEEE



MICROWAVE SYMPOSIUM

MAY 23-28, 2010 • ANAHEIM, CALIFORNIA

THE GOLDEN STATE OF MICROWAVES



ANAHEIM  
CALIFORNIA

The text 'ANAHEIM CALIFORNIA' is rendered in large, white, outlined letters. The letters are semi-transparent, allowing a colorful cityscape of Anaheim, California, to be seen through them. The cityscape features various buildings, including a prominent red and yellow structure, and is set against a background of palm trees and a sunset sky. To the left of the text, there is a silhouette of a person standing and looking towards the city.

## Sunday

07:00-08:00 – Workshop and Short Course Breakfast	<b>08:00 Full-Day and Morning Workshops and Short Courses</b>	<b>13:00 Afternoon Workshops</b>
	<b>WSA:</b> Software Defined Radio for Microwave Applications	<b>WSB:</b> Advances in Filtering and Sampling for Integrated Transceivers
	<b>WSC:</b> Interference, Noise and Coupling Effects in Modern SoC and SiP Products: Issues, Problems and Solutions	
	<b>WSD:</b> Ultra-Wideband (UWB) Technology: The State-of-the-Art and Applications	
	<b>WSE:</b> High Speed Signal Integrity Workshop	
	<b>WSF:</b> GaN for High Power, High Bandwidth Applications, Finally Fulfilling the Promise	
	<b>WSG:</b> MOSFET Modeling for RFIC Design Based On the Industry-Standard PSP Model	
	<b>WSH:</b> Power Management for Integrated RF Circuits: Challenges and Solutions	
	<b>WSI:</b> Substrate Integrated Circuits (SICs)	
	<b>WSJ:</b> Re-configurable Multi-Radios at the Nanoscale	
<b>WSK:</b> Multi-Mode Front End Design Challenges and Techniques		
<b>WSL:</b> Silicon-Based Technologies for Millimeter-Wave Applications		
<b>WSM:</b> RF Packaging Solutions for Wireless Communication Platforms		
<b>WSN:</b> The State of Art of Microwave Filter Synthesis, Optimization and Realization		
<b>Registration 07:00-18:00 • RFIC Plenary Session 17:30-19:00 (ACC Room 210)</b>		

## Monday

07:00-08:00 – Workshop and Short Course Breakfast RFIC Attendee Breakfast 07:00-08:00	<b>08:00 Full-Day and Morning Workshops and Short Courses</b>	<b>12:00-13:10 Panel</b>	<b>13:00 Afternoon Workshops</b>
	<b>WMA:</b> SiGe HBTs towards THz Operation	Hubbert's Peak, The Coal Question, and Climate Change (ACC Room 210AB)  The Challenges, Competitions and Future Prospect of 60 GHz (ACC Room 210CD)	<b>WMF:</b> High Efficiency High Power Microwave Amplifiers for High Data Rate Space Communications
	<b>WMB:</b> Advances in Photovoltaic Solar Cell Technology and its Possible Applications in Microwave Communications Systems as an Energy Source		
	<b>WMC:</b> Recent Advancements and Challenges in mm-Wave Applications and Systems		
	<b>WMD:</b> New Microwave Devices and Materials Based on Nanotechnology		
	<b>WME:</b> High-Power-Density Packaging of Gallium Nitride		
	<b>WMG:</b> Ultra-high Speed Microwave and Photonic Devices and Systems: How will they be tested?		
	<b>WMH:</b> 3D Microwave and Millimeter-Wave Packaging		
	<b>WMI:</b> Making Reliable Measurements at Millimeter and Submillimeter Wavelengths		
	<b>WMJ:</b> Recent Advances in Reconfigurable Filters		
<b>WMK:</b> RF MEMS for Antennas and Integrated RF Front End			
<b>SC-1:</b> Theory and Design of Phased Locked Loop			
<b>SC-2:</b> Low Phase Noise Oscillators: Lecture (theory and design) and Laboratory			
<b>SC-2A:</b> Low Noise Oscillators: Lecture Only			
<b>SC-3:</b> Microwave Packaging and Manufacturing 101			
<b>Registration 07:00-18:00 • RFIC Symposium 08:00-17:10</b>			

## Tuesday

07:00-08:00 Attendee breakfast	<b>08:00-09:40 TU1 Oral Sessions</b>	<b>10:10-11:50 Plenary Session</b>	<b>12:00-13:10 Panel</b>	<b>13:20-15:00 TU3 Oral Sessions</b>	<b>15:30-17:10 TU4 Oral Sessions</b>
	<b>TU1A:</b> Novel Guiding and Radiating Structure (ACC Room 203B)	Plenary Session (ACC Third Level Ballroom A-C)	Silicon at THz Frequencies: A Reality or a Dream? (ACC Room 210AB)  Future of High-Speed I/O: Electrical, Optical or Wireless? (ACC Room 210CD)	<b>TU3A:</b> Time-Domain Techniques and Applications (ACC Room 203B)	<b>TU4A:</b> Advances in Space Mapping Technologies (ACC Room 203B)
	<b>TU1B:</b> Metamaterial Structures, Phenomena, and Applications (ACC Room 205AB)			<b>TU3B:</b> Advances in Power Divider/Combiner Technology (ACC Room 205AB)	<b>TU4B:</b> Ultra Wide Band Planar Filters and Devices (ACC Room 205AB)
	<b>TU1C:</b> Submillimeter-Wave Amplifiers and Enabling Components (ACC Room 206AB)			<b>TU3C:</b> III-V Compound Semiconductor Based Microwave Circuit Technology (ACC Room 206AB)	<b>TU4C:</b> Millimeter-Wave Power Amplifiers and Power-Combining Techniques (ACC Room 206AB)
	<b>TU1D:</b> Beamforming and Retrodirective Arrays (ACC 202AB)			<b>TU3D:</b> Advances in Radar Systems for Detection in Detection, Imaging, Mapping and Localization (ACC Room 202AB)	<b>TU4D:</b> Novel Circuit and System Technologies for Wireless Communication (ACC Room 202AB)
				<b>TU3E:</b> Novel Structures, Effects and Techniques (ACC Room 207C)	<b>TU4E:</b> Microwave and Millimeter Wave VCO's (ACC Room 207C)
<b>Registration 07:00-18:00 • IMS Exhibition 09:00-17:00 • Micro Apps 09:10-16:50 • IMS Interactive Forum 15:00-17:00 (ACC Room 204 ABC) • RFIC Symposium 08:00-17:10 • RFIC Interactive Forum 14:00-17:00</b>					

## Wednesday

07:00-08:00 Attendee Breakfast	<b>08:00-09:40 WE1 Oral Sessions</b>	<b>10:10-11:50 WE2 Oral Sessions</b>	<b>12:00-13:10 Panel</b>	<b>13:20-15:00 WE3 Oral Sessions</b>	<b>15:30-17:10 WE4 Oral Sessions</b>
	<b>WE1A:</b> Modeling and Characterization of Devices (ACC Room 205AB)	<b>WE2A:</b> Nonlinear circuit analysis and system modeling (ACC Room 205AB)	Semiconductor Technology Impact on Microwave and Millimeter Wave Markets (ACC Room 210AB)  Standardizing Attributes for RF and Microwave Components and Assemblies - The Time is Now? (ACC Room 210CD)	<b>WE3A:</b> Frequency-domain based modeling of microwave components (ACC Room 205AB)	<b>WE4A:</b> RFID and power harvesting technologies (ACC Room 205AB)
	<b>WE1B:</b> New Synthesis Techniques for Filter and Multiplexers (ACC Room 206AB)	<b>WE2B:</b> Novel Techniques for Planar Filter Design (ACC Room 206AB)		<b>WE3B:</b> Novel 3-dB Coupler Structures (ACC Room 206AB)	<b>WE4B:</b> Novel Transmission Structures and Characterization (ACC Room 206AB)
	<b>WE1C:</b> Advanced Millimeter-Wave Packaging (ACC Room 207AB)	<b>WE2C:</b> Advances in Measurement: Microwaves Through Sub-Millimeter-Waves (ACC Room 207AB)		<b>WE3C:</b> Microwave Photonic Technologies (ACC Room 207AB)	<b>WE4C:</b> Novel Technological Realizations of Filters and Multiplexers (ACC Room 207AB)
	<b>WE1D:</b> Advances in microwave sensors and objects detection systems (ACC Room 207C)	<b>WE2D:</b> RF and Microwave in Medicine: Medical Sensors and Devices (ACC Room 207C)		<b>WE3D:</b> RF and Microwave in Medicine: Imaging and Monitoring (ACC Room 207C)	<b>WE4D:</b> High-speed Signal Processing Circuits for Wireless and Optical Communication Systems (ACC Room 207C)
	<b>WE1E:</b> Advances in Low Noise Technologies (ACC Room 207D)	<b>WE2E:</b> Emerging Technologies for mm to Submm systems (ACC Room 207D)		<b>WE3E:</b> Frequency Conversion and Control Component IC's (ACC Room 207D)	<b>WE4E:</b> Power-Amplifier and Combiner Techniques for HF, VHF, and UHF (ACC Room 207D)
	<b>WE1F:</b> High Efficiency Power Devices in Various Technologies (ACC Room 208AB)	<b>WE2F:</b> Power Amplifiers Systems Concepts (ACC Room 208AB)		<b>WE3F:</b> Techniques to Enhance Power Amplifier Linearity and Efficiency (ACC Room 208AB)	<b>WE4F:</b> Novel Si-based devices and Circuits (ACC Room 208AB)
	<b>WE1G:</b> Status and Trends in E-scan Radar for Air- and Spaceborne Applications (ACC Room 209AB)	<b>WE2G:</b> Trends in Future Systems with Low Cost Phased Array (ACC Room 209AB)		<b>WE3G:</b> Microwave Space Sensors (ACC Room 209AB)	<b>WE4G:</b> CAD Techniques and Methodologies: Future Directions (ACC Room 209AB)
					<b>SPECIAL SESSION IN HONOR OF DR. KIYO TOMIYASU (ACC Room 210AB)</b>
<b>Registration 07:00-18:00 • IMS Exhibition 09:00-18:00 • Micro Apps 09:10-17:50 • IMS Interactive Forum 15:00-17:00 (ACC Room 204 ABC)</b>					

## Thursday

07:00-08:00 Attendee Breakfast	<b>08:00-09:40 TH1 Oral Sessions</b>	<b>10:10-11:50 TH2 Oral Sessions</b>	<b>12:00-13:10 Panel</b>	<b>13:20-15:00 TH3 Oral Sessions</b>	<b>15:30-17:10 TH4 Oral Sessions</b>
	<b>TH1A:</b> Filter Terahertz Electronics (ACC Room 205AB)	<b>TH2A:</b> Wide Bandgap Semiconductor Applications (ACC Room 205 AB)	On-Die Synthesized Inductors: Boon or Bane? (ACC Room 210AB)  RF GaN Reliability: Where does the Technology Stand? (ACC Room 210CD)	<b>TH3A:</b> Advances in Silicon-based Millimeter-Wave Integrated Circuits (ACC Room 205AB)	<b>TH4A:</b> Microwave High Power Processes: Modeling and Applications (ACC Room 205AB)
	<b>TH1B:</b> RF-MEMS Circuits (ACC Room 206AB)	<b>TH2B:</b> RF MEMS Switches and Switched Capacitors (ACC Room 206AB)		<b>TH3B:</b> Ferrite Materials and Devices (ACC Room 206AB)	<b>TH4B:</b> Ferro-Electric and Acoustic Devised and Components (ACC Room 206AB)
	<b>TH1C:</b> Large Signal Measurements (ACC Room 207AB)	<b>TH2C:</b> Phased Array Systems and Integration (ACC Room 207AB)		<b>TH3C:</b> Tunable, active and integrated filter technologies (ACC Room 207AB)	<b>TH4C:</b> Compact reconfigurable filter technology (ACC Room 207AB)
	<b>TH1D:</b> Developments in Microwave Signal Generation (ACC Room 207C)	<b>TH2D:</b> Novel Concepts for Advanced Packaging and Interconnect Technologies (ACC Room 207C)		<b>TH3D:</b> High Power and Broad Band Amplifiers (ACC Room 207C)	<b>TH4D:</b> Advances in Doherty Power Amplifier Technology (ACC Room 207C)
	<b>TH1E:</b> Advances in Active Device Modeling (ACC Room 207D)	<b>TH2E:</b> Advances in MMIC Packaging (ACC Room 207D)		<b>TH3E:</b> The Impact of Nanoelectronics on Radio Frequency Technology (ACC Room 207D)	<b>TH4E:</b> Advances in RFID Circuits and Systems (ACC Room 207D)
		<b>GOLD PANEL SESSION: WE WANT YOU! BUT, WHAT'S IN IT FOR ME? 10:20-11:40 (ACC Room 208AB)</b>			
<b>Registration 07:00-16:00 • IMS Exhibition 09:00-15:00 • Micro Apps 09:10-13:10 • IMS Interactive Forum 09:40-11:40, 15:00-17:00 (ACC Room 204 ABC)</b>					

## Friday

07:00-08:00 – Workshop and Short Course Breakfast	<b>08:00 Full-Day and Morning Workshops and Short Courses</b>
	<b>WFA:</b> The Expanding Role of GaN in RF Systems
	<b>WFB:</b> Wireless Power Transmission
	<b>WFC:</b> Millimeter-Wave SiGe/CMOS and III-V Chips and Imaging Systems
	<b>WFF:</b> New Theories, Applications and Practices of Electromagnetic Field Simulators
	<b>WFG:</b> Emerging Optical Modulator Technologies for RF Photonics
	<b>WFI:</b> Practical Metamaterial RF and Antennas for Commercial Application
<b>ARFTG Conference and Interactive Forum 08:00-17:00 • ARFTG Late Registration 07:00-09:00</b>	

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	<p><b>Newport Harbor Cruise</b> 13:30-16:30</p>	
<p><b>IMS 2010 Welcome Reception</b> 18:00-20:00 Hilton Hotel, Sunset Deck</p>	<p><b>Quiet on the Set!</b> 09:00-14:30</p>	24 May 2010
	<p><b>A Presidential Peek</b> 13:00-17:00</p>	
<p><b>Special Luncheon for Chuck Swift</b> 12:00-14:00 ACC Rooms AR1&amp;2</p>	<p><b>In Vino Veritas- Wine Country of Temecula</b> 8:15-16:30</p>	25 May 2010
<p><b>Women In Engineering Reception</b> 17:30-19:30 Uva Bar Downtown Disney</p>	<p><b>Brushstrokes of Laguna</b> 10:30-14:30</p>	
<p><b>Ham Radio Social</b> 18:00-21:00 Hilton Hotel Room California A</p>		
<p><b>Student Reception</b> 19:00-21:00 Hilton Hotel Room California B</p>		
<p><b>Industry Hosted Cocktail Reception</b> 17:00-18:00 ACC Exhibition Floor</p>	<p><b>The Glitz and Glamour...An Inside Look</b> 10:00-16:30</p>	26 May 2010
<p><b>MTT-S Awards Banquet</b> 19:00-22:00 Hilton Hotel, California Room</p>	<p><b>Windows of Discovery at Bowers Museum</b> 11:15-13:45</p>	
<p><b>MTT-S Student Awards Luncheon</b> 12:00-14:00 Hilton Hotel, California B</p>	<p><b>Landmarks of Long Beach</b> 08:45-14:45</p>	27 May 2010
<p><b>MTT-S Graduates of the Last Decade (GOLD) Reception</b> 17:30-19:00 300 Anaheim</p>	<p><b>Secrets of the Sea</b> 09:00-12:00</p>	
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## WELCOME FROM THE IMS CHAIR

On behalf of the entire 2010 International Microwave Symposium Steering Committee, it is an honor and pleasure to both invite, and welcome, you to Anaheim for Microwave Week. The Steering Committee has endeavored to attract the best workshops, technical papers, sessions, short courses, and microwave exhibition possible from around the world.

During Microwave Week, May 23rd through May 28th, you will be able to participate in the Radio-Frequency Integrated Circuit Symposium ([www.rfic2010.org](http://www.rfic2010.org)), International Microwave Symposium ([www.ims2010.org](http://www.ims2010.org)), and the 75th Automatic Radio-Frequency Test Group Conference ([www.arftg.org](http://www.arftg.org)). In conjunction with the IMS, you will have the opportunity to attend the world's largest microwave industry exhibition featuring over 808 booths from more than 484 exhibitors. Microwave week offers an unmatched opportunity for networking and interacting with leading researchers and professionals from all aspects of radio-frequency and microwave fields.

All registered attendees are encouraged, and welcome, to attend the Plenary Session. This year's Keynote Address is being provided by the Honorable Zachary Lemnios, whose talk is entitled "A Strategic View of Defense Research and Engineering".

An extensive guest program allowing all ages to experience many of the wonderful aspects Anaheim and Southern California has been arranged. A children friendly hospitality suite will be available to assist and provide additional individual options to all guests as needed.

Anaheim has significantly expanded dining and social opportunities since we were last here in 1999. Downtown Disney and the newly completed Garden Walk along with top name restaurants are now available. Local transportation may not be required as these are within easy walking distance. Anaheim Resort Transit is available should one desire.

Please have a wonderful time attending IMS2010 in Anaheim!

Best regards,

JK





# THINGS TO NOTE FOR YOUR ULTIMATE MICROWAVE WEEK EXPERIENCE!

## Plenary Session

The Plenary Session will be held on Tuesday Morning, starting at 10:10 AM. All registered attendees are encouraged to come and hear Honorable Zachary Lemnois, Director of the Defense Research and Engineering Office of the Secretary of Defense. See page 19 for more details.

## Student Paper Competition

The Student Paper Competition posters will be available all day in Room 213AB on Tuesday along with the Student Design Competitions organized by the various Technical Coordinating Committees (TCC's) of the IEEE MTT Society. See pages 21–23 for a complete listing of the Student Paper Finalists and information on the various design competitions.

## Panel Sessions

Panel Sessions present current opinions on hot topics. Order optional and convenient box lunches with your registration so you can keep up to date on the latest topics without skipping lunch!

## Interactive Forum

The IMS Interactive Forum will include demonstrations, hardware, and simulations presented by authors. Authors will be available to discuss their work from 15:00 to 17:00 each afternoon of the IMS, including Tuesday, Wednesday, and Thursday, and in addition, in the morning at 9:40 to 11:40 a.m. on Thursday. All IMS Interactive Forum Sessions will be located in Room 204 ABC. Please review the IMS Technical program section for specifics on the posters.

## MicroApps

Informative MicroApps seminars from vendors of products and services in the microwave industry will be presented daily in the updated MicroApps Theater. Do not miss the “key-note” talks by David Root of Agilent (Nonlinear Analog Behavioral Modeling of Microwave Devices and Circuits) on Wednesday at 9:50 AM and Jim Rautio of Sonnet (Title: A Tutorial on Silicon Spiral Inductor Ground Return Effects on RFIC Design) on Wednesday at 5:20 PM. Please see pages 96 – 97 for the detailed schedule of topics and speakers.

## Exhibition

Free Exhibit Only registration for Wednesday has returned. Come experience the many vendors and learn about recent advances within the Microwave industry. Be sure to be on the exhibit floor on Wednesday afternoon from 5:00 PM to 6:00 PM for the Industry Hosted Reception. Please come and visit as drinks and refreshments will be provided throughout the show floor. A complete list of participating companies is available on pages 92 – 97.

## Hospitality Suite and Guest Program

Families and guests will enjoy the hospitality suite located in the Sheraton Park next door to the Hilton. A children friendly hospitality suite will be available to come and relax in a comfortable, welcoming environment. Please visit pages 99 – 106 to plan your tours and activities while in Anaheim!

## Print on Demand

Print on Demand (PoD) is back again and will be available at a centralized station located in the Registration area at the Anaheim Convention Center. This will allow all registered attendees to print out any paper FREE!





# IEEE AND MTT-S MEMBERSHIPS

## IEEE

The IEEE is a nonprofit, professional association with more than 375,000 members (including 80,00 students) in over 160 countries. This global organization helps support the development and application of technology and science around the world for the benefit of humanity, the individual, and the profession.

## MTT-S

The IEEE Microwave Theory and Techniques Society (MTT-S) is a transnational society with more than 11,000 members and 125 chapters worldwide. Our society promotes the advancement of microwave theory and its applications, at frequencies from 200 MHz to 1 THZ and beyond. As we enter into an exciting future, our mission is to continue to understand and influence microwave technology.

## Benefits of Membership

The benefits of IEEE membership include:

- Discounted conference registration rates
- Subscriptions to the award-winning IEEE Spectrum and online access to IEEE Potentials magazines
- Online access to the tables of contents and expanded abstract from over million IEEE documents with full text-searching capability
- Free IEEE e-mail alias including virus scanning and optional spam filtering
- The IEEE Financial Advantage- negotiated exclusively for IEEE member

## Join the IEEE and MTT-S

Web: <http://www.ieee.org/web/membership/join/join.htm>

Phone:

- (US and Canada): + 1.800.678.4333
- (Worldwide): + 1.732.981.0060

Attendees who join the IEEE for \$84.50 and MTT-S for \$7.00 before the Symposium will save \$195 on their registration fee. The price of an IEEE/MTT-S membership more than pays for itself!

Half-year rates apply to new members only. New applications received between 1 March 2010 and 15 August 2010

will automatically be processed for half-year membership. An exception is if the application specifically requests their application be processed for the full year.

## IEEE and MTT-S Membership Dues

Residence	IEEE Half Year Dues		MTT-S Half Year Dues	
	Member	Student	Member	Student
United States	\$84.50	\$15.00	\$7.00	\$3.50
Canada (Including GST)	\$77.23	\$15.90	\$7.00	\$3.50
Canada (Including HST)	\$82.39	\$17.10	\$7.00	\$3.50
Africa, Europe, Middle East	\$71.00	\$12.50	\$7.00	\$3.50
Latin America	\$66.50	\$12.50	\$7.00	\$3.50
Asia, Pacific	\$67.00	\$12.50	\$7.00	\$3.50

The optional MTT-S dues include a subscription to IEEE Microwave Magazine. MTT-S members can also purchase electronic and print subscriptions to the IEEE Transactions on Microwave Theory and Techniques, IEEE Microwave and Wireless Components Letter, IEEE/OSA Journal of Lightwave Technology, and IEEE MTT CD-Rom Collection. See IEEE Membership website for pricing.

# ADVANCE REGISTRATION

## Registration Categories

The Registration process is split into three tiers in order to better serve membership needs. The 1st tier is the **Early Bird Registration** period. It begins Tuesday, January 19th and will last through Friday, May 7th. This period provides an opportunity to register for the Symposium at the lowest possible cost. Immediately following the Early Bird period is the 2nd tier or **Advance Registration** period. It extends from Saturday May 8th through Friday, May 21st, just prior to the start of **Microwave Week**. The 3rd and final tier is the **On-Site Registration** period that will remain the same as in past Symposia, starting on Saturday May 22nd, the first day of Microwave Week, and ending on Friday, May 28th.

<b>Early Bird Period</b>	<b>January 19th</b>	<b>May 7th (thru midnight PST)</b>
<b>Advance Period</b>	<b>May 8th</b>	<b>May 21st (thru midnight PST)</b>
<b>On-Site Period</b>	<b>May 22nd</b>	<b>May 28th (throughout Microwave Week)</b>

## Symposium SUPERPASS

The Symposium **SUPERPASS**. For one low price, registrants can attend as many technical sessions as they can from any of the three contributing organizations, MTT, RFIC, and ARFTG, as well as attend one full-day workshop (or two half-day workshops, if desired). In addition, the **SUPERPASS** will allow you to attend the Awards Banquet on Wednesday and the Symposium Reception on Thursday.

The **SUPERPASS** is a **SUPER DEAL** offering a **15% discount** over the combined ala-carte pricing.

## Early Bird Registration

Please follow these instructions for completing the Early Bird Registration Form on the facing page. Early Bird Registration rates provide significant savings from the on-site fees shown on page 10 of this Program Book and are available through midnight May 7th. Registration is required for all attendees including SESSION CHAIRS and PRESENTERS. Only paid attendees will be admitted to the breakfasts, workshops, technical sessions, and Exhibition Hall. This form is not used for guest tour registration, which is described elsewhere in this Program Book. Each registrant must submit a separate form with payment.

## 1) Methods of Registration

Individuals can register online, by fax or by mail. All registrations must be accompanied with a payment; we accept Visa, MasterCard, American Express, and checks drawn from a U.S. bank. Registration forms received without a form of payment will be discarded. We do NOT accept phone registrations.

## 2) Personal Information

If you would like to receive information by email from the IEEE, MTT-S, or microwave companies, simply select the appropriate boxes. An optional complimentary badge for one guest allows access to the Hospitality Suite, Plenary Session, and Exhibition Hall, but does not allow access to Technical Sessions and Workshops.

## 3) Membership

Check boxes of all organizations of which you are a member. To receive IEEE member rates, enter your member number and present your IEEE card upon check in at the conference. Registrants who do not have a current IEEE membership card at check in will be charged non-member rates. If you are not a member and would like to learn about the advantages of being a member and receiving the conference member rate, please visit [www.ieee.org/services/](http://www.ieee.org/services/) join or call 1-800-678-IEEE. Please note that you must be a member at the time of registration to receive the member rate.

## 4) Symposia

Microwave Week includes the IMS Technical program ([www.ims2010.org](http://www.ims2010.org)), and Exhibition, as well as the RFIC Symposium ([www.rfic2010.org](http://www.rfic2010.org)), and ARFTG Conference ([www.arftg.org](http://www.arftg.org)).

Select the conference(s) you wish to attend. Students, Retiree's, and IEEE Life Members receive a discount on some registration fees. To qualify as a student, a registrant must be either an IEEE Student Member or a full time student carrying a course load of at least nine credit hours.

- IMS Technical Sessions are held on Tuesdays, Wednesday, and Thursday. Registration includes continental breakfast, admission to the exhibits, abstract books, and a CD ROM.
- RFIC Technical Sessions are held on Monday and Tuesday. Registration includes continental breakfast, admission to the RFIC, Reception, and Exhibition
- ARFTG Technical Sessions are held on Friday. Registration includes breakfast, lunch, a CD-ROM, and admission the ARFTG Exhibition. ARFTG Conference member rates are available to both ARFTG and IEEE Members.
- Microwave Week hosts the largest exhibition of its kind with over 400 companies. Exhibit only registration is available.

## 5) Extra CD-ROMs and Digests

Additional CD ROMS (IMS, RFIC, and ARFTG) and digests (RFIC only) are available for purchase and pickup at the conference. After the Symposium, these digests and CD ROMS will be available for purchase from IEEE.

## 6) Awards Banquet

The MTT Awards Banquet will be held on Wednesday, May 26 from 6:30 to 10:00pm at the Hilton Anaheim. The evening will include fine dining, an awards presentation, and excellent entertainment. Major Society Awards will be presented.

## 7) Boxed Lunches

Optional boxed lunches are available for purchase by all attendees but are especially convenient for those attending the panel sessions or exhibition hall during lunchtime. Please purchase boxed lunches before Microwave Week. Boxed lunches are NOT available for purchase on-site. Refunds for lunches will not be available since they are ordered in advance.

## 8) Workshops

The workshop fee includes a CD ROM and speaker's notes for that workshop. Full-day workshops include a continental breakfast, a morning refreshment break, a boxed lunch, and an afternoon refreshment break. Morning workshops include a continental breakfast, a morning refreshment break, and a boxed lunch. Afternoon workshops include a boxed lunch and an afternoon refreshment break. The All-Workshop DVD-ROM includes material for all RFIC and IMS workshops on one DVD-ROM, but the DVD-ROM price alone does not include admission to any workshops. Note: Registrants can save by selecting a combined Workshop (one full-day or two half-day workshops) and All-Workshop DVD-ROM.

## 9) Payment

Individual payment must accompany the registration form and is payable in U.S. dollars only, using a personal check drawn on US bank or credit card (VISA, MasterCard, or American Express only). Bank drafts, wire transfers, cash, international money order, and purchase orders are unacceptable and will be returned. Personal checks must be encoded at the bottom with the bank, bank account number, and check number. Bank drafts, wire transfers, cash, and purchase orders are UNACCEPTABLE and will be returned. Please make checks payable to "2010 IEEE IMS". Written requests for refunds will be honored if received by May 7, 2010. Refer to the Refund Policy for complete details.



2010

IEEE MTT-S  
INTERNATIONAL  
MICROWAVE SYMPOSIUM

MAY 23-28, 2010 • ANAHEIM, CALIFORNIA  
THE GOLDEN STATE OF MICROWAVES

IMS - RFIC - ARFTG Registration Form  
Anaheim Convention Center  
May 23-28, 2010



**1** All Early Bird and Advance registration must be received by **online:** [www.mpassociates.com/IMS2010/IMS\\_registration.html](http://www.mpassociates.com/IMS2010/IMS_registration.html) **by mail:** IMS 2010 Registration, MP Associates, Inc.  
May 7 and May 21, respectively, for appropriate costs to apply. **by fax:** +1 (303) 530-4334  
1721 Boxelder St. Suite 107  
Louisville, CO 80027 USA

### 2 Attendee Information

First Name										Last Name														
Company																				Mail Stop				
Address:																								
Street					City																			
State		Postal Code			Country			Email																
Telephone										IEEE Membership #					Member of: <input type="radio"/> MTT-S <input type="radio"/> ARFTG									

### Guest Information:

First Name										Last Name									
Email										I would you like to receive emails from: <input type="checkbox"/> IEEE and MTT-S <input type="checkbox"/> Industry									

### 3 Attendee Survey

#### 1) What is your principal job function?

- 101 Executive/Senior Management
- 102 Engineering Management
- 103 Design Engineering
- 104 Engineering Services
- 105 Manufacturing/Production Engineering
- 106 Application Engineer
- 107 Procurement/Purchasing
- 108 Professor/Research - Academic
- 109 Research & Development - Government
- 110 Research & Development - Industry
- 111 Student
- 112 Financial or Industry Analyst
- 113 Editor/Publisher
- 114 Marketing/Sales
- 115 Consultant
- 116 Other \_\_\_\_\_

#### 2) What primary end product or service do you work on?

- 201 Communication systems, equipment
- 202 Wireless (WiFi, WiMAX, UWB)
- 203 Government - Military
- 204 Government - Other
- 205 Defense Electronics
- 206 Medical Electronics
- 207 Navigation/telemetry/GPS systems
- 208 Industrial automation/control systems
- 209 Transportation (Automotive/Aviation)
- 210 Consumer Electronics
- 211 Computers or peripherals
- 212 Test & Measurement

- 213 Components/Hardware
- 214 Data Transmission
- 215 Semiconductors & Ics
- 216 Materials
- 217 Services
- 218 Software
- 219 Other \_\_\_\_\_

#### 3) Which products and/or services in the following areas do you recommend, purchase or influence the purchase of? (Answer all that apply)

- 301 Active Components
- 302 Antennas
- 303 Control Components
- 304 Materials
- 305 Manufacturing Equipment
- 306 Optoelectronics & Fiber-Optics
- 307 Passive Components
- 308 Semiconductors/Integrated Circuits
- 309 Services
- 310 Signal Processing Components
- 311 Software & CAD
- 312 Subsystems & Systems
- 313 Test Equipment and Instruments
- 314 Transmission-Line Components

#### 4) At what frequency is your primary work?

- 401 RF
- 402 Microwave
- 403 Both
- 404 Other \_\_\_\_\_

#### 5) Number of engineers in your

#### organization

- 501 10 or fewer
- 502 11 to 40
- 503 41 to 100
- 504 More than 100

#### 6) Which hotel will you be using while in Anaheim?

- 601 Hilton Anaheim Headquarter Hotel
- 602 Anabella Hotel
- 603 Best Western Stovall's Inn
- 604 Clarion Hotel Anaheim Resort
- 605 Crowne Plaza
- 606 Hyatt Regency Orange County
- 607 Portofino Inn & Suites
- 608 Red Lion Anaheim Maingate Hotel
- 609 Sheraton Park Hotel at the Anaheim Resort
- 610 Desert Palms Hotel & Suites
- 611 Other Hotel
- 612 Other Accomadations
- 613 Local - no accommodations

#### 7) Is this the first time you have attended International Microwave Week?

- 701 Yes
- 702 No

#### 8) Are you an MTT member?

- 801 Yes
- 802 No

IMS provides an email list of attendees to exhibitors. If you do NOT want to receive this correspondence, check here:

#### 4 Registration Pricing

##### Superpass

All IMS, RFIC, & ARFTG Sessions, Awards Banquet, & All Workshop DVD (RFIC/IMS) plus Full Day (or 2 Half Day) Workshop Attendance

##### IMS

All IMS Sessions  
All IMS Sessions (No CD-ROM)  
Single Day Registration

##### RFIC Symposium

All RFIC Sessions  
RFIC Reception Only

##### ARFTG Conference

All ARFTG Sessions

##### Exhibition

Exhibition Only Pass  x \$20  
Wednesday Exhibition Only Pass  x FREE

#### Early Bird (1/19 - 5/7)

IEEE or ARFTG Membership Member Student, Retiree, Life Member Non-Member

#### Advance (5/8 - 5/21)

IEEE or ARFTG Membership Member Student, Retiree, Life Member Non-Member

#### Cost

<input type="radio"/> \$995	<input type="radio"/> \$595	<input type="radio"/> \$1,495	<input type="radio"/> \$1,195	<input type="radio"/> \$695	<input type="radio"/> \$1,745	\$ <input type="text"/>
<input type="radio"/> \$405	<input type="radio"/> \$70	<input type="radio"/> \$600	<input type="radio"/> \$485	<input type="radio"/> \$80	<input type="radio"/> \$720	\$ <input type="text"/>
<input type="radio"/> \$350		<input type="radio"/> \$540	<input type="radio"/> \$415		<input type="radio"/> \$610	\$ <input type="text"/>
<input type="radio"/> \$205		<input type="radio"/> \$300	<input type="radio"/> \$255		<input type="radio"/> \$355	\$ <input type="text"/>
<input type="radio"/> \$220		<input type="radio"/> \$320	<input type="radio"/> \$250		<input type="radio"/> \$370	\$ <input type="text"/>
<input type="radio"/> \$55		<input type="radio"/> \$75	<input type="radio"/> \$60		<input type="radio"/> \$80	\$ <input type="text"/>
<input type="radio"/> \$210	<input type="radio"/> \$130	<input type="radio"/> \$310	<input type="radio"/> \$240	<input type="radio"/> \$145	<input type="radio"/> \$360	\$ <input type="text"/>
						\$ <input type="text"/>
						\$ <input type="text"/>

#### 5 Extra CDs & Digests

IMS CD-ROM <input type="text"/> x \$60	<input type="text"/> x \$110	<input type="text"/> x \$75	<input type="text"/> x \$140	\$ <input type="text"/>
RFIC Digest <input type="text"/> x \$60	<input type="text"/> x \$110	<input type="text"/> x \$75	<input type="text"/> x \$140	\$ <input type="text"/>
RFIC CD-ROM <input type="text"/> x \$60	<input type="text"/> x \$110	<input type="text"/> x \$75	<input type="text"/> x \$140	\$ <input type="text"/>
ARFTG CD-ROM <input type="text"/> x \$60	<input type="text"/> x \$110	<input type="text"/> x \$75	<input type="text"/> x \$140	\$ <input type="text"/>
ARFTG Conf. Compendium CD-ROM 1982-2006 <input type="text"/> x \$65	<input type="text"/> x \$90	<input type="text"/> x \$65	<input type="text"/> x \$90	\$ <input type="text"/>

#### 6 Events

Special Luncheon for Chuck Swift (Tuesday) <input type="text"/> x \$35	<input type="text"/> x \$35	<input type="text"/> x \$35	<input type="text"/> x \$35	\$ <input type="text"/>
Awards Banquet (Wed. Night) <input type="text"/> x \$50	<input type="text"/> x \$50	<input type="text"/> x \$60	<input type="text"/> x \$60	\$ <input type="text"/>

#### 7 Lunch

Boxed Lunches <input type="radio"/> Mon <input type="radio"/> Tues <input type="radio"/> Wed <input type="radio"/> Thur <input type="text"/> x \$20	<input type="text"/> x \$20	<input type="text"/> x \$20	<input type="text"/> x \$20	\$ <input type="text"/>
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#### 8 Workshops and Short Courses

Full Day Workshops: WSC WSD WSE WSF WSH WSI WSJ WSK WSL WSM WSN  
WMA WMB WMC WMD WMH WMI WMJ WMK WFC WFF WFG

Half Day Workshops: WSA WSB WSG WME WMF WMG WFA WFB WFH WFI

Full Day Short Course: SC1 SC2  
Half Day Short Course: SC2A SC3

Full Day Workshops <input type="text"/> x \$160	<input type="text"/> x \$110	<input type="text"/> x \$230	<input type="text"/> x \$190	<input type="text"/> x \$130	<input type="text"/> x \$280	\$ <input type="text"/>
Half Day Workshops <input type="text"/> x \$110	<input type="text"/> x \$80	<input type="text"/> x \$180	<input type="text"/> x \$145	<input type="text"/> x \$95	<input type="text"/> x \$210	\$ <input type="text"/>
Full Day Short Course SC1 <input type="text"/> x \$285	<input type="text"/> x \$200	<input type="text"/> x \$410	<input type="text"/> x \$340	<input type="text"/> x \$230	<input type="text"/> x \$500	\$ <input type="text"/>
Full Day Short Course SC2 (class and lab) <input type="text"/> x \$335	<input type="text"/> x \$250	<input type="text"/> x \$460	<input type="text"/> x \$390	<input type="text"/> x \$280	<input type="text"/> x \$550	\$ <input type="text"/>
Half Day Short Courses <input type="text"/> x \$200	<input type="text"/> x \$140	<input type="text"/> x \$320	<input type="text"/> x \$260	<input type="text"/> x \$170	<input type="text"/> x \$375	\$ <input type="text"/>
All Workshop DVD (RFIC/IMS) <input type="text"/> x \$240	<input type="text"/> x \$165	<input type="text"/> x \$345	<input type="text"/> x \$285	<input type="text"/> x \$195	<input type="text"/> x \$420	\$ <input type="text"/>
All Workshop DVD (RFIC/IMS) with attendance* <input type="text"/> x \$315	<input type="text"/> x \$220	<input type="text"/> x \$460	<input type="text"/> x \$375	<input type="text"/> x \$260	<input type="text"/> x \$545	\$ <input type="text"/>

\*Includes One Full Day Workshop or Two Half Day Workshops

#### 9

Card Number         Expiration Date  /  Total Remittance: \$

MasterCard  Visa  American Express Security Code     Signature: \_\_\_\_\_

#### 10 Submit via Fax or Mail to:

Make checks payable to: **IMS2010**

**IMS2010** Fax registrations accepted with credit card payment only!  
Attn: Registration Desk Phone Number: (303) 530-4562  
1721 Bolxelder St., Ste 107 Louisville, CO 80027 USA Fax Number: (303) 530-4334

Refund Policy: Written requests for cancellations received on or before May 7, 2010, will be honored. Cancellations received after May 7, 2010 will NOT be honored and all registration fees will be forfeited. **After May 14, 2010, faxed registrations will not be accepted in office - You MUST register on-site.** **TELEPHONE REGISTRATIONS WILL NOT BE ACCEPTED! ANY REGISTRATION WITHOUT PAYMENT WILL BE DISCARDED!** If payment is received from a non-US bank, attendees will be charged a collection fee of \$45.00.



# ON SITE REGISTRATION

## On Site Registration

On Site registration for all Microwave Week events will be available in the Anaheim Convention Center Lobby C. Registration hours are:

Day	Time
Saturday, May 22	14:00 – 17:00
Sunday, May 23	07:00 – 18:00
Monday, May 24	07:00 – 18:00
Tuesday, May 25	07:00 – 18:00
Wednesday, May 26	07:00 – 18:00
Thursday, May 27	07:00 – 16:00
Friday, May 28	07:00 – 09:00

## Exhibit Only Registration

Exhibit only registration is available.

## Guest Tour Registration

Registration for guest tours will be available in the hospitality suite in the Garden Terrace Room at the Sheraton Park Hotel. Please refer to the Guest Tour Program section of this program book for further details and tour descriptions.

## Press Registration

Credentialed press representatives are welcome to register without cost, receiving access to technical sessions and exhibits. Digests are not included. The Press Room will be available from Tuesday thru Friday of Microwave Week.

## ARFTG Registration

Late on-site registration will be available at the Anaheim Convention Center Lobby C on Friday from 7:00 to 9:00am. If at all possible, please pre-register earlier in the week to reduce the on-site workload.

## Refund Policy

Written requests received by May 7, 2010 will be honored. Refund requests postmarked after this date and on-site refunds will be generated only if an event is cancelled. This policy applies to the registration for the symposium sessions, workshops, digests, extra CD-ROM's, awards banquet and boxed lunches. Please state the pre-registrants name and provide an email address for the refund check. If registration was paid for by credit card, the refund will be made through an account credit. An account number must be provided if the initial registration was completed on-line. Address your requests to:

## MTT-S Registration

Nannette Jordan  
 MP Associates  
 1721Boxelder St. Ste. 107  
 Louisville, CO 80027  
 nannette@mpassociates.com

## Registration Fees

On-site registration fees are as follows:

	Member	Non-Member
<b>SuperPass</b>		
All IMS, RFIC, and ARFTG Sessions, Awards Banquet, and All Workshop CD (RFIC/IMS) + Full Day (or 2 Half Day) Attendance	1295	1895
Student, Retiree, Life Member SuperPass	745	
<b>IMS</b>		
All IMS Sessions	525	785
All IMS Sessions (No CD ROM)	450	665
Single Day Registration	275	385
Student, Retiree, Life Member All IMS Sessions	85	
<b>RFIC Symposium</b>		
All RFIC Sessions	270	400
RFIC Reception Only	65	85
<b>ARFTG Conference</b>		
All ARFTG Sessions	260	390
Student, Retiree, Life Member All ARFTG Sessions	160	
<b>Exhibition Only</b>		
Exhibition Only Pass	25	25
Wednesday Exhibition Only Pass	FREE	FREE
<b>Extra CD's and Digests</b>		
IMS CD-ROM	80	150
RFIC Digest	80	150
RFIC CD ROM	80	150
ARFTG CD-ROM	80	150
ARFTG Conference Compendium CD-ROM 1982 - 2006	65	90
<b>Events</b>		
Special Luncheon for Chuck Swift (Tuesday)	35	35
Awards Banquet (Wed. Night)	75	75
<b>Workshops</b>		
Full Day	205	305
Half Day	155	230
Full Day Short Courses	365	540
Full Day Short Course w/Lab	415	590
Half Day Short Course	275	410
All Workshop CD (RFIC/IMS)	308	458
All Workshop CD (RFIC/IMS) plus Full Day (or 2 Half Day) Attendance	405	595

# UNITED STATES VISA ADVISORY

The United States has updated its visa policy for increased security. As a result, it now takes longer to obtain a visa. Advance planning by travelers is essential to avoid frustration and disappointment.

- Review your visa status to find out if you need a U.S. visa or a visa renewal.
- Plan to submit your visa application well in advance of your intended departure date.
- Contact your nearest U.S. embassy or consulate for current time estimates and recommendations.
- Visit the embassy or consular section website to find important information on how to schedule an interview appointment and pay fees. An interview is required as a standard part of processing for most visa applicants.
- Plan on having finger scans as part of the visa application process. Two index-finger scans are normally collected by the consular officer at the visa interview window. However; in some countries, they may be collected prior to the actual visa interview.

## Visa Waiver Program (VWP)

Citizens of the following countries can travel to the U.S. without a visa for tourism or business for 90 days or less under the Visa Waiver Program (VWP) if they meet other travel requirements. As of June 26, 2005, all VWP travelers must have a machine-readable passport to enter the United States without a visa.

Andorra	France	Lithuania	Singapore
Australia	Germany	Luxembourg	Slovakia
Austria	Hungary	Malta	Slovenia
Belgium	Iceland	Monaco	South Korea
Brunei	Ireland	the Netherlands	Spain
Czech Republic	Italy	New Zealand	Sweden
Denmark	Japan	Norway	Switzerland
Estonia	Latvia	Portugal	United Kingdom
Finland	Liechtenstein	San Marino	

Some citizens of Canada and Bermuda do not need a visa to visit the United States. Contact your nearest U.S. embassy or consulate for guidance. Travelers should be aware that by requesting admission under the Visa Waiver Program, they are generally waiving their right to review or appeal a CBP (Customs and Border Protection) officer's decision as to their application for admission at the port of entry

Effective January 20, 2010, the Department of Homeland Security is transitioning to enforced compliance of the Electronic System for Travel Authorization (ESTA) requirement for VWP travelers. Therefore, VWP travelers who have not obtained approval through ESTA should expect to be denied boarding on any air carrier bound for the United States. ESTA applications may be completed FREE online at the official DHS website, which is: <https://esta.cbp.dhs.gov>

## Passports

A passport with a validity date of at least six months beyond the applicant's intended period of stay in the U.S. is required. If more than one person is included in the passport, each person desiring a visa must make a separate application. Please check with the website, <https://www.cbp.gov>, to confirm that your passport is compliant. Temporary Passports will likely merit special scrutiny. To avoid complications, check with your local US consular offices, well ahead of your intended departure dates.

## Visa Letters

A visa support letter can be provided for authors and registered attendees upon request. Please submit your requests for letters of support well in advance of your interview dates to allow sufficient time for processing. Spouses requiring visa assistance must be registered for an IMS Guest Program Event. Check the IMS 2010 website ([www.ims2010.org](http://www.ims2010.org)) for Guest Program details. For additional assistance, please contact Dr. Zaher Bardai at [zb@ieee.org](mailto:zb@ieee.org)

## Disclaimer

This information is provided in good faith but travel regulations do change. The only authoritative sources of information are the U.S. Government websites at [www.unitedstatesvisas.gov](http://www.unitedstatesvisas.gov) and [http://travel.state.gov/visa/visa\\_1750.html](http://travel.state.gov/visa/visa_1750.html).



# Accommodations:



The IMS2010 has secured special rates for Attendees at the official IMS2010 hotels in Anaheim. The map below shows the location and rates of these hotels.

For advanced hotel reservations, visit [www.ims2010.org](http://www.ims2010.org) for online reservations, or submit the Attendee Housing Form by fax or postal mail before 16 April 2010.

**ANAHEIM**  
hotel locator map

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**IMS 2010**

- 1 Hilton Anaheim Headquarter Hotel
- 2 Anabella Hotel
- 3 Best Western Stovall's Inn
- 4 Clarion Hotel Anaheim Resort
- 5 Crowne Plaza
- 6 Desert Palms
- 7 Hyatt Regency Orange County
- 8 Portofino Inn & Suites
- 9 Red Lion Anaheim Maingate Hotel
- 10 Sheraton Park Hotel at the Anaheim Resort

Number on Map	Hotel Name	Rate
1	Hilton Anaheim- Headquarter Hotel	\$215 Standard Guest Rooms \$235 Lanai Guest Rooms \$255 Executive Guest rooms
2	Anabella Hotel	\$149 Single/Double Room
3	Best Western Stovall's Inn	\$129 Single/Double Room
4	Clarion Hotel Anaheim Resort	\$129 Single/Double Room
5	Crowne Plaza	\$159 Single/Double
6	Desert Palms	\$140 Standard Deluxe \$159 Tanami Suites \$159 Mohave Suites \$179 Borrego Suites \$199 Sahara Kitchen Suites
7	Hyatt Regency Orange County	\$199 Single/Double
8	Portofino Inn & Suites	\$135 Deluxe Room \$159 Suite
9	Red Lion Anaheim Maingate Hotel	\$149 Single/Double Room
10	Sheraton Park Hotel at the Anaheim Resort	\$199 Single/Double Room

**All reservation requests must be received by 16 April 2010.**

Changes to existing reservations may be made through the housing bureau until 16 April 2010. Listed convention rates available until 16 April 2010 based on availability.

**Online:**

www.ims2010.org

**Fax:**

1-732-465-6447

**Mail:**

IMS 2010 Housing Bureau  
IEEE Meetings & Conference Management  
445 Hoes Lane, Piscataway, NJ 08854

**Instructions and Housing Bureau Policies:**

1. Acknowledgements will be sent after each reservation booking, modification and/or cancellation. If you do not receive a confirmation via e-mail within 24 hours after any transaction, contact the Housing Bureau by phone or e-mail. You will not receive a confirmation from the hotel.
2. All rates are per room, per night and are subject to 15% tax (subject to change).
3. Request room and bedding and please indicate special requests in the section provided on the form. Specific room types will be assigned at check-in. Please be advised that requests are not guaranteed.
4. A credit card is needed to guarantee a room reservation. Credit cards must be valid through June 2010 to be used for deposits.
5. Changes, modifications and cancellations prior to 16 April 2010 must be made in writing through the Housing Bureau. Reservations guaranteed by a credit card may be cancelled without penalty until 16 April 2010 after which a \$15.00 fee will be charged for each cancellation.
6. Any hotel reservation changes or cancellations after 16 April 2010 must be made with the hotel directly.
7. You will receive your hotel confirmation number three weeks before the start of the 2010 IMS Conference.

**Housing Reservation Information:**

Full Name: \_\_\_\_\_

E-mail Address: \_\_\_\_\_

Company: \_\_\_\_\_

Address: \_\_\_\_\_

City: \_\_\_\_\_ State: \_\_\_\_\_ Zip: \_\_\_\_\_

Country: \_\_\_\_\_ Daytime Phone: \_\_\_\_\_ Fax: \_\_\_\_\_

Frequent Hotel Stay Number: \_\_\_\_\_

Credit Card Type (Circle):    MasterCard    Visa    Amex    Discover

Cardholder Name (As it appears on card) \_\_\_\_\_

Cardholder Signature (REQUIRED) \_\_\_\_\_

Card Number: \_\_\_\_\_ Exp. Date \_\_\_\_\_

Hotel names, locations and rates are on the facing page. Please list a minimum of three choices.

First Choice: \_\_\_\_\_ Second Choice: \_\_\_\_\_ Third Choice: \_\_\_\_\_

First Choice Rate: \_\_\_\_\_ Second Choice Rate: \_\_\_\_\_ Third Choice Rate: \_\_\_\_\_

Arrival Date \_\_\_\_\_ Departure Date \_\_\_\_\_

If hotel choice is not available, which is most important:    Rate: \_\_\_\_\_ or Location \_\_\_\_\_ (Please select one)

Special Requests

Government Rate    King Bed    Two Beds    Wheelchair Accessible

Other Requests \_\_\_\_\_

If more than one room is required, attach a list of occupants names and the above information for each additional room.





# WELCOME TO ANAHEIM AND ORANGE COUNTY!

Popularly recognized as The OC, this world-class visitor destination is the center of Southern California fun located between Los Angeles and San Diego. OC's second largest city is Anaheim - the perfect starting point for your OC adventures. You'll find plenty of things to see and do: inviting beaches, unparalleled shopping and entertainment, trendy restaurants, abundant nightlife, championship golf, lively art districts, beautiful historic landmarks and the ultimate family attractions. Warm sunshine, swaying palm trees and breathtaking ocean views create a relaxed lifestyle where shorts, sandals and sunglasses are always in style.



## THE HISTORY OF ANAHEIM:

More than 150 years ago, German colonists came to the land that is now Anaheim to grow grapes and produce wine. The original purchase price? A humble \$2.00 an acre!

The city's name was originally spelled "Annaheim." "Anna" was taken from the nearby Santa Ana River, a vital part of the early settlers and farmers life and named for Saint Anne by Spanish explorers. The word "Heim" is the German word for home, so the name meant "home by the Santa Ana River." Today, the second "n" is dropped, blending Spanish (Ana) with German (heim)

Anaheim was the wine capital of California for many years, but in the late 1880s a blight completely wiped out the vineyards, thus ending the thriving industry.

Then, the orange industry developed and grew, as did the prosperous new city of Anaheim. The area remained a booming agricultural community until post World War II.

On July 17, 1955, an enterprising visionary named Walt Disney opened the doors of his fabled "magic kingdom" - Disneyland.

Only 11 years later, in 1966, Anaheim Stadium was built. It is currently the home field of Major League Baseball's Angels. Just across the street from the baseball stadium is the Honda Center, a 19,200-seat state-of-the-art entertainment facility and home ice for National Hockey League's Anaheim Ducks - 2006/07 Stanley Cup Champion.

The Anaheim Convention Center was built in 1967 directly across from Disneyland and received five major expansions since its opening. The fifth expansion, which was completed in December 2000, gave the center a total 1.6 million gross square feet, making it the largest convention center on the West Coast. The latest expansion of the Anaheim Convention Center was part of a \$5 billion renovation now called The Anaheim Resort™ district. The 1,100-acre garden district encompasses the Anaheim Convention Center and the Disneyland® Resort, which features Disneyland® Park, Disney's California Adventure™ Park and Downtown Disney District. Today, the Resort is also home of the Anaheim Arsenal NBA D-League team and the USA Men's National Volleyball team. Anaheim is now the second largest city in Orange County and is the center of Orange County's visitor industry, which attracts nearly 45 million people annually.

IMS 2010 is pleased to offer a complete Guest tour program which can be found on pages 99 – 106 of this program book! You can also view the Guest tour program online at <http://www.pra-tours.com/IEEE>.

For more information on all that Anaheim and the O.C. has to offer please visit [www.anaheimoc.org](http://www.anaheimoc.org).

# TRANSPORTATION

## Flying to Anaheim/Orange County:

Anaheim/Orange County has four nearby airports to choose from:

### JOHN WAYNE ORANGE COUNTY AIRPORT (SNA)

18601 Airport Way, Santa Ana, CA 92707 (949) 252-5200

Drive time: 20 minutes (13 miles/20.92km) to Anaheim

#### Approximate rates to & from Anaheim:

Shuttle Services: starting at \$10 per person/one way

Disneyland Express Bus: \$15 per person/one way.

Taxi: metered rates, ranging from \$45-\$75 per car or van load/one way.

Rental Car, Van or SUV: \$50-\$95 per car/daily.

Limousine Service: approx. \$115.00.

Town car or SUV: approx. \$85

### LOS ANGELES INTERNATIONAL AIRPORT (LAX)

1 World Way, Los Angeles, CA 90045 (310)646-5252

Drive time: 50 minutes (35 miles/56.33km) to Anaheim

#### Approximate rates to & from Anaheim:

Shuttle Services: starting at \$16 per person/one way

Disneyland Express Bus: \$20 per person/one way

Taxi: metered rates, ranging from \$90-\$130 per car or van load/one way

Rental Car, Van or SUV: \$50-\$130 per car or van/daily

Limousine Service: approx. \$160

Town car or SUV: approx. \$100

### LONG BEACH AIRPORT (LGB)

4100 Donald Douglas Dr., Long Beach, CA 90808 (562)570-2619

Drive time: 30 minutes (18 miles/28.97km) to Anaheim

#### Approximate rates to & from Anaheim:

Shuttle Services: starting at \$35 for the first person + \$9-10 each additional person/one way

Taxi: metered rates, ranging from \$50-\$80 per car or van/one way

Rental Car, Van or SUV: \$75-\$100 per car or van/daily

Limousine Service: approx. \$110, per car/one way

Town car or SUV: approx. \$90

### ONTARIO INTERNATIONAL AIRPORT (ONT)

2500 Airport Dr., Ontario, CA 91761 (909)937-2700

Drive time: 45 minutes (36 miles/57.94km) to Anaheim

#### Approximate rates to & from Anaheim:

Shuttle Services: starting at \$43 for the first person + \$9-10 each additional person/one way

Taxi: metered rates, ranging from \$95-\$135 per car or van/one way.

Rental Car, Van or SUV: \$45-\$95 per car or van/daily.

Limousine Service: approx. \$170.

Town car or SUV: approx. \$110.

For more information on these airports and ground transportation please visit:

[www.anaheimoc.org](http://www.anaheimoc.org)

## Driving Directions to the Anaheim Convention Center:

### FROM POINTS NORTH

Take I-5 South. Take the HARBOR BLVD. exit. Keep RIGHT at the fork in the ramp. Merge onto S. HARBOR BLVD. Cross W. Katella Ave. Turn RIGHT onto CONVENTION WAY. Anaheim Convention Center is straight ahead.

### FROM POINTS SOUTH

Take I-5 North. Take the KATELLA AVE. exit toward DISNEY WAY. Turn SLIGHT LEFT onto ANAHEIM WAY. Turn LEFT (west) onto E. KATELLA AVE. (becomes W. Katella Ave.) Turn LEFT onto S. HARBOR BLVD. Turn RIGHT onto CONVENTION WAY. Anaheim Convention Center is straight ahead.

### FROM POINTS EAST

Take CA-91 West. Merge onto CA-57 South toward SANTA ANA. Take the KATELLA AVE. exit. Turn RIGHT (west) onto E. KATELLA AVE. (becomes W. Katella Ave.) Turn LEFT onto S. HARBOR BLVD. Turn RIGHT onto CONVENTION WAY. Anaheim Convention Center is straight ahead.

## Bus and Rail Information Routes:

Local bus service is provided by Orange County Transportation Authority. OCTA can be reached at (714) 636-RIDE (7433) or [www.octa.net/busrail](http://www.octa.net/busrail). The following bus routes have stops near the Anaheim Convention Center (ACC):

Route 50 Long Beach – Anaheim via Katella Ave.: stops on W. Katella Ave. between S. Harbor Blvd. & West St., short walk South to Anaheim Convention Center entrance.

Route 205 Laguna Hills – Anaheim: stops on W. Katella Ave. between S. Harbor Blvd. & West St., short walk South to Anaheim Convention Center entrance.

Route 430 Anaheim Metrolink/Amtrak Station – Anaheim Resort: stops at S. Harbor & W. Katella Ave., and also stops at West St. & W. Katella Ave., short walk South to ACC.

## Air Travel and Rental Car Discounts

For your convenience, airline tickets and car rentals may be booked through IEEE's corporate travel agency, World Travel Inc. Hours of operation are 08:00 to 17:30 EDT, Monday through Friday.

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# WELCOME FROM TECHNICAL PROGRAM COMMITTEE CHAIR



## Welcome to The Technical Program of IEEE MTT-S International Microwave Symposium 2010 Anaheim, CA, May 25-27, 2010.

**From: Madhu S. Gupta, Chair, IMS2010 Technical Program Committee**

A warm welcome to the International Microwave Symposium (IMS), which has been the premier annual event of the IEEE Microwave Theory & Techniques Society (MTT-S) for over half a century, and is the world's largest and most prestigious conference in the technology of RF, microwave, millimeter- and sub-millimeter wave components, devices, circuits, modules and systems. We have organized a vast and varied technical program for IMS2010, to meet the expectations of all the attendees, each with their own needs and preferences, and we are confident that the technical program of IMS2010 will measure up to your expectations in every respect. No matter what your field of work or specialization, and whether you are a newcomer or an old-timer, there is something here that will interest you.

### Please sample some the following parts of the technical program:

<p>We have over 250 technical papers, being presented orally in some five dozen sessions, that describe original research, development, and application work on radio-frequency and microwave theory and techniques, within the four major areas of this discipline: (1) Microwave Field and Circuit Techniques; (2) Passive RF and Microwave Components; (3) Active RF and Microwave Components; and (4) RF and Microwave Systems and Applications.</p>	<p>There are close to four dozen workshops this year that provide an opportunity to hob knob with the experts in some of the newly emerging fields as well as those experiencing an intense activity.</p>
<p>There are 122 papers being presented as interactive forum papers that permit a one-on-one discussion with presenters, as well as an opportunity to observe prototypes and simulations being demonstrated by them.</p>	<p>There are short courses during the Microwave Week, if you are looking for a refresher, or retreading, in a new field or specialization.</p>
<p>There is a student paper contest, presented in the interactive forum format, where you can find out how well the new entrants to your profession are currently being prepared, and renew your confidence that the future of the microwave discipline is in good hands.</p>	<p>There is a historical exhibit that displays hardware, books, and photographs from the bygone eras, that will bring back memories if you go back as long as those artifacts, or satisfy your curiosity about the past if you are younger than the displayed artifacts.</p>
<p>Carry out a technical exchange with the presenters of oral and interactive forum papers to help them in refining their ideas by asking questions, engaging them in discussion, and bringing up ignored considerations.</p>	<p>There are Microapps seminars, from the vendors of products and services in the microwave industry, that can help in learning the latest techniques, skills, and methods.</p>
<p>Get exposed to new technical sessions in areas that are appearing for the first time in IMS this year: in the fields of high-power microwaves for industrial and material processing, and RFID and power scavenging technologies</p>	<p>Attend and join the various technical committee meetings dealing with specialized technical and professional issues, being organized by the MTT Society Technical Committees.</p>
<p>At the plenary session, learn from a national leader of advanced research and innovation in the defense sector how the current technological advances are likely to influence the future evolution of the microwave field.</p>	<p>Participate in the student design competitions organized by the various technical committees (TCs) of the IEEE MTT Society.</p>
<p>If controversy and debate attract you, we have panel sessions each day, with panelists, who are recognized experts of the field, presenting their opinions and rationales on each side of the issue.</p>	<p>Enjoy the hallway discussions with old friends and new acquaintances, and network with the shakers and movers of the field from all around the world.</p>
<p>Sample some of the special sessions dedicated to significant research areas and themes that are currently drawing a lot of attention.</p>	<p>Catch up on the latest advances in the industry by taking a stroll through the industry exhibits area where hundreds of exhibitors display their latest products and services for a period of three days.</p>

IMS is the centerpiece of the "microwave week" which comprises still other technical activities, including the RFIC Symposium, and the ARFTG conference, co-located with IMS2010 in Anaheim during the week of Sunday, May 23 through Friday, May 29, 2010.

Please enjoy the International Microwave Symposium in Anaheim during May 2010, and give us the benefit of your opinion about the success of our efforts at developing a conference with an outstanding technical program. We are confident you will agree that IMS2010 offers everything that we have come to expect from IMS.



## MONDAY PANEL SESSIONS

**Monday 12:00 – 13:10 Room 210AB**

**Hubbert's Peak, The Coal Question, and Climate Change**

**David Rutledge, Tomiyasu Professor of Electrical Engineering,  
*California Institute of Technology***

**Panel Session Abstract:**

**A**n accurate estimate of the ultimate production of oil, gas, and coal would be helpful for the ongoing policy discussion on alternatives to fossil fuels and climate change. By ultimate production, we mean total production, past and future. It takes a long time to develop energy infrastructure, and this means it matters whether we have burned 20% of our oil, gas, and coal, or 40%. In modeling future temperature and sea-level rise, the carbon dioxide from burning fossil fuels is the most important factor. The time frame for the climate response is much longer than the time frame for burning fossil fuels, and this means that the total amount burned is more important than the burn rate. Oil, gas, and coal ultimates are traditionally estimated by government geological surveys from measurements of oil and gas reservoirs and coal seams, together with an allowance for future discoveries of oil and gas. We will see that where these estimates can be tested, they tend to be too high, and that more accurate estimates can be made by curve fits to the production history. Professor Rutledge will discuss the implications of this analysis for climate, and comment on the Climategate episode.



TUESDAY TECHNICAL SESSIONS

8:00-9:40

**TU1A: Novel Guiding and Radiating Structures**  
David Jackson, *University of Houston*  
Jan Machac, *Czech Technical University in Prague*  
**Room: 203B**

**TU1B: Metamaterial Structures, Phenomena and Applications**  
Guoan Wang, *IBM*  
Francisco Mesa, *University of Seville*  
**Room: 205AB**

**TU1C: Submillimeter-Wave Amplifiers and Enabling Components**  
Goutam Chattopadhyay, *NASA JPL*  
Vesna Radisic, *Northrop Grumman Corporation*, Redondo Beach, United States  
**Room: 206AB**

**TU1D: Beamforming and Retrodirective Arrays**  
Wayne Shiroma, *University of Hawaii*  
Joseph Modelski, *Warsaw University of Technology*  
**Room: 202AB**

8:00 - 8:20

**TU1A-1: Dispersion Characteristics of Metamaterial Slow-Wave Coupled Lines**  
H. Ma, H. Yang, *University of Illinois*, Chicago, United States

**TU1B-1: Fully planar implementation of generalized composite right/left handed transmission lines for quad-band applications**  
M. Durán-Sindreu, G. Sisó, J. Bonache, F. Martín, *Universitat Autònoma de Barcelona*, Bellaterra, Spain

**TU1C-1: A 50 mW 220 GHz Power Amplifier Module**  
V. Radisic, K. M. Leong, X. Mei, S. Sarkozy, W. Yoshida, P. Liu, J. Uyeda, R. Lai, W. R. Deal, *Northrop Grumman Corporation*, Redondo Beach, United States

**TU1D-1: CMOS 4x4 and 8x8 Butler Matrices**  
B. Cetinoneri<sup>1</sup>, Y. A. Atesal<sup>1</sup>, J. Kim<sup>2</sup>, G. M. Rebeiz<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Kwangwoon University, Seoul, Republic of Korea

8:20 - 8:40

**TU1A-2: A Substrate Integrated Waveguide Leaky Wave Antenna Radiating from a Slot in the Broad Wall**  
J. Machac<sup>1</sup>, P. Lorenz<sup>2</sup>, M. Saglam<sup>2</sup>, C. Bui<sup>3</sup>, W. Kraemer<sup>2,1</sup> *Czech Technical University in Prague*, Prague, Czech Republic, <sup>2</sup>Rohde & Schwarz GmbH & Co. KG, Muenchen, Germany, <sup>3</sup>RWTH Aachen, Aachen, Germany

**TU1B-2: Dispersion characterization of CRLH transmission lines by electro-optic visions of forward/backward waves**  
M. Tsuchiya<sup>1</sup>, T. Shiozawa<sup>2</sup>, <sup>1</sup>National Institute of Information and Communications Technology, Koganei, Japan, <sup>2</sup>Kagawa National College of Technology, Takuma, Japan

**TU1C-2: 300 GHz Six-Stage Differential-Mode Amplifier**  
H. J. Park<sup>1</sup>, J. S. Rieh<sup>1</sup>, M. Kim<sup>1</sup>, J. B. Hacker<sup>2</sup>, <sup>1</sup>Korea University, Seoul, Republic of Korea, <sup>2</sup>Teledyne Scientific, Thousand Oaks, United States

**TU1D-2: A V-band Switched Beam-Forming Network Using Absorptive SP4T Switch Integrated with 4x4 Butler Matrix in 0.13- $\mu$ m CMOS**  
K. Park, W. Choi, Y. Kim, K. Kim, Y. Kwon, *Seoul National University*, Seoul, Republic of Korea

8:40 - 9:00

**TU1A-3: Dual-Mode Leaky-Wave Excitation in Symmetric Composite Right/Left-Handed Structure with Center Vias**  
M. M. Hashemi, T. Itoh, *University of California*, Los Angeles, Los Angeles, United States

**TU1B-3: 2D Transformation Optics using Anisotropic Transmission-Line Metamaterials**  
M. Zedler, G. V. Eleftheriades, *U of Toronto*, Toronto, Canada

**TU1C-3: High-Gain Submillimeter-Wave mHEMT Amplifier MMICs**  
A. Tessmann, A. Leuther, V. Hurm, H. Massler, M. Zink, M. Riessle, R. Loesch, *Fraunhofer IAF*, Freiburg, Germany

**TU1D-3: Polar Phase-Conjugating Active Arrays for Spectrally-Efficient Linear Wireless Links**  
L. Gabria<sup>1</sup>, J. A. Garcia<sup>1</sup>, T. Aballo<sup>1</sup>, Z. Popovic<sup>2</sup>, <sup>1</sup>Universidad de Cantabria, Santander, Spain, <sup>2</sup>University of Colorado at Boulder, Boulder, United States

9:00 - 9:10

**TU1A-4: Tunable Composite Right/Left-Handed Leaky Wave Antenna Based on a Rectangular Waveguide Using Liquid Crystals**  
C. Damm, *TU-Darmstadt*, Darmstadt, Germany

**TU1B-4: Negative and Zero Group Velocity in Microstrip/Negative-refractive-index Transmission-line Couplers**  
H. Mirzaei, G. V. Eleftheriades, *University of Toronto*, Toronto, Canada

**TU1C-4: A 210-280GHz 3-Stage Amplifier in 35nm InP mHEMT, Using a Thin-film Microstrip Environment**  
Z. Griffith, W. Ha, P. Chen, D. Kim, B. Brar, *Teledyne Scientific Company*, Thousand Oaks, United States

**TU1D-4: A Retrodirective Null-Scanning Array**  
R. T. Iwami, A. Zamora, T. F. Chun, M. K. Watanabe, W. A. Shiroma, *University of Hawaii* at Manoa, Honolulu, United States

9:10 - 9:20

**TU1A-5: The Geometric Characteristics and Mechanism Analysis of Quasi-TEM Waveguides with Dipole-FSS Walls**  
D. Li<sup>1</sup>, K. Wu<sup>2</sup>, <sup>1</sup>Anhui University of Science & Technology, Huainan, China, <sup>2</sup>École Polytechnique de Montréal, Montréal, Canada

**TU1B-5: Pseudo-Traveling-Wave Resonator Based on Nonreciprocal Phase-Shift Composite Right/Left Handed Transmission Lines**  
T. Ueda, H. Kishimoto, *Kyoto Institute of Technology*, Kyoto, Japan

**TU1C-5: Analog Type Millimeter Wave Phase Shifters Based on MEMS Tunable High-Impedance Surface**  
D. Chicherin<sup>1</sup>, M. Sterner<sup>2</sup>, J. Oberhammer<sup>2</sup>, S. Dudorov<sup>1</sup>, J. Aberg<sup>3</sup>, A. V. Räisänen<sup>1</sup>, <sup>1</sup>Aalto University (formerly TKK), Espoo, Finland, <sup>2</sup>KTH - Royal Institute of Technology, Stockholm, Sweden, <sup>3</sup>MicroComp Nordic AB, Tullinge, Sweden

**TU1D-5: Development of Robust Safety-of-Life Navigation Receivers at the German Aerospace Center (DLR)**  
M. V. Heckler, M. Cuntz, A. Konovaltsev, L. A. Greda, A. Dreher, M. Meurer, *German Aerospace Center*, Wessling, Germany

9:20 - 9:30

**TU1A-6: Analysis of Periodic Structures by Means of a Generalized Transverse Resonance Approach**  
J. E. Varela, J. Esteban, *Universidad Politécnica de Madrid*, Madrid, Spain

**TU1B-5: Pseudo-Traveling-Wave Resonator Based on Nonreciprocal Phase-Shift Composite Right/Left Handed Transmission Lines**  
T. Ueda, H. Kishimoto, *Kyoto Institute of Technology*, Kyoto, Japan

**TU1C-5: Analog Type Millimeter Wave Phase Shifters Based on MEMS Tunable High-Impedance Surface**  
D. Chicherin<sup>1</sup>, M. Sterner<sup>2</sup>, J. Oberhammer<sup>2</sup>, S. Dudorov<sup>1</sup>, J. Aberg<sup>3</sup>, A. V. Räisänen<sup>1</sup>, <sup>1</sup>Aalto University (formerly TKK), Espoo, Finland, <sup>2</sup>KTH - Royal Institute of Technology, Stockholm, Sweden, <sup>3</sup>MicroComp Nordic AB, Tullinge, Sweden

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9:30 - 9:40

**TU1C-6: Micromachined On-wafer Probes**  
T. J. Reck<sup>1</sup>, L. Chen<sup>1</sup>, C. Zhang<sup>1</sup>, C. Groppi<sup>2</sup>, H. Xu<sup>1</sup>, A. Arsenovic<sup>1</sup>, N. S. Barker<sup>1</sup>, A. Lichtenberger<sup>1</sup>, R. M. Weikle<sup>1</sup>, <sup>1</sup>University of Virginia, Charlottesville, United States, <sup>2</sup>Arizona, Tempe, United States

# PLENARY PRESENTATION

A Strategic View of Defense Research and Engineering

Tuesday, 10:10-11:50

Anaheim Convention Center, Third level Ballroom A-C



## Plenary Speaker: Honorable Zachary J. Lemnios

**Abstract:** In this presentation, Mr. Lemnios will give an overview of a number of defense related technology opportunities and challenges facing the electronic industry. From defense research and engineering perspective, the first major challenge is to preserve the technological edge of the forces, by extending the capabilities of the defense systems – through better intelligence, greater speed, longer range, higher precision, and more effectiveness. The second major challenge is to identify breakthrough capabilities. Finally, the third major challenge is to provide a hedge against an uncertain future via a set of scientific and engineering options to deter against strategic surprise. To enhance defense capabilities, development programs shall balance near and long term activities and balance incremental change with revolutionary technologies. We should understand where the state-of-the-art is in science, and understand how to apply these technologies, and create opportunities through investment.

## Biography of the speaker:

The Honorable Zachary J. Lemnios currently serves as the Chief Technology Officer (CTO) for the Department of Defense.

Prior to acceptance of his current role, Mr. Lemnios was the MIT Lincoln Laboratory Chief Technology Officer (CTO) responsible for coordinating technology strategy across the Laboratory and for establishing and growing strategic relationships outside the Laboratory to support current and future Laboratory missions. He also served as Assistant Division Head of the MIT Lincoln Laboratory Solid State Division, as a member of the Laboratory's Senior Management Council and as the Co-Chair of the Laboratory's New Technology Initiative (NTI) Board.

Mr. Lemnios was also the Director of the Defense Advanced Research Projects Agency (DARPA) Microsystems Technology Office (MTO) as well as the Deputy Director of Information Processing Technology Office (IPTO). In these positions, he oversaw the development of research thrusts, analyzed and evaluated program proposals and engagements with commercial, academic organizations and represented DARPA on various national committees.

He has been in close contact with industry - he held various positions within industry at Hughes Aircraft Company, Westinghouse Electric Corporation and Ford Microelectronics, Inc. that led to the development and demonstration of advanced microelectronic components.

Mr. Lemnios has served on numerous DoD, industry and academic committees. Mr. Lemnios has authored over 40 papers, holds 4 patents in advanced GaAs device and MMIC technology and is a Senior Member of the IEEE.



## TUESDAY PANEL SESSIONS

**Tuesday 12:00 – 13:10 Room 210AB**

**Silicon at THz Frequencies: A Reality or a Dream?**

**Chair/Moderator:** Prof. Gabriel M. Rebeiz, University of California, San Diego

**Panelists:**

- Bill Deal, Northrop Grumman
- Jonathan Lynch, HRL Laboratories
- K.K. O, University of Florida/University of Dallas
- Ullrich Pfeifer, University of Wuppertal
- Sorin Voinigescu, University of Toronto

**Panel Session Abstract:**

**InP** MMICs are the only technology used at Terahertz frequencies. This technology has demonstrated low-noise amplifiers and oscillators up to 300 GHz, and recently state of the art amplifiers up to 500 GHz. Also, GaAs Schottky-diodes are the technology of choice for low-noise room-temperature mixers and multipliers up to 1 THz. However, both the InP and GaAs technologies are developed in few research labs world-wide and are quite expensive. These technologies are therefore used nowadays for radio-astronomy and in laboratory set-ups such as biological detection systems, and test and instrumentation, and there is minimal adoption of THz systems for general use (imaging, portable medical diagnostics, high-data rate communications, etc.).

Recently, silicon circuits have demonstrated acceptable performance up to 650 GHz using standard CMOS and SiGe technologies and with no additional processing. The NF (or NEP), output power and phase noise does not compare to InP and GaAs MMICs, but still, they are being developed as an alternative low-cost solution. Will we have high performance CMOS/SiGe circuits at THz frequencies in the next few years? Can we build low-cost THz silicon RFICs for large volume commercial applications? There are many different challenges such as available output power vs. frequency, integrated high efficiency THz antennas on low-resistivity silicon substrates, and  $1/f$  phase noise in oscillators, to name a few. Several of the panel members believe that these challenges are currently being solved, paving the way to low cost THz silicon RFICs.

This panel will present an honest discussion of silicon and InP/GaAs circuits at THz frequencies with distinguished scientists in the field.

# STUDENT PAPER COMPETITION

Tuesday, May 25, 2010

14:00-16:00

213CD, Anaheim Convention Center

The student paper competition had become one of the largest technical events at IMS. The purpose of the competition is to determine and acknowledge the best student work of the year in the MTT-S. This year we received 218 student papers approximately 26% of all submitted papers. Each student paper went through the regular review process by the Technical Program Committee. Approximately 49% of the student submitted papers were accepted for presentations. Based on the review scores, only 27 of the accepted student papers were selected as finalists. The finalists are given complimentary registration for IMS 2010, complimentary tickets to the MTT-S awards banquet and travel subsidies. The student finalists will present their papers at their appropriate regular sessions and make special presentations at the Interactive Forum on Tuesday from 14:00-16:00pm. Six top papers and four honorable mentions will be selected to receive cash awards, certificates, and gifts. These will be announced and presented during the Students Awards Luncheon on Thursday. We are very pleased to announce the finalists for the IMS 2010 Student Paper Competition:

<p>Dispersion Characteristics of Metamaterial Slow-Wave Coupled Lines H. Ma, H. Yang, University of Illinois, Chicago, United States</p>	<p>Dual-Mode Leaky-Wave Excitation in Symmetric Composite Right/Left-Handed Structure with Center Vias M. M. Hashemi, T. Itoh, University of California, Los Angeles, Los Angeles, United States</p>
<p>Exploiting the Relativistic Formulation of Maxwell's Equations to Introduce Moving Grids into Finite Difference Time Domain Solvers R. B. Armenta, C. D. Sarris, University of Toronto, Toronto, Canada</p>	<p>Single Section Wilkinson Type UWB Power Divider with Bandpass Filter and DC Block Characteristics in LTCC Technology T. Duong, I. Kim, Kyung Hee University, Yongin-si, Republic of Korea</p>
<p>A 20-90 MHz 26-Channel Cochlear-Based Channelizer Y. C. Ou, G. M. Rebeiz, University of California, San Diego, La Jolla, United States</p>	<p>Oscillator Phase-Noise Reduction Using Low-Noise High-Q Active Resonators M. Nick, A. Mortazawi, University of Michigan, Ann Arbor, United States</p>
<p>Sub-nanosecond Pulse Characteristics of InGaP/GaAs HBTs R. Jin, C. Chen, S. Halder, W. R. Curtice, J. C. Hwang, Lehigh University, Bethlehem, United States</p>	<p>Third-Order Intermodulation Distortion due to Self-heating in Gold Coplanar Waveguides E. Rocas<sup>1</sup>, C. Collado<sup>1</sup>, N. Orloff<sup>2</sup>, J. C. Booth<sup>2</sup>, <sup>1</sup> Universitat Politècnica de Catalunya, Barcelona, Spain, <sup>2</sup>National Institute of Standards and Technology, Boulder, United States</p>
<p>A New Mixed Time-Frequency Simulation Method for Nonlinear Heterogeneous Multirate RF Circuits J. S. Oliveira<sup>1</sup>, J. C. Pedro<sup>2</sup>, <sup>1</sup>Polytechnic Institute of Leiria, Leiria, Portugal, <sup>2</sup>University of Aveiro, Aveiro, Portugal</p>	<p>Lumped Isolation Circuits for Improvement of Matching and Isolation in Three-Port Balun Band-Pass Filter T. Yang<sup>1</sup>, P. Chi<sup>1</sup>, T. Itoh<sup>1</sup>, <sup>1</sup>University of California, Los Angeles, Los Angeles, United States, <sup>2</sup>University of Electronic and Science Technology of China, Chengdu, China</p>
<p>A novel methodology for fast harmonic-load control with a passive tuner and an active loop S. Bonino, V. Teppati, A. Ferrero, Politecnico di Torino, Torino, Italy</p>	<p>Wideband High Efficiency Digitally-Assisted Envelope Amplifier with Dual Switching Stages for Radio Base-Station Envelope Tracking Power Amplifiers C. Hsia<sup>1</sup>, D. F. Klmball<sup>1</sup>, S. Lanfranco<sup>2</sup>, P. M. Asbeck<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Nokia Siemens Networks, Mountain View, United States</p>
<p>Application of Composite Right/Left-Handed Half-Mode Substrate Integrated Waveguide to the Design of a Dual-Band Rat-Race Coupler Y. Dong, T. Itoh, UCLA Microwave Electronics Lab., Los Angeles, United States</p>	<p>A Method to Control Non-uniformity RF <math>\text{dB}_1</math> Field for High Field Magnetic Resonance Imaging H. Yoo, A. Gopinath, T. Vaughan, University of Minnesota, Minneapolis, United States</p>





## STUDENT PAPER COMPETITION

<p>An 85-95.2 GHz Transformer-Based Injection-Locked Frequency Tripler in 65nm CMOS Z. Chen, P. Heydari, University of California, Irvine, Irvine, United States</p>	<p>TM Dual-Mode Pseudoelliptic Filters using Nonresonating Modes S. Bastioli<sup>1</sup>, C. Tomassoni<sup>1</sup>, R. Sorrentino<sup>1</sup>, <sup>1</sup>University of Perugia, Perugia, Italy, <sup>2</sup>RF Microtech srl, Perugia, Italy</p>
<p>Switch-Controlled Multi-Octave Bandwidth Radial Power Divider/Combiner Y. Hong<sup>1</sup>, D. F. Kimball<sup>2</sup>, J. Yook<sup>1</sup>, P. M. Asbeck<sup>2</sup>, L. E. Larson<sup>2</sup>, <sup>1</sup>Yonsei University, Seoul, Republic of Korea, <sup>2</sup>University of California, San Diego, La Jolla, United States</p>	<p>A Ka-Band High-Pass Distributed Amplifier in 120nm SiGe BiCMOS T. D. Gathman, J. F. Buckwalter, University of California, San Diego, La Jolla, United States</p>
<p>Low-Power Low-Noise 0.13 <math>\mu</math>m CMOS X-Band Phased Array Receivers D. Shin, G. M. Rebeiz, UCSD, La Jolla, United States</p>	<p>An RF-MEMS Switch with mN Contact Forces C. D. Patel, G. M. Rebeiz, University of California, San Diego, La Jolla, United States</p>
<p>X/Ku-Band 8-Element Phased Arrays Based on Single Silicon Chips Y. A. Atesal<sup>1</sup>, B. Cetinoneri<sup>1</sup>, K. Koh<sup>2</sup>, G. M. Rebeiz<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Intel Corp., Hillsboro, United States</p>	<p>Adjustable Dielectric Using Magnetically Aligned Conductive Particles for Microwave Applications S. Moon, W. J. Chappell, Purdue University, West Lafayette, United States</p>
<p>Concurrent Enhancement of Q and Power Handling in Multi-Tether High-Order Extensional Resonators M. Shahmohammadi, B. P. Harrington, R. Abdolvand, Oklahoma State University, Tulsa, United States</p>	<p>Dual-Band Integrated Self-biased Edge-Mode Isolator based on the Double Ferromagnetic Resonance of a Bistable Nanowire Substrate L. Carignan<sup>1</sup>, C. Caloz<sup>2</sup>, D. Ménard<sup>1</sup>, <sup>1</sup>Polytechnique School of Montreal, Montreal, Canada, <sup>2</sup>Ecole Polytechnique of Montreal, Montreal, Canada</p>
<p>Tunable, Substrate Integrated, High Q Filter Cascade for High Isolation E. J. Naglich, J. Lee, D. Peroulis, W. J. Chappell, Purdue University, West Lafayette, United States</p>	<p>Highly Directive Package-Integrated Dipole Arrays for Low-Cost 60-GHz Front End Modules A. L. Amadjikpè<sup>1</sup>, D. Choudhury<sup>2</sup>, G. E. Ponchak<sup>3</sup>, J. Papapolymerou<sup>1</sup>, <sup>1</sup>Georgia Institute of Technology, Atlanta, United States, <sup>2</sup>Intel Corporation, Hillsboro, United States, <sup>3</sup>NASA Glenn Research Center, Cleveland, United States</p>
<p>Implementation and Analysis of a 30 GHz Wireless Communication System with a Novel Receiver Front-end tZ. Zhang, Y. Wei, K. Wu, Ecole Polytechnique Montreal, Montreal, Canada</p>	



# STUDENT DESIGN COMPETITIONS

The Technical Committees of MTT-S are sponsoring four Student Design Competitions at IMS. This year the student competition topics are low noise amplifier, packaged ultra-wide-band filter, and high efficiency power amplifier. These topics are geared toward the practical applications that working engineers face every day and therefore represent an excellent opportunity for students to show off how well prepared they are for a professional career. These competitions are open to all students registered at an educational institution. The winners will receive cash awards and participants will be recognized at the Student Awards Luncheon on Thursday.

## High Efficiency Power Amplifier

Tuesday May 25, 2010

9:00-11:00

Anaheim Convention Center, Room 213AB

This competition is the fifth sponsored by High Power Amplifiers (MTT-5) and is open to students enrolled at a university. Competitors are required to design, construct, and measure a high efficiency power amplifier, at a frequency of their choice above 1 GHz but less than 20 GHz, and having an output power level of at least 5 Watts. The winner will be judged on the design which demonstrates the highest Power Added Efficiency (PAE) weighted for frequency.

## ASH Receiver Design Competition

Tuesday May 25, 2010

9:00-11:00

Anaheim Convention Center, Room 213AB

This competition is sponsored by the Microwaves Systems (MTT-16) and Microwave Acoustics (MTT-2) sub-committees. This Competition is open to all students and graduate students registered at an educational establishment. The competitors are required to design, construct, and measure an Amplifier-Sequenced Hybrid Receiver (ASH receiver) at a frequency of 433.92 MHz.

## Packaged Diplexer Design Competition

Tuesday May 25, 2010

12:00-14:00

Anaheim Convention Center, Room 213AB

This competition is sponsored by Microwave Filters, Multiplexers, and Passive Components (MTT-8) and Interconnects, Packaging, and Manufacturing (MTT-12) and is open to IEE IMS students enrolled at a university. Competitors are required to design, construct, and measure a packaged diplexer. The designs will be judged using criteria that include filter performance, robustness and weight.

## Optical-to-Microwave Converter Design Competition

Tuesday May 25, 2010

12:00-14:00

Anaheim Convention Center, Room 213AB

This competition is sponsored by the Microwave photonics (MTT-3) and is open to all IEEE MTT-S members who are enrolled as students at a university. The objective of the contest is to demonstrate new and effective photodiode power combining and power extraction techniques. The designs will be judged by members of MTT-3 using pre-defined criteria that include converter efficiency, maximum power output, and linearity.

## MTT-S Student Awards Luncheon

Thursday May 27, 2010

12:00-14:00

Hilton Hotel, Room California B

All students are invited to attend this luncheon which recognizes recipients of the MTT-S Undergraduate Scholarships, MTT-S Graduate Fellowships, IMS2010 Student Volunteers, IMS2010 Student Paper Awards, and the winners and participants of the IMS2010 Student Design Competitions.



TUESDAY TECHNICAL SESSIONS

13:20-15:00

**TU3A: Time-Domain Techniques and Applications**  
 Costas Sarris, *University of Toronto*  
 Nathan Bushyager, *Northrop Grumman*  
**Room: 203B**

**TU3B: Advances in Power Divider/Combiner Technology**  
 Victor Fouad Hanna, *University of Paris*  
 Rashaunda Henderson, *University of Texas at Dallas*  
**Room: 205AB**

**TU3C: III-V Compound Semiconductor Based Microwave Circuit Technology**  
 Cheng P. Wen, *Peking University*  
 Ho C. Huang, *AMCOM Communications, Inc.*  
**Room: 206AB**

13:20 - 13:40

**TU3A-1: Time Domain Study of Electromagnetic Cloaks for Wideband Invisibility under Transient Illumination**  
 W. J. Hoefler, G. H. Park, E. P. Li, Institute of High Performance Computing, Singapore, Singapore

**TU3B-1: Design of a Compact Balun With Three Octant-Wavelength Coupled Lines**  
 C. Tang<sup>1</sup>, W. Cheng<sup>1</sup>, J. Wu<sup>1</sup>, Y. Lin<sup>2</sup>, <sup>1</sup>National Chung Cheng University, Chia-Yi, Taiwan, <sup>2</sup>Cheng Shiu University, Kaohsiung, Taiwan

**TU3C-1: A Complete Transmit, Receive, and LO Buffer Chip Set in Low Cost SMT Package Covering 38 & 42 GHz Applications**  
 H. Morkner, K. Fujii, S. Kumar, K. Phan, T. Niedzwiecki, B. Ostermann, Avago Technologies INC, San Jose, United States

13:40 - 14:00

**TU3A-2: Exploiting the Relativistic Formulation of Maxwell's Equations to Introduce Moving Grids into Finite Difference Time Domain Solvers**  
 R. B. Armenta, C. D. Sarris, University of Toronto, Toronto, Canada

**TU3B-2: Isolation Circuit of Impedance-Transforming 3-dB Compact Baluns for Perfect Output Matching and Isolation**  
 H. Ahn, T. Itoh, UCLA, Los Angeles, United States

**TU3C-2: Design of a 0.5-30 GHz Darlington Amplifier for Microwave Broadband Applications**  
 S. Weng<sup>1</sup>, H. Chang<sup>1</sup>, C. Chiong<sup>2</sup>, <sup>1</sup>National Central University, Jhongli, Taiwan, <sup>2</sup>Institute of Astronomy and Astrophysics, Taipei, Taiwan

14:00 - 14:20

**TU3A-3: Meshless RPIM Modeling of Open-Structures Using PMLs**  
 Y. Yu<sup>1</sup>, Z. Chen<sup>2</sup>, <sup>1</sup>Dalhousie University, Halifax, Canada, <sup>2</sup>Dalhousie University, Halifax, Canada

**TU3B-3: Single Section Wilkinson Type UWB Power Divider with Bandpass Filter and DC Block Characteristics in LTCC Technology**  
 T. Duong, I. Kim, Kyung Hee University, Yongin-si, Republic of Korea

**TU3C-3: Multi-octave GaN MMIC Amplifier**  
 A. Darwish<sup>1</sup>, A. Hung<sup>1</sup>, E. Viveiros<sup>1</sup>, M. Kao<sup>2</sup>, <sup>1</sup>Army Research Laboratory, Adelphi, United States, <sup>2</sup>TriQuint Semiconductor, Richardson, United States

14:20 - 14:40

**TU3A-4: Microstrip-Based Nanosecond Pulse Generators: Numerical and Circuital Modeling**  
 C. Merla<sup>1</sup>, S. El-Amari<sup>1</sup>, F. Danei<sup>2</sup>, M. Liberti<sup>2</sup>, F. Apollonio<sup>2</sup>, D. Arnaud-Cormos<sup>1</sup>, V. Couderc<sup>1</sup>, P. Leveque<sup>1</sup>, <sup>1</sup>XLIM, CNR-University of Limoges, Limoges, France, <sup>2</sup>CEMBA at "Sapienza" University of Rome, Rome, Italy

**TU3B-4: A Miniaturized Power Combiner for Compact Design of CMOS Phase Shifter at K-band**  
 C. Wang, H. Wu, C. C. Tzuang, National Taiwan University, Taipei, Taiwan

**TU3C-4: Wideband High Power GaN on SiC SPDT Switch MMICs**  
 C. F. Campbell, D. C. Dumka, TriQuint Semiconductor, Richardson, United States

14:40 - 14:50

**TU3A-5: Transient Thermal Analysis of Active device (FETs) for High-Power Applications**  
 L. Zhou<sup>1</sup>, Z. Wang<sup>1</sup>, W. Yin<sup>2</sup>, J. Mao<sup>1</sup>, <sup>1</sup>Center for Microwave and RF Technology, Shanghai, China, <sup>2</sup>Center for Optics and EM Research, State Key Lab of MOI, Hangzhou, China

**TU3B-5: A Novel Power Divider Design with Enhanced Harmonic Suppression and Simple Layout**  
 W. IP, K. M. Cheng, The Chinese University of Hong Kong, Hong Kong, Hong Kong

**TU3C-5: Current Collapse, Memory Effect Free GaN HEMT**  
 C. P. Wen, J. Wang, Y. Hao, Peking University, Beijing, China

14:50 - 15:00

**TU3B-6: A Novel Power Divider with Enhanced Physical and Electrical Port Isolation.**  
 C. J. Trantanella, Custom MMIC Design Services, Westford, United States

TUESDAY

TECHNICAL SESSIONS

13:20-15:00

**TU3D: Advances in Radar Systems for Detection in Detection, Imaging, Mapping and Localization**  
 Gregory Lyons, *MIT Lincoln Laboratory*  
 Mohamed Abouzahra, *MIT Lincoln Laboratory*  
**Room: 202AB**

**TU3E: Novel structures, Effects, and Techniques**  
 Tapan K. Sarkar, *Syracuse University*  
 Silvio E. Barbin, *University of Sao Paulo*  
**Room: 207C**

**TU3D-1: Fast Response Retrodirective Radar**  
 V. Fusco, N. B. Buchanan, P. Sundaralingam, *Queens University Belfast, Belfast, United Kingdom*

**TU3E-1: Broadband Negative Refraction at Microwaves with a Multilayered Mushroom-Type Metamaterial**  
 A. B. Yakovlev<sup>1</sup>, M. G. Silveirinha<sup>2</sup>, C. S. Kaipia<sup>1</sup>, <sup>1</sup>University of Mississippi, University, United States, <sup>2</sup>University of Coimbra - Instituto de Telecomunicações, Coimbra, Portugal

13:20 - 13:40

**TU3D-2: Development of a Multi-Frequency Airborne Radar Instrumentation Package for Ice Sheet Mapping and Imaging**  
 F. Rodriguez-Morales, P. Gogineni, C. Leuschen, C. T. Allen, S. Seguin, J. Ledford, C. Lewis, A. Patel, L. Shi, W. Blake, B. Panzer, K. Byers, R. Crowe, L. Smith, C. Gifford, *University of Kansas, Lawrence, United States*

**TU3E-2: Photonic Choke-Joints for Dual-Polarization Waveguides**  
 E. J. Wollack, K. U-yen, D. T. Chuss, *NASA Goddard Space Flight Center, Greenbelt, United States*

13:40 - 14:00

**TU3D-3: Calibration of a Digital Phased Array for Polarimetric Radar**  
 C. J. Fulton, W. J. Chappell, *Purdue University, West Lafayette, United States*

**TU3E-3: High-Frequency Scattering by a Narrow Gap on a Microstrip Line**  
 R. R. Berral<sup>1</sup>, F. Mesa<sup>1</sup>, D. R. Jackson<sup>2</sup>, <sup>1</sup>University of Seville, Seville, Spain, <sup>2</sup>University of Houston, Houston, United States

14:00 - 14:20

**TU3D-4: Advanced System Level Simulation of UWB Three-Dimensional Through-Wall Imaging Radar for Performance Limitation Prediction**  
 Y. Wang<sup>1</sup>, M. J. Kuhn<sup>2</sup>, A. E. Fathy<sup>1</sup>, <sup>1</sup>The University of Tennessee, Knoxville, United States, <sup>2</sup>The University of Tennessee, Knoxville, United States

**TU3E-4: Heat Distribution Pattern of Double Brillouin Pulse Inside Water**  
 B. Montazeri Najafabadi, R. Safian, *Isfahan university of technology, Isfahan, Iran*

14:20 - 14:40

**TU3D-5: A 3-5 GHz impulse radio UWB transceiver IC optimized for precision localization at longer ranges**  
 J. J. Xia, C. L. Law, K. S. Koh, Y. Zhou, C. Fang, *Nanyang Technological University, Singapore, Singapore*

**TU3E-5: Detection at Microwave Frequencies Based on Self-Adjoint Sensitivity Analysis**  
 L. Liu, A. Trehan, N. K. Nikolova, *McMaster University, Hamilton, Canada*

14:40 - 15:00



TUESDAY

INTERACTIVE FORUM

15:00 - 17:00

**TUPA: MEMS Switches**  
Jim Hwang, *Lehigh University*

**TUPB: Advanced Devices and Circuits in III-V and Silicon Technologies**  
James Buckwalter, *University of California San Diego*

**TUPC: Power-Amplifiers at HF, VHF, and UHF, and GHz Signal Processing**  
Frederick Raab, *Green Mountain Radio Research*  
John Heaton, *BAE Systems*

**TUPA-1: Performance of Temperature-Stable RF MEMS Switched Capacitors under High RF Power Conditions**

I. C. Reines<sup>1</sup>, G. Rebeiz<sup>1</sup>, B. Pillans<sup>2</sup>, <sup>1</sup>University of California San Diego, La Jolla, United States, <sup>2</sup>Raytheon Systems, Dallas, United States

**TUPB-1: Fabrication of AlGaIn/GaN HEMT with the improved ohmic contact by encapsulation of silicon dioxide thin film**

J. G. Heo<sup>1</sup>, H. K. Sung<sup>1</sup>, J. W. Lim<sup>2</sup>, S. K. Kim<sup>1</sup>, W. K. Park<sup>1</sup>, C. G. Ko<sup>1</sup>, <sup>1</sup>Device dev., Suwon, Republic of Korea, <sup>2</sup>CC & MR Lab., Daejeon, Republic of Korea

**TUPC-1: Lumped-element Output Networks for High-efficiency Power Amplifiers**

R. A. Beltran<sup>1</sup>, F. H. Raab<sup>2</sup>, <sup>1</sup>Tijuana, Mexico, <sup>2</sup>Green Mountain Radio Research Company, Colchester, United States

**TUPA-2: Magnetically-Actuated Dielectric Cantilever RF MEMS Switches**

A. A. Fomani, S. Fouladi, R. R. Mansour, University of Waterloo, Waterloo, Canada

**TUPB-2: A novel active variable gain X-Band amplifier in SiGe technology**

R. Corbier<sup>1</sup>, B. Louis<sup>1</sup>, J. Tartarin<sup>2</sup>, <sup>1</sup>Thales Airborne Systems, Elancourt, France, <sup>2</sup>LAAS, Toulouse, France

**TUPC-2: Second harmonic reduction in broadband HF/VHF/UHF class E RF power amplifiers**

K. Narendra<sup>1</sup>, A. Mediano<sup>2</sup>, L. Anand<sup>3</sup>, C. Prakash<sup>1</sup>, <sup>1</sup>Motorola Technology, Pulau Pinang, Malaysia, <sup>2</sup>University of Zaragoza, Zaragoza, Spain, <sup>3</sup>University Science Malaysia, Pulau Pinang, Malaysia

**TUPA-3: CMOS-based Monitoring of Contact Events up to 4 MHz in Ohmic RF MEMS Switches**

A. J. Fruehling, M. Abu Khater, B. Jung, D. Peroulis, Purdue University - Birck Nanotechnology Center, West Lafayette, United States

**TUPB-3: The Impact of Uniaxial Strain on Low Frequency Noise of Nanoscale PMOSFETs with e-SiGe and i-SiGe Source/Drain**

K. Yeh, W. Hong, J. Guo, National Chiao-Tung University, Hsinchu, Taiwan

**TUPC-3: A Novel Inverse Class-D Output Matching Network and its Application to Dynamic Load Modulation**

M. Gamal El Din, B. Geck, I. Rolfs, H. Eul, Leibniz Universität Hannover, Hannover, Germany

**TUPA-4: Variable Spring Constant, High Contact Force RF MEMS Switch**

H. Sedaghat-Pisheh, G. M. Rebeiz, University of California, San Diego (UCSD), San Diego, United States

**TUPB-4: Channel Temperature Estimation in GaAs FET Devices**

A. P. Fattorini<sup>1</sup>, J. Tarazi<sup>2</sup>, S. J. Mahon<sup>1</sup>, <sup>1</sup>Mimix Broadband, North Sydney, Australia, <sup>2</sup>Macquarie University, Sydney, Australia

**TUPC-4: DSP Assisted Low Cost IQ Mismatch Measurement and Compensation Using Built in Power Detector**

S. Sen, S. K. Devarakond, A. Chatterjee, Georgia Institute of Technology, Atlanta, United States

TUESDAY

ROOM 204ABC

15:00 - 17:00

**TUPE: mm-Wave and THz Signal Generation, Detection and Transmission**Jae-Sung Rieh, *Korea University*  
Tsuneo Tokumitsu, *Sumitomo Electric Ind.***TUPF: Microwave Photonics and Low Noise Receivers**Bill Jemison, *Lafayette College***TUPH: Packaging, Interconnect, MCMs, and Integration**Rudy Emrick, *General Dynamics***TUPE-1:Optically Generated Sub-THz Continuous Wave Using Feedbacked 3<sup>rd</sup> Order Double Sideband-Suppressed Carriers (DSB-SCs)**

S. Kim, K. Kang, Electronics and Telecommunications Research Institute, Daejeon, Republic of Korea

**TUPF-1: Microwave Photonic Instantaneous Frequency Measurement with Simultaneous Parallel Operation within a Single Optical Fiber**

N. Sarkhosh, H. Emami, L. Bui, A. Mitchell, School of Electrical and Computer Engineering, GPO Box 2476, Australia

**TUPH-1:Analytical Approaches to Calculating the Parasitic Coupling between Packages and Microwave Circuits**A. Beyer<sup>1</sup>, T. Bolz<sup>2</sup>, <sup>1</sup>Duisburg-Essen University, Campus Duisburg, Duisburg, Germany, <sup>2</sup>IMST GmbH, Kamp-Lintfort, Germany**TUPE-2:A Broadband Heterostructure Barrier Varactor Tripler Source**T. Bryllert<sup>2</sup>, J. Vukusic<sup>2</sup>, A. Olsen<sup>1</sup>, J. Stake<sup>2</sup>, <sup>1</sup>Wasa Millimeter Wave, Torslanda, Sweden, <sup>2</sup>Chalmers University of Technology, Goteborg, Sweden**TUPF-2:Optimization of Phase Noise in an All-optical Frequency Upconverter Utilizing an Optical Interleaver and a Semiconductor Optical Amplifier for Radio-over-Fiber Applications**

H. Kim, J. Song, Gwangju Institute of Science and Technology (GIST), Gwangju, Republic of Korea

**TUPH-2:Dual-band CRLH branch-line coupler in LTCC by lump elements with parasite control**

H. Lu, Y. Kuo, P. Huang, Y. Chang, National Taiwan University, Taipei, Taiwan

**TUPE-3:Highly Directive Package-Integrated Dipole Arrays for Low-Cost 60-GHz Front End Modules**A. L. Amadjikpè<sup>1</sup>, D. Choudhury<sup>2</sup>, G. E. Ponchak<sup>3</sup>, J. Papapolymerou<sup>1</sup>, <sup>1</sup>Georgia Institute of Technology, Atlanta, United States, <sup>2</sup>Intel Corporation, Hillsboro, United States, <sup>3</sup>NASA Glenn Research Center, Cleveland, United States**TUPF-3: Dynamics of the Optical Frequency Locked Loop using tunable Nd: YVO4 microchip lasers**M. Alemohammad<sup>1</sup>, Y. Li<sup>2</sup>, P. R. Herzfeld<sup>1</sup>, <sup>1</sup>Drexel University, Philadelphia, United States, <sup>2</sup>UMass Dartmouth, North Dartmouth, United States**TUPH-3:Cost-Effective High-Yield Manufacturing Process of Integrated Passive Devices (IPDs) for RF and Microwave Application**C. Wang<sup>1</sup>, W. Lee<sup>2</sup>, N. Kim<sup>1</sup>, <sup>1</sup>Kwangwoon University, Seoul, Republic of Korea, <sup>2</sup>Nano ENS Inc., Suwon, Republic of Korea**TUPE-4:SIP-based 60GHz 4x4 Antenna Array with 90nm CMOS OOK Modulator in LTCC**M. F. Karim<sup>1</sup>, M. Sun<sup>1</sup>, M. L. Ong<sup>1</sup>, Y. Guo<sup>2</sup>, J. Brinkhoff<sup>3</sup>, K. Kang<sup>3</sup>, F. Lin<sup>3</sup>, <sup>1</sup>Institute for Infocomm Research, Singapore, Singapore, <sup>2</sup>National University of Singapore, Singapore, Singapore, <sup>3</sup>Institute of Microelectronics, Singapore, United States**TUPF-4:A 18.85 mW 20-29 GHz Wideband CMOS LNA with 3.85±0.25 dB NF and 18.1±1.9 dB Gain**

Y. Chiu, Y. Lin, J. Chang, National Chi Nan University, Puli, Taiwan

**TUPH-4:Miniaturised Low Cost Solid State 4W TXRX Common leg for 6÷18 GHz Phased Array**

D. Baccello, M. D'Antoni, B. Orobello, E. Sperduti, Elettronica S.p.A., Roma, Italy

**TUPE-5:Analysis of Plasmon Excited by Metal-Insulator-Metal Structure with Insulator Thickness of Hundreds of Nanometers**

M. Tamura, H. Kagata, Panasonic Electronic Devices Co., Ltd., Kadoma, Japan

**TUPF-5:Differential Noise Figure Measurement: A Matrix Based Approach**

M. Robens, R. Wunderlich, S. Heinen, RWTH Aachen University, Aachen, Germany

**TUPH-5:Packaging of Microstrip Circuits Using Spring Mattress to Suppress Cavity Modes - a Replacement for Bed of Nails**E. Rajo-Iglesias<sup>1</sup>, P. Kildal<sup>2</sup>, A. A. Kishk<sup>3</sup>, <sup>1</sup>University Carlos III of Madrid, Leganes, Spain, <sup>2</sup>Chalmers University of Technology, Gothenburg, Sweden, <sup>3</sup>University of Mississippi, Mississippi, United States**TUPE-6:Energy Detection and Radiation by Metallic Rings Embedded into a Self-Rolled InGaAs/GaAs Micro-Tube**G. Monti<sup>1</sup>, R. De Paolis<sup>1</sup>, L. Tarricone<sup>1</sup>, M. T. Todaro<sup>2</sup>, M. De Vittorio<sup>2</sup>, A. Passaseo<sup>2</sup>, <sup>1</sup>University of Salento, Lecce, Italy, <sup>2</sup>Consiglio Nazionale delle Ricerche INFM, Lecce, Italy**TUPE-7:Experimental Characterization of EC-CPW Transmission Lines and Passive Components for 60-GHz CMOS Radios**I. Haroun<sup>2</sup>, J. Wight<sup>1</sup>, C. Plett<sup>1</sup>, A. Fathy<sup>3</sup>, <sup>1</sup>Calreton University, Ottawa, Canada, <sup>2</sup>Communications Research Centre Canada, Nepean, Canada, <sup>3</sup>The University of Tennessee, Knoxville, United States



TUESDAY TECHNICAL SESSIONS

15:30-17:10

**TU4A: Advances in Space Mapping Technologies for Design Optimization**

Paul Draxler, *Qualcomm, Inc. and UCSD*  
Jose E. Rayas-Sanchez, *ITESO*  
**Room: 203B**

**TU4B: Ultra Wide Band Planar Filters and Devices**

Magdalena Salazar-Palma, *Universidad Carlos III de Madrid*  
Roberto Gomez-Garcia, *Universidad de Alcala*  
**Room: 205AB**

**TU4C: Millimeter-Wave Power Amplifiers and Power-Combining Techniques**

Debasis Dawn, *Georgia Institute of Technology*  
Chang-Ho Lee, *Samsung Electro-Mechanics*  
**Room: 206AB**

15:30 - 15:50

**TU4A-1: Response Corrected Tuning Space Mapping for Yield Estimation and Design Centering**  
Q. S. Cheng<sup>1</sup>, J. W. Bandler<sup>1</sup>, S. Koziel<sup>2</sup>, <sup>1</sup>McMaster University, Hamilton, Canada, <sup>2</sup>Reykjavik University, Reykjavik, Iceland

**TU4B-1: A 20-90 MHz 26-Channel Cochlear-Based Channelizer**  
Y. C. Ou, G. M. Rebeiz, University of California, San Diego, La Jolla, United States

**TU4C-1: W-Band GaN MMIC with 842 mW Output Power at 88 GHz**  
M. Micovic<sup>1</sup>, A. Kurdoghlian<sup>1</sup>, K. Shinohara<sup>1</sup>, I. Milosavljevic<sup>1</sup>, S. D. Burnham<sup>1</sup>, M. Hu<sup>1</sup>, A. L. Corrion<sup>1</sup>, W. S. Wong<sup>1</sup>, A. Schmitz<sup>1</sup>, P. B. Hashimoto<sup>1</sup>, P. J. Willadsen<sup>1</sup>, D. H. Chow<sup>1</sup>, A. Fung<sup>2</sup>, R. H. Lin<sup>2</sup>, L. Sarnoska<sup>2</sup>, P. P. Kangaslahti<sup>2</sup>, B. H. Lambriqtsen<sup>2</sup>, P. F. Goldsmith<sup>2</sup>, <sup>1</sup>HRL Laboratories LLC, Malibu, United States, <sup>2</sup>JPL, Pasadena, United States

15:50 - 16:10

**TU4A-2: Surrogate Modeling of Microwave Circuits Using Polynomial Functional Interpolants**  
J. E. Rayas-Sanchez, J. Aguilar-Torrentera, J. A. Jasso-Urzuza, *ITESO, Tlaquepaque, Mexico*

**TU4B-2: Two Novel Classes of Band-Reject Filters Realizing Broad Upper Pass Bandwidth**  
W. M. Fathelbab, H. M. Jaradat, D. Reynolds, South Dakota School of Mines and Technology, Rapid City, United States

**TU4C-2: W-Band, 5W Solid-State Power Amplifier/Combiner**  
J. Schellenberg<sup>1</sup>, E. Watkins<sup>1</sup>, M. Micovic<sup>2</sup>, B. Kim<sup>1</sup>, K. Han<sup>1</sup>, <sup>1</sup>QuinStar Technology, Torrance, United States, <sup>2</sup>HRL Laboratories, Malibu, United States

16:10 - 16:30

**TU4A-3: Robust Multi-Fidelity Simulation-Driven Design Optimization of Microwave Structures**  
S. Koziel, S. Ogurtsov, Reykjavik University, Reykjavik, Iceland

**TU4B-3: A Compact UWB Bandpass Filter with Ultra Narrow Notched Band and Competitive Attenuation Slope**  
X. Luo<sup>1</sup>, H. Qian<sup>1</sup>, J. Ma<sup>2</sup>, K. Ma<sup>3</sup>, K. S. Yeo<sup>4</sup>, <sup>1</sup>University of Electronic Science and Technology of China, Chengdu, China, <sup>2</sup>Tianjin University, Tianjin, China, <sup>3</sup>ST Electronics, Singapore, Singapore, <sup>4</sup>Nanyang Technological University, Singapore, Singapore

**TU4C-3: A Compact Self-similar Power Combining Topology**  
K. Sengupta, A. Hajimiri, California Institute of Technology, Pasadena, United States

16:30 - 16:50

**TU4A-4: Adaptively Constrained Parameter Extraction for Robust Space Mapping Optimization of Microwave Circuits**  
S. Koziel<sup>1</sup>, J. W. Bandler<sup>2</sup>, Q. S. Cheng<sup>2</sup>, <sup>1</sup>Reykjavik University, Reykjavik, Iceland, <sup>2</sup>McMaster University, Hamilton, Canada

**TU4B-4: New Bandstop Filter Based on Capacitively Coupled Lambda/4 Short-Circuited Lines Embedded into U.S. UWB BPF**  
T. Duong, I. Kim, Kyung Hee University, Yongin-si, Republic of Korea

**TU4C-4: A 22-dBm 24-GHz power amplifier using 0.18-µm CMOS technology**  
P. Huang, J. Joo, Z. Tsai, K. Lin, H. Wang, Department of Electrical Engineering, Taipei, Taiwan

16:50 - 17:10

**TU4A-5: Automated Synthesis of Resonant-type Metamaterial Transmission Lines using Aggressive Space Mapping**  
A. Rodriguez<sup>1</sup>, J. Selga<sup>2</sup>, M. Gil<sup>2</sup>, J. Carbonell<sup>3</sup>, V. E. Boria<sup>1</sup>, F. Martín<sup>2</sup>, <sup>1</sup>Universidad Politécnica de Valencia, Valencia, Spain, <sup>2</sup>Universitat Autònoma de Barcelona, Bellaterra, Spain, <sup>3</sup>Universidad Politécnica de Valencia, Valencia, Spain

**TU4B-5: Wideband Ring Resonator Bandpass Filter With Dual Stepped Impedance Stubs**  
C. H. Kim, K. Chang, Texas A&M University, College Station, United States

17:00 - 17:10

**TU4B-6: Novel Low Cost Compact Size Planar Low Pass Filters with Deep Skirt Selectivity and Wide Stopband Rejection**  
K. Ma<sup>1</sup>, K. Yeo<sup>2</sup>, <sup>1</sup>ST Electronics, Singapore, Singapore, <sup>2</sup>Nanyang Technological University, Singapore, Singapore

TUESDAY

TECHNICAL SESSIONS

15:30-17:10

**TU4D: Novel Circuit and System Technologies for Wireless Communications**  
 Kyutae Lim, *Georgia Institute of Technology*  
 Shoichi Narahashi, *NTT DOCOMO, INC.*  
**Room: 202AB**

**TU4E: Microwave and Millimeter Wave VCOs**  
 John Papapolymerou, *Georgia Institute of Technology*  
 Yi-Jan Emery Chen, *National Taiwan University*  
**Room: 207C**

**TU4D-1: ISO-less, SAW-less Open-loop Polar Modulation Transceiver for 3G/GSM/EDGE Multi-mode/Multi-band Handset**  
 T. Tsukizawa<sup>1</sup>, M. Nakamura<sup>1</sup>, G. L. Do<sup>2</sup>, M. Igarashi<sup>3</sup>, K. Ishida<sup>1</sup>, <sup>1</sup>Panasonic Corporation, Yokohama, Japan, <sup>2</sup>Panasonic Corporation, San Jose, United States, <sup>3</sup>Panasonic Corporation, Nagaokakyo, Japan

**TU4E-1: 300GHz Fixed-Frequency and Voltage-Controlled Fundamental Oscillators in an InP DHBT Process**  
 M. Seo<sup>1</sup>, M. Urteaga<sup>1</sup>, A. Young<sup>1</sup>, V. Jain<sup>2</sup>, Z. Griffith<sup>1</sup>, J. Hacker<sup>1</sup>, P. Rowell<sup>1</sup>, R. Pierson<sup>1</sup>, M. Rodwell<sup>2</sup>, <sup>1</sup>Teledyne Scientific & Imaging, Thousand Oaks, United States, <sup>2</sup>University of California, Santa Barbara, Santa Barbara, United States

15:30 - 15:50

**TU4D-2: A Highly Integrated Dual Band SiGe BiCMOS Power Amplifier that Simplifies Dual-band WLAN and MIMO Front-End Circuit Designs**  
 Chun-Wen Paul Huang, Mark Doherty, Philip Antognetti, Lui (Ray) Lam, and William Vaillancourt  
 SiGe Semiconductor, Andover, MA 01810, USA  
 C. P. Huang, M. Doherty, P. Antognetti, L. Lam, W. Vaillancourt, SiGe Semiconductor, Andover, United States

**TU4E-2: Oscillator Phase-Noise Reduction Using Low-Noise High-Q Active Resonators**  
 M. Nick, A. Mortazawi, University of Michigan, Ann Arbor, United States

15:50 - 16:10

**TU4D-3: A Technique for Wireless LAN Connection through Building Concrete Wall at 2.4GHz.**  
 S. Mizushima, A. Adachi, Enegene Co. Ltd., Hamamatsu, Japan

**TU4E-3: Low Phase Noise Load Independent Switched LC VCO**  
 P. Liu<sup>1</sup>, P. Upadhyaya<sup>2</sup>, J. Jung<sup>1</sup>, T. Luo<sup>3</sup>, Y. Chen<sup>2</sup>, D. Heo<sup>1</sup>, <sup>1</sup>Washington State University, Pullman, United States, <sup>2</sup>Xilinx Inc., San Jose, United States, <sup>3</sup>National Taiwan University, Taipei, Taiwan

16:10 - 16:30

**TU4D-4: Asymmetric multilevel outphasing transmitter using Class-E PAs with discrete pulse width modulation**  
 S. Chung, P. A. Godoy, T. W. Barton, J. L. Dawson, D. J. Perreault, Massachusetts Institute of Technology, Cambridge, United States

**TU4E-4: A C-Band GaAs-pHEMT MMIC Low Phase Noise VCO for Space Applications Using a New Cyclostationary Nonlinear Noise Model**  
 C. Florian<sup>1</sup>, P. A. Traverso<sup>1</sup>, M. Feudale<sup>2</sup>, F. Filicori<sup>1</sup>, <sup>1</sup>University of Bologna, Bologna, Italy, <sup>2</sup>Thales Alenia Space Italia, Roma, Italy

16:30 - 16:50

**TU4D-5: Experimental Performance Evaluation of IQ Imbalance and DC Offset Estimation and Compensation Technique for 3GPP LTE Base Station**  
 A. Yamaoka, K. Yamaguchi, T. Kato, Y. Tanabe, TOSHIBA Corporation, Kawasaki, Japan

**TU4E-5: A Millimeter-Wave Reflection-Type Dual-Frequency VCO MMIC with a Coupled Line**  
 H. Mizutani, K. Nishida, M. Tsuru, K. Kawakami, M. Hieda, E. Taniguchi, M. Shimozawa, Y. Hirano, Mitsubishi Electric Corporation, Kamakura, Japan

16:50 - 17:10





WEDNESDAY TECHNICAL SESSIONS

8:00-9:40

**WE1A: Modeling and Characterization of Devices**

John Atherton, *Win Semiconductor*  
 Jim Hwang, *Lehigh University*  
**Room: 205AB**

**WE1B: New Synthesis Techniques for Filter and Multiplexers**

Ming Yu, *COM DEV*  
 Giuseppe Macchiarella, *Politecnico di Milano*  
**Room: 206AB**

**WE1C: Advanced Millimeter-Wave Packaging**

Kavita Goverdhanam, *US Army CERDEC*  
 C.K. Clive Tzuang, *National Taiwan University*  
**Room: 207AB**

**WE1D: Advances in microwave sensors and object detection systems.**

Lora Schulwitz, *General Dynamics*  
 Manos Tentzeris, *GEDC, Georgia Tech*  
**Room: 207C**

8:00 - 8:20

**WE1A-1: Sub-nanosecond Pulse Characteristics of InGaP/GaAs HBTs**

R. Jin, C. Chen, S. Halder, W. R. Curtice, J. C. Hwang, *Lehigh University, Bethlehem, United States*

**WE1B-1: Design of Triplexer Combiners for Base Stations of Mobile Communications**

G. Macchiarella<sup>1</sup>, S. Tamiazzo<sup>2</sup>, <sup>1</sup>Politecnico di Milano, Milano, Italy, <sup>2</sup>Andrew Telecommunication Products, Agrate Brianza, Italy

**WE1C-1: Cost-Effective 60-GHz Antenna-Packaging with End-Fire Radiation from Open-Ended Post-Wall Waveguide for Wireless File-Transfer System**

R. Suga<sup>1</sup>, H. Nakano<sup>2</sup>, Y. Hirachi<sup>2</sup>, J. Hirokawa<sup>1</sup>, M. Ando<sup>1</sup>, <sup>1</sup>Tokyo Institute of Technology, Tokyo, Japan, <sup>2</sup>AMMSYS Inc., Tokyo, Japan

**WE1D-1: A Microwave-Based Gamma-Ray Detector**

B. Cetinoneri<sup>1</sup>, Y. A. Atesal<sup>1</sup>, R. A. Kroeger<sup>2</sup>, G. Tepper<sup>3</sup>, J. Losee<sup>2</sup>, C. Hicks<sup>1</sup>, M. Rasmussen<sup>2</sup>, G. M. Rebeiz<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Space and Naval Warfare Systems Center, San Diego, United States, <sup>3</sup>Virginia Commonwealth University, Richmond, United States

8:20 - 8:40

**WE1A-2: Characterization of Trapping and Thermal Dispersion in GaN HEMTs**

S. A. Albahrani, A. E. Parker, *Macquarie University, Sydney, Australia*

**WE1B-2: Direct Synthesis of General Chebyshev Bandpass Filters with A Frequency Variant Complex Load**

M. Meng, K. L. Wu, *The Chinese University of Hong Kong, Hong Kong, Hong Kong*

**WE1C-2: A 77 GHz Broadband Flip-Chip Transition on LTCC Submount**

F. J. Schmueckle<sup>1</sup>, U. Pursche<sup>1</sup>, W. Heinrich<sup>1</sup>, J. Purden<sup>2</sup>, <sup>1</sup>Ferdinand-Braun-Institut für Höchstfrequenztechnik (FBH), Berlin, Germany, <sup>2</sup>Delphi, Malibu, United States

**WE1D-2: A Novel Passive Wireless Ultra-sensitive Temperature RF Transducer for Remote Sensing**

T. T. Thai<sup>2</sup>, M. Jatlaoui<sup>1</sup>, P. Pons<sup>1</sup>, H. Aubert<sup>4</sup>, M. Tentzeris<sup>2</sup>, G. DeJean<sup>3</sup>, R. Plana<sup>1</sup>, <sup>1</sup>LAAS, Toulouse, France, <sup>2</sup>Georgia Institute of Technology, Atlanta, United States, <sup>3</sup>Microsoft Research, One Microsoft Way, Redmond, United States, <sup>4</sup>Université de Toulouse, Toulouse, France

8:40 - 9:00

**WE1A-3: Large-signal FET Models with Multiple Time Scale Dynamics from Nonlinear Vector Network Analyzer Data**

J. Xu, J. Horn, M. Iwamoto, D. E. Root, *Agilent Technologies, Inc., Santa Rosa, United States*

**WE1B-3: New Distributed Model for Synthesis of Classical Dual Mode Filters**

S. Cogollos<sup>1</sup>, M. Brumos<sup>1</sup>, V. E. Boria<sup>1</sup>, C. Vicente<sup>2</sup>, B. Gimeno<sup>3</sup>, M. Guglielmi<sup>4</sup>, <sup>1</sup>Universidad Politecnica de Valencia, Valencia, Spain, <sup>2</sup>Aurorasat, s.l., Valencia, Spain, <sup>3</sup>Universidad de Valencia, Burjasot, Spain, <sup>4</sup>European Space Research and Technology Centre (ESTEC), Noordwijk, Netherlands

**WE1C-3: Broadband, Quad Flat No-Lead (QFN) Package Developed using Standard Overmold Leadframe Technology**

M. J. Chen, S. A. Tabatabaei, *Endwave Corporation, San Jose, United States*

**WE1D-3: Novel Image Reconstruction Algorithm for a UWB Cylindrical Microwave Imaging System**

M. E. Bialkowski, Y. Wang, A. Abu Bakar, W. Khor, *University of Queensland, Brisbane, Australia*

9:00 - 9:20

**WE1A-4: Compact RF Large-Signal Model for MEMS Capacitive Switches**

S. Halder<sup>1</sup>, C. Palego<sup>1</sup>, J. C. Hwang<sup>1</sup>, C. L. Goldsmith<sup>2</sup>, <sup>1</sup>Lehigh University, Bethlehem, United States, <sup>2</sup>Memtronics Corporation, Plano, United States

**WE1B-4: Wide-Band Bandpass Filters Simulation, Design and Diagnosis**

H. Lee<sup>1</sup>, K. Zaki<sup>1</sup>, A. Atia<sup>2</sup>, <sup>1</sup>College Park, United States, <sup>2</sup>Orbital Sciences Corporation, Dulles, United States

**WE1C-4: A Highly Integrated Heterogeneous Micro- and mm-wave Platform**

P. Alleaume<sup>1</sup>, L. Aspemyr<sup>2</sup>, S. Gevorgian<sup>3</sup>, J. Houdbert<sup>4</sup>, H. Jacobsson<sup>2</sup>, L. Pettersson<sup>5</sup>, D. Platt<sup>5</sup>, M. Salter<sup>5</sup>, A. Vorobiev<sup>3</sup>, <sup>1</sup>United Monolithic Semiconductors, Orsay Cedex, France, <sup>2</sup>Ericsson AB, Mölndal, Sweden, <sup>3</sup>Chalmers University of Technology, Gothenburg, Sweden, <sup>4</sup>STMicroelectronics, Tours Cedex 2, France, <sup>5</sup>Acree, Norrköping, Sweden

**WE1D-4: Multi-Resonant Perturbation Method for Capacitive Sensing with Composite Right/Left-Handed Transmission Lines**

M. Schüßler, M. Puentes, C. Mandel, R. Jakoby, *TU Darmstadt, Darmstadt, Germany*

9:20 - 9:40

**WE1A-5: Third-Order Intermodulation Distortion due to Self-heating in Gold Coplanar Waveguides**

E. Rocas<sup>1</sup>, C. Collado<sup>1</sup>, N. Orloff<sup>2</sup>, J. C. Booth<sup>2</sup>, <sup>1</sup>Universitat Politècnica de Catalunya, Barcelona, Spain, <sup>2</sup>National Institute of Standards and Technology, Boulder, United States

**WE1B-5: Tri-band Filter Design using Substrate Integrated Waveguide Resonators in LTCC.**

W. Tsai<sup>1</sup>, R. Wu<sup>2</sup>, <sup>1</sup>Graduate Institute of Communication Engineering, Taipei, Taiwan, <sup>2</sup>Graduate Institute of Communication Engineering, Taipei, Taiwan

**WE1C-5: W-band Flip-Chip Assembled CMOS Amplifier with Transition Compensation Network for SiP Integration**

C. Kuo<sup>1</sup>, P. Lin<sup>2</sup>, H. Lu<sup>1</sup>, Y. Jiang<sup>1</sup>, C. Liu<sup>1</sup>, Y. Hsin<sup>2</sup>, H. Wang<sup>1</sup>, <sup>1</sup>National Taiwan University, Taipei, Taiwan, <sup>2</sup>National Central University, Zhongli, Taiwan

WEDNESDAY TECHNICAL SESSIONS

8:00-9:40

**WE1E: Advances in Low Noise Technologies**  
James Whelehan, *JJW Consulting, Inc*,  
Matthias Rudolph, *Brandenburg Univ. of  
Technology*  
Room: 207D

**WE1F: High Efficiency Power Devices in  
Various Technologies**  
Aryeh Platzker, *Raytheon Company*  
Douglas Teeter, *RFMD*  
Room: 208AB

**WE1G: Status and Trends in E-scan Radar for  
Air- and Spaceborne Applications.**  
Hans van Bezouwen, *EADS Deutschland*  
Wolfgang Holpp, *EADS Deutschland*  
Room: 209AB

<p><b>WE1E-1: A 6.5kV ESD-Protected Low Noise Amplifier in 65-nm CMOS</b> M. H. Tsai<sup>1</sup>, F. L. Hsueh<sup>1</sup>, C. P. Jou<sup>1</sup>, M. H. Song<sup>1</sup>, J. C. Tseng<sup>1</sup>, S. S. Hsu<sup>2</sup>, S. Chen<sup>1</sup>, <sup>1</sup>Taiwan Semiconductor Manufacturing Company, Hsinchu, Taiwan, <sup>2</sup>National Tsing Hua University, Hsinchu, Taiwan</p>	<p><b>WE1F-1: 43W, 52% PAE X-Band AlGaIn/GaN HEMTs MMIC Amplifiers</b> S. Piotrowicz<sup>1</sup>, Z. Ouarch<sup>2</sup>, E. Chartier<sup>1</sup>, R. Aubry<sup>1</sup>, G. Callet<sup>1</sup>, D. Floriot<sup>2</sup>, J. Jacquet<sup>1</sup>, O. Jardel<sup>1</sup>, E. Morvan<sup>1</sup>, T. Reveyrand<sup>3</sup>, N. Sarazin<sup>1</sup>, S. Delage<sup>1</sup>, <sup>1</sup>ALCATEL-THALES III-V Lab, Marcoussis, France, <sup>2</sup>United Monolithic Semiconductors, Orsay, France, <sup>3</sup>XLIM, Limoges, France</p>	<p><b>WE1G-1: Status and Trends in AESA-based Radar</b> H. van Bezouwen, H. Feldle, EADS Deutschland GmbH, Ulm, Germany</p>	<p>8:00 - 8:20</p>
<p><b>WE1E-2: A 4.9-dB NF 53.5-62-GHz Micro-machined CMOS Wideband LNA with Small Group-Delay-Variation</b> Y. Lin<sup>1</sup>, C. Chen<sup>1</sup>, P. Huang<sup>2</sup>, S. Lu<sup>2</sup>, <sup>1</sup>National Chi Nan University, Puli, Taiwan, <sup>2</sup>National Taiwan University, Taipei, Taiwan</p>	<p><b>WE1F-2: Evaluation of a GaN HEMT Transistor for Load- and Supply-Modulation Applications Using Intrinsic Waveform Measurements</b> H. Mashad Nemat<sup>1</sup>, A. L. Clarke<sup>2</sup>, S. C. Cripps<sup>2</sup>, J. Benedikt<sup>2</sup>, P. J. Tasker<sup>2</sup>, C. Fager<sup>1</sup>, J. Grahn<sup>1</sup>, H. Zirath<sup>1</sup>, <sup>1</sup>Chalmers University of Technology, Gothenburg, Sweden, <sup>2</sup>Cardiff School of Engineering, Cardiff University, Cardiff, United Kingdom</p>	<p><b>WE1G-2: The New Generation of European E-Scan Fighter Radars</b> W. Holpp, EADS Deutschland GmbH, Ulm, Germany</p>	<p>8:20 - 8:40</p>
<p><b>WE1E-3: An Ultra-Broadband Robust LNA for Defence Applications in AlGaIn/GaN Technology</b> E. Limiti<sup>1</sup>, W. Ciccognani<sup>1</sup>, P. E. Longhi<sup>2</sup>, C. Mitrano<sup>2</sup>, A. Nanni<sup>3</sup>, M. Peroni<sup>3</sup>, <sup>1</sup>Università di Roma Tor Vergata, Roma, Italy, <sup>2</sup>Elettronica S.p.A., Roma, Italy, <sup>3</sup>Selex Sistemi Integrati S.p.A., Roma, Italy</p>	<p><b>WE1F-3: High-efficiency class E MMIC power amplifiers at 4.0 GHz using AlGaIn/GaN HEMT technology</b> V. Zomorrodian, Y. Pei, U. K. Mishra, R. A. York, University of California Santa Barbara, Santa Barbara, United States</p>	<p><b>WE1G-3: The SAR/GMTI Airborne Radar PAMIR: Technology and Performance</b> H. Wilden<sup>2</sup>, A. Brenner<sup>2</sup>, <sup>1</sup>Fraunhofer FHR, Wachtberg, Germany, <sup>2</sup>Fraunhofer FHR, Wachtberg, Germany</p>	<p>8:40 - 9:00</p>
<p><b>WE1E-4: Miniature Low Noise G-band I-Q Receiver</b> P. Kangaslahti<sup>1</sup>, D. Pukala<sup>1</sup>, A. Tanner<sup>1</sup>, I. O'Dwyer<sup>1</sup>, B. Lambrigtsen<sup>1</sup>, T. Gaier<sup>1</sup>, X. Mei<sup>2</sup>, R. Lai<sup>2</sup>, <sup>1</sup>Jet Propulsion Laboratory, California Institute of Technology, Pasadena, United States, <sup>2</sup>Northrop Grumman Corporation, Redondo Beach, United States</p>	<p><b>WE1F-4: A 1 W Si-LDMOS Power Amplifier with 40 % Drain Efficiency for 6 GHz WLAN Applications</b> D. Gruner<sup>1</sup>, R. Sorge<sup>2</sup>, O. Bengtsson<sup>1</sup>, A. Z. Markos<sup>1</sup>, G. Boeck<sup>1</sup>, <sup>1</sup>Berlin Institute of Technology, Berlin, Germany, <sup>2</sup>IHP GmbH, Frankfurt (Oder), Germany</p>	<p><b>WE1G-4: Spaceborne SAR Systems and Technologies</b> C. Heer, C. Fischer, Astrium, Friedrichshafen, Germany</p>	<p>9:00 - 9:20</p>
<p><b>WE1E-5: A Versatile and Cryogenic mHEMT-Model Including Noise</b> M. Seelmann-Eggebert<sup>1</sup>, F. Schäfer<sup>2</sup>, A. Leuther<sup>1</sup>, H. Massler<sup>1</sup>, <sup>1</sup>Fraunhofer IAF, Freiburg, Germany, <sup>2</sup>MPiFR, Bonn, Germany</p>	<p><b>WE1F-5: High Efficiency Push-Pull Inverse Class F Power Amplifier Using a Balun and Harmonic Trap Waveform Shaping Network</b> A. N. Stameroff<sup>1</sup>, A. V. Pham<sup>1</sup>, R. E. Leoni III<sup>2</sup>, <sup>1</sup>University of California Davis, Davis, United States, <sup>2</sup>Raytheon Company, Andover, United States</p>	<p><b>WE1G-5: Earth Observation Instruments with E-Scan Antennas State-of-the-Art and Outlook</b> M. Ludwig<sup>1</sup>, C. H. Buck<sup>1</sup>, S. D'Addio<sup>1</sup>, R. Torres<sup>1</sup>, F. Rostan<sup>2</sup>, C. Schaefer<sup>2</sup>, R. Croci<sup>3</sup>, <sup>1</sup>Esa/Estec, Noordwijk, Netherlands, <sup>2</sup>Astrium GmbH, Friedrichshafen, Germany, <sup>3</sup>Thales Alenia Space, Roma, Italy</p>	<p>9:20 - 9:40</p>



# WEDNESDAY FOCUSED AND PANEL SESSIONS

**Wednesday 08:00 – 09:40 Room 209AB**

**Status and Trends in E-Scan Radar for Air- and Spaceborne Applications**

**Chair:** Hans van Bezouwen  
*EADS Deutschland*

**Co-Chair:** Wolfgang Holpp,  
*EADS Deutschland*

**Sponsor:** IMS 2010 TPC

**Abstract:** Active Electronically Steered Array (AESA) antennas provide today's and future radar systems with an enormous degree of operational flexibility. These arrays constitute the very foundation kernels of E-Scan radars with highly enhanced capabilities, and opening up a wide spectrum of new air- and spaceborne applications. This Focused Session will give an overview of the current status and trends in E-Scan Radar, with emphasis on air- and spaceborne applications, and will illustrate actual European advances in the area of fighter radar, air- and spaceborne SAR/GMTI radar as well as spaceborne radar for Global Monitoring for Environment and Security.

**Wednesday 10:10 – 11:50 Room 209AB**

**Trends in Future Systems with Low Cost Phased Arrays**

**Chair:** Jeffery Herd  
*MIT Lincoln Laboratory*

**Co-Chair:** John Horton  
*J. B. Horton Group*

**Sponsor:** IMS 2010 TPC, MTT-12

**Abstract:** Electronically steered phased array antennas will provide a large degree of operational flexibility in future systems. These arrays, with the new capabilities, open a wide spectrum of new applications. The applications covered here rely on low cost arrays. This session will provide an overview of the developments required for wide spread use of low cost arrays in future systems.

**Wednesday 12:00 – 13:10 Room 210AB**

**Semiconductor Technology Impact on Microwave and Millimeter Wave Markets**

**Chair/Moderator:** Doug Lockie, *Gigabeam*

**Panelists:**

Mike Peters, *TriQuint Semiconductor*  
Miroslav Micovic, *HRL Laboratories*  
Earl Lum, *EJL Wireless*  
Paul Blount, *Custom MMIC Design Services*

**Abstract:** Continuing progress in Silicon (Standard CMOS and SiGe) and GaN technologies is setting the stage for rewriting the application rules in microwave and millimeter wave market spaces. At the same time, GaAs performance and cost improvements are holding their own against silicon incursions at lower frequencies for cellular phone and WiFi/Wimax radios.

This panel will review recent progress in semiconductor technologies, emerging microwave and millimeter wave markets, and the give and take between silicon, SiGe, GaAs, InP and GaN semiconductor platforms. Projections on the future markets and semiconductor market shares will be made by industry experts.

**Wednesday 12:00 – 13:10 Room 210CD**

**Standardizing Attributes for RF and Microwave Components and Assemblies – The Time Is Now?**

**Chairs/Moderators:**

Dr. Chandra Gupta, *Aeroflex-KDI*  
Dr. Paul Khanna, *Phase Matrix*

**Panelists:**

Douglas Bajgot Cobham *DES*  
Thomas Eichenberger, *Northrop Grumman*  
Joe Graycar, *Teledyne Microwave*  
Peter Pupalaiakis, *LeCroy Corporation*  
Steve Schwerdtfeger, *Telephonics Corporation*

**Abstract:** At this panel we will explore on the need for standards for RF and Microwave Components and Sub-Assemblies. We will discuss electrical and mechanical parameters and characteristics such as connector interfaces, biases, EMI, mechanical dimensions as well as the pros and cons of developing standards. The potential advantages are immense: standardization will lead to lower manufacturing costs, economy of scale, faster development cycles and will eliminate repetitive analyses by different manufacturers for the same part. In this forum, we bring together key representatives from the user and manufacturing community to discuss this timely topic as this industry reaches maturity and applications proliferate. One session will naturally not be enough for this broad topic; however, this panel session will allow us to share opinions on the topic, and a course of action may be determined from the outcome of this session.



## WEDNESDAY FOCUSED AND PANEL SESSIONS

**Wednesday**    **13:20 – 15:00**    **Room 209AB**

### **Microwave Space Sensors**

**Chair:** J Frank Maiwald,  
*JPL/Caltech*

**Co-Chair:** Alain Maestrini,  
*Observatoire de Paris*

**Sponsor:** MTT 4, IMS 2010 TPC

**Abstract:** This focused session includes progress made in development of microwave space Sensors for past and future space missions. Along with a review of space missions and their impact on the science community, two recent projects will be presented in detail: 1) JUNO, a polar orbiter around Jupiter (currently under development), and 2) the Herschel space telescope (launched in 2009). New hardware including digital radiometers and frontend hardware using HEMT MMIC devices, operating at frequencies beyond 100 GHz, will be presented.

**Wednesday**    **15:30 – 17:10**    **Room 209AB**

### **CAD Techniques and Methodologies: Future Directions**

**Chair:** Q.J. Zhang  
*Department of Electronics, Carleton University*

**Co-Chair:** Arvind Sharma  
*Northrop Grumman Aerospace Systems*

**Sponsor:** IMS 2010 Steering Committee

**Abstract:** CAD techniques and methodologies are essential in helping microwave designers to achieve improved designs in a shorter time. Also, accurate modeling has become more challenging as the industry moves towards higher frequencies, from RF/microwave to millimeter-wave and beyond. This focused session will present a review of the state of the art, and describe future trends of Microwave CAD.

# SPECIAL SESSION IN HONOR OF DR. KIYO TOMIYASU

Wednesday, May 26, 2010

15:30 - 17:10

Convention Center, Room 210 AB

**Chair:** John Horton

**Co-Chair:** Josef Modelski

**Plenary Session:** Dr. Tomiyasu will receive the Thomas Alva Edison Medal at the IMS 2010 Plenary Session, and he will be inducted into the IEEE Heritage Circle, which is the IEEE Foundation's donor recognition program. Dr. Tomiyasu has helped established two IEEE Foundation Funds that support students: the Harold Sobol Student Grant, administered by the MTT Society; and the Mike Takagi Student Prize, Administered by the IEEE Geoscience and Remote Sensing Society (GRSS).. Also, he set up and funded the IEEE Kiyo Tomiyasu Award, the technical field award that recognizes early-to-mid-career contributions to technologies that show promise of innovative applications.



## Special Session (WE4S)

This Special Session will include invited speakers to recall activities associated with Dr. Tomiyasu, and his contributions to the MTTs, GRSS and the IEEE. Three speakers have been invited, but additional speakers can be heard, as time permits.

**Session Abstract:** This session is dedicated to the career of Dr. Kiyo Tomiyasu. His career includes technical accomplishments in Microwaves, Lasers, and remote sensing of the earth using satellite-borne radiometers, scatterometers and synthetic radars. He has contributed much to MTT-S, and to the IEEE, including creating awards and providing contributions to guarantee perpetuation of the awards.

**Biography:** Kiyo Tomiyasu received his B. S. degree in electrical engineering from the California Institute of Technology, Pasadena, CA, in 1940; the M. S. degree in communication engineering from Columbia University, New York, NY, in 1941; and his Ph.D degree in engineering science and applied physics from Harvard University in 1948. In 1949, he joined the Sperry Gyroscope Company (in Seymour Cohn's group), Great Neck, NY in 1941 as a Project Engineer. In 1955 he joined the General Electric Microwave Laboratory, Palo Alto, CA, as a Consulting Engineer, and five years later he transferred to the General Electric Research and Development Center, Schenectady, NY, where he was involved with lasers and microwave projects. In 1969 he became a Consulting Engineer in the General Electric Valley Forge Space Center, Philadelphia, PA. He was involved with microwave remote sensing of the earth using satellite-borne radiometers, scatterometers, and synthetic aperture radars.

**IEEE Activities:** Dr. Tomiyasu is a Life Fellow of IEEE, with over 60 years membership. He was President of the IEEE MTT Society during 1960-1961, and served on its Nomination Committee and Awards Committee. He was Editor of the Transactions of MTT in 1958 and 1959, and Guest Editor of the of the May 1978 Special Issue of the Transactions of MTT on High Power Microwaves. In 1973, he was elected Honorary Life Member of the MTT Society and its Administration Committee (AdCom). He was named recipient of the Microwave Career Award in 1980, and the Distinguished Service Award in 1987. He was recipient of the IEEE Centennial Medal in 1984 and the Third Millennium Medal in 2000. He is an Honorary Lifetime Member of the IEEE GRSS and its AdCom, and he received its Outstanding Service Award in 1986.



WEDNESDAY TECHNICAL SESSIONS

10:10-11:50

	<p><b>WE2A: Nonlinear circuit analysis and system modeling</b>                  J Stevenson Kenney, <i>Georgia Institute of Technology</i>                  Jose Carlos Pedro, <i>University of Aveiro</i>  <b>Room: 205AB</b></p>	<p><b>WE2B: Novel Techniques for Planar Filter Design</b>                  Christopher Galbraith, <i>MIT Lincoln Laboratory</i>                  Chi Wang, <i>Orbital Sciences Corp.</i>  <b>Room: 206AB</b></p>	<p><b>WE2C: Advances in Measurement: Microwaves Through Sub-Millimeter-Waves</b>                  Ken Wong, <i>Agilent Technologies</i>                  Leonard Hayden, <i>Cascade Microtech, Inc.</i>  <b>Room: 207AB</b></p>	<p><b>WE2D: RF and Microwave in Medicine: Medical Sensors and Devices</b>                  Mohammad-Reza Tofighi, <i>Penn State University</i>                  Natalia K. Nikolava, <i>McMaster University</i>  <b>Room: 207C</b></p>
10:10 - 10:30	<p><b>WE2A-1: A New Mixed Time-Frequency Simulation Method for Nonlinear Heterogeneous Multirate RF Circuits</b>                  J. S. Oliveira<sup>1</sup>, J. C. Pedro<sup>2</sup>, <sup>1</sup>Polytechnic Institute of Leiria, Leiria, Portugal, <sup>2</sup>University of Aveiro, Aveiro, Portugal</p>	<p><b>WE2B-1: Synthesis of 4th order lossy filters with uniform Q distribution</b>                  J. Mateu<sup>1</sup>, A. Padilla<sup>1</sup>, C. Collado<sup>1</sup>, M. Martinez-Mendoza<sup>2</sup>, E. Rocas<sup>1</sup>, C. Ernst<sup>2</sup>, J. M. O'Callaghan<sup>1</sup>, <sup>1</sup>Universitat Politècnica de Catalunya, Castelldefels, Spain, <sup>2</sup>ESA, Noordwijk, Netherlands</p>	<p><b>WE2C-1: Understanding the Effect of Uncorrelated Phase Noise on the Phase Coherency of Multi-Channel RF Vector Signal Analyzers</b>                  D. A. Hall, A. Hinde, National Instruments, Austin, United States</p>	<p><b>WE2D-1: An Implantable Batteryless Wireless Impedance Sensor for Gastroesophageal Reflux Diagnosis</b>                  T. Ativanichayaphong<sup>1</sup>, S. Tang<sup>2</sup>, L. Hsu<sup>1</sup>, W. Huang<sup>1</sup>, Y. Seo<sup>1</sup>, H. F. Tibbals<sup>4</sup>, S. J. Spechler<sup>3</sup>, J. C. Chiao<sup>1</sup>, <sup>1</sup>University of Texas at Arlington, Arlington, United States, <sup>2</sup>Trinity Mother Frances Hospitals and Clinics, Tyler, United States, <sup>3</sup>University of Texas Southwestern Medical Center, Dallas, United States, <sup>4</sup>University of Texas Southwestern Medical Center, Dallas, United States</p>
10:30 - 10:50	<p><b>WE2A-2: Discrete-Time Representation of Band-pass Frequency-Domain Data for Envelope Transient Simulation</b>                  Z. Su, T. Brazil, University College Dublin, Dublin, Ireland</p>	<p><b>WE2B-2: Design of Dual-Band Net-Type Bandpass Filter</b>                  C. Tseng, H. Shao, National Taiwan University of Science and Technology, Taipei, Taiwan</p>	<p><b>WE2C-2: The Impact of Long-term Memory Effects on Diode Power Probes</b>                  H. Gomes<sup>1</sup>, A. R. Testera<sup>2</sup>, N. B. Carvalho<sup>1</sup>, M. F. Barciela<sup>2</sup>, K. A. Remley<sup>3</sup>, <sup>1</sup>Instituto de Telecomunicações, Aveiro, Portugal, <sup>2</sup>Universidad de Vigo, Vigo, Spain, <sup>3</sup>NIST, Boulder, United States</p>	<p><b>WE2D-2: 3D Packaging Technique on Liquid Crystal Polymer (LCP) for Miniature Wireless Biomedical Sensor</b>                  D. Ha, B. Kim, T. Lin, Y. Ouyang, P. Irazoqui, W. Chappell, Purdue University, West Lafayette, United States</p>
10:50 - 11:30	<p><b>WE2A-3: A Polar-oriented Volterra Model for Power Amplifier Characterization</b>                  T. R. Cunha, E. G. Lima, J. C. Pedro, Instituto de Telecomunicações - Universidade de Aveiro, Aveiro, Portugal</p>	<p><b>WE2B-3: New Dual-Mode Dual-Band Bandpass Filter With Quasi-Elliptic Function Passbands and Controllable Bandwidths</b>                  T. Lin, U. Lok, J. Kuo, National Chiao Tung University, Hsinchu, Taiwan</p>	<p><b>WE2C-3: On-Wafer S-Parameter De-embedding of Silicon Active and Passive Devices up to 170 GHz</b>                  K. You<sup>1</sup>, I. Sarkas<sup>1</sup>, A. Tomkins<sup>1</sup>, P. Chevalier<sup>2</sup>, S. Voinigescu<sup>1</sup>, <sup>1</sup>University of Toronto, Toronto, Canada, <sup>2</sup>STMicroelectronics, Crolles, France</p>	<p><b>WE2D-3: An Ultrasensitive CMOS Magnetic Biosensor Array with Correlated Double Counting Noise Suppression</b>                  H. Wang, S. Kosai, C. Sideris, A. Hajimiri, California Institute of Technology, Pasadena, United States</p>
11:00 - 11:10				
11:10 - 11:30	<p><b>WE2A-4: Design of pulsed waveform oscillators with a short nonlinear transmission line</b>                  M. Ponton, F. Ramirez, A. Suarez, University of Cantabria, Santander, Spain</p>	<p><b>WE2B-4: Application of Generalized Bagley-Polygon Four-Port Power Dividers to Designing Microwave Dual-Band Bandpass Planar Filters</b>                  R. Gomez-Garcia, M. Sanchez-Renedo, University of Alcalá, Alcalá de Henares, Spain</p>	<p><b>WE2C-4: A Ring-Centered Waveguide Flange for Millimeter- and Submillimeter-Wave Applications</b>                  H. Li<sup>1</sup>, A. R. Kerr<sup>2</sup>, J. L. Hesler<sup>3</sup>, H. Xu<sup>1</sup>, R. M. Weikle<sup>1</sup>, <sup>1</sup>University of Virginia, Charlottesville, United States, <sup>2</sup>National Radio Astronomy Observatory, Charlottesville, United States, <sup>3</sup>Virginia Diodes, Inc., Charlottesville, United States</p>	<p><b>WE2D-4: Microwave Sensors for Stem Cell Identification and Discrimination</b>                  C. Dalmay<sup>1</sup>, A. Pothier<sup>1</sup>, M. Cheray<sup>2</sup>, F. Lalloué<sup>2</sup>, M. Jauberteau<sup>2</sup>, P. Blondy<sup>1</sup>, <sup>1</sup>XLIM – UMR 6172 Université de Limoges/CNRS, Limoges, France, <sup>2</sup>Homéostasie Cellulaire et Pathologies – EA 3842 Université de Limoges, Limoges, France</p>
11:30 - 11:40	<p><b>WE2A-5: Stochastic characterization of the phase noise spectrum of coupled-oscillator circuits</b>                  A. Suarez, S. Sancho, F. Ramirez, University of Cantabria, Santander, Spain</p>	<p><b>WE2B-5: Lumped Isolation Circuits for Improvement of Matching and Isolation in Three-Port Balun Band-Pass Filter</b>                  T. Yang<sup>1</sup>, P. Chi<sup>1</sup>, T. Itoh<sup>1</sup>, <sup>1</sup>University of California, Los Angeles, Los Angeles, United States, <sup>2</sup>University of Electronic and Science Technology of China, Chengdu, China</p>		<p><b>WE2D-5: A Novel Zigbee-based Low-cost, Low-Power Wireless EKG system</b>                  V. Mukala, V. Lakafosis, A. Traille, M. M. Tentzeris, GEDC, Atlanta, United States</p>
11:40 - 11:50		<p><b>WE2B-6: Reconfigurable 4 Pole Bandstop Filter based on RF-MEMS-loaded Split Ring Resonators</b>                  D. Bouyge<sup>1</sup>, A. Crunteanu<sup>2</sup>, A. Pothier<sup>2</sup>, P. Martin<sup>2</sup>, P. Blondy<sup>2</sup>, A. Velez<sup>1</sup>, J. Bonache<sup>1</sup>, J. Orlianges<sup>3</sup>, F. Martin<sup>1</sup>, <sup>1</sup>Cimatec, Bellaterra (Cerdanyola del Valles), Spain, <sup>2</sup>XLIM Research Institute - CNRS, Limoges, France, <sup>3</sup>SPCTS Research Insitute - CNRS, Limoges, France</p>		<p><b>WE2D-6: Substrate Integrated Resonant Near-Field Sensor for Material Characterization</b>                  M. Ambrozkiwicz, A. F. Jacob, Hamburg University of Technology, Hamburg, Germany</p>

WEDNESDAY TECHNICAL SESSIONS

10:10-11:50

**WE2E: Emerging Technologies for mm to Submm systems**  
 Imran Mehdi, *NASA JPL*  
 H. Alfred Hung, *Army Research Lab*  
**Room: 207D**

**WE2F: Power Amplifier System Concepts.**  
 John Wood, *Freescale Semiconductor, Inc.*  
 Fadhel Ghannouchi, *University of Calgary*  
**Room: 208AB**

**WE2G: Trends in Future Systems with Low Cost Phased Arrays**  
 Jeffery Herd, *MIT Lincoln Laboratory*  
 John Horton, *J.B. Horton Group*  
**Room: 209AB**

**WE2E-1: 10-Gbit/s QPSK Modulator and Demodulator for a 120-GHz-band Wireless Link**  
 H. Takahashi<sup>1</sup>, T. Kosugi<sup>2</sup>, A. Hirata<sup>1</sup>, K. Murata<sup>2</sup>, N. Kukutsu<sup>1</sup>, <sup>1</sup>Nippon Telegraph and Telephone Corporation, Atsugi, Japan, <sup>2</sup>Nippon Telegraph and Telephone Corporation, Atsugi, Japan

**WE2F-1: Behavioral Modeling and Digital Predistortion of Power Amplifiers with Memory using Two Hidden Layers Artificial Neural Networks**  
 F. Mkadem<sup>1</sup>, M. Ben Ayed<sup>1</sup>, S. Boumaiza<sup>1</sup>, J. Wood<sup>2</sup>, P. Aaen<sup>2</sup>, <sup>1</sup>University of Waterloo, Waterloo, Canada, <sup>2</sup>Freescale Semiconductor, Inc., Tempe, United States

**WE2G-1: Advanced Architecture for a Low Cost Multifunction Phased Array Radar**  
 J. Herd<sup>1</sup>, S. Duffy<sup>1</sup>, M. Weber<sup>1</sup>, G. Brigham<sup>1</sup>, C. Weigand<sup>2</sup>, D. Curcio<sup>2</sup>, <sup>1</sup>MIT Lincoln Laboratory, Lexington, United States, <sup>2</sup>M/A-COM Technology Solutions, Lowell, United States

10:10 - 10:30

**WE2E-2: High-phase-resolution 77-GHz-band radar module for near-field millimeter-wave imaging**  
 S. Mochizuki<sup>1</sup>, S. Oka<sup>2</sup>, H. Togo<sup>1</sup>, N. Kukutsu<sup>1</sup>, <sup>1</sup>NTT Microsystem Integration Laboratories, Atsugi, Japan, <sup>2</sup>NTT Access Network Service Systems Laboratories, Tsukuba, Japan

**WE2F-2: High Accuracy Wide Band Analog Predistortion Linearizer for Telecom Satellite Transmit Section**  
 J. Villemazet, H. Yahi, D. Lopez, M. Perrel, J. Maynard, J. Cazaux, Thales Alenia Space France, Toulouse, France

**WE2G-2: Commercial Manufacturing Practices Applied to Phased Array Radars**  
 D. J. Carlson, C. Weigand, D. Curcio, T. Boles, M/A-COM Technology Solutions Inc., Lowell, United States

10:30 - 10:50

**WE2E-3: Waveguide Transition to Feed a Fully PCB Integrated Dielectric Rod Antenna**  
 F. Poprawa<sup>1</sup>, A. Zanati<sup>1</sup>, A. Ziroff<sup>1</sup>, F. Ellinger<sup>2</sup>, <sup>1</sup>Siemens AG, Munich, Germany, <sup>2</sup>Dresden University of Technology, Dresden, Germany

**WE2F-3: Novel Wide Band High-Efficiency Active Harmonic Injection Power Amplifier Concept**  
 A. Al-Muhaisen, P. Wright, J. Lees, P. Tasker, S. Cripps, J. Benedikt, Cardiff University, Cardiff, United Kingdom

**WE2G-3: Leveraging Commercial Wireless Communications Industry Advances to Lower the Cost of Phased Arrays**  
 M. B. Davis, Ball Aerospace and Technology Corporation, Westminster, United States

10:50 - 11:00

**WE2E-4: Hollow-core Electromagnetic Band Gap (EBG) Waveguide Fabricated by Rapid Prototyping for Low-loss Terahertz Guiding**  
 Z. Wu, W. Ng, M. Gehm, H. Xin, University of Arizona, Tucson, United States

**WE2F-4: High Efficiency Envelope Tracking Supply Voltage Modulator for High Power Base Station Amplifier Applications**  
 T. M. Aitto-oja, Nokia Siemens Networks, Oulu, Finland

**WE2G-4: Low Cost Electronically Scanned Arrays Based on Surface Mount Active Antennas**  
 M. Sanchez-Barberty, R. W. Jackson, University of Massachusetts, Amherst, United States

11:00 - 11:10

**WE2E-5: Monolithic 28.3 THz Thermal Image Sensor Incorporating 0.18-um CMOS Foundry**  
 S. Yang, L. Su, I. Huang, C. C. Tzuang, National Taiwan University, Taipei, Taiwan

**WE2F-5: Wideband High Efficiency Digitally-Assisted Envelope Amplifier with Dual Switching Stages for Radio Base-Station Envelope Tracking Power Amplifiers**  
 C. Hsia<sup>1</sup>, D. F. Klmball<sup>1</sup>, S. Lanfranco<sup>2</sup>, P. M. Asbeck<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Nokia Siemens Networks, Mountain View, United States

**WE2G-5: Technology Trends for Future Low Cost Phased Arrays**  
 M. Sarcone, Raytheon Company, Sudbury, United States

11:10 - 11:30

**WE2E-6: Waveguide Design for Bi-Modal Operation of THz Quantum Cascade Lasers**  
 S. Razavipour<sup>1</sup>, S. Fatholouloumi<sup>1</sup>, G. Z. Rafi<sup>1</sup>, D. Ban<sup>1</sup>, S. Safavi-Naeini<sup>1</sup>, S. R. Laframboise<sup>2</sup>, Z. Wasilewski<sup>2</sup>, H. Liu<sup>2</sup>, <sup>1</sup>University of Waterloo, Waterloo, Canada, <sup>2</sup>National Research Council of Canada, Ottawa, Canada

11:30 - 11:50



WEDNESDAY TECHNICAL SESSIONS

13:20-15:00

	<p><b>WE3A: Frequency-domain based modeling of microwave components</b>                  Abbas Omar, <i>University of Magdeburg</i>                  Luca Perregrini, <i>University of Pavia</i>  <b>Room: 205AB</b></p>	<p><b>WE3B: Novel 3-dB Coupler Structures</b>                  Roberto Vincenti Gatti, <i>University of Perugia</i>                  Jesse Taub, <i>Consultant</i>  <b>Room: 206AB</b></p>	<p><b>WE3C: Microwave Photonic Technologies</b>                  Adil Karim, <i>JHU/APL</i>                  Ron Reano, <i>Ohio State University</i>  <b>Room: 207AB</b></p>	<p><b>WE3D: RF and Microwave in Medicine: Imaging and Monitoring</b>                  J-C. Chiao, <i>University of Texas at Arlington</i>                  Arye Rosen, <i>Drexel University</i>  <b>Room: 207C</b></p>
13:20 - 13:40	<p><b>WE3A-1: Modeling of Printed Periodic Structures with Thick Metal Patches by the MoM/BI-RME Method</b>                  M. Bozzi, M. Montagna, L. Perregrini, <i>University of Pavia, Pavia, Italy</i></p>	<p><b>WE3B-1: Novel uniplanar synthesized coplanar waveguide and the application to miniaturized rat-race coupler</b>                  C. Wang, C. Lai, T. Ma, <i>National Taiwan University of Science and Technology, Taipei, Taiwan</i></p>	<p><b>WE3C-1: Highly Linear InP Phase Modulator for High Dynamic Range RF/Photonic Links</b>                  R. Wang<sup>1</sup>, A. Bhardwaj<sup>2</sup>, S. Ristic<sup>2</sup>, P. Herczfeld<sup>3</sup>, Y. Li<sup>1</sup>, <sup>1</sup>University of Massachusetts Dartmouth, North Dartmouth, United States, <sup>2</sup>University of California, Santa Barbara, Santa Barbara, United States, <sup>3</sup>Drexel University, Philadelphia, United States</p>	<p><b>WE3D-1: A Method to Control Non-uniformity RF <math>\text{dB}_{-1\text{S}}</math> Field for High Field Magnetic Resonance Imaging</b>                  H. Yoo, A. Gopinath, T. Vaughan, <i>University of Minnesota, Minneapolis, United States</i></p>
13:40 - 13:50	<p><b>WE3A-2: Use of Ground Planes within the Spatial Images Technique: Application to the Analysis of Rectangular Multilayered Shielded Enclosures</b>                  J. S. Gomez-Diaz, M. Garcia-Viguera, D. Cañete-Rebenaque, F. D. Quesada-Pereira, A. Alvarez-Melcon, <i>Technical University of Cartagena, Cartagena, Spain</i></p>	<p><b>WE3B-2: Application of Composite Right/Left-Handed Half-Mode Substrate Integrated Waveguide to the Design of a Dual-Band Rat-Race Coupler</b>                  Y. Dong, T. Itoh, <i>UCLA Microwave Electronics Lab., Los Angeles, United States</i></p>	<p><b>WE3C-2: A New Optoelectronic Oscillator Topology Based on a Class E Analog Fiber Optic Link</b>                  W. D. Jemison<sup>1</sup>, T. A. Wey<sup>1</sup>, A. Paolella<sup>2</sup>, <sup>1</sup>Lafayette College, Easton, United States, <sup>2</sup>Artisan Laboratories, Inc., Jamison, United States</p>	<p><b>WE3D-2: Alternating Impedance Multi-Channel Transmission Line Resonators for High Field Magnetic Resonance Imaging</b>                  C. E. Akgun<sup>1</sup>, L. DelaBarre<sup>1</sup>, C. J. Snyder<sup>1</sup>, S. Sohn<sup>2</sup>, G. Adriany<sup>1</sup>, K. Ugurbil<sup>1</sup>, A. Gopinath<sup>2</sup>, J. T. Vaughan<sup>1</sup>, <sup>1</sup>University of Minnesota, Minneapolis, United States, <sup>2</sup>University of Minnesota, Minneapolis, United States</p>
13:50 - 14:00				<p><b>WE3D-3: Near-Field Microwave Imaging Based on Planar Aperture Scanning</b>                  R. Khalaj Amineh, M. Ravan, A. Trehan, N. K. Nikolova, <i>McMaster University, Hamilton, Canada</i></p>
14:00 - 14:10	<p><b>WE3A-3: A Novel Skin-Effect Based Surface Impedance Model for Accurate Broadband Characterization of Interconnects with Method of Moments</b>                  M. A. Al-Qedra, V. I. Okhmatovski, <i>University of Manitoba, Winnipeg, Canada</i></p>	<p><b>WE3B-3: Quasi-Optical Cruciform Substrate Integrated Waveguide (SIW) Coupler for Millimeter-Wave Systems</b>                  T. Djerafi, J. Gauthier, K. Wu, <i>Ecole Polytechnique de Montreal, Montreal, Canada</i></p>	<p><b>WE3C-3: Front-End Design of W-band Integrated Photonic Transmitter with Wide Optical-to-Electrical Bandwidth for Wireless-Over-Fiber Applications</b>                  H. Tsai, N. Chen, F. Kuo, J. Shi, <i>National Central University, Jhongli, Taiwan</i></p>	
14:10 - 14:20				<p><b>WE3D-4: A Fast Clutter Cancellation Method in Quadrature Doppler Radar for Noncontact Vital Signal Detection</b>                  T. Chin, K. Lin, S. Chang, C. Chang, <i>National Chung Cheng Univ., Ming-Hsiung Chia-Yi, Taiwan</i></p>
14:20 - 14:30	<p><b>WE3A-4: Design Equations for Tapered Microstrip-to-Substrate Integrated Waveguide Transitions</b>                  D. Deslandes, <i>UQAM, Montreal, Canada</i></p>	<p><b>WE3B-4: A Planar Magic-T Structure Using Substrate Integrated Circuits Concept</b>                  F. He<sup>1</sup>, K. Wu<sup>1</sup>, X. Chen<sup>1</sup>, L. Han<sup>1</sup>, W. Hong<sup>2</sup>, <sup>1</sup>Poly-Grames Research Center, Montreal, Canada, <sup>2</sup>State Key Laboratory of Millimeter Waves, Nanjing, China</p>	<p><b>WE3C-4: Whispering-gallery mode based photonic RF receiver</b>                  V. Ilchenko, J. Byrd, A. Savchenkov, P. Koonath, A. Matsko, D. Seidel, L. Maleki, <i>OEwaves Inc., Pasadena, United States</i></p>	
14:30 - 14:40				<p><b>WE3D-5: An Injection-Locked Detector for Concurrent Spectrum and Vital Sign Sensing</b>                  F. Wang<sup>1</sup>, C. Li<sup>1</sup>, C. Hsiao<sup>1</sup>, T. Horng<sup>1</sup>, J. Lin<sup>2</sup>, K. Peng<sup>3</sup>, J. Jau<sup>4</sup>, J. Li<sup>4</sup>, C. Chen<sup>4</sup>, <sup>1</sup>National Sun Yat-Sen University, Kaohsiung, Taiwan, <sup>2</sup>University of Florida, Gainesville, United States, <sup>3</sup>National Kaohsiung First University of Science and Technology, Kaohsiung, Taiwan, <sup>4</sup>Industrial Technology Research Institute, Hsinchu, Taiwan</p>
14:40 - 14:50		<p><b>WE3B-5: Advanced Characterization and Design of Compensated High Directivity Quadrature Coupler</b>                  J. Müller, A. F. Jacob, <i>Technische Universität Hamburg Harburg, Hamburg, Germany</i></p>	<p><b>WE3C-5: Experimental Demonstration of a Downlink Multi-Channel Hybrid Fiber-Radio using Digitized RF-over-Fiber Technique</b>                  Y. Yang, C. Lim, A. Nirmalathas, <i>the University of Melbourne, Melbourne, Australia</i></p>	<p><b>WE3D-6: A Wire Patch Cell for "in vitro" Exposure at the Wi-Fi Frequencies</b>                  A. Paffi<sup>1</sup>, F. Apollonio<sup>1</sup>, M. Liberti<sup>1</sup>, G. A. Lovisolo<sup>2</sup>, R. Lodato<sup>2</sup>, S. Mancini<sup>2</sup>, S. Chicarella<sup>1</sup>, G. d'Inzeo<sup>1</sup>, <sup>1</sup>ICeMB at "Sapienza" University of Rome, Rome, Italy, <sup>2</sup>ICeMB at RC Casaccia ENEA, Rome, Italy</p>
14:50 - 15:00		<p><b>WE3B-6: Broadband and Compact 3-dB MMIC Directional Coupler with Lumped Element</b>                  K. Nishikawa<sup>1</sup>, M. Kawashima<sup>2</sup>, T. Seki<sup>1</sup>, K. Hiraga<sup>1</sup>, <sup>1</sup>NTT Corporation, Yokosuka, Japan, <sup>2</sup>NTT Advanced Technology, Yokosuka, Japan</p>		



WEDNESDAY TECHNICAL SESSIONS

13:20-15:00

**WE3E: Frequency Conversion and Control Component IC's**  
 Brad Nelson, *RFMD*  
 Bert Henderson, *Cobham Sensor Systems*  
**Room: 207D**

**WE3F: Techniques to Enhance Power Amplifier Linearity and Efficiency**  
 Wayne Kennan, *ACCO Semiconductor, Inc*  
 Raghu Mallavarpu, *Raytheon Company*  
**Room: 208AB**

**WE3G: Microwave Space Sensors**  
 Frank Maiwald, *JPL/CALTECH*  
 Alain Maestrini, *Observatoire de Paris*  
**Room: 209AB**

**WE3E-1: An 85-95.2 GHz Transformer-Based Injection-Locked Frequency Tripler in 65nm CMOS**  
 Z. Chen, P. Heydari, University of California, Irvine, Irvine, United States

**WE3F-1: 30.3% PAE HBT Doherty Power Amplifier for 2.5~2.7 GHz Mobile WiMAX**  
 D. Kang<sup>1</sup>, J. Choi<sup>1</sup>, D. Kim<sup>1</sup>, D. Yu<sup>2</sup>, K. Min<sup>2</sup>, B. Kim<sup>1</sup>,  
<sup>1</sup>Postech, Pohang, Republic of Korea, <sup>2</sup>WIPAM, Seongnam, Republic of Korea

**WE3G-1: THz for Space: The Golden Age**  
 P. H. Siegel, California Institute of Technology, Pasadena, United States

13:20-13:40

**WE3E-2: A Dual-Mode mm-Wave Injection-Locked Frequency Divider with Greater than 18% Locking Range in 65nm CMOS**  
 H. M. Cheema<sup>1</sup>, X. Yu<sup>2</sup>, R. Mahmoudi<sup>1</sup>, P. T. van Zeijl<sup>3</sup>, A. van Roermund<sup>1</sup>, <sup>1</sup>Eindhoven University of Technology, Eindhoven, Netherlands, <sup>2</sup>Zhejiang University, Hangzhou, China, <sup>3</sup>Philips Research, Eindhoven, Netherlands

**WE3F-2: A Fully Integrated CMOS RF Power Amplifier with Tunable Matching Network for GSM/EDGE Dual-Mode Application**  
 H. Kim<sup>1</sup>, Y. Yoon<sup>1</sup>, O. Lee<sup>1</sup>, K. An<sup>1</sup>, D. Lee<sup>2</sup>, W. Kim<sup>3</sup>, C. Lee<sup>3</sup>, J. Laskar<sup>1</sup>, <sup>1</sup>Georgia Electronic Design Center, Georgia Institute of Technology, Atlanta, United States, <sup>2</sup>Skyworks, Cedar Rapids, United States, <sup>3</sup>Samsung Design Center, Atlanta, United States

**WE3G-2: The Juno Microwave Experiment**  
 S. J. Bolton, Southwest Research Institute, Dallas, United States

13:40-14:00

**WE3E-3: A 15-50 GHz Broadband Resistive FET Ring Mixer Using 0.18- $\mu$ m CMOS Technology**  
 H. Wang<sup>1</sup>, Y. Hsin<sup>2</sup>, J. Chen<sup>1</sup>, C. Kuo<sup>1</sup>, <sup>1</sup>National Taiwan University, Taipei, Taiwan, <sup>2</sup>National Central University, Jhongli, Taiwan

**WE3F-3: Efficiency Improvement of a Handset WCDMA PA Module Using Adaptive Digital Predistortion**  
 C. D. Presti<sup>1</sup>, A. G. Metzger<sup>2</sup>, H. M. Banbrook<sup>2</sup>, P. J. Zampardi<sup>2</sup>, P. M. Asbeck<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Skyworks Solutions Inc., Newbury Park, United States

**WE3G-3: Sub-millimeter and Far-Infrared Technology in the Herschel Space Observatory and Beyond**  
 J. C. Pearson, Jet Propulsion Laboratory, California Institute of Technology, Pasadena, United States

14:00-14:20

**WE3E-4: A linear 70-95 GHz differential IQ modulator for E-band Wireless Communication**  
 M. Gavelli<sup>1</sup>, H. Zirath<sup>1</sup>, M. Ferndahl<sup>2</sup>, S. E. Gunnarsson<sup>2</sup>, <sup>1</sup>Chalmers University of Technology, Göteborg, Sweden, <sup>2</sup>Gotmic AB, Göteborg, Sweden

**WE3F-4: A Pulse Modulated Polar Transmitter for CDMA Handsets**  
 H. Yang<sup>1</sup>, H. Shih<sup>1</sup>, J. Chen<sup>2</sup>, Y. E. Chen<sup>1</sup>, <sup>1</sup>National Taiwan University, Taipei, Taiwan, <sup>2</sup>National Taiwan University, Taipei, Taiwan

**WE3G-4: Digital Radiometers for Earth Science**  
 C. Ruf, S. Gross, University of Michigan, Ann Arbor, United States

14:20-14:40

**WE3E-5: A 6-18 GHz 5-Bit Active Phase Shifter**  
 K. Koh<sup>1</sup>, G. Rebeiz<sup>2</sup>, <sup>1</sup>University of California San Diego, La Jolla, United States, <sup>2</sup>University of California San Diego, La Jolla, United States

**WE3F-5: RF Class-S Power Amplifiers: State-of-the-Art Results and Potential**  
 A. Wentzel, C. Meliani, W. Heinrich, Ferdinand-Braun-Institut für Höchstfrequenztechnik, Berlin, Germany

**WE3G-5: HEMT MMW MMICS for Radiometer Sensor Applications**  
 R. Lai, Northrop Grumman, Redondo Beach, United States

14:40-15:00



WEDNESDAY INTERACTIVE FORUM

15:00 - 17:00

**WEPA: Development in Signal Generation**  
Scott Wetenkamp, *SCEAN*

**WEPB: Frequency Conversion and Control**  
Hiroshi Okazaki, *NTT DOCOMO, INC.*

**WEPD: Advanced Fabrication Techniques in Phased Arrays**  
Julio Navarro, *Boeing Research & Technology*  
Constantine Balanis, *Arizona State University*

**WEPA-1: Impact of Radiated EMI in High Frequency Crystal Oscillator**  
U. L. Rohde<sup>2</sup>, A. K. Poddar<sup>1</sup>, <sup>1</sup>Synergy Microwave Corp., Paterson, United States, <sup>2</sup>University of Cottbus, Cottbus, Germany

**WEPB-1: A 90 nm CMOS 14.5 GHz Injection Locked LO Generator with Digital Phase Control**  
A. Axholt, H. Sjöland, Lund University, Lund, Sweden

**WEPD-1: Compact Tunable Ka-Band Phase Shifter based on Liquid Crystals**  
A. Moessinger, C. Fritsch, S. Bildik, R. Jakoby, Technische Universität Darmstadt, Darmstadt, Germany

**WEPA-2: Time-Filtered Squarewave Output from Direct Digital Synthesis**  
E. W. McCune, RF Communications Consulting, Santa Clara, United States

**WEPB-2: High Power, High Conversion Gain Frequency Doublers using SiC MESFETs and AlGaN/GaN HEMTs**  
K. S. Yuk, G. R. Branner, C. Wong, University of California, Davis, United States

**WEPD-2: A Light Weight 8-Element Broadband Phased Array Receiver on Liquid Crystal Polymer**  
J. S. Chieh<sup>1</sup>, A. Pham<sup>1</sup>, T. W. Dalrymple<sup>2</sup>, D. G. Kuhl<sup>2</sup>, B. Garber<sup>2</sup>, K. Aihara<sup>2</sup>, <sup>1</sup>University of California Davis, Davis, United States, <sup>2</sup>Air Force Research Laboratory, Wright Patterson Air Force Base, United States

**WEPA-3: Frequency-tunable High-Efficiency Power Oscillator using GaN HEMT**  
S. Shin, G. Choi, H. Kim, S. Lee, S. Kim, J. Choi, Kwangwoon University, Seoul, Republic of Korea

**WEPB-3: A 22-39 GHz Passive Mixer in SiGe:C Bipolar Technology**  
V. Issakov<sup>1</sup>, H. Knapp<sup>2</sup>, M. Wojnowski<sup>2</sup>, A. Thiede<sup>1</sup>, W. Simbauer<sup>2</sup>, <sup>1</sup>University Paderborn, Paderborn, Germany, <sup>2</sup>Infiniteon Technologies AG, Neubiberg, Germany

**WEPD-3: 3D System-in-Package Integration of 60 GHz Aperture-Coupled Micromachined Microstrip Antennas**  
S. Brebels<sup>1</sup>, K. Mohammadpour-Aghdam<sup>2</sup>, W. De Raedt<sup>1</sup>, G. Vandenbosch<sup>2</sup>, <sup>1</sup>IMEC, Heverlee, Belgium, <sup>2</sup>Katholieke Universiteit Leuven, Heverlee, Belgium

**WEPB-4: Dynamic Range Reduction Due to RF and Image Signal Co-Existence in a Highly-Merged 2.4/5.7-GHz Dual-Band Low-IF Downconverter**  
J. Syu<sup>1</sup>, C. Meng<sup>1</sup>, G. Huang<sup>2</sup>, <sup>1</sup>National Chiao Tung University, Hsinchu, Taiwan, <sup>2</sup>National Nano Device Laboratories, Hsinchu, Taiwan

WEDNESDAY

ROOM 204ABC

15:00 - 17:00

**WEPE: Microwave High Power Processes: Modeling and Applications**

Yoshio Nikawa, *Kokushikan University*  
Monika Willert-Porada, *University of Bayreuth*

**WEFP: Power Amplifier Circuits**

Franco Sechi, *Microwave Power*

**WEPG: Power Amplifier Devices**

Leo de Vreede, *Delft University of Technology*  
Peter Asbeck, *University of California San Diego*

**WEPE-1:2.45 GHz Waveguide Plasma Generation in Cylindrical Structures**

G. Cerri, R. De Leo, V. Mariani Primiani, P. Russo, E. Vecchioni, *Università Politecnica delle Marche, Ancona, Italy*

**WEFP-1:Signal Pre-Distortion and Bandwidth Requirements for Sequential Power Amplifiers.**

T. Lehmann, R. Knoechel, *University of Kiel, Kiel, Germany*

**WEPG-1:A Compact Flip Chip Single Die WiFi FEM for Smart Phone Application**

C. Yuen<sup>1</sup>, K. Laursen<sup>1</sup>, D. Chu<sup>1</sup>, Y. Pao<sup>1</sup>, A. Chernyakov<sup>2</sup>, P. Heide<sup>2</sup>, <sup>1</sup>Epic Communications, Inc., Sunnyvale, United States, <sup>2</sup>Epos AG, Munich, Germany

**WEPE-2:2.45 GHz Perfluorator Heating Module for Industrial Infiltration Processes**

S. Stanculovic<sup>1</sup>, L. E. Feher<sup>2</sup>, <sup>1</sup>Karlsruhe Institute of Technology, Karlsruhe, Germany, <sup>2</sup>Karlsruhe Institute of Technology, Karlsruhe, Germany

**WEFP-2:A 29dBm Linear Output Power Amplifier with 21.3% Efficiency for 700MHz-band 3GPP LTE OFDMA applications**

Y. H. Chow, H. H. Nyeo, W. C. Chan, K. L. Lau, S. H. Khoo, *Avago Technologies, Bayan Lepas, Malaysia*

**WEPG-2:A Highly Efficient 1-GHz, 15-W Power Amplifier Design Based on a 50-V LDMOS Transistor**

P. Singer<sup>1</sup>, C. Fager<sup>2</sup>, Z. Wang<sup>3</sup>, C. Schubert<sup>3</sup>, <sup>1</sup>Infinion Technologies Austria AG, Villach, Austria, <sup>2</sup>Chalmers University of Technology, Gothenburg, Sweden, <sup>3</sup>Vienna University of Technology, Vienna, Austria

**WEPE-3:Wood Timber Disinfestation by Microwave Power Application**

A. T. Zona-Ortiz, O. Calderón-Luna, J. V. Balbastre-Tejedor, E. de los Reyes, *ITACA Research Institute, Valencia, Spain*

**WEFP-3:A Novel Broadband Power Amplifier Architecture for High Efficiency and High Linearity Applications**

R. I. Alidio, W. Lee, A. Gummalla, M. Achour, *Rayspan Corporation, San Diego, United States*

**WEPG-3:High-Efficiency Broadband Power Amplifier Design Technique Based on a Measured-Load-Line Approach**

S. Di Falco<sup>1</sup>, A. Raffo<sup>1</sup>, F. Scappaviva<sup>2</sup>, D. Resca<sup>2</sup>, M. Pagani<sup>3</sup>, G. Vannini<sup>1</sup>, <sup>1</sup>University of Ferrara, Ferrara, Italy, <sup>2</sup>MEC s.r.l., Bologna, Italy, <sup>3</sup>Ericsson R&D Italy, Vimodrone (MI), Italy

**WEPE-4:Measurement of dielectric properties at high-temperatures in real-time with cylindrical cavity**

A. J. Canos-Marin, F. L. Penaranda-Foix, J. M. Catala-Civera, B. Garcia-Banos, *UPV, Valencia, Spain*

**WEFP-4:A measurement Set-up and methodology combining dynamic biasing and baseband predistorsion for high efficiency and linear amplifier design**

M. Saad El Dine<sup>1</sup>, T. Reveyard<sup>1</sup>, G. Neveux<sup>1</sup>, P. Bouysse<sup>1</sup>, D. Barataud<sup>1</sup>, J. Nebus<sup>1</sup>, W. Rebernak<sup>2</sup>, <sup>1</sup>University of Limoges, Limoges, France, <sup>2</sup>THALES Communications, Colombes, France

**WEPG-4:Laser Driver Switching 20 A with 2 ns Pulse Width Using GaN**

A. Liero, A. Klehr, S. Schwertfeger, T. Hoffmann, W. Heinrich, *Ferdinand-Braun-Institut für Hochofenerfrequenz-technik, Berlin, Germany*

**WEPE-5:High-Q Applicators for Microwave Processes in Material Science**

P. Kopyt, W. K. Gwarek, *Warsaw Univ. of Technology, Warsaw, Poland*

**WEFP-5:Envelope Tracking Power Amplifier Robust to Battery Depletion**

J. Choi, D. Kim, D. Kang, J. Park, B. Jin, B. Kim, *Pohang University of Science and Technology, Pohang, Republic of Korea*

**WEPG-5:Investigation and Analysis into Device Optimization for Attaining Efficiencies In-Excess of 90% When Accounting for Higher Harmonics**

A. L. Clarke, M. Akmal, J. Lees, P. J. Tasker, J. Benedikt, *Cardiff University, Cardiff, United Kingdom*

**WEPE-6:Dielectric Relaxation Study of Binary Mixtures of 2-Methoxyethanol in Nitrobenzene and Chlorobenzene Using Time Domain Reflectometry**

R. H. Fattapur<sup>1</sup>, S. B. Sayyad<sup>2</sup>, N. H. Ayachit<sup>3</sup>, P. W. Khirade<sup>4</sup>, S. C. Mehrotra<sup>3</sup>, <sup>1</sup>Basaveshwar Science College, Bagalkot, India, <sup>2</sup>Milliya Arts Science and Management Science College, Beed, India, <sup>3</sup>BVB College of Engineering and Technology, Hubli, India, <sup>4</sup>Dr B A M University, Aurangabad, India, <sup>5</sup>Dr B A M University, Aurangabad, India

**WEFP-6:Quad-Band Inverse Class-F Power Amplifier using Novel Composite Right/Left-Handed Transmission Line**

J. Choi, C. Seo, *Soongsil Univ., Seoul, Republic of Korea*

**WEFP-7:High Performance Wideband Digital Predistortion Platform for 3G+ Applications with Better than 55dBc over 40 MHz Bandwidth**

A. Kwan<sup>1</sup>, O. Hammi<sup>1</sup>, M. Helaoui<sup>2</sup>, F. M. Ghannouchi<sup>2</sup>, <sup>1</sup>Green Radio Technologies Inc., Calgary, Canada, <sup>2</sup>University of Calgary, Calgary, Canada

**WEFP-8:Doherty Amplifier with Envelope Tracking for High Efficiency**

J. Moon<sup>1</sup>, J. Son<sup>1</sup>, J. Kim<sup>1</sup>, I. Kim<sup>1</sup>, S. Jee<sup>1</sup>, Y. Y. Woo<sup>2</sup>, B. Kim<sup>1</sup>, <sup>1</sup>Pohang University of Science and Technology, Pohang, Republic of Korea, <sup>2</sup>Samsung Electronics co., LTD, Suwon, Republic of Korea

**WEFP-9:Design of a Broadband and Highly Efficient 45W GaN Power Amplifier via Simplified Real Frequency Technique**

D. Wu, F. Mkaem, S. Boumaiza, *University of Waterloo, Waterloo, Canada*

**WEFP-10:Adaptive digital pre-distortions based on affine projection algorithm for WCDMA power amplifier applications**

Y. Kim<sup>1</sup>, S. Chun<sup>1</sup>, J. Kim<sup>1</sup>, D. Kim<sup>2</sup>, C. Hahn<sup>2</sup>, J. Kim<sup>1</sup>, <sup>1</sup>Kwangwoon University, Seoul, Republic of Korea, <sup>2</sup>Korea Electronics Technology Institute, Seongnam, Republic of Korea



WEDNESDAY TECHNICAL SESSIONS

15:30-17:10

	<p><b>WE4A: RFID and power harvesting technologies</b> Apostolos Georgiadis, <i>Centre Tecnologic de Telecomunicacions de Catalunya (CTTC)</i> Luca Roselli, <i>University of Perugia</i> <b>Room: 205AB</b></p>	<p><b>WE4B: Novel Transmission Structures and Characterization</b> George Eleftheriades, <i>U. Toronto</i> Michael Zedler, <i>U. Toronto</i> <b>Room: 206AB</b></p>	<p><b>WE4C: Novel Technological Realizations of Filters and Multiplexers</b> Vicente Boria, <i>Technical University of Valencia</i> Huiwen Yao, <i>Orbital Sciences Corp.</i> <b>Room: 207AB</b></p>	<p><b>WE4D: High-speed Signal Processing Circuits for Wireless and Optical Communication Systems</b> Koichi Murata, <i>NTT Photonics Labs.</i> Edward Gebara, <i>Georgia Institute of Technology</i> <b>Room: 207C</b></p>
15:30 - 15:40	<p><b>WE4A-1: Long range, low power UHF RFID analog front-end suitable for batteryless wireless sensors</b> A. Vaz<sup>1</sup>, H. Solar<sup>1</sup>, I. Rebollo<sup>2</sup>, I. Gutiérrez<sup>1</sup>, R. Berenguer<sup>1</sup>,<sup>1</sup>CEIT and Tecnun, San Sebastián, Spain, <sup>2</sup>Farsens, San Sebastián, Spain</p>	<p><b>WE4B-1: Compact Artificial Line Phase Shifter on Ferroelectric Thick-Film Ceramics</b> M. Sazegar<sup>1</sup>, Y. Zheng<sup>1</sup>, H. Maune<sup>1</sup>, X. Zhou<sup>2</sup>, C. Damm<sup>1</sup>, R. Jakoby<sup>1</sup>,<sup>1</sup>TU-Darmstadt, Darmstadt, Germany, <sup>2</sup>Karlsruhe Institute of Technology, Karlsruhe, Germany</p>	<p><b>WE4C-1: TM Dual-Mode Pseudoelliptic Filters using Nonresonating Modes</b> S. Bastioli<sup>1</sup>, C. Tomassoni<sup>1</sup>, R. Sorrentino<sup>1</sup>,<sup>1</sup>University of Perugia, Perugia, Italy, <sup>2</sup>RF Microtech srl, Perugia, Italy</p>	<p><b>WE4D-1: A 50-GS/s 5-b ADC in 0.18-um SiGe BiCMOS</b> J. Lee, Y. Chen, Alcatel-Lucent, Murray Hill, United States</p>
15:40 - 15:50	<p><b>WE4A-2: An RFID System with Enhanced Hardware-Enabled Authentication and Anti-counterfeiting Capabilities</b> V. Lakafoxis<sup>1</sup>, A. Traille<sup>1</sup>, H. Lee<sup>1</sup>, G. Orecchini<sup>2</sup>, E. Gebara<sup>1</sup>, M. M. Tentzeris<sup>1</sup>, J. Laskar<sup>1</sup>, G. DeJean<sup>2</sup>, D. Kirovski<sup>2</sup>,<sup>1</sup>Georgia Institute of Technology, Atlanta, United States, <sup>2</sup>Microsoft Research, Redmond, United States, <sup>3</sup>University of Perugia, Perugia, Italy</p>	<p><b>WE4B-2: Accurate Analysis of Irregular Periodic Substrate Integrated Waveguide Structures and Its Applications</b> L. Han, K. Wu, X. Chen, F. He, Poly-Grames Research Center, Montreal, Canada</p>	<p><b>WE4C-2: Coupling Topologies for Realizing Compact Microwave Diplexers with Dual-mode Cavities</b> H. Ezzeddine<sup>1</sup>, S. Bila<sup>1</sup>, S. Verdeyme<sup>1</sup>, F. Seyfert<sup>2</sup>, D. Pacaud<sup>3</sup>,<sup>1</sup>XLIM, Limoges, France, <sup>2</sup>INRIA, Sophia Antipolis, France, <sup>3</sup>Thalès Alenia space, Toulouse, France</p>	<p><b>WE4D-2: A 17pJ/bit Broadband Mixed-Signal Demodulator in 90nm CMOS</b> K. S. Chuang, D. Yeh, F. Barale, B. Perumana, S. Sarkar, P. Sen, S. Pinel, J. Laskar, Georgia Electronic Design Center, Atlanta, United States</p>
15:50 - 16:00				
16:00 - 16:10	<p><b>WE4A-3: Crossed dipole frequency doubling RFID TAG based on paper substrate and ink-jet printing technology</b> F. Alimenti<sup>1</sup>, V. Palazzari<sup>1</sup>, G. Orecchini<sup>1</sup>, G. Pinca<sup>2</sup>, P. Mezzanotte<sup>1</sup>, M. M. Tentzeris<sup>3</sup>, L. Roselli<sup>1</sup>,<sup>1</sup>University of Perugia, Perugia, Italy, <sup>2</sup>Wireless Solutions S.r.l., Passignano sul Trasimeno, Italy, <sup>3</sup>Georgia Institute of Technology, Atlanta, United States</p>			<p><b>WE4D-3: Pulse Shaping and Clock Data Recovery for Multi-Gigabit Standard Compliant 60 GHz Digital Radio</b> F. Barale, G. B. Iyer, B. G. Perumana, P. Sen, S. Sarkar, A. Rachamadugu, N. Dubeabout, S. Pinel, J. Laskar, Georgia Institute of Technology, Atlanta, United States</p>
16:10 - 16:20	<p><b>WE4A-4: Harmonic Generation from Integrated Nonlinear Transmission Lines for RFID Applications</b> F. Yu, K. G. Lyon, E. C. Kan, Cornell University, Ithaca, United States</p>	<p><b>WE4B-3: Conductor Profile Effects on the Propagation Constant of Microstrip Transmission Lines</b> A. F. Horn, III<sup>1</sup>, J. W. Reynolds<sup>1</sup>, J. C. Rautio<sup>2</sup>,<sup>1</sup>Rogers Corporation, Rogers, United States, <sup>2</sup>Sonnet Software, Inc., North Syracuse, United States</p>	<p><b>WE4C-3: A Novel Ku-Band Dielectric Resonator Triplexer based on Generalized Multiplexer Theory</b> F. Loras-Gonzalez<sup>1</sup>, I. Hidalgo-Carpintero<sup>1</sup>, S. Sobrino-Arias<sup>1</sup>, A. García-Lampérez<sup>2</sup>, M. Salazar-Palma<sup>2</sup>,<sup>1</sup>Thales Alenia Space, Tres Cantos, Spain, <sup>2</sup>Universidad Carlos III de Madrid, Leganés, Spain</p>	<p><b>WE4D-4: A 1 V 6-bit 2.4 GS/s Nyquist CMOS DAC for UWB Systems</b> B. Kim, M. Cho, Y. Kim, J. Kwon, Electronics and Telecommunications Research Institute, Daejeon, Republic of Korea</p>
16:20 - 16:30				
16:30 - 16:40	<p><b>WE4A-5: A device-level analog and digital subsystem SPICE library for the design of low-cost pentacene OFET RFIDs</b> R. Tinivella, S. Shen, M. Pirola, G. Ghione, V. Camarchia, Politecnico di Torino, Torino, Italy</p>	<p><b>WE4B-4: Bandwidth Enhancement of Substrate Integrated Waveguide Tunnels by Longitudinal Resonances</b> A. Corona-Chavez<sup>1</sup>, T. Itoh<sup>1</sup>,<sup>1</sup>University of California at Los Angeles, Los Angeles, United States, <sup>2</sup>INAOE, Puebla, Mexico</p>	<p><b>WE4C-4: Compact Wide-Band Ridge Waveguide Dual-Band Filters</b> M. M. Fahmi<sup>1</sup>, J. A. Ruiz-Cruz<sup>2</sup>, R. R. Mansour<sup>1</sup>, K. A. Zaki<sup>3</sup>,<sup>1</sup>University of Waterloo, Waterloo, Canada, <sup>2</sup>Universidad Autónoma de Madrid, Madrid, Spain, <sup>3</sup>University of Maryland, College Park, College Park, United States</p>	<p><b>WE4D-5: A 6 Bit Linear Binary RF DAC in 0.25um SiGe BiCMOS for Communication Systems</b> M. Khafaji, H. Gustat, J. Scheytt, IHP Microelectron-ics, Frankfurt Oder, Germany</p>
16:40 - 16:50	<p><b>WE4A-6: Temporally Resolved Impedance Measurement of Differential, RF-Powered Devices using the Example of a <math>\mu</math>Wave RFID Front-End</b> C. Bansleben<sup>1</sup>, S. Kühn<sup>2</sup>, N. Gay<sup>1</sup>, W. J. Fischer<sup>1</sup>,<sup>1</sup>Fraunhofer IPMS, Dresden, Germany, <sup>2</sup>Ferdinand-Braun-Institut, Berlin, Germany</p>	<p><b>WE4B-5: Micromachined High Aspect Ratio Coplanar Waveguide with High Impedance and Low Loss on Low Resistivity Silicon</b> S. T. Todd<sup>1</sup>, J. E. Bowers<sup>1</sup>, N. C. MacDonald<sup>2</sup>,<sup>1</sup>University of California, Santa Barbara, Santa Barbara, United States, <sup>2</sup>University of California, Santa Barbara, Santa Barbara, United States</p>	<p><b>WE4C-5: A New Class of 3-D Filter/Antenna Integration with High Quality Factor and High Efficiency</b> Y. Yusuf, X. Gong, University of Central Florida, Orlando, United States</p>	<p><b>WE4D-6: Distributed Amplifiers in InP DHBT for 100-Gbit/s Operation</b> J. Dupuy, A. Konczykowska, F. Jorge, M. Riet, J. Godin, Alcatel-Lucent, Marcoussis, France</p>
16:50 - 17:00	<p><b>WE4A-7: Co-design of Ultra Low Power RF/Microwave Receivers and Converters for RFID and Energy Harvesting Applications</b> A. Costanzo<sup>1</sup>, M. Fabiani<sup>1</sup>, A. Romani<sup>1</sup>, D. Masotti<sup>2</sup>, V. Rizzoli<sup>2</sup>,<sup>1</sup>University of Bologna, Cesena, Italy, <sup>2</sup>University of Bologna, Bologna, Italy</p>		<p><b>WE4C-6: Quasi-elliptic 150 GHz Highly Selective LTCC Filter</b> A. Khalil<sup>1</sup>, D. Passerieux<sup>1</sup>, D. Baillargeat<sup>1</sup>, N. Delhote<sup>1</sup>, S. Verdeyme<sup>1</sup>, L. Rigauddau<sup>2</sup>, J. Puech<sup>3</sup>,<sup>1</sup>Xlim Laboratory CNRS 6172, Limoges, France, <sup>2</sup>French National Space Agency, Toulouse, France</p>	
17:00 - 17:10				

WEDNESDAY TECHNICAL SESSIONS

15:30-17:10

**WE4E: Power-Amplifier and Combiner Techniques for HF, VHF, and UHF**  
Richard Campbell, *Portland State University*  
Robert Caverly, *Villanova University*  
**Room: 207D**

**WE4F: Novel Si-based devices and circuits**  
Zaher Bardai, *IMN Epiphany*  
Kenjiro Nishikawa, *NTT Corporation*  
**Room: 208AB**

**WE4G: CAD Techniques and Methodologies: Future Directions**  
Q.J. Zhang, *Carleton University*  
Arvind Sharma, *Northrop Grumman*  
**Room: 209AB**

<p><b>WE4E-1: Class-D Power Amplifier with RF Pulse-Width Modulation</b> F. H. Raab, <i>Green Mountain Radio Research Company, Colchester, United States</i></p>	<p><b>WE4F-1: A Novel Small Capacitance RF-MOSFET with small-resistance Long-finger Gate Electrode</b> H. Nagase, A. Tanabe, Y. Hayashi, <i>NEC Electronics Corporation, Sagamihara, Japan</i></p>	<p><b>WE4G-1: Techniques for Nonlinear High-Frequency Circuit-Level Simulation</b> T. Brazil, <i>University College Dublin, Dublin, Ireland</i></p>	<p>15:30-15:50</p>
<p><b>WE4E-2: An Efficient, 35 dBm, Inverse Class-F, UHF RF Power Amplifier Module on a 10 mm<sup>2</sup> Footprint Designed in First Pass through Accurate Modeling and Simulation</b> M. J. Franco, <i>RFMD, Greensboro, United States</i></p>	<p><b>WE4F-2: Silicon-Based PIN SPST RF Switches for Improved Linearity</b> P. Sun<sup>1</sup>, G. Wang<sup>1</sup>, P. Liu<sup>2</sup>, P. Upadhyaya<sup>2</sup>, D. Jeong<sup>3</sup>, D. Heo<sup>2</sup>, <sup>1</sup>IBM, <i>Essex Junction, United States</i>, <sup>2</sup>Washington State University, <i>Pullman, United States</i>, <sup>3</sup>Handong Global University, <i>Pohang, United States</i></p>	<p><b>WE4G-2: Historical Trends and Evolution of Circuit-Simulation Technology</b> S. Maas, <i>AWR Corp., El Segundo, United States</i></p>	<p>15:50-16:10</p>
<p><b>WE4E-3: Switch-Controlled Multi-Octave Bandwidth Radial Power Divider/Combiner</b> Y. Hong<sup>1</sup>, D. F. Kimball<sup>2</sup>, J. Yook<sup>1</sup>, P. M. Asbeck<sup>2</sup>, L. E. Larson<sup>2</sup>, <sup>1</sup>Yonsei University, <i>Seoul, Republic of Korea</i>, <sup>2</sup>University of California, <i>San Diego, La Jolla, United States</i></p>	<p><b>WE4F-3: A Ka-Band High-Pass Distributed Amplifier in 120nm SiGe BiCMOS</b> T. D. Gathman, J. F. Buckwalter, <i>University of California, San Diego, La Jolla, United States</i></p>	<p><b>WE4G-3: Multi-PC FDTD: Solving Large Scale EM Problems</b> A. Wien, A. Lauer, I. Wolff, <i>IMST GmbH, Kamp-Lintfort, Germany</i></p>	<p>16:10-16:30</p>
<p><b>WE4E-4: High-Efficiency 400-W Power Amplifier with Dynamic Drain Voltage Control for 6-MHz OFDM Signal</b> S. Hiura, H. Sumi, H. Takahashi, <i>Toshiba Corporation, Corporate Manufacturing Engineering Center, Yokohama, Japan</i></p>	<p><b>WE4F-4: Low-Power Low-Noise 0.13 <math>\mu</math>m CMOS X-Band Phased Array Receivers</b> D. Shin, G. M. Rebeiz, <i>UCSD, La Jolla, United States</i></p>	<p><b>WE4G-4: ANN and Space Mapping for Microwave Modeling and Optimization</b> Q. Zhang<sup>1</sup>, J. W. Bandler<sup>2</sup>, S. Koziel<sup>3</sup>, H. Kabir<sup>1</sup>, L. Zhang<sup>1</sup>, <sup>1</sup>Carleton University, <i>Ottawa, Canada</i>, <sup>2</sup>McMaster University, <i>Hamilton, Canada</i>, <sup>3</sup>Reykjavik University, <i>Reykjavik, Iceland</i></p>	<p>16:30-16:50</p>
<p><b>WE4E-5: 100 W GaN HEMT Power Amplifier Module with 60% Efficiency over 100–1000 MHz Bandwidth</b> K. Krishnamurthy, T. Driver, R. Vetry, J. Martin, <i>RF Micro Devices, Charlotte, United States</i></p>	<p><b>WE4F-5: An L-Band Gain and Bandwidth Tunable Low-Noise Differential Amplifier Using Varactor-Tuned Bias Circuits and Active Loads</b> Y. Itoh, W. Cao, T. Murata, K. Sakurai, <i>Shonan Institute of Technology, Fujisawa, Japan</i></p>	<p><b>WE4G-5: State-of-the-Art, Challenges, and Future Directions of Nonlinear Behavioral Modeling</b> D. E. Root, <i>Agilent Technologies, Santa Rosa, United States</i></p>	<p>16:50-17:10</p>



THURSDAY TECHNICAL SESSIONS

8:00-9:40

**TH1A: Terahertz Electronics**  
 Reynold Kagiwada, Northrop Grumman  
 Aaron Oki, Northrop Grumman  
**Room: 205AB**

**TH1B: RF-MEMS Circuits**  
 Joachim Oberhammer, Royal Institute of Technology  
 Jing Wang, University of South Florida  
**Room: 206AB**

**TH1C: Large Signal Measurements**  
 Nuno Borges Carvalho, Universidade de Aveiro  
 Kate A. Remley, NIST  
**Room: 207AB**

8:00 - 8:20

**TH1A-1: THz Electronics Projects at DARPA: Transistors, TMICs, and Amplifiers**  
 J. D. Albrecht<sup>1</sup>, M. J. Rosker<sup>1</sup>, H. B. Wallace<sup>2</sup>, T. Chang<sup>3</sup>,  
<sup>1</sup>Defense Advanced Research Projects Agency, Arlington,  
 United States, <sup>2</sup>MMW Concepts LLC, Havre de Grace,  
 United States, <sup>3</sup>Booz Allen Hamilton Inc., Arlington,  
 United States

**TH1B-1: A High Power-Handling RF MEMS Tunable Capacitor Using Quadruple Series Capacitor Structure**  
 H. Yamazaki<sup>1</sup>, T. Ikehashi<sup>1</sup>, T. Saito<sup>1</sup>, E. Ogawa<sup>1</sup>, T.  
 Masunaga<sup>2</sup>, T. Ohguro<sup>1</sup>, Y. Sugizaki<sup>1</sup>, H. Shibata<sup>1</sup>,  
<sup>1</sup>Toshiba Corporation, Yokohama, Japan, <sup>2</sup>Toshiba  
 Corporation, Yokohama, Japan

**TH1C-1: A novel methodology for fast harmonic-load control with a passive tuner and an active loop**  
 S. Bonino, V. Teppati, A. Ferrero, Politecnico di Torino,  
 Torino, Italy

8:20 - 8:40

**TH1A-2: Solid-State Amplifiers for Terahertz Electronics**  
 W. R. Deal, X. B. Mei, D. Scott, V. Radisic, M. K. Leong, S.  
 Sarkozy, B. Gorospe, J. Lee, P. H. Liu, W. Yoshida, J. Zhou,  
 R. Elmadjian, S. Wang, M. Lange, J. Uyeda, R. Lai, A.  
 Gutierrez, R. Kagiwada, Northrop Grumman, Redondo  
 Beach, United States

**TH1B-2: Anti-Biased RF MEMS Varactor Topology for 20-25 dB Linearity Enhancement**  
 K. Chen, A. Kovacs, D. Peroulis, Purdue University,  
 West Lafayette, United States

**TH1C-2: A Low-Cost and Accurate Technique for the Prediction of Load-Pull Contours**  
 V. Vadalà, A. Raffo, S. Di Falco, G. Vannini, University of  
 Ferrara, Ferrara, Italy

8:40 - 9:00

**TH1A-3: THz MMICs based on InP HBT Technology**  
 J. Hacker<sup>1</sup>, M. Seo<sup>1</sup>, A. C. Young<sup>1</sup>, Z. Griffith<sup>1</sup>, M. Urteaga<sup>1</sup>,  
 T. Reed<sup>2</sup>, M. Rodwell<sup>2</sup>, <sup>1</sup>Teledyne Scientific & Imaging,  
 Thousand Oaks, United States, <sup>2</sup>University of California,  
 Santa Barbara, Santa Barbara, United States

**TH1B-3: A Tunable Asymmetric Notch Filter using RFMEMS**  
 J. R. De Luis<sup>2</sup>, A. S. Morris III<sup>1</sup>, Q. Gu<sup>1</sup>, F. De Flaviis<sup>2</sup>,  
<sup>1</sup>Wispry Inc, Irvine, United States, <sup>2</sup>University of  
 California Irvine, Irvine, United States

**TH1C-3: Active Simultaneous Harmonic Source and Load Pull Assisted by Local Polyharmonic Distortion Models**  
 R. E. Leoni III, S. A. Harris, D. G. Ries Jr., Raytheon  
 Company, Andover, United States

9:00 - 9:20

**TH1A-4: N-polar GaN-based MIS-HEMTs for Mixed Signal Applications**  
 U. K. Mishra<sup>1</sup>, M. Wong<sup>1</sup>, N. Nidhi<sup>1</sup>, S. Dasgupta<sup>1</sup>, D. F.  
 Brown<sup>1</sup>, B. L. Swenson<sup>1</sup>, S. Kellera<sup>1</sup>, J. S. Speck<sup>2</sup>, <sup>1</sup>Univer-  
 sity of California, Santa Barbara, Santa Barbara, United  
 States, <sup>2</sup>University of California, Santa Barbara, Santa  
 Barbara, United States

**TH1B-4: An Experimental Investigation on Viscoelastic Behavior in Tunable Planar RF-MEMS Resonators**  
 H. Hsu, D. Peroulis, Purdue University, West Lafay-  
 ette, United States

**TH1C-4: A Method to Select Correct Stimuli Levels for S-functions Behavioral Model Extraction**  
 M. Myslinski<sup>1</sup>, F. Verbeyst<sup>2</sup>, M. Vanden Bossche<sup>2</sup>, D.  
 Schreurs<sup>1</sup>, <sup>1</sup>K.U.Leuven, Leuven, Belgium, <sup>2</sup>NMDG n.v.,  
 Bornem, Belgium

9:20 - 9:40

**TH1A-5: Toward practical applications over 100 GHz**  
 N. Kukutsu<sup>1</sup>, A. Hirata<sup>1</sup>, M. Yaita<sup>1</sup>, K. Ajito<sup>1</sup>, H. Takahashi<sup>1</sup>,  
 T. Kosugi<sup>2</sup>, H. Song<sup>1</sup>, A. Wakatsuki<sup>2</sup>, Y. Muramoto<sup>2</sup>, T.  
 Nagatsuma<sup>3</sup>, Y. Kado<sup>1</sup>, <sup>1</sup>NTT Microsystem Integre-  
 tion Laboratories, Atsugi-shi, Japan, <sup>2</sup>NTT Photonics  
 Laboratories, Atsugi-shi, Japan, <sup>3</sup>Osaka University,  
 Toyonaka, Japan

**TH1B-5: A MEMS Variable Capacitor with Piezoresistive Position Sensing Fabricated in a Standard 0.35um CMOS Process**  
 N. Zahirovic<sup>1</sup>, R. R. Mansour<sup>1</sup>, M. Yu<sup>2</sup>, <sup>1</sup>University of  
 Waterloo, Waterloo, Canada, <sup>2</sup>COM DEV Interna-  
 tional, Cambridge, Canada

THURSDAY

TECHNICAL SESSIONS

8:00-9:40

**TH1D: Developments in Microwave Signal Generation**  
 Scott Wetenkamp, *SCEAN*  
 Bhaskar Banerjee, *University of Texas at Dallas*  
**Room: 207C**

**TH1E: Advances in Active Device Modeling**  
 Arvind Sharma, *Northrop Grumman*  
 Q.J. Zhang, *Carleton University*  
**Room: 207D**

**TH1D-1: Study of Direct-Conversion Transmitter Pulling Effects in Constant Envelope Modulation Systems**  
 C. Hsiao<sup>1</sup>, C. Li<sup>1</sup>, F. Wang<sup>1</sup>, T. Horng<sup>1</sup>, K. Peng<sup>2</sup>,  
<sup>1</sup>National Sun Yat-Sen University, Kaohsiung, Taiwan, <sup>2</sup>National Kaohsiung First University of Science and Technology, Kaohsiung, Taiwan

**TH1E-1: Nonlinear Modeling of Compound Semiconductor HEMTs, State of the Art**  
 W. R. Curtice, W. R. Curtice Consulting, Washington Crossing, United States

8:00 - 8:20

**TH1D-2: Low-Phase-Noise Wide-Frequency-Range Ring-VCO-Based Scalable PLL with Subharmonic Injection Locking in 0.18  $\mu\text{m}$  CMOS**  
 S. Lee, S. Amakawa, N. Ishihara, K. Masu, Integrated Research Institute, Yokohama, Japan

**TH1E-2: Empirical Modeling of GaN FETs for Nonlinear Microwave Circuit Applications**  
 A. Santarelli, V. Di Giacomo, Univ. of Bologna, Bologna, Italy

8:20 - 8:40

**TH1D-3: Ku Band Second Harmonic N-Coupled Push-Push Oscillator Array using Microstrip Resonator**  
 K. Kawasaki, T. Tanaka, M. Aikawa, Saga University, Saga, Japan

**TH1E-3: Strategies for addressing linearity Issues in Active Device Modeling**  
 A. Mediavilla, J. A. Garcia, L. Cabria, F. R. Marante, Univ. of Cantabria, Santander, Spain

8:40 - 9:00

**TH1D-4: Low Phase Noise K-Band Oscillator on Organic Liquid Crystal Polymer (LCP) Substrate**  
 W. T. Khan, S. K. Bhattacharya, S. Horst, J. D. Cressler, J. Papapolymerou, Georgia Institute of Technology, Atlanta, United States

**TH1E-4: Compact HBT modeling: status and challenges**  
 M. Rudolph, Brandenburg University of Technology, Cottbus, Germany

9:00 - 9:20

**TH1D-5: A Sub-Resonant 40GHz Clock Distribution Network with Near Zero Skew**  
 F. Aryanfar<sup>1</sup>, T. Wu<sup>1</sup>, M. Koochakzadeh<sup>2</sup>, C. Werner<sup>1</sup>, K. Chang<sup>1</sup>, <sup>1</sup>Rambus Inc, Los Altos, United States, <sup>2</sup>Arizona State University, Tempe, United States

**TH1E-5: State-of-Art, Challenges and Future Directions in Large Signal Measurements for Active Device Modeling**  
 D. Schreurs, K.U.Leuven, Leuven, Belgium

9:20 - 9:40



THURSDAY

INTERACTIVE FORUM

9:40 - 11:40

**THPA: Transmission Line Circuits**

Dominic Deslandes, *University of Quebec, Montreal*

**THPB: Recent Advancements in Passive Circuitry**

Nickolas Kingsley, *Auriga Measurement Systems*  
Peter Russer, *Munich University of Technology*

**THPD: Biological Effects and Medical Applications of RF and Microwave**

Mohammad Reza Tofghi, *Pennsylvania State University*

**THPA-1:Metamaterial Transmission Line Transformers/Baluns**

H. Yang, V. Chekka, H. Ma, *University of Illinois, Chicago, United States*

**THPB-1:A Modified Wilkinson Divider using Zero-Degree Phase Shifting Composite Right/Left-Handed Transmission Line**

S. Kim<sup>1</sup>, J. Yoon<sup>1</sup>, Y. Kim<sup>1</sup>, Y. Yoon<sup>2</sup>, <sup>1</sup>Kumoh National Institute of Technology, Gumi, Republic of Korea, <sup>2</sup>Kwandong University, Gangneung-shi, Republic of Korea

**THPD-1:The response of electric field probes to realistic RF environments**

D. Adamson, D. Bownds, A. Fernández, E. Goodall, *National Physical Laboratory, Teddington, United Kingdom*

**THPA-2:Novel Synthesized Microstrip Line with Quasi-Elliptic Response for Harmonic Suppressions**

C. Lai, T. Ma, *National Taiwan University of Science and Technology, Taipei, Taiwan*

**THPB-2:High CMRR in Reduced-Coupling Monolithic Baluns**

R. C. Frye<sup>1</sup>, K. Liu<sup>2</sup>, P. Hlaing<sup>3</sup>, <sup>1</sup>RF Design Consulting, LLC, Piscataway, United States, <sup>2</sup>STATS ChipPAC, Tempe, United States, <sup>3</sup>STATS ChipPAC, Ltd., Singapore, Singapore

**THPD-2:Multiplicative Regularized Gauss-Newton Approach for Three-Dimensional Microwave Imaging**

A. Abubakar, T. M. Habashy, *Schlumberger-Doll Research, Cambridge, United States*

**THPA-3:Design of Microwave Circuits in Ridge-Gap Waveguide Technology**

E. Alfonso<sup>1</sup>, M. Baquero<sup>1</sup>, P. Kilda<sup>2</sup>, A. Valero-Nogueira<sup>1</sup>, E. Rajo-Iglesias<sup>3</sup>, J. I. Herranz<sup>1</sup>, <sup>1</sup>Universidad Politecnica de Valencia, Valencia, Spain, <sup>2</sup>Chalmers University of Technology, Gothenburg, Sweden, <sup>3</sup>Universidad Carlos III, Leganes, Spain

**THPB-3:A Novel TE10-TE20 Mode Transducer Utilizing Vertical Cross-Excitation**

H. Ikeuchi<sup>1</sup>, S. Matsumoto<sup>2</sup>, T. Kawai<sup>1</sup>, I. Ohta<sup>1</sup>, <sup>1</sup>University of Hyogo, Himeji, Japan, <sup>2</sup>Furuno Electric Co., Ltd., Nishinomiya, Japan

**THPD-3:A Heterodyne Receiver for Harmonic Doppler Radar Cardio-pulmonary Monitoring with Body-worn Passive RF Tags**

A. Singh, V. M. Lubecke, *University of Hawaii at Manoa, Honolulu, United States*

**THPA-4:A Novel Multi-Octave Differential Power Divider**

C. F. Marki, V. D. Kodwani, F. A. Marki, *Marki Microwave, Morgan Hill, United States*

**THPB-4:Wireless Power Transmission Based on Directional Coupler or Directional Filter**

I. Awai, K. Hori, S. Yakuno, K. Namikoshi, *Ryukoku University, Otsu, Japan*

**THPD-4:Energy Efficient 136 Mb/s OOK Implantable Transmitter for Wireless Brain Computer Interface**

J. Jung, S. Zhu, P. Liu, D. Heo, *Washington State University, Pullman, United States*

**THPA-5:A Reconfigurable Impedance Matching Network Using Dual-Beam MEMS Switches for an Extended Operating Frequency Range**

F. Domingue<sup>1</sup>, S. Fouladi<sup>2</sup>, R. R. Mansour<sup>2</sup>, <sup>1</sup>Universite du Quebec à Trois-rivières, Trois-Rivières, Canada, <sup>2</sup>Univeristy of Waterloo, Waterloo, Canada

**THPB-5:A New UWB Coupled Transmission Line Power Divider**

R. Kravchenko<sup>1</sup>, M. Stadler<sup>1</sup>, E. Leitgeb<sup>2</sup>, <sup>1</sup>EPCOS, Deutschlandsberg, Austria, <sup>2</sup>TU Graz, Graz, Austria

**THPD-5:A Planar Covered Multi-Slot-Array Heat Applicator with Beam Scanning Capability for Interstitial Microwave Hyperthermia**

D. Kim<sup>1</sup>, N. Kim<sup>1</sup>, C. Cheon<sup>2</sup>, Y. Kwon<sup>1</sup>, <sup>1</sup>Seoul National University, Seoul, Republic of Korea, <sup>2</sup>University of Seoul, Seoul, Republic of Korea

**THPB-6:Dual-Band Hybrid Balun Structure using Transmission-lines and Lumped Component Resonators**

P. Aflaki<sup>1</sup>, R. Negra<sup>2</sup>, F. Ghannouchi<sup>1</sup>, <sup>1</sup>University of Calgary, Calgary, Canada, <sup>2</sup>RWTH Aachen University, Aachen, Germany

**THPB-7:A Novel Compact Three-Dimensional CMOS Branch-Line Coupler using the Meandering ECPW/TFMS and Buried Micro Coaxial Technologies at 60 GHz**

K. Hettak, *Communications Research Center, Ottawa, Canada*

**THPB-8:A Novel Volumetric Folded Ring Resonator Metamaterial Structure**

N. R. Labadie, S. K. Sharma, *San Diego State University, San Diego, United States*

**THPB-9:Design and Characterization of Periodically-Loaded Substrate Integrated Waveguide Phase Shifters**

A. Suntives, K. Payandehjoo, R. Abhari, *McGill University, Montreal, Canada*

**THPB-10:Compact Wilkinson Power Divider with Simultaneous Bandpass Response and Harmonic Suppression**

P. Cheong, K. Lai, K. Tam, *University of Macau, Macau, Macau*



THURSDAY

ROOM 204ABC

9:40 - 11:40

**THPF: Advances in Communication, Radar, Sensor and Measurement Systems**

Shoichi Narahashi, *NTT DOCOMO, Inc*

**THPH: RFID and Power Harvesting Technologies**

Luca Roselli, *University of Perugia*  
Apostolos Geprgoados, *CTTC, Barcelona*

**THPF-1: Implementation and Analysis of a 30 GHz Wireless Communication System with a Novel Receiver Front-end**

Z. Zhang, Y. Wei, K. Wu, *Ecole Polytechnique Montreal, Montreal, Canada*

**THPH-1: CAD of Wireless Resonant Energy Links (WREL) Realized by Coils**

M. Dionigi, M. Mongiardo, *Università di Perugia, Perugia, Italy*

**THPF-2: A 3.1-10.6 GHz RF Receiver Front-end in 0.18 um CMOS for Ultra-Wideband Applications**

B. Park<sup>1</sup>, K. Lee<sup>1</sup>, S. Choi<sup>1</sup>, S. Hong<sup>2</sup>, <sup>1</sup>ETRI, Daejeon, Republic of Korea, <sup>2</sup>KAIST, Daejeon, Republic of Korea

**THPH-2: Wireless Remote Localization System utilizing Ambient RF/Solar Power Scavenging RFID Tags**

R. J. Vyas, V. Lakafofis, M. Tentzeris, *Georgia Institute of Technology, Atlanta, United States*

**THPF-3: Cable imaging with an active W-band millimeter-wave sensor**

D. Goshi, Y. Liu, K. Mai, L. Bui, Y. Shih, *Honeywell International, Torrance, United States*

**THPH-3: CAD Procedure for Predicting the Energy Received by Wireless Scavenging Systems in the Near- and Far-field Region**

V. Rizzoli<sup>1</sup>, D. Masotti<sup>1</sup>, N. Arbizzani<sup>1</sup>, A. Costanzo<sup>2</sup>, <sup>1</sup>University of Bologna, Bologna, Italy, <sup>2</sup>Il School of Engineering-University of Bologna, Cesena, Italy

**THPF-4: Time-Domain Calibration Technique for Ultra-Wide Instantaneous-Bandwidth Vector Waveform Generation Using Parallel I/Q Channels**

J. X. Qiu, *Army Research Laboratory, Adelphi, United States*

**THPH-4: Sensor Data Transmission Through Passive RFID Tags to Feed Wireless Sensor Networks**

L. Catarinucci, R. Colella, L. Tarricone, *University of Salento, Lecce, Italy*

**THPF-5: Interferometric Detection of the Angular Velocity of Moving Objects**

J. A. Nanzer, *Johns Hopkins University, Laurel, United States*

**THPH-5: Piggyback Modulation for UHF RFID Sensors**

H. Chen, A. Bhadkamkar, D. W. van der Weide, *University of Wisconsin - Madison, Madison, United States*

**THPF-6: Design and Implementation of a Wireless Link Coupled Channel Emulator for DSRC Wireless Systems**

T. Faseth, M. Winkler, C. Schubert, H. Arthaber, G. Mag-erl, *Vienna University of Technology, Vienna, Austria*

**THPF-7: Miniature Radio Frequency Ion Trap Mass Spectrometry**

J. D. Maas, W. Xu, W. J. Chappell, *Purdue University, West Lafayette, United States*



THURSDAY TECHNICAL SESSIONS

10:10-11:50

**TH2A: Wide Bandgap Semiconductor Applications**  
 Aaron Oki, *Northrop Grumman*  
 Reynold Kagiwada, *Northrop Grumman*  
**Room: 205AB**

**TH2B: RF MEMS Switches and Switched Capacitors**  
 Dimtri Peroulis, *Purdue University*  
 Art Morris, *Wispry Inc.*  
**Room: 206AB**

**TH2C: Phased Array Systems and Integration**  
 Zoya Popovic, *University of Colorado*  
 Glenn Hopkins, *GTRI*  
**Room: 207AB**

10:10 - 10:30

**TH2A-1: DARPA's GaN Technology Thrust**  
 M. J. Rosker<sup>1</sup>, J. D. Albrecht<sup>1</sup>, E. Cohen<sup>2</sup>, J. Hodiak<sup>3</sup>, T. Chang<sup>3</sup>, <sup>1</sup>Defense Advanced Research Projects Agency, Arlington, United States, <sup>2</sup>EBCO Technology Advising, Inc., North Potomac, United States, <sup>3</sup>Booz Allen Hamilton Inc., Arlington, United States

**TH2B-1: Sub-Hundred Nanosecond Reconfiguration Capabilities of Nanogap RF MEMS Switched Capacitor**  
 A. Verger<sup>1</sup>, A. Pothier<sup>1</sup>, C. Guines<sup>1</sup>, A. Crunteanu<sup>1</sup>, P. Blondy<sup>1</sup>, J. Orlianges<sup>2</sup>, J. Dhennin<sup>3</sup>, F. Courtade<sup>4</sup>, O. Vendier<sup>5</sup>, <sup>1</sup>XLIM UMR 6172 – Université de Limoges/CNRS, Limoges, France, <sup>2</sup>spcts CNRS UMR 6638, Limoges, France, <sup>3</sup>NovaMEMS, Ramonville, France, <sup>4</sup>CNES, Toulouse Cedex9, France, <sup>5</sup>Thales Alenia Space, Toulouse, France

**TH2C-1: X/Ku-Band 8-Element Phased Arrays Based on Single Silicon Chips**  
 Y. A. Atesal<sup>1</sup>, B. Cetinoneri<sup>1</sup>, K. Koh<sup>2</sup>, G. M. Rebeiz<sup>1</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>Intel Corp., Hillsboro, United States

10:30 - 10:50

**TH2A-2: Reliable GaN HEMTs for High Frequency Applications**  
 B. Heying<sup>1</sup>, W. Luo<sup>1</sup>, I. Smorchkova<sup>1</sup>, Y. Chen<sup>1</sup>, P. Huang<sup>1</sup>, S. Din<sup>1</sup>, M. Siddiqui<sup>1</sup>, W. Sutton<sup>1</sup>, V. Gambin<sup>1</sup>, M. Wojtowicz<sup>2</sup>, A. Oki<sup>1</sup>, <sup>1</sup>Northrop Grumman Corporation, Redondo Beach, United States, <sup>2</sup>Northrop Grumman Corporation, Redondo Beach, United States

**TH2B-2: An RF-MEMS Switch with mN Contact Forces**  
 C. D. Patel, G. M. Rebeiz, University of California, San Diego, La Jolla, United States

**TH2C-2: UWB Array Antenna Utilizing Novel Electrical Scanning System with Tapped Delay Lines**  
 F. Sakai, K. Ohta, Sakuratech Corporation, Kawasaki-city, Japan

10:50 - 11:10

**TH2A-3: GaN Technology for Microwave and Millimeter Wave Applications**  
 N. J. Kolas, T. E. Kazior, C. S. Whelan, S. K. Brierley, K. V. Smith, E. M. Chumbes, S. D. Bernstein, J. A. Smolko, Raytheon Company, Andover, United States

**TH2B-3: Charging Characteristics of Ultra-nano-crystalline Diamond in RF MEMS Capacitive Switches**  
 C. L. Goldsmith<sup>1</sup>, A. V. Sumant<sup>2</sup>, O. Auciello<sup>2</sup>, J. A. Carlisle<sup>3</sup>, J. C. Hwang<sup>6</sup>, C. Palego<sup>4</sup>, W. Wang<sup>6</sup>, R. W. Carpick<sup>5</sup>, V. Adiga<sup>5</sup>, A. Datta<sup>4</sup>, C. Gudeman<sup>4</sup>, S. O'Brien<sup>1</sup>, S. Sampath<sup>4</sup>, H. Zeng<sup>3</sup>, <sup>1</sup>MEMtronics Corporation, Plano, United States, <sup>2</sup>Argonne National Laboratory, Argonne, United States, <sup>3</sup>Advanced Diamond Technologies, Inc., Romeoville, United States, <sup>4</sup>Innovative Micro Technology, Santa Barbara, United States, <sup>5</sup>University of Pennsylvania, Philadelphia, United States, <sup>6</sup>Lehigh University, Bethlehem, United States

**TH2C-3: Narrowband Frequency Scanning Array Antenna at 5.8 GHz for Short Range Imaging**  
 A. Fackelmeier, E. Biebl, Technische Universität München, Munich, Germany

11:10 - 11:20

**TH2A-4: 100 mm GaN-on-SiC RF MMIC Technology**  
 J. W. Palmour, C. Hallin, A. Burk, F. Radulescu, D. Namishia, H. Hagleitner, J. Duc, B. Pribble, S. T. Sheppard, J. B. Barner, J. Milligan, Cree, Inc., Durham, United States

**TH2B-4: Effect of Surface Conduction on Dielectric Charging in RF MEMS Capacitive Switches**  
 Z. Peng<sup>1</sup>, D. Molinero<sup>1</sup>, C. Palego<sup>1</sup>, J. Hwang<sup>1</sup>, C. Moody<sup>2</sup>, A. Malczewski<sup>2</sup>, B. W. Pillans<sup>2</sup>, <sup>1</sup>Lehigh University, Bethlehem, United States, <sup>2</sup>Raytheon Systems Co., Dallas, United States

**TH2C-4: A New Approach to Design Low Cost, Low Complexity Phased Arrays**  
 D. Ehyae, A. Mortazawi, University of Michigan, Ann Arbor, United States

11:20 - 11:30

**TH2A-5: Wideband Power Amplifier MMICs Utilizing GaN on SiC**  
 E. Reese, D. Allen, C. Lee, T. Nguyen, TriQuint Semiconductor, Richardson, United States

**TH2B-5: Electrostatic RF MEMS Tunable Capacitors with Analog Tunability and Low Temperature Sensitivity**  
 R. Mahameed, G. M. Rebeiz, University of California, San Diego, La Jolla, United States

**TH2C-5: Sidelobe Level Reduction in Wide-Angle Scanning Array System Using Pattern-Reconfigurable Antennas**  
 J. Wu, C. Chang, T. Chin, S. Huang, S. Chang, National Chung Cheng University, Ming-Hsiung Chia-Yi, Taiwan

11:30 - 11:40

**TH2A-6: Gallium Nitride RF-Devices: An Overview on the Development Activities in Europe**  
 R. Quay, M. Mikulla, Fraunhofer IAF, Freiburg, Germany

**TH2C-6: Active 30 GHz Antenna Array for Digital Beam Forming and Polarization Multiplexing**  
 K. Kuhlmann<sup>1</sup>, A. F. Jacob<sup>2</sup>, <sup>1</sup>Physikalisch-Technische Bundesanstalt, Braunschweig, Germany, <sup>2</sup>Tech. Univ. Hamburg-Harburg, Hamburg, Germany

11:40 - 11:50

THURSDAY

TECHNICAL SESSIONS

10:10-11:50

**TH2D: Novel Concepts for Advanced Packaging and Interconnect Technologies**  
 Rhonda Franklin, *University of Minnesota*  
 Eric Strid, *Cascade Microtech*  
**Room: 207C**

**TH2E: Advances in MMIC Packaging**  
 Arvind Sharma, *Northrop Grumman*  
 Debabani Choudhury, *Intel*  
**Room: 207D**

**TH2D-1: K-band Near-Hermetic Surface Mount Package using Liquid Crystal Polymer for High Power Applications.**  
 C. Chen, A. Pham, *University of California, Davis, Davis, United States*

**TH2E-1: 3D Integration Technologies for Emerging Microsystems (Invited)**  
 D. Choudhury, *Intel, Hillsboro, United States*

10:10 - 10:30

**TH2D-2: Heterogeneous Flip-Chip Assembly of a GaAs C-band Power Amplifier MMIC Using Liquid Metal Vertical Interconnects**  
 P. E. Ralston<sup>1</sup>, J. Wood<sup>2</sup>, K. Vummidi<sup>1</sup>, J. M. Oliver<sup>1</sup>, S. Raman<sup>1</sup>, <sup>1</sup>Virginia Tech, Blacksburg, United States, <sup>2</sup>BAE Systems, Nashua, United States

**TH2E-2: A wafer-level interposer based microwave circuit and system integration technology**  
 C. Hillman, J. B. Hacker, W. Ha, P. Stupar, *Teledyne Scientific Company, Thousand Oaks, United States*

10:30 - 10:50

**TH2D-3: Adjustable Dielectric Using Magnetically Aligned Conductive Particles for Microwave Applications**  
 S. Moon, W. J. Chappell, *Purdue University, West Lafayette, United States*

**TH2E-3: Ultra Compact RFICs Using Three-dimensional MMIC technology**  
 T. Kaho, Y. Yamaguchi, K. Nishikawa, I. Toyoda, K. Uehara, *NTT Corporation, Yokosuka, Japan*

10:50 - 11:10

**TH2D-4: Modeling and Metrology of Metallic Nanowires with Application to Microwave Interconnects**  
 K. Kim<sup>1</sup>, M. Wallis<sup>2</sup>, P. Rise<sup>3</sup>, C. Chiang<sup>4</sup>, A. Imtiaz<sup>2</sup>, P. Kabos<sup>2</sup>, D. S. Filipovic<sup>1</sup>, <sup>1</sup>University of Colorado, Boulder, United States, <sup>2</sup>National Institute of Science and Technology, Boulder, United States, <sup>3</sup>University of Colorado, Boulder, United States, <sup>4</sup>National Changhua University of Education, Changhua City, Taiwan

**TH2E-4: Ultra Compact & Light Weight T/R Module Constructed by Hermetic Wafer-Scale Assembly Technology**  
 P. Chang-Chien, *Northrop Grumman Aerospace Systems, Redondo Beach, United States*

11:10 - 11:30

11:30 - 11:50



# THURSDAY FOCUSED AND PANEL SESSIONS

**Thursday**      **08:00 – 09:40**      **Room 207D**

## Advances in Active Device Modeling

**Chair:** Arvind Sharma, *Northrop Grumman Aerospace Systems*

**Co-Chair:** Q.J. Zhang, *Department of Electronics, Carlton University*

**Sponsor:** IMS 2010 Steering Committee

**Abstract:** First-pass design of microwave and millimeter-wave circuits require that device models accurately describe the device under various operating environments. There has been considerable progress in the test equipment and measurement procedures, as well as in characterization and modeling techniques. Several new compound semiconductor technologies have also emerged to address demanding system application requirements. Modeling complex device behavior requires innovative approaches. In this focused session, presenters will report on the status of linear models, noise, and nonlinear models, and address future directions in measurement approaches and modeling techniques.

**Thursday**      **08:00 – 09:40**      **Room 205AB**

## Terahertz Electronics:

**Chair:** Reynold S. Kagiwada, *Northrop Grumman Aerospace Systems*

**Co-Chair:** Aaron Oki, *Northrop Grumman Aerospace Systems*

**Sponsor:** IMS 2010 Steering Committee

**Abstract:** Recent advances in device technology are making the dream of terahertz electronics a reality. Rapid progress is being made in solid state devices, amplifiers, and MMICs. Recently InP HEMT amplifiers have been produced with gain above 500 GHz. This session will cover the state-of-the-art in Terahertz Electronics.

**Thursday**      **10:10 – 11:30**      **Room 207D**

## Advances in MMIC Packaging

**Chair:** Arvind Sharma, *Northrop Grumman Aerospace Systems*

**Co-Chair:** Debabani Choudhury, *Intel*

**Sponsor:** IMS 2010 Steering Committee

**Abstract:** Higher performance requirements of millimeter and sub-millimeter systems are driving the development of various packaging technologies such as 3D-on-wafer integration, 3D-IC stacking including wafer-level packaging (3D-WLP), and stacked IC (3D-SIC). This focused session will present an overview of 3D packaging technologies, and will provide state-of-the-art performance of components and systems utilizing these technologies.

**Thursday**      **10:10 – 11:50**      **Room 205AB**

## Wide Bandgap Semiconductor Applications

**Chair:** Aaron Oki, *Northrop Grumman Aerospace Systems*

**Co-Chair:** Reynold S. Kagiwada, *Northrop Grumman Aerospace Systems*,

**Sponsor:** MTT-2, MTT-15, MTT-16, MTT-20, RFIC; IMS 2010

**Abstract:** Wide bandgap technologies continue to make significant advances with improvements in gain, bandwidth, power added efficiency, and reliability. Microwave power applications are moving up to millimeter wave frequencies. Industry leaders will present the state-of-the-art in wide bandgap devices, MMICs, and applications.

**Thursday**      **12:00 – 13:10**      **Room 210AB**

## On-Die Synthesized Inductors: Boon or Bane?

**Chair/Moderator:** Jim Wight, *Carleton University*

### Panelists:

John Long, *Delft University of Technology*

Rick Carley, *Carnegie Mellon University*

Tom Riley, *Kaben Wireless Silicon*

**Abstract:** Since the introduction of full transceivers on-silicon, inductor design has presented a problem. Inductors are necessary in the design of VCOs for frequency synthesizers, as well as in reconstruction filters following transmitter DACs. However, inductors are costly in terms of die area, and can attain only a modest Q in performance.

Alternative approaches have been developed to render the on-die inductor unnecessary. In particular, synthesized inductors can be achieved using active elements. Further, since most inductors in a transceiver are needed to form part of a resonator section for an oscillator or filter, approaches that realize the complete resonator could be useful. Such techniques include microelectromechanical systems (MEMS) and sampled analog finite impulse response (FIR) techniques.

While these approaches avoid the disadvantages of the on-die inductor, they have their

# THURSDAY FOCUSED AND PANEL SESSIONS

own disadvantages. The competing strengths and inherent limitations of different realizations of on-die inductors will be discussed in this panel session. Whether the industry would adopt Synthesized (Active) Inductors, or other alternatives such as MEMS or Sampled Analog (FIR) techniques, is an open question.

**Thursday 12:00 – 13:10 Room 210CD**

## RF GaN Reliability: Where Does the Technology Stand?

### Chair/Moderator:

Frank Sullivan, *Raytheon*  
Bernie Geller, *Vadum, Inc.*

**Sponsor:** MTT-6 & MTT-7

### Panelists:

Steve Binari, *Naval Research Laboratory*  
Toshihiro Ohki, *Fujitsu*  
Ruediger Quay, *Fraunhofer Institute*  
Robert Trew, *North Carolina State University*  
David Via, *Air Force Research Laboratory, Wright Patterson*  
Roger Wallace, *BAE Systems*  
Colin Whelan, *Raytheon*

**Abstract:** This panel session will address the reliability issues associated with GaN discrete devices and MMICs in RF applications. The technology has made very large advances in the past few years and is starting to be vigorously deployed in a variety of applications, both commercial and military. At this point reliability becomes a major concern. Degradation mechanisms related to traps, hot carriers, passivation, material defects and metallization will be covered. The panel will address where the technology stands today, both in terms of intrinsic device properties and implementation issues. Data will be presented to substantiate the current reliability status.

**Thursday 13:20 – 15:40 Room 207D**

## Advances in Silicon-based Millimeter-Wave Integrated Circuits

**Chair:** Dietmar Kissinger, *University of Erlangen-Nuermberg*

**Co-Chair:** Robert Weigel, *University of Erlangen-Nuermberg*

**Sponsor:** MTT-2, MTT-15, MTT-16, MTT-20, RFIC, IMS 2010

**Abstract:** The advancement of silicon-based technologies like CMOS and SiGe has enabled the low-cost fabrication of fully integrated millimeter-wave transceivers for consumer applications in communication and sensor technologies. Current research in silicon technology is targeting transition frequencies of 500GHz, which will enable the integration of systems with operational frequencies well above 100GHz, paving the way towards monolithic electronic THz solutions. This session focuses on recent advancements in millimeter-wave circuits based on silicon technologies for emerging applications around 100GHz and beyond.

**Thursday 13:20 – 15:00 Room 207D**

## The Impact of Nanoelectronics on Radiofrequency Technology

**Chair:** Peter Russer, *Technische Universitaet Muenchen*

**Co-Chair:** Lucia Pierantoni, *Universita Ploitecnica delle Marche Ancona*

**Sponsor:** MTT-15, IMS 2010 TPC

**Abstract:** For future electronic devices, circuits and systems using information and communication technologies, nanotechnology will provide EXCELLENT POTENTIALITIES. The future development of systems using information and communications technologies, will be characterized by substantially increasing the amounts of data to be stored, processed and transmitted. The evolution of devices following Moores law will be possible only on the basis of nanoelectronic concepts. The goal of this Focused Session is to present an overview of recent developments of new microwave materials, devices and systems based on nanotechnology.

**Thursday 15:30 – 17:10 Room 207D**

## Advances in RFID Circuits and Systems

**Chair:** Jürgen Heidrich, *University of Erlangen-Nuermberg*

**Co-Chair:** Robert Weigel, *University of Erlangen-Nuermberg*

**Sponsor:** MMT-2, MMT-16, MTT-24, RFIC, IMS 2010 TPC

**Abstract:** Contactless technologies, especially RFID systems operating in the HF region, have become very popular in commercial and industrial application areas. They are well-known for article surveillance, access control and near field communications. Lately, higher frequency ranges have become a growing interest. Also, greater demands on the circuit and antenna design are being made. This focused session will show the different requirements for antenna and circuit design, and the performance required by the RFID systems and the devices used in the systems.



## GOLD PANEL SESSION

**Thursday 10:20-11:40**  
**Room 208 AB**

**We Want YOU!**  
**But**  
**What's In It For ME?**

**Chair:** Sergio Pacheco, Freescale Semiconductor

**Co-Chair:** Rashaunda Henderson, University of Texas at Dallas

**Sponsor:** IEEE MTT-S GOLD Committee

This panel is comprised of leaders of the Microwave Theory and Techniques Society (MTT-S). They share their vast experience of the society and good reasons for becoming a committed member through technical and voluntary contributions. Speakers from industry, academia, US and International regions will be available to explain how they were "retained" in MTT-S.

IEEE Graduates of the Last Decade (GOLD) was created in 1996 as a membership program to help students transition to young professionals within the larger IEEE community. MTT-S GOLD activities began at the IMS2007 meeting in Honolulu, HI. GOLD makes up approximately 10% of the MTT-S population and are a valuable part of the community.



THURSDAY TECHNICAL SESSIONS

13:20-15:00

**TH3A: Advances in Silicon-based Millimeter-Wave Integrated Circuits**  
 Dietmar Kissinger, *University of Erlangen-Nuernberg*  
 Robert Weigel, *University of Erlangen-Nuernberg*  
**Room: 205AB**

**TH3B: Ferrite Materials and Devices**  
 Steven N. Stitzer, *Northrop Grumman ES*  
 Spartak Gevorgian, *Chalmers University*  
**Room: 206AB**

**TH3C: Tunable, Active and Integrated Filter Technologies**  
 Har Dayal, *BAE SYSTEMS -EWS*  
 Atsushi Sanada, *Yamaguchi University*  
**Room: 207AB**

13:20 - 13:30

**TH3A-1: On the Development of CMOS Sub-THz Phased Array Technology for Communication/Sensing Nodes**  
 J. Laskar, S. Pinel, S. Sarkar, P. Sen, B. Perunama, D. Dawn, M. Leung, F. Barale, D. Yeh, J. Shin, S. W. Hsiao, K. Chuang, E. Juntunen, G. Iyer, A. Muppalla, P. Melet, Georgia Tech, Atlanta, United States

**TH3B-1: Dual-Band Integrated Self-biased Edge-Mode Isolator based on the Double Ferromagnetic Resonance of a Bistable Nanowire Substrate**  
 L. Carignan<sup>1</sup>, C. Caloz<sup>2</sup>, D. Ménard<sup>1</sup>, <sup>1</sup>Polytechnique School of Montreal, Montreal, Canada, <sup>2</sup>Ecole Polytechnique of Montreal, Montreal, Canada

**TH3C-1: Novel MMIC Architectures for Tunable Microwave Wideband Active Filters**  
 F. Bergeras<sup>1</sup>, P. Duème<sup>2</sup>, J. Plaze<sup>2</sup>, L. Darcel<sup>3</sup>, B. Jarry<sup>1</sup>, M. Campovecchio<sup>1</sup>, <sup>1</sup>XLIM Research Institute, Limoges, France, <sup>2</sup>Thales Airborne Systems, Elancourt, France, <sup>3</sup>Thales Air Systems, Elancourt, France

13:30 - 13:40

**TH3A-2: A 76GHz PLL for mm-Wave Imaging Applications**  
 K. M. Nguyen<sup>1</sup>, H. Kim<sup>2</sup>, C. G. Sodini<sup>1</sup>, <sup>1</sup>Massachusetts Institute of Technology, Cambridge, United States, <sup>2</sup>Lincoln Laboratory, Lexington, United States

**TH3B-2: Magnetically Tunable Nanocomposites for Microwave Applications**  
 C. Morales<sup>1</sup>, J. Dewdney<sup>1</sup>, S. Pal<sup>2</sup>, K. Stojak<sup>2</sup>, H. Srikanth<sup>2</sup>, J. Wang<sup>1</sup>, T. Weller<sup>1</sup>, <sup>1</sup>Center for Wireless and Microwave Information Systems (WAMI), Tampa, United States, <sup>2</sup>Functional Materials Lab (FML), Tampa, United States

**TH3C-2: Three Approaches for the realization of a Chebyshev Cross-Coupled UWB Filter**  
 W. Galal El Dine<sup>1</sup>, H. Ezzeddine<sup>1</sup>, S. Bila<sup>2</sup>, S. Verdeyme<sup>2</sup>, <sup>1</sup>STMicroelectronics, Tours, France, <sup>2</sup>XLIM - UMR CNRS n°6172, Limoges, France

13:40 - 13:50

**TH3A-3: Towards High-Performance 100 GHz SiGe and CMOS Circuits**  
 G. M. Rebeiz<sup>1</sup>, J. W. May<sup>1</sup>, M. Uzunkol<sup>1</sup>, W. Shin<sup>1</sup>, O. Inac<sup>1</sup>, M. Chang<sup>2</sup>, <sup>1</sup>University of California, San Diego, La Jolla, United States, <sup>2</sup>University of Michigan, Ann Arbor, Ann Arbor, United States

**TH3C-3: High Rejection BPF for WiMAX Applications from Silicon Integrated Passive Device Technology**  
 K. Liu<sup>1</sup>, R. C. Frye<sup>2</sup>, B. Ahn<sup>1</sup>, <sup>1</sup>STATS ChipPAC, Tempe, United States, <sup>2</sup>RF Design Consulting, LLC, Piscataway, United States

13:50 - 14:00

**TH3A-4: Highly Integrated 79, 94, and 120-GHz SiGe Radar Frontends**  
 M. Jahn, A. Stelzer, A. Hamidipour, Johannes Kepler University of Linz, Linz, Austria

**TH3B-3: L-Band High Power Electronically Rotatable Ferrite Half-Wave Plate**  
 C. R. Boyd, Jr., W. E. Hord, S. T. Van Dyke, S. J. McKechnie, Microwave Applications Group, Santa Maria, United States

**TH3C-4: Single-Chip Integration of Electronically Switchable Bandpass Filter for 3.5GHz WiMAX Application**  
 W. Liao, C. Chen, Y. Lin, National Central University, Jhongli City, Taoyuan County, Taiwan

14:10 - 14:20

**TH3A-5: Second Generation Transceivers for D-Band Radar and Data Communication Applications**  
 I. Sarkas<sup>1</sup>, E. Laskin<sup>1</sup>, J. Hasch<sup>2</sup>, P. Chevalier<sup>3</sup>, S. P. Voinigescu<sup>1</sup>, <sup>1</sup>University of Toronto, Toronto, Canada, <sup>2</sup>Robert Bosch GmbH, Stuttgart, Germany, <sup>3</sup>STMicroelectronics, Crolles, France

**TH3B-4: Toroid Microinductors Using Segmented Magnetic Cores**  
 F. Hettstedt, U. Schürmann, R. Knöchel, E. Quandt, Christian-Albrechts-University, Kiel, Germany

**TH3C-5: Very Compact Transformer-Coupled Balun-Integrated Bandpass Filter Using Integrated Passive Device Technology on Glass Substrate**  
 C. Chen<sup>1</sup>, C. Huang<sup>1</sup>, T. Horng<sup>1</sup>, S. Wu<sup>2</sup>, C. Chiu<sup>3</sup>, C. Hung<sup>3</sup>, J. Li<sup>4</sup>, C. Chen<sup>4</sup>, <sup>1</sup>National Sun Yat-Sen University, Kaohsiung, Taiwan, <sup>2</sup>National University of Kaohsiung, Kaohsiung, Taiwan, <sup>3</sup>Advanced Semiconductor Engineering Inc., Kaohsiung, Taiwan, <sup>4</sup>Industrial Technology and Research Institute, Hsinchu, Taiwan

14:20 - 14:30

**TH3A-6: 122 GHz ISM-Band Transceiver Concept and Silicon ICs for Low-Cost Receiver in SiGe BiCMOS**  
 K. Schmalz<sup>1</sup>, W. Winkler<sup>2</sup>, J. Borngräber<sup>1</sup>, W. Debski<sup>2</sup>, B. Heinemann<sup>1</sup>, J. C. Scheytt<sup>1</sup>, <sup>1</sup>IHP GmbH, Frankfurt (Oder), Germany, <sup>2</sup>Silicon Radar GmbH, Frankfurt (Oder), Germany

**TH3B-5: High Isolation Lange-Ferrite Circulators with NF Suppression for Simultaneous Transmit and Receive**  
 S. K. Cheung, W. H. Weedon, C. C. Caldwell, Applied Radar, Inc., North Kingstown, United States

**TH3C-6: Low Temperature Superconductive Tunable Band-Stop Resonators and Filters**  
 S. S. Attar, S. Setoodeh, R. R. Mansour, University of Waterloo, Waterloo, Canada

14:30 - 14:40

**TH3C-7: A Vertically Integrated Tunable UHF Filter**  
 E. E. Hoppenjans, W. J. Chappell, Purdue University, West Lafayette, United States

14:40 - 15:00

THURSDAY

TECHNICAL SESSIONS

13:20-15:00

**TH3D: High Power and Broad Band Amplifiers.**

Bumman Kim, *POSTECH*  
Kiki Ikossi, *DTRA*  
**Room: 207C**

**TH3E: The Impact of Nanoelectronics on Radio Frequency Technology**

Peter Russer, *Technische Universitaet Munenchen*  
Lucia Pierantoni, *Universita Ploitecnica delle Marche*  
**Room: 207D**

**TH3D-1: A 68% Efficiency, C-Band 100W GaN Power Amplifier for Space Applications**

T. Yamasaki<sup>1</sup>, Y. Kittaka<sup>3</sup>, H. Minamide<sup>1</sup>, K. Yamauchi<sup>2</sup>, S. Miwa<sup>1</sup>, S. Goto<sup>1</sup>, M. Nakayama<sup>1</sup>, M. Kono<sup>1</sup>, N. Yoshida<sup>1</sup>, <sup>1</sup>Mitsubishi Electric Corporation, Itami, Japan, <sup>2</sup>Mitsubishi Electric Corporation, Kamakura, Japan, <sup>3</sup>Wave Technology Inc, Kawanishi, Japan

**TH3E-1: Semiconductor Nanomaterials For Radio Frequency Devices and Systems**

J. A. Rogers, University of Illinois, Champaign-Urbana, Champaign-Urbana, United States

13:20 - 13:40

**TH3D-2: Over 10W C-Ku Band GaN MMIC Non-uniform Distributed Power Amplifier with Broadband Couplers**

S. Masuda, A. Akasegawa, T. Ohki, K. Makiyama, N. Okamoto, K. Imanishi, T. Kikkawa, H. Shigematsu, Fujitsu Laboratories Ltd., Atsugi, Japan

**TH3E-2: Molecular electronics on its way to RF**

E. Albert, C. Erlen, S. Locci, P. Lugli, Technische Universitaet Muenchen, Munich, Germany

13:40 - 14:00

**TH3D-3: Three Stage 6-18 GHz High Gain and High Power Amplifier based on GaN Technology**

Z. Ouarch<sup>1</sup>, G. Mougnot<sup>1</sup>, B. Lefebvre<sup>1</sup>, S. Heckmann<sup>1</sup>, J. Lhortolary<sup>1</sup>, D. Baglieri<sup>1</sup>, D. Floriot<sup>1</sup>, M. Camiade<sup>1</sup>, H. Blanck<sup>2</sup>, M. Le Pipec<sup>3</sup>, D. Meslager<sup>3</sup>, P. Le Helleye<sup>3</sup>, <sup>1</sup>UMS, Orsay, France, <sup>2</sup>UMS GmbH, Ulm, Germany, <sup>3</sup>Dga/Celar, Bruz Cedex, France

**TH3E-3: Nanostructure Antennas for the LW-IR Regime**

W. Porod, J. A. Bean, Z. Sun, B. Tiwari, G. Szakmany, G. H. Bernstein, P. Fay, University of Notre Dame, Notre Dame, United States

14:00 - 14:20

**TH3D-4: High Efficiency 80W X-Band Power Amplifier using Coaxial Waveguide Spatial Power Combining Technique**

P. G. Courtney, T. Tran, C. Bartak, S. Behan, P. Jia, CAP Wireless Inc., Newbury Park, United States

**TH3E-4: Recent Advances in Micro-structured Electric and Nano-structured Magnetic Microwave Metamaterials**

C. Caloz, L. Carignan, V. Boucher, T. Kodera, S. Couture, A. Parsa, D. Ménard, A. Yelon, École Polytechnique de Montréal, Montréal, Canada

14:20 - 14:40

**TH3D-5: High-Efficiency K-Band Space Traveling-Wave Tube Amplifier for Near-Earth High Data Rate Communications**

R. N. Simons<sup>1</sup>, D. A. Force<sup>1</sup>, P. C. Spitsen<sup>2</sup>, W. L. Menninger<sup>2</sup>, N. R. Robbins<sup>2</sup>, D. R. Dibb<sup>2</sup>, P. C. Todd<sup>2</sup>, <sup>1</sup>NASA Glenn Research Center, Cleveland, United States, <sup>2</sup>L-3 Communications Electron Technologies, Inc., Torrance, United States

**TH3E-5: All-semiconducting nanotube devices for RF and microwave applications**

N. Rouhi, D. Jain, K. Zand, P. Burke, UC Irvine, Irvine, United States

14:40 - 15:00





THURSDAY

INTERACTIVE FORUM

15:00 - 17:00

**THPJ: Advances in Metamaterial, EM Analysis and Circuit Modeling**

Tapan K. Sarkar, *Syracuse University*  
Peter Aaen, *Freescale Semiconductor Inc*

**THPM: Device Modeling and Characterization**

Peter Asbeck, *University of California, San Diego*

**THPN: Nonlinear Circuit and System Simulation**

Almudena Suarez, *University of Cantabria*

**THPJ-1: The Quantum Effects on The Transmission Properties of Periodic Rod Array**

S. Li<sup>1</sup>, Q. Zhu<sup>1</sup>, X. Yu<sup>1</sup>, N. Zhou<sup>1</sup>, R. Mo<sup>1</sup>, W. Liu<sup>2</sup>, H. Xin<sup>3</sup>, L. Qiu<sup>4</sup>, <sup>1</sup>University of Sci. &Tech. of China, Hefei, China, <sup>2</sup>University of Sci. &Tech. of China, Hefei, China, <sup>3</sup>Univ. of Arizona, Tucson, United States, <sup>4</sup>Stanford University, Stanford, United States

**THPM-1: Improved Parameter Extraction Method for GaN HEMT on Si Substrate**

A. Jarndal<sup>1</sup>, A. Z. Markos<sup>2</sup>, G. Kompa<sup>3</sup>, <sup>1</sup>Hodeidah University, Hodeidah, Yemen, <sup>2</sup>Berlin University of Technology, Berlin, Germany, <sup>3</sup>University of Kassel, Kassel, Germany

**THPN-1: Modeling Band-Pass Sampling Receivers Nonlinear Behavior in Different Nyquist Zones**

P. M. Cruz, N. B. Carvalho, *IT Universidade de Aveiro, Aveiro, Portugal*

**THPJ-2: Experimental Dielectric Sensing of materials using Epsilon-Near-Zero tunnel in SIW technology**

H. Lobato-Morales<sup>1</sup>, A. Corona-Chavez<sup>1</sup>, D. V. Murthy<sup>1</sup>, J. Martinez-Brito<sup>2</sup>, L. G. Guerrero-Ojeda<sup>2</sup>, <sup>1</sup>INAOE, Tonanzintla, Mexico, <sup>2</sup>UDLA-P, Cholula, Mexico

**THPM-2: Thermal Resistance Modeling for the Electrothermal Layout of High-Power RF Transistors**

P. H. Aaen, J. Wood, Q. Li, E. Mares, *Freescale Semiconductor Inc., Tempe, United States*

**THPN-2: Behavioral Model Analysis of Active Harmonic Load-pull Measurements**

S. P. Woodington<sup>1</sup>, R. S. Saini<sup>1</sup>, D. Williams<sup>2</sup>, J. Lees<sup>1</sup>, J. Benedikt<sup>1</sup>, P. J. Tasker<sup>1</sup>, <sup>1</sup>Cardiff University, Cardiff, United Kingdom, <sup>2</sup>Mimix Broadband, Belfast, United Kingdom

**THPJ-3: A Concentrically Corrugated Near-Field Plate**

M. F. Imani, A. Grbic, *University of Michigan, Ann Arbor, United States*

**THPM-3: Nonlinear HEMT Model Direct Formulated From the Second-Order Derivative of the I-V/ Q-V Characteristics**

L. Liu<sup>1</sup>, J. Ma<sup>2</sup>, H. Wu<sup>1</sup>, G. Ng<sup>3</sup>, Q. Zhang<sup>4</sup>, <sup>1</sup>University of Electronic Science and Technology of China, Chengdu, China, <sup>2</sup>Tianjin University, Tianjin, China, <sup>3</sup>Nanyang Technological University, Singapore, <sup>4</sup>Carleton University, Ottawa, Canada

**THPN-3: A Dual Branch Hammerstein-Wiener Architecture for Behavior Modeling of Wideband RF Transmitters**

F. Taringou, O. Hammi, F. M. Ghannouchi, *University of Calgary, Calgary, Canada*

**THPJ-4: A Sparse Grid based Collocation Method for Model Order Reduction of Finite Element Approximations of Passive Electromagnetic Devices under Uncertainty**

P. S. Sumant<sup>1</sup>, H. Wu<sup>2</sup>, A. C. Cangelaris<sup>1</sup>, N. R. Aluru<sup>3</sup>, <sup>1</sup>University of Illinois at Urbana-Champaign, Urbana, United States, <sup>2</sup>Extreme-DA Corporation, Santa Clara, United States, <sup>3</sup>University of Illinois at Urbana-Champaign, Urbana, United States

**THPM-4: Nonlinear Characterization Techniques for Improving Accuracy of GaN HEMT Model Predictions in RF Power Amplifiers**

R. Marante<sup>1</sup>, J. A. Garcia<sup>1</sup>, L. Cabria<sup>1</sup>, T. Aballo<sup>1</sup>, P. Cabral<sup>2</sup>, J. C. Pedro<sup>2</sup>, <sup>1</sup>Universidad de Cantabria, Santander, Spain, <sup>2</sup>Universidade de Aveiro, Aveiro, Portugal

**THPJ-5: A General 2D-FDFD based Eigen-Dielectric Formulation of the Maxwell Equations for Arbitrary Waveguide Structures**

A. Gaebler, F. Goelden, O. H. Karabey, R. Jakoby, *Technische Universitaet Darmstadt, Darmstadt, Germany*

**THPJ-6: Shape-Preserving Response Prediction for Microwave Circuit Modeling**

S. Koziel, *Reykjavik University, Reykjavik, Iceland*

**THPJ-7: A Simplified Methodology for Matched Filter Design with constraints - Filter-Antenna Subsystem for Space Application**

U. Naeem<sup>1</sup>, S. Bila<sup>1</sup>, S. Verdyme<sup>1</sup>, H. Chreim<sup>1</sup>, R. Chantalat<sup>1</sup>, M. Thevenot<sup>1</sup>, T. Monediere<sup>1</sup>, B. Palacin<sup>2</sup>, Y. Cailloce<sup>3</sup>, <sup>1</sup>XLIM-University of Limoges, Limoges, France, <sup>2</sup>CNES, Toulouse, France, <sup>3</sup>Thales Alenia Space, Toulouse, France

THURSDAY

ROOM 204ABC

15:00 - 17:00

**THPP: Advances in Planar Filter Designs**  
Chi Wang, *Orbital Sciences Corp*

**THPQ: Non-Planar Passive Filters and Multiplexers**  
Raafat Mansour, *University of Waterloo*  
Kawthar Zaki, *University of Maryland*

**THPR: Frequency Agile, Reconfigurable, Tunable and Active Filters**  
Ian Hunter, *University of Leeds*

**THPP-1: Sharp-Rejection Broadband Microstrip Bandpass Filters Using Loaded Open-Loop Resonator**  
W. Tu, National Central University, Taoyuan, Taiwan

**THPQ-1: Synthesis of Multi-Coupled Resonator Filters with Frequency-Dependent Couplings**  
W. Meng<sup>1</sup>, H. Lee<sup>1</sup>, K. A. Zaki<sup>1</sup>, A. E. Atia<sup>2</sup>, <sup>1</sup>University of Maryland, College Park, United States, <sup>2</sup>Orbital Science Corporation, Dulles, United States

**THPR-1: 26 GHz on Chip Cascaded Filter Using Low Q Inductors**  
B. K. Kormanyos<sup>1</sup>, T. K. Quach<sup>2</sup>, P. L. Orlando<sup>2</sup>, A. G. Mattamana<sup>2</sup>, K. S. Groves<sup>2</sup>, <sup>1</sup>Boeing Research and Technology, Seattle, United States, <sup>2</sup>Air Force Research Laboratory, Dayton, United States

**THPP-2: Design of Wide Single-/Dual-Passband Microstrip Bandpass Filters With Comb-Loaded Resonators**  
C. Tang, Y. Hsu, J. Wu, National Chung Cheng University, Chia-Yi, Taiwan

**THPQ-2: Comparison of lossy filters and predistorted filters using novel software**  
A. Padilla<sup>1</sup>, J. Mateu<sup>1</sup>, C. Collado<sup>1</sup>, C. Ernst<sup>2</sup>, J. M. Rius<sup>1</sup>, J. M. Tamayo<sup>1</sup>, J. M. O'Callaghan<sup>1</sup>, <sup>1</sup>Universitat Politècnica de Catalunya, Castelldefels, Spain, <sup>2</sup>ESA, Noordwijk, Netherlands

**THPR-2: A New Floating Active Inductor Using Resistive Feedback Technique**  
Q. Lai, J. Mao, Center for Microwave and RF Technologies, Shanghai, China

**THPP-3: Design of A Microstrip Bandpass Filter With a Wide Stopband**  
H. Lai<sup>1</sup>, C. Tang<sup>1</sup>, J. Wu<sup>1</sup>, Y. Lin<sup>2</sup>, <sup>1</sup>National Chung Cheng University, Chia-Yi, Taiwan, <sup>2</sup>Cheng Shiu University, Kaohsiung, Taiwan

**THPQ-3: Fabrication of PTFE-Filled Waveguide Bandpass Filter Using SR Direct Etching**  
M. Kishihara<sup>1</sup>, M. Kato<sup>2</sup>, H. Ikeuchi<sup>3</sup>, K. Murai<sup>3</sup>, Y. Ukita<sup>2</sup>, Y. Utsumi<sup>2</sup>, T. Kawai<sup>3</sup>, I. Ohta<sup>3</sup>, <sup>1</sup>Okayama Prefectural University, Soja, Japan, <sup>2</sup>University of Hyogo, Kamigori, Japan, <sup>3</sup>University of Hyogo, Himeji, Japan

**THPR-3: A Tunable Bandpass Patch Filter with Varactors**  
A. L. Serrano<sup>1</sup>, T. P. Vuong<sup>1</sup>, F. S. Correr<sup>2</sup>, P. Ferrari<sup>1</sup>, <sup>1</sup>Grenoble INP, Grenoble, France, <sup>2</sup>University of São Paulo (USP), São Paulo, Brazil

**THPP-4: RF System Integration and Miniaturization using Advanced Polymers**  
M. Swaminathan, S. Hwang, N. Altunyurt, S. Min, Georgia Institute of Technology, Atlanta, United States

**THPQ-4: Dual Bandpass Ladder-type Filter**  
J. Verdú, O. Menéndez, P. de Paco, E. Corrales, Universitat Autònoma de Barcelona, Cerdanyola del Vallés, Spain

**THPR-4: Reconfigurable-Order Bandpass Filter for Frequency Agile Systems**  
H. H. Sigmarsson, J. Lee, D. Peroulis, W. J. Chappell, Purdue University, West Lafayette, United States

**THPP-5: Design of 60 GHz CMOS Bandpass Filters Using Complementary-Conducting Strip Transmission Lines**  
Y. Hsiao, C. Tseng, National Taiwan University of Science and Technology, Taipei, Taiwan

**THPQ-5: X-Band Microwave Power Divider Based on Bow-Tie Shaped Dielectric Resonator High-Order Modes**  
L. K. Hadyl<sup>1</sup>, A. A. Kishk<sup>2</sup>, D. Kajfez<sup>2</sup>, L. Talbi<sup>1</sup>, <sup>1</sup>Université du Québec en Outaouais, Gatineau (Hull), Canada, <sup>2</sup>The University of Mississippi, University, United States

**THPQ-6: A Novel Integrated Tx-Rx Diplexer for Dual-band WiMAX System**  
D. H. Kim<sup>2</sup>, D. S. Kim<sup>1</sup>, J. I. Ryu<sup>1</sup>, J. C. Kim<sup>1</sup>, J. C. Park<sup>1</sup>, C. D. Park<sup>2</sup>, <sup>1</sup>Korea Electronics Technology Institute, Gyeonggi-do, Republic of Korea, <sup>2</sup>Myongji University, Gyeonggi-do, Republic of Korea

**THPQ-7: High Q SAW Resonator Using upper-electrodes on Grooved-electrodes in LiTaO<sub>3</sub>**  
T. Kimura, M. Kadota, Y. Ida, Murata mfg.,co.ltd., Yasu, Japan



THURSDAY TECHNICAL SESSIONS

15:30-17:10

**TH4A: Microwave High Power Processes: Modeling and Applications**  
 Malgorzata Celuch, *Warsaw University of Technology*  
 Vadim Yakovlev, *Worcester Polytechnic Institute*  
**Room: 205AB**

**TH4B: Ferro-Electric and Acoustic Devised and Components**  
 Clemens Ruppel, *TDK-EPC*  
 Amir Mortazawi, *University of Michigan*  
**Room: 206AB**

**TH4C: Compact reconfigurable filter technology**  
 Doug Jachowski, *Naval Research Laboratory*  
 Sanghoon Shin, *RS Microwave*  
**Room: 207AB**

15:30 - 15:50

**TH4A-1: Microwave Antenna Array for High Temperature Materials Processing**  
 T. Gerdes<sup>1</sup>, H. Park<sup>2</sup>, A. Rosin<sup>3</sup>, A. Schmidt<sup>3</sup>, M. A. Willert-Porada<sup>1</sup>, <sup>1</sup>University of Bayreuth, Bayreuth, Germany, <sup>2</sup>Centre of New Materials, Bayreuth, Germany, <sup>3</sup>InVerTec eV., Bayreuth, Germany

**TH4B-1: Tunable BaxSr1-xTiO3 FBARs Based on SiO2/W Bragg Reflectors**  
 A. Vorobiev<sup>1</sup>, S. Gevorgian<sup>2</sup>, <sup>1</sup>Chalmers University, Gothenburg, Sweden, <sup>2</sup>Ericsson AB, Moelndal, Sweden

**TH4C-1: Tunable, Substrate Integrated, High Q Filter Cascade for High Isolation**  
 E. J. Naglich, J. Lee, D. Peroulis, W. J. Chappell, Purdue University, West Lafayette, United States

15:50 - 16:00

**TH4A-2: A Modeling-Based Technique for Non-destructive Evaluation of Metal Powders Undergoing Microwave Sintering**  
 A. V. Brovko<sup>1</sup>, E. K. Murphy<sup>2</sup>, V. V. Yakovlev<sup>3</sup>, <sup>1</sup>Saratov State Technical University, Saratov, Russian Federation, <sup>2</sup>Rensselaer Polytechnic Institute, Troy, United States, <sup>3</sup>Worcester Polytechnic Institute, Worcester, United States

**TH4B-2: Interdigitated Contour Mode Resonators Based on Barium Titanate Thin Films**  
 V. C. Lee, S. A. Sis, X. A. Zhu, A. Mortazawi, University of Michigan, Ann Arbor, United States

**TH4C-2: Electronically Tunable Diplexer for Frequency-Agile Transceiver Front-End**  
 E. E. Djoumessi, K. Wu, Ecole polytechnique de Montreal, Montreal, Canada

16:00 - 16:10

**TH4C-3: Combine Filter with Tunable Bandwidth and Centre Frequency**  
 A. I. Abunjaileh, I. C. Hunter, Institute of Microwaves and Photonics, Leeds, United Kingdom

16:10 - 16:20

**TH4A-3: Latest Developments in the Microwave Processing of Oil Contaminated Drill Cuttings**  
 S. Kingman, J. Robinson, C. Antonio, I. Pereira, University of Nottingham, Nottingham, United Kingdom

**TH4B-3: Concurrent Enhancement of Q and Power Handling in Multi-Tether High-Order Extensional Resonators**  
 M. Shahmohammadi, B. P. Harrington, R. Abdolvand, Oklahoma State University, Tulsa, United States

**TH4C-4: Compact 2-pole and 4-Pole 2.4-2.8GHz Dual-Mode Tunable Filters**  
 R. Stefanini<sup>1</sup>, M. Chatras<sup>1</sup>, P. Blondy<sup>1</sup>, G. M. Rebeiz<sup>2</sup>, <sup>1</sup>XLIM, Limoges, France, <sup>2</sup>UCSD, La Jolla, United States

16:20 - 16:30

**TH4C-5: Widely Tunable High-Q Filter using Plasma Material**  
 A. Djermoun<sup>2</sup>, G. Prigent<sup>2</sup>, N. Raveu<sup>2</sup>, T. Callegari<sup>1</sup>, <sup>1</sup>INPT, France, France, <sup>2</sup>INPT, France, France, <sup>3</sup>CNRS, France, France

16:30 - 16:40

**TH4A-4: Influence of the magnetron operating frequency on the results of microwave heating**  
 M. Soltysiak<sup>1</sup>, U. Erle<sup>2</sup>, M. Celuch<sup>3</sup>, <sup>1</sup>QWED, Warsaw, Poland, <sup>2</sup>Nestle, Solon, United States, <sup>3</sup>Warsaw University of Technology, Warsaw, Poland

**TH4B-4: Electromagnetic Modeling, Simulation and Design of Balanced Ceramic IF SAW Filters**  
 G. Moreno-Granado<sup>1</sup>, J. E. Kiwitt<sup>2</sup>, F. M. Pitschi<sup>2</sup>, M. Mayer<sup>2</sup>, W. Menzel<sup>1</sup>, <sup>1</sup>University of Ulm, Ulm, Germany, <sup>2</sup>Epcos AG, Munich, Germany

**TH4C-6: Switchable Microstrip Bandpass Filters With Reconfigurable Frequency Responses**  
 W. Tu, National Central University, Taoyuan, Taiwan

16:40 - 16:50

**TH4C-7: BaSrTiO3-Based 30-88MHz Tunable Filter**  
 K. Zhang, T. Watson, A. Cardona, M. Fink, Agile RF, Inc., Santa Barbara, United States

16:50 - 17:10

**TH4A-5: Microwave-induced electromigration in multicomponent metallic alloys**  
 S. Vaucher<sup>1</sup>, L. Bernau<sup>3</sup>, M. Stir<sup>1</sup>, K. Ishizaki<sup>1</sup>, J. Catala-Civera<sup>2</sup>, R. Nicula<sup>1</sup>, <sup>1</sup>Empa- Swiss Federal Laboratories for Materials Testing and Research, Thun, Switzerland, <sup>2</sup>Polytechnic University of Valencia, Valencia, Spain, <sup>3</sup>Empa- Swiss Federal Laboratories for Materials Testing and Research, Thun, Switzerland

**TH4B-5: Small-sized SAW Duplexer on Non-flat SiO2/Al/LiNbO3 Structure for UMTS Band I System**  
 H. Nakamura, H. Nakanishi, T. Tsurunari, J. Fujiwara, Y. Hamaoka, R. Goto, Panasonic Electronic Devices Co., Ltd., Kadoma City, Japan

THURSDAY

TECHNICAL SESSIONS

15:30-17:10

**TH4D: Advances in Doherty Power Amplifier Technology.**

Allen Katz, *TCNJ/Linearizer Technology, Inc.*  
Paul Tasker, *Cardiff University*  
**Room: 207C**

**TH4E: Advances in RFID Circuits and Systems**

Jurgen Heidrich, *University of Erlangen-Nuernberg*  
Robert Weigel, *University of Erlangen-Nuernberg*  
**Room: 207D**

**TH4D-1: A 2.655 GHz 3-stage Doherty Power Amplifier using Envelope Tracking Technique**

I. Kim, B. Kim, Pohang university of Science and Technology (POSTECH), Pohang, Republic of Korea

**TH4E-1: Design of a Low-voltage Reference circuit with reconfigurable Temperature Range for RFID applications**

J. Heidrich<sup>1</sup>, D. Brenk<sup>1</sup>, J. Essel<sup>1</sup>, M. Heinrich<sup>1</sup>, G. Hofer<sup>2</sup>, G. Holweg<sup>2</sup>, G. Fischer<sup>1</sup>, R. Weigel<sup>1</sup>, <sup>1</sup>University of Erlangen-Nuremberg, Erlangen, Germany, <sup>2</sup>Infineon Technologies AG, Graz, Austria

15:30 - 15:40

**TH4E-2: Multiresonator Based Chipless RFID Tag and Dedicated RFID Reader**

S. Preradovic, N. C. Karmakar, Monash University, Melbourne, Australia

15:40 - 15:50

**TH4D-2: Advanced Design of Double Doherty Power Amplifier with a Flat Efficiency Range**

Y. Lee, M. Lee, S. Kam, Y. Jeong, Pohang University of Science and Technology, Pohang, Republic of Korea

**TH4E-3: Parameter Analysis and Reader Architectures for Broadband 13.56 MHz RFID Systems**

M. Gossar<sup>1</sup>, H. Witschnig<sup>2</sup>, H. Enzinger<sup>3</sup>, <sup>1</sup>Graz University of Technology, Graz, Austria, <sup>2</sup>IXP Semiconductors Austria, Gratkorn, Austria, <sup>3</sup>University of Applied Science, Kapfenberg, Austria

15:50 - 16:10

**TH4D-3: A Wide-Band 20W LDMOS Doherty Power Amplifier**

J. H. Qureshi<sup>1</sup>, L. Nan<sup>1</sup>, E. Neo<sup>2</sup>, F. V. Rijs<sup>2</sup>, I. Blednov<sup>2</sup>, L. de Vreede<sup>1</sup>, <sup>1</sup>Tudelft, Delft, Netherlands, <sup>2</sup>IXP, Nijmegen, Netherlands

**TH4E-4: Battery-free RFID-enabled Wireless Sensors**

L. Yang<sup>1</sup>, G. Orecchini<sup>2</sup>, G. Shaker<sup>3</sup>, H. Lee<sup>2</sup>, M. Tentzeris<sup>2</sup>, <sup>1</sup>Texas Instruments, Dallas, United States, <sup>2</sup>Georgia Institute of Technology, Atlanta, United States, <sup>3</sup>University of Waterloo, Waterloo, Canada

16:10 - 16:30

**TH4D-4: Generation 2 High Voltage Heterojunction Bipolar Transistor Technology for High Efficiency Base Station Power Amplifiers**

T. R. Landon, J. Delaney, C. F. Steinbeiser, O. B. Krutko, R. Branson, R. Hajji, P. Page, S. Wey, C. Hall, L. Witkowski, TriQuint Semiconductor, Richardson, United States

**TH4E-5: Low-Cost Assembly of UHF RFID Chips and Flexible Substrate Antennas by Magnetic Coupling Approach**

F. Alimenti<sup>1</sup>, M. Virili<sup>1</sup>, P. Mezzanotte<sup>1</sup>, V. Palazzari<sup>1</sup>, L. Roselli<sup>1</sup>, M. M. Tentzeris<sup>2</sup>, <sup>1</sup>University of Perugia, Perugia, Italy, <sup>2</sup>Georgia Institute of Technology, Atlanta, United States

16:30 - 16:50

**TH4D-5: A Doherty Amplifier for TD-SCDMA Base Station Applications Based on A Single Packaged Dual-path Integrated LDMOS Power Transistor**

G. Wang, L. Zhao, M. Szymanowski, Freescale Semiconductor, Inc., Tempe, United States

**TH4E-6: Active Carrier Compensation for a Multi-Antenna RFID Reader Frontend**

R. Langwieser, G. Lasser, C. Angerer, M. Fischer, A. L. Scholtz, Vienna University of Technology, Vienna, Austria

16:50 - 17:10



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Vesna Radisic

## Microwave Photonics

Bill Jemison, Chair  
Edward Rezek  
Dalma Novak  
Ronald Reano  
Tibor Berceci  
Dieter Jaeger  
Yifei Li  
Young-Kai Chen  
Adil Karim

## Signal Processing Circuits at GHz Speeds

Keh-Chung Wang, Chair  
Agnieszka Konczykowska, Co-Chair  
Edward Gebara  
Hermann Boss  
Andreas Weisshaar  
Koichi Murata  
Johann Luy

## Packaging, Interconnects, MCMs and Integration

Kavita Goverdhanam, Chair  
Eric Strid  
Rudy Emrick  
C-K (Clive) Tzuang  
Bruce Kopp  
Shamsur Mazumder  
Daniela Staiculescu  
Rhonda Franklin

## Instrumentation and Measurement Techniques

Andrea Ferrero, Chair  
Michael Janezic, Co-Chair  
Kate Remley  
John Barr  
Jon Martens  
Nuno Borges Carvalho  
Ken Wong  
Leonard Hayden

## Biological Effects and Medical Applications

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Arye Rosen, Co-Chair  
Guglielmo d'Inzeo  
Claude Weil  
Anand Gopinath  
Natalia Nikolova  
J-C. Chiao

## RF Arrays as Antennas and Power Combiners

Julio Navarro, Chair  
Constantine Balanis, Co-Chair  
Wayne Shiroma  
Ronglin Li  
Chris Rodenbeck  
Jozef Modelski  
Glenn Hopkins  
Zoya Popovic  
Darren Goshi

## Radar and Broadband Communication Systems

Reinhard Knoechel, Chair  
Arne Jacob, Co-Chair  
Ryan Miyamoto  
Mohamed Abouzahra  
Roger Kaul  
Ramesh Gupta  
Gregory Lyons

## Wireless and Cellular Communication Systems

Vijay Nair, Chair  
Shoichi Narahashi, Co-Chair  
Ethan Wang  
Richard Ranson  
Mohamed Megahed  
Kyutae Lim

## Sensors and Sensor Systems

Alan Jenkins, Chair  
George Heiter, Co-Chair  
Ian Gresham  
Lora Schulwitz  
Manos Tentzeris  
Hiroshi Kondoh  
Peter Staecker

## Microwave Processing

Malgorzata Celuch, Chair  
Yoshio Nikawa  
Vadim Yakovlev  
John Osepchuck  
Monika Willert-Porada

## RFID

Luca Roselli, Chair  
Daniel van der Weide  
Marrocco Gaetano  
Alexandros Margomenos  
Apostolos Georgiadis

## IEEE MTT-S Administrative Committee

<b>President</b> Samir El-Ghazaly	<b>President Elect</b> Richard Snyder	<b>Treasurer</b> Nick Koliass	<b>Secretary</b> Mohammad Madihian
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## Elected Adcom Members

### Term Expires in 2010:

Jonathan Hacker	Tim Lee	Amir Mortazawi	Vijay Nair
Barry Perlman	Wayne Shiroma	Richard Snyder	

### Term Expires in 2011:

Madhu Gupta	Joy Laskar	Jenshan Lin	Yoshio Nikawa
Dominique Schreurs	Bela Szendreyi	Ke Wu	

### Term Expires in 2012:

Luciano Boglione	William Chappell	Mark Gouker	Nick Koliass
Shiban Koul	George Ponchak	Robert Weigel	

## Immediate Past Presidents:

<b>2009</b> Barry Perlman	<b>2008</b> Jozef Modelski	<b>2007</b> Steve Kenney
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## Honorary Life Members:

Tatsuo Itoh	Arthur Oliner	Theodore Saad	Peter Staecker	Kiyo Tomiyasu
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## Future IEEE MTT-S International Microwave Symposia Sites

<b>2011: Baltimore, MD</b> Jeff Pond, Chairman Naval Research Laboratory j.m.pond@ieee.org	<b>2012: Montreal, Can</b> Ke Wu, Chairman Ecole Polytechnique Ke.wu@ieee.org	<b>2013: Seattle, WA</b> Tom Raschko Sea-Port Technical Sales Tom.Raschko@ieee.org	<b>2014: Tampa, FL</b> Larry Dunleavy, Chairman University of South Florida Dunleavy@eng.usf.edu
<b>2015: Phoenix, AZ</b> Vijay Nair, Chairman Intel Corporation v.nair@ieee.org	<b>2016: San Francisco, CA</b> Paul Khanna, Chairman Phase Matrix, Inc. apskhanna@ieee.org	<b>2017: Honolulu, HI</b> Kevin Miyashiro, Chairman TeraSys kmiyashi@ieee.org	





# IEEE MTT-S AWARDS

## Microwave Career Award

This award recognizes an individual for a career of meritorious achievement and outstanding technical contribution in the field of microwave theory and techniques. This year's recipient is **Arye Rosen**.

"For a Career of Leadership, Meritorious Achievement, Creativity and Outstanding Contributions in the Field of Microwave Theory and Techniques"

## Distinguished Service Award

This award recognizes significant contributions and outstanding service to the MTT-S and the microwave profession over a sustained period of time. This year's recipient is **Roger Sudbury**.

"For his Outstanding and Dedicated Service to the Society"

## Distinguished Educator Award

This award was inspired by the untimely death of Prof. F.J. Rosenbaum (1937-1992), an outstanding teacher of microwave science and a dedicated AdCom Member and contributor. The award recognizes a distinguished educator in the field of microwave engineering and science who best exemplifies the special human qualities of Fred Rosenbaum who considered teaching a high calling and demonstrated his dedication to the Society through tireless service. This year's recipient is **Gabriel Rebeiz**.

"For Outstanding Achievements as an Educator, Mentor and Role Model of Microwave Engineers and Engineering Students"

## N. Walter Cox Award

This award was established in recognition of the qualities of N. Walter Cox and his service to the MTT-S prior to his untimely death in 1988. It is given to a Society volunteer whose efforts on behalf of MTT-S best exemplify Walter's spirit and dedication. This year's recipient is **Herbert (Mike) Harris**.

"For Exemplary Service, Given in a Spirit of Selfless Dedication and Cooperation"

## Microwave Application Award

This award recognizes an individual or team for outstanding application of microwave theory and techniques. This year's recipients are **Tom Hyltin** and **Britton Vincent**.

## Outstanding Young Engineer Award

This award recognizes MTT-S members, who have distinguished themselves through technical achievements, service to the MTT-S, or a combination of both. Nominees must not have reached their 39th birthday and must be an MTT-S member at the time of nomination. This year's recipients are **Frank Ellinger**, **Telesphor Kamgaing**, **Linus Maurer** and **Fernando Teixeira**.

## IEEE FELLOWS

The member grade of Fellow is conferred in recognition of unusual and outstanding professional distinction. It is awarded at the initiative of the IEEE Board of Directors following a rigorous nomination and evaluation process. Individuals receiving this distinction have demonstrated extraordinary contributions to one or more fields of electrical engineering, or related sciences. The total number of Fellows selected in any one year does not exceed one tenth of one percent of the total voting Institute membership. Fifteen MTT-S members who were evaluated by our Society were elevated to the grade of Fellow, effective 1 January 2010. The new IEEE Fellows are:

Christophe Caloz	for contributions to the development and application of electromagnetic metamaterial structures
Zhizhang Chen	for contributions to time-domain electromagnetic modeling and simulation
Charles Goldsmith	for development of micro-electromechanical capacitive switches
Ganesh Gopalakrishnan	for leadership in microwave photonics and high-speed optical lithium niobate modulator development
Ching-Wen Hsue	for contribution to discrete-time signal processing in microwave engineering
Rhee Jin Koo	for contributions to Gallium Arsenide, Microwave and Millimeter-wave Monolithic Integrated Circuits
Shiban Koul	for contributions to analysis and design of microwave and millimeter wave components and circuits
Richard Lai	for development and space-qualified insertion of millimeter-wave transistor and integrated-circuit technologies
Jenshan Lin	for contributions to integrated microwave circuits and systems for wireless sensors
Imran Mehdi	for contributions to submillimeter-wave device technology
Francisco Mena	for contributions to the analysis and physical understanding of planar structures, anisotropic media, and metamaterials
Ahmadreza Rofougaran	for contributions to single chip system integration of radio frequency complementary metal-oxide semiconductor technology
Emmanouil Tentzeris	for contributions to three dimensional conformal integrated devices for wireless communications and sensing
Charles Weitzel	for contributions to compound semiconductor technology and microwave devices
Ruey-Beei Wu	for contributions to coplanar waveguide passive components
MTT-S members who were evaluated by another IEEE Society are shown below; the other Society is shown in parentheses.	
Shanker Blasubramaniam (AP)	for contributions to time and frequency domain in computational electromagnetics
Jennifer Bernhard (AP)	for development of multifunctional, reconfigurable, and integrated antennas
Jose Encinar Garcinuno (AP)	for contributions to analysis and design of reflectarray antennas
Powen Hsu (AP)	for leadership in electrical engineering education
Douglas Riley (AP)	for contributions to time-domain techniques in computational electromagnetics
Abdel Sebak (AP)	for contributions to electromagnetics scattering, and design and modeling of antennas
Guiseppe Vecchi (AP)	for the application of multi-resolution algorithms to computational electromagnetics
Kiyotoshi Yasumoto (AP)	for contributions to electromagnetic wave scattering and wave guiding
Takamaro Kikkawa (ED)	for contributions to interconnect technologies for integrated circuits
Christopher Holloway (EMC)	for application of new material in the field of electromagnetic compatibility
Maria Sabrina Sarto (EMC)	for contributions to advanced materials in electromagnetic compatibility applications
Motoyuki Sato (GRS)	for contributions to radar remote sensing technologies in environmental and humanitarian applications
Paul Dodd (NPS)	for contributions to the understanding and simulation of single-event effects in microelectronics
Norman Chapman (OE)	for contributions to geoacoustic characterization of ocean bottom environments
Katherine Ferrara (UFFC)	for contributions to ultrasound and its applications in molecular imaging and drug delivery
Pooi Kam (VT)	for contributions to receiver design and performance analysis for wireless communications



# WELCOME TO THE 2010 RFIC SYMPOSIUM

On behalf of the Steering Committee, we would like to welcome you to the RFIC Symposium!

The 2010 RFIC Symposium maintains its reputation as one of the foremost IEEE technical conferences dedicated to the latest innovations in RFIC development for wireless and wireline communication IC's. Running in conjunction with the International Microwave Symposium and Exhibition, the RFIC Symposium adds to the excitement of Microwave Week with three days focused exclusively on RFIC technology and innovation. The RFIC symposium will be held at the Anaheim Convention Center, May 23-25, 2010.

The RFIC Symposium will start on Sunday with half-day and full-day workshops, covering a large breadth of topics. Some of the topics include: SiGe HBTs towards THz operation, power management for integrated RF circuits, challenges and techniques for 3G/4G multi-mode front end designs and silicon-based design techniques for millimeter-wave applications. Don't miss out on this great opportunity to expand your horizons!

Sunday evening activities continue at 5:30pm with RFIC Plenary Session. Two renowned speakers will share their views on the direction and challenges that the RF IC industry will be facing. The first speaker is Professor David Allstot from the University of Washington, and the second speaker is Gregory Waters, Executive Vice President of Skyworks Inc. In addition to the keynote addresses, the best student paper awards are presented in the Plenary Session. The highly anticipated RFIC Reception will follow immediately after the Plenary Session, providing a relaxing time for all to mingle with old friends and catch up on the latest news.

The technical program includes oral sessions, an Interactive Forum (poster session), and two exciting lunch panel sessions. The oral presentation sessions start on Monday, May 24th with four parallel sessions throughout the morning and the afternoon. The oral sessions continue on Tuesday, May 25th synchronized with the IMS technical Program. The Interactive Forum will be held on Tuesday afternoon. This forum is the perfect place to have an opportunity to have more detailed technical discussions with the authors. Panel Sessions are also planned at lunch time on Monday and Tuesday, the topics being respectively "The Challenges, Competitions and Future Prospects of 60 GHz" and "Future of High-Speed I/O: Electrical, Optical or Wireless?".

The RFIC Symposium concludes on Tuesday allowing participants to attend the IMS and ARFTG as well as plenty of time to visit the exhibit hall.

The RFIC organization is thankful to the IMS2010 team, without whom we could not make this conference successful. Most of all, we are particularly thankful to all the technical contributors to the RFIC Symposium. We look forward to your participation. Please continue to make this conference so vibrant within the wireless industry!

We look forward to seeing you in Anaheim!



Yann Deval  
General Chair  
2010 RFIC Symposium



David Ngo  
TPC Chair  
2010 RFIC Symposium

# RFIC PLENARY SESSION

Sunday, May 23, 2010, 17:30-19:00, ACC Room 210 ABCD



## RF Power Amplification: Can CMOS Deliver?

David J. Allstot — Dept. of Electrical Engineering, *Univ. of Washington*

The total energy consumed by cellular telephones in the United States is currently estimated at about 750,000 times the energy used by an average home in one year. Moreover, about 7,500 tons of CO<sub>2</sub> are emitted into the atmosphere.

The RF power amplifier dissipates a large fraction of the total power because of its low efficiency. Despite more than two decades of intensive research, the challenge of on-chip RF PAs with high efficiency in digital-friendly CMOS technologies has not been met.

Switching PA topologies with relatively high efficiency have gained momentum for use in CMOS RF transceivers, and relatively high output power is being delivered using power combining techniques with several PA cells. Supply regulation techniques have enabled higher efficiency when amplifying non-constant envelope modulated signals.

This talk will cite leading-edge designs and on-going research to assess the remaining challenges for CMOS RF power amplifiers.

David J. Allstot received the B.S. from the Univ. of Portland in 1969, the M.S. from Oregon State Univ. in 1974 and the Ph.D. from the Univ. of California, Berkeley in 1979.

He has held several industrial and academic positions and has been the Boeing-Egtvedt Chair Professor of Engineering at the Univ. of Washington since 1999. He was Chair of the Dept. of Electrical Engineering from 2004 to 2007.

Dr. Allstot has advised approximately 100 M.S. and Ph.D. graduates, published about 275 papers, and received several awards for outstanding teaching and graduate advising. Awards include the 1980 IEEE W.R.G. Baker Award, 1995 IEEE Circuits and Systems Society (CASS) Darlington Award, 1998 IEEE International Solid-State Circuits Conference (ISSCC) Beatrice Winner Award, 1999 IEEE CASS Golden Jubilee Medal, 2004 IEEE CASS Technical Achievement Award, 2005 Semiconductor Research Corp. Aristotle Award, and 2008 Semiconductor Industries Assoc. University Research Award. His service includes: 1990-93 Assoc. Editor and 1993-95 Editor of IEEE TCAS II, 1990-93 Member of Technical Program Committee of the IEEE CICC Conference, 1992-95 Member, Board of Governors of IEEE CASS, 1994-2004, Member, Technical Program Committee, IEEE ISSCC, 1995-97, 2001, 2003-04, Member, Executive Committee of IEEE ISSCC, 1996-2000 Short Course Chair of IEEE ISSCC, 2000-2001 Distinguished Lecturer, IEEE CASS, 2001 and 2008 Co-General Chair of IEEE ISCAS, 2006-2007 Distinguished Lecturer, IEEE Solid-State Circuits Society and 2009 President of IEEE CASS.



## The Universal Connector: RF Application Trends over the next decade

Gregory L. Waters — Executive Vice President and General Manager, *Skyworks Solutions Inc.*

RF technology has enjoyed a significant expansion in consumer electronics and everyday appliances over the past two decades. This presentation will outline key new opportunities and requirements for the RF industry to assume a much greater application reach. This talk will outline why RF growth will accelerate in non-traditional markets, and the key technical and commercial problems that must be solved to enable this. We will conclude with examples of how this growth will affect industry R&D practices, and result in a different business model for leading RF firms.

Gregory L. Waters, 49, is executive vice president and general manager, front-end solutions for Skyworks Solutions, Inc. He joined the company in April 2003. Prior to joining Skyworks, he served as senior vice president of Strategy and Business development at Agere Systems, and previously held positions there as Vice president of the Wireless Communications business, and

Vice president of the Broadband Communications business. Prior to this, he held a variety of senior management positions within Texas Instruments, including director of Network Access Products and Director of North American sales.

Waters received a bachelor's of science in engineering from the University of Vermont, and a master's in computer science from Northeastern University.



# RFIC PANEL SESSIONS

Monday May 24<sup>th</sup>, 2010

12:00 – 13:10

Room Number: 210CD

## The Challenges, Competitions and Future Prospect of 60 GHz

### Chair/Moderator:

1. SK Yong, *Samsung Electronics*,
2. Myron Hattig, *Intel Corporation*

### Panelists:

1. Mr. Jason Trachewsky, *Senior Technical Director and Broadcom Fellow, Broadcom Corporation*
2. Dr. Scott Reynolds, *Manager, IBM TJ Watson*
3. Mr. Myron Hattig, *Director of WLAN Standards, Intel Corporation*
4. Mr. Raja Banerjee, *Principal Architect, Marvell Semiconductor, Inc.*
5. Mr. Michiaki Matsuo, *Senior Manager/Chief Engineer, Panasonic Corporation*
6. Dr. Jisung Oh, *Principle Engineer/Director, Samsung Electronics*

### Sponsors: RFIC

### Panel Session Abstract:

The ever growing demand for multi-gigabit data rates to support variety of new applications has pushed to the emergence of 60 GHz radio technology. Significant R&D work in the past decade have demonstrated the viability of wideband 60 GHz CMOS RFIC circuit and transceiver, which were difficult if not impossible to realize in the past, have now become a reality for commercialization. The momentum is further intensified by the heavily harmonized regulations and frequency allocation globally that allow higher EIRP limit and operation of huge unlicensed (i.e. 7 GHz) bandwidth in the 60 GHz band.

As a result, various standards (IEEE 802.11ad and IEEE 802.15.3c) and industry alliances (WirelessHD™ and WiGig Alliance) have emerged to deliver the promise of gigabit wireless solution. Multiple standard solutions could lead to two contradictory effects: On one hand, competition could lead to better 60 GHz products and drives the cost down towards commoditization. On the other hand, competition could create market confusion and co-existence issues among different products if not handled correctly. To date, among the various different standards, only 60 GHz products based on WirelessHD™ solution that supports wireless transmission of full HD contents has reported to hit the high end TV market in Jan 2009. Other 60 GHz products are under rigorous development and in the pipeline for productization. However, the question remains on their timeline in delivering the promise of gigabit experience to the customers.

In addition, Wi-Fi based IEEE 802.11n solution has started to enter the market for audio/video distribution on top of the widespread used of wireless Ethernet. Built strongly upon a broad ecosystem and interoperability among billions of Wi-Fi devices, Wi-Fi centric solution is set to evolve into gigabit data rate range with the recent development in IEEE 802.11ac. This could potentially yet another solution that serves the similar applications and thus creates competition in market place with 60 GHz. However, the distinct characteristics of Wi-Fi (2.4/5 GHz) and 60 GHz provide a different deployment perspective in which both technologies could be complementary rather than competing to each other. Such complementary technology requires multi-band radios that allow fast and seamless session transfer between them whenever the performance of the current radio deteriorates or an enhanced performance could be achieved.

In this panel, industry leaders and experts will discuss the challenges ahead of full scale commercialization of 60 GHz technology including implementation, tug-of-war among competitive standards, co-existence issues and future direction of 60 GHz.



# RFIC PANEL SESSIONS

Tuesday May 25<sup>th</sup>, 2010

12:00 – 13:10

Room Number: 210CD

## Future of High-Speed I/O: Electrical, Optical, or Wireless?

**Chair/ Moderator:** Jacques C. Rudell, *University of Washington*

**Co-Organizer:** Sam Palermo, *Texas A&M*

**Panelists:**

1. Ali Hajimiri, *Caltech*
2. Byunghoo Jung, *Purdue University*
3. Jared Zerbe, *Rambus*
4. Sam Palermo, *Texas A&M*
5. Ronald Ho, *Sun Microsystems*

**Sponsors:** RFIC

**Panel Session Abstract:**

The rising power consumption associated with microprocessors realized in nanometer length silicon processes, has placed a fundamental limit on core clock rates. This has lead to new advanced microprocessor architectures which seek to increase computational power by replicating the number of cores on a single die. Processors currently under development are estimated to use as many as 128 cores integrated on the same IC, leaving the routing of data via high-speed signaling from core-to-core, core-to-cache, or core-to-off-chip memory as a critical aspect of modern microprocessor performance. What is the future of high-speed I/O? Will the future demand for higher data rate I/Os come through incremental advances of all-electrical integrated transceivers, or will a new breed of high-speed I/O come to life in the form of either integrated optical (nanophotonics) transceivers, or perhaps mmWave wireless transceivers. Come hear a panel of experts debate what the future holds for high-speed signaling.



## MONDAY

## TECHNICAL SESSIONS

08:00-11:50

<p><b>RM01A: Cellular Transceivers</b> Room: 208AB Chair: Fazal Ali, <i>Qualcomm</i> Co-Chair: Didier Belot, <i>ST Microelectronics</i></p>	<p><b>RM01B: RF CMOS Modulators &amp; Receivers</b> Room: 209AB Chair: Sayfe Kiaei, <i>Arizona State University, Tempe, Arizona</i> Co-Chair: Noriharu Suematsu, <i>Tohoku University, Japan</i></p>	<p><b>RM01C: Frequency Generation and Synthesis</b> Room: 211AB Chair: Lawrence Kushner, <i>Intersil Co.</i> Co-Chair: Bertan Bakkaloglu, <i>Arizona State University</i></p>	<p><b>RM01D: W-band and Above</b> Room: 212AB Chair: Jenshan Lin, <i>University of Florida</i> Co-Chair: Georg Boeck, <i>Berlin Institute of Technology</i></p>
<p><b>RM01A-1: A 28mW WCDMA/GSM/GPRS/EDGE Transformer-Based Receiver in 45nm CMOS</b> D. L. Griffith, V. Srinivasan, S. Pennisi, V. Rentala, Y. Su, S. Sankaran, I. Elahi, S. Samala, H. Kiper, B. Patel, S. Akhtar, D. Edmondson <i>Texas Instruments</i></p>	<p><b>RM01B-1: A Quadrature Charge-Domain Filter with an Extra In-Band Filtering for RF Receivers</b> Ming-Feng Huang <i>SoC Technology Center, Industrial Technology Research Institute, Taiwan</i></p>	<p><b>RM01C-1: A D-Band PLL Covering the 81-82 GHz, 86-92 GHz and 162-164 GHz Bands</b> S. Shahramian*, A. Hart*, A. C. Carusone*, P. Garcia**, P. Chevalier**, S.P. Voinigescu* *University of Toronto, Canada, **STMicroelectronics, France</p>	<p><b>8:00-00 AM: RM01D-1: Transmitter Chipset for 24/77-GHz Automotive Radar Sensors</b> V. Giammello, E. Ragonese, G. Palmisano <i>Università di Catania, Facoltà di Ingegneria, DIEES, Catania, Italy</i></p>
<p><b>RM01A-2: An EDGE Transmitter with Mitigation of Oscillator Pulling</b> I. Bashir, R. B. Staszewski, O. Eliezer, K. Waheed, V. Zocias, N. Tal, J. Mehta, P. T. Balsara, B. Banerjee <i>University of Texas at Dallas, Texas Instruments Inc., USA, Delft University of Technology, Netherlands</i></p>	<p><b>RM01B-2: A Low-Power Receiver Down-Converter with High Dynamic Range Performance</b> D. Ghosh, R. Gharpurey <i>University of Texas, Austin, USA</i></p>	<p><b>RM01C-2: An Integrated Frequency Synthesizer for 81-86GHz Satellite Communications in 65nm CMOS</b> Zhiwei Xu, Qun Jane Gu, Yi-Cheng Wu, Heng-Yu Jian, Frank Wang, Mau-Chung Frank Chang <i>University of California, Los Angeles, CA 90095, USA</i></p>	<p><b>RM01D-2: A 94-GHz Passive Imaging Receiver using a Balanced LNA with Embedded Dicke Switch</b> L. Gilreath, V. Jain*, H.C. Yao, L. Zheng, and P. Heydari <i>University of California, Irvine, *SaberTek, Irvine CA</i></p>
<p><b>RM01A-3: An All-Digital Offset PLL Architecture</b> R. B. Staszewski, S. Vemulapalli* <i>Texas Instruments, *Delft University of Technology</i></p>	<p><b>RM01B-3: A Multiphase PWM RF Modulator Using a VCO-Based Opamp in 45nm CMOS</b> M. Park, M. H. Perrott* <i>Massachusetts Institute of Technology (now at Maxim Integrated Products), *SiTime Corporation</i></p>	<p><b>8:40-00 AM: RM01C-3: Low-Noise Fractional-N PLL Design with Mixed-Mode Triple-Input LC VCO in 65nm CMOS</b> Yuanfen Sun*, Xueyi Yu*, Woogeun Rhee*, Sangsoo Ko**, Wooseung Choo**, Byeong-Ha Park**, and Zhihua Wang* *Tsinghua University, Beijing, China, **MSC Development Team, Samsung Electronics, Yongin-City, Gyeonggi-Do, Korea</p>	<p><b>RM01D-3: 3.94 GHz silicon co-integrated LNA and antenna in a mm-wave dedicated BiCMOS technology</b> R. Pilard (1,2), D. Gloria (1), F. Giancesello (1), F. Le Pennec (2), C. Person (2) (1) STMicroelectronics, (2) Lab-STICC/MOM, FRANCE</p>
<p><b>RM01A-4: An Interstage Filter-Free Mobile Radio Receiver with Integrated TX Leakage Filtering</b> R. Vazny, W. Schelmbauer, H. Pretz, S. Herzinger*, R. Weigel** <i>Danube Integrated Circuit Engineering GmbH, Austria, *Infineon Technologies AG, Germany, **Institute for Electronics Engineering Friedrich-Alexander-University Erlangen-Nuremberg, Germany</i></p>	<p><b>RM01B-4: Spurious Noise Reduction by Modulating Switching Frequency in DC-to-DC Converter for RF Power Amplifier</b> E. J. Kim, C. Cho*, W. Kim*, C.-H. Lee*, J. Laskar <i>Georgia Institute of Technology at Atlanta, *Samsung Design Center at Atlanta</i></p>	<p><b>RM01C-4: A Wideband Millimeter-Wave Frequency Doubler-Tripler in 0.13-<math>\mu</math>m CMOS</b> S. Saberi Ghouchani, J. Paramesh <i>Carnegie Mellon University</i></p>	<p><b>RM01D-4: A 3 G-Bit/s W-Band SiGe ASK Receiver with a High-Efficiency On-Chip Electromagnetically-Coupled Antenna</b> Jason W. May, Ramadan A. Alhalabi, Gabriel M. Rebeiz <i>University of California at San Diego</i></p>
<p><b>RM01A-5: A SAW-less CMOS TX for EGPRS and WCDMA</b> K. Hausmann, J. Ganger, M. Kirschenmann, G. B. Norris, W. Shepherd, V. Bhan., and D. B. Schwartz. <i>Fujitsu Microelectronics of America</i></p>	<p><b>RM01B-5: A Rail-To-Rail Input Receiver Employing Successive Regeneration and Adaptive Cancellation of Intermodulation Products</b> Edward A. Keehr, Ali Hajimiri <i>California Institute of Technology</i></p>	<p><b>RM01C-5: 200GHz CMOS Prescalers with Extended Dividing Range via Time-Interleaved Dual Injection Locking</b> Qun Jane Gu*, Heng-Yu Jian*, Zhiwei Xu*, Yi-Cheng Wu*, Mau-Chung Frank Chang*, Yves Baeyens** and Young-Kai Chen** *University of California, Los Angeles, CA, USA, **Alcatel-Lucent/Bell-Labs, Murray Hills, NJ, USA</p>	<p><b>RM01D-5: A 325 GHz Frequency Multiplier Chain in a SiGe HBT Technology</b> E. Öjefors, B. Heinemann*, U. R. Pfeiffer <i>University of Wuppertal, *HPH GmbH, Germany</i></p>
<p><b>RM02A: RFID Circuits</b> Room: 208AB Chair: Glenn Chang, <i>MaxLinear</i> Co-Chair: Natalino Camilleri, <i>Alien Technology</i></p>	<p><b>RM02B: Wideband LNAs</b> Room: 209AB Chair: Jean-Baptiste Begueret, <i>IMS Lab, University of Bordeaux, France</i> Co-Chair: Danilo Manstretta, <i>University of Pavia, Italy</i></p>	<p><b>RM02C: Millimeter-Wave VCOs</b> Room: 211AB Chair: Jing-Hong Chen, <i>Analog Devices</i> Co-Chair: Tian-Wei Huang, <i>National Taiwan University</i></p>	<p><b>RM02D: Reconfigurable PA Concepts</b> Room: 212AB Chair: Joseph Staudinger, <i>Freescale</i> Co-Chair: Jyoti P. Mondal, <i>Northrop Grumman</i></p>
<p><b>RM02A-1: Semi-Active High-Efficient CMOS Rectifier for Wireless Power Transmission</b> S. T. Kim, T. Song, J. Choi, F. Bien*, K. Lim, J. Laskar <i>Georgia Institute of Technology, *Ulsan National Institute of Science and Technology</i></p>	<p><b>RM02B-1: A 2-1100 MHz Wideband Low Noise Amplifier with 1.43 dB minimum Noise Figure</b> M. El-Nozahi, A. A. Helmy, E. Sanchez-Sinencio, K. Entesari <i>Department of Electrical and Computer Engineering, Texas A&amp;M University, College station, TX, 77843</i></p>	<p><b>RM02C-1: A mm-Wave Arbitrary 2<sup>N</sup> Band Oscillator Based on Even-Odd Mode Technique</b> A. H.T. Yu, S.-W. Tam, D. Murphy, T. Itoh, F. Chang <i>University of California at Los Angeles</i></p>	<p><b>RM02D-1: Multi-Mode WCDMA Power Amplifier Module with Improved Low-Power Efficiency using Stage-Bypass</b> G. Hau, M. Singh <i>ANADIGICS, Inc., USA.</i></p>
<p><b>RM02A-2: A Single-Chip CMOS UHF RFID Reader Transceiver</b> Runxi Zhang, Chunqi Shi, Yihao Chen, Wei He, Ping Xu, Shuai Xu and Zongshen Lai <i>Dept. of Electronic Engineering, Suzhou Vocational University, IMCS, East China Normal University, Shanghai, China</i></p>	<p><b>RM02B-2: An 0.045mm<sup>2</sup> 0.1-6GHz reconfigurable multi-band, multi-gain LNA for SDR</b> A. Geis**, Y. Rolain*, G. Vandersteen*, J. Craninckx** *Vrije Universiteit Brussel, Belgium, **IMEC, Belgium</p>	<p><b>RM02C-2: A 24-GHz and 60-GHz Dual-Band Standing-Wave VCO in 0.13<math>\mu</math>m CMOS</b> L. Wu*, A. W. L. Ng*, L. L. K. Leung** and H. C. Luong* *Hong Kong University of Science and Technology, Clear Water Bay, Hong Kong, **Qualcomm, San Diego, USA</p>	<p><b>RM02D-2: A 3.4 GHz to 4.3 GHz Frequency-Reconfigurable Class E Power Amplifier with an Integrated CMOS-MEMS LC Balun</b> L. Wang, T. Mukherjee <i>Department of ECE, Carnegie Mellon University, Pittsburgh, PA, 15213</i></p>
<p><b>RM02A-3: Near Zero Turn-on Voltage High-Efficiency UHF RFID Rectifier in Silicon-on-Sapphire CMOS</b> P. T. Theilmann, C. D. Presti, *D. Kelly, P. M. Asbeck <i>University of California at San Diego, *Peregrine Semiconductor Corp., USA</i></p>	<p><b>RM02B-3: A Linearity-Enhanced Wideband Low-Noise Amplifier</b> K. Choi, T. Mukherjee*, J. Paramesh* <i>Samsung Electronics, *Carnegie Mellon University</i></p>	<p><b>RM02C-3: Multi-band Local Oscillator Generation for Direct up/down Conversion Transceiver Architectures Supporting WiFi and WiMax Standards</b> Ram Sadhwani, Assaf Ben Bassat, Adil A. Kidwai, Shahar Rivet*, Jonathan C. Jensen <i>Intel Corporation, Hillsboro, OR, *Intel Corporation, Petah Tikva, Israel</i></p>	<p><b>RM02D-3: A Q-band 6W MMIC Power Amplifier with 3-way Power Combination Circuit</b> Hiroshi Otsuka, Kazuhisa Yamauchi, Koji Yamanaka, Shin Chaki., Kazuhiko Nakahara, Kunihito Endo, Akira Inoue and Yoshihito Hirano <i>Mitsubishi Electric Corp., Japan</i></p>
<p><b>RM02A-4: A Low Power Low Cost Fully Integrated UHF RFID Reader with 17.6dBm Output 1dB in 0.18 <math>\mu</math>m CMOS Process</b> J.C. Wang, C. Zhang, Z.H. Wang <i>Institute of Microelectronics, Tsinghua University</i></p>	<p><b>RM02B-4: Power Efficient Distributed Low-Noise Amplifier in 90 nm CMOS</b> B. Machiels, P. Reynaert, M. Steyaert <i>ESAT-MICAS</i></p>	<p><b>RM02C-4: A 0.13-<math>\mu</math>m CMOS Local Oscillator for 60-GHz Applications Based on Push-Push Characteristic of Capacitive Degeneration</b> Tino Copani, Hyungseok Kim, Bertan Bakkaloglu, Sayfe Kiaei <i>Electrical, Energy and Computer Engineering, Arizona State University, Tempe, AZ, 85287, USA</i></p>	<p><b>RM02D-4: A Multi-Band Reconfigurable Power Amplifier for UMTS Handset Applications</b> U. Kim, K. Kim, J. Kim*, and Y. Kwon <i>Seoul National University, *Hanyang University, Korea</i></p>
<p><b>RM02A-5: Far-field RF Powering System for RFID and Implantable Devices with Monolithically Integrated On-Chip Antenna</b> Sohel Radiomi, Majid Baghaei-Nejad*, Guy Vandenbosch, Li-Rong Zheng*, Georges Gielen <i>MICAS-ESAT, Katholieke Universiteit Leuven Belgium, *Royal Institute of Technology Stockholm Sweden</i></p>	<p><b>RM02B-5: A Wide-Band RF Front-End with Linear Active Notch Filter for Mobile TV Applications</b> Seung Hwan Jung, Kang Hyuk Lee, Young Jae Lee*, Hyun Kyu Yu* Yun Seong Eo <i>University of Kwangjuwon in Seoul Korea, *Electronic and Telecommunications Research Institute in Daejeon Korea</i></p>	<p><b>RM02C-5: A Switched-Capacitor mm-Wave VCO in 65 nm Digital CMOS</b> M. Nariman, F. De Flaviis <i>University of California at Irvine, Broadcom Corporation, USA</i></p>	<p><b>RM02D-5: High-efficiency Reconfigurable RF transmitter for Wireless Sensor Network Applications</b> F. Carrara and G. Palmisano <i>University of Catania - DIEES, Italy</i></p>

## MONDAY

## TECHNICAL SESSIONS

13:20-17:10

<p><b>RM03A: CMOS Wideband Transceiver ICs</b> Room: 208AB Chair: Domine Leenaerts, <i>NXP Semiconductor</i> Co-Chair: Haolu Xie, <i>Fujitsu Microelectronics</i></p>	<p><b>RM03B: Advanced Characterization of mm-Wave Components</b> Room: 209AB Chair: Kevin McCarthy, <i>University of College Cork</i> Co-Chair: Herbert Zirath, <i>Chalmers University of Technology</i></p>	<p><b>RM03C: Advanced Device Technologies &amp; Design Techniques</b> Room: 211AB Chair: Aditya Gupta, <i>Northrup Grumman</i> Co-Chair: Eli Reese, <i>TriQuint Semiconductor</i></p>	<p><b>RM03D: Switch &amp; Switch-mode Technologies</b> Room: 212AB Chair: Nick Cheng, <i>Skyworks Solutions</i> Co-Chair: Youngwoo Kwon, <i>Seoul National University</i></p>	13:20 - 13:40
<p><b>RM03A-1: A Tri-band 65nm CMOS Tuner for ATSC Mobile DTV SoC</b> Sanghoon Kang, Huijung Kim, Jeong-Hyun Choi, Jae-Hong Chang, Jong-Dae Bae, Wooseung Cho, Byeong-ha Park <i>Samsung Electronics System LSI/MS team, Korea</i></p>	<p><b>RM03B-1: The "Load-Thru" (LT) De-embedding Technique for the Measurements of mm-Wave Balanced 4-Port Devices</b> Z. Deng, A. M. Niknejad <i>Berkeley Wireless Research Center</i></p>	<p><b>RM03C-1: Integration of multi-standard Front End Modules SOCs on High Resistivity SOI RF CMOS Technology</b> F. Gianesello*, S. Boret*, B. Martineau*, C. Durand*, R. Pilard*, D. Gloria*, B. Rauber* and C. Raynaud** <i>*STMicroelectronics, TR&amp;D, STD, Crolles, France, **CEA Leti, Grenoble, France</i></p>	<p><b>RM03D-1: High Efficiency and Wideband Envelope Tracking Power Amplifier with Sweet Spot Tracking</b> D. Kim, J. Choi, D. Kang, B. Kim <i>University of Science and Technology, Korea</i></p>	13:40 - 14:00
<p><b>RM03A-2: A Multi-standard Multi-band Tuner for Mobile TV SoC with GSM Interoperability</b> H. Kim, S. Kang, J. Chang, J. Choi, H. Chung, J. Heo, J. Bae, W. Choo, and B. Park <i>Samsung Electronics Co. Ltd.</i></p>	<p><b>RM03B-2: RF-pad, Transmission Lines and Balun Optimization for 60GHz 65nm CMOS Power Amplifier</b> S. Aloui, E. Kerherve, R. Plana*, D. Belot** <i>Universite de Bordeaux 1, IMS Laboratory, 351 Cours de la Liberation, Talence, France, *LAAS-CNRS, 7 avenue du fonel Roche, Toulouse, France, **STMicroelectronics, Central R&amp;D - Colles, France.</i></p>	<p><b>RM03C-2: Low-Parasitic Ultra-Low-Triggering ULTDCSR ESD Protection for RF ICs in CMOS</b> Jian Liu, Lin Lin, Xin Wang, Hui Zhao, He Tang, Qiang Fang, Albert Wang, Hongyi Chen, Haolu Xie, Siqiang Fan and Gary Zhang <i>Dept. of Electrical Engineering, University of California, Riverside, CA</i></p>	<p><b>RM03D-2: A 150MHz, 84% efficiency, Two Phase Interleaved DC-DC Converter in AlGaAs/GaAs P-HEMT Technology for Integrated Power Amplifier M</b> H. Peng, V. Pala, T. P. Chow, and M. Hella <i>Rensselaer Polytechnic Institute, ECSE Department</i></p>	13:40 - 14:00
<p><b>RM03A-3: A 2.2 mW Regenerative FM-UWB Receiver in 65 nm CMOS</b> N. Saputra, J. R. Long, and J. J. Pekarik* <i>Delft University of Technology, the Netherlands, *IBM Microelectronics, USA</i></p>	<p><b>RM03B-3: 200GHz ft SiGe HBT Load Pull Characterization at mm-Wave Frequencies</b> Luciano Bognione, Richard T. Webster* <i>University of Massachusetts, Lowell, *Air Force Research Laboratories, Hanscom AFB, MA</i></p>	<p><b>RM03C-3: A Cost-Competitive High Performance Junction-FET (JFET) in CMOS Process for RF Front-End-Module Applications</b> Y. Shi, R. M. Rassel, R. A. Phelps, P. Candra, D. B. Hershberger, X. Tian, S. L. Sweeney, J. Rascoe, B. Rainey, J. Dunn, and D. Haramme <i>IBM Microelectronics, Essex Junction, Vermont, USA</i></p>	<p><b>RM03D-3: A 0dBm 10Mbps 2.4GHz Ultra-Low Power ASK/OOK Transmitter with Digital Pulse-Shaping</b> Xionghuan Huang, Pieter Harpe, Xiaoyan Wang, Guido Dolmans, Harmke de Groot <i>Holst Centre - IMEC, Eindhoven, The Netherlands</i></p>	14:00 - 14:20
<p><b>RM03A-4: A 75 pJ/bit All-Digital Quadrature Coherent IR-UWB Transceiver in 0.18 <math>\mu</math>m CMOS</b> D. Gómez, D. Mateo, J.L. González <i>Universitat Politècnica Catalunya, SPAIN</i></p>	<p><b>RM03B-4: A Miniature 26-/77-GHz Dual-band Branch-line Coupler Using Standard 0.18-<math>\mu</math>m CMOS Technology</b> Y.S. Lin*, C. Y. Hsu*, H. R. Chuang*, C. Y. Chen** <i>*National Cheng Kung University, Tainan, Taiwan, R.O.C, **National University of Tainan, Tainan, Taiwan, R.O.C.</i></p>	<p><b>RM03C-4: Reconfiguration of Bulk Acoustic Wave Filters Using CMOS Transistors: Concept, Design and Implementation</b> M. El Hassan, E. Kerherve*, Y. Deval*, J.B. David**, D. Belot*** <i>University of Balamand - Alkoura Lebanon, *IMS Laboratory - UMR 5218 CNRS - ENSEIRB - University of Bordeaux, **CEA-Leti - Minatex - Grenoble, ***STMicroelectronics Crolles.</i></p>	<p><b>RM03D-4: A Linear-in-dB SiGe HBT Wideband High Dynamic Range RF Envelope Detector</b> Hsuan-yu Marcus Pan and Lawrence E. Larson <i>University of California, San Diego, 9500 Gilman Drive, La Jolla, CA, 92093, USA</i></p>	14:20 - 14:40
<p><b>RM03A-5: A 90nm-CMOS, 500Mbps, Fully-Integrated IR-UWB Transceiver Using Pulse Injection-Locking for Receiver Phase Synchronization</b> C.H.Hu, P.Y. Chiang, K.M.Hu, R. Khanna*, J. Nejedlo* <i>Oregon State University, *Intel</i></p>	<p><b>RM03B-5: Compact Transformer Power Combiners for Millimeter-wave Wireless Applications</b> Y. Zhao, J.R. Long, M. Spirito <i>Delft University of Technology, The Netherlands</i></p>	<p><b>RM03C-5: A Layout Efficient, Vertically Stacked, Resonator-Coupled Bandpass Filter in LTCC for 60 GHz SOP Transceivers</b> R. E. Amaya <i>Communications Research Centre</i></p>	<p><b>RM03D-4: Cellular Antenna Switches for Multimode Applications Based on a Silicon-on-Insulator Technology</b> A. Tombak, C. Iversen*, J.-B. Pierres**, D. Kerr, M. Carroll, P. Mason, E. Spears and T. Gillenwater <i>RFMD Inc., USA, **RFMD Denmark Design Center, DENMARK, **RFMD Toulouse Design Center, FRANCE</i></p>	14:40 - 15:00
<p><b>RM04A: Ultra Low Power Receivers and Transmitters</b> Room: 208AB Chair: Julian Tham, <i>Arda Technologies</i> Co-Chair: Bill Redman-White, <i>NXP</i></p>	<p><b>RM04B: Optimized Design Techniques for RF Front-end Building Blocks</b> Room: 209AB Chair: Osama Shana'a, <i>Mediatek Corp.</i> Co-Chair: Ali Afshahi, <i>Broadcom</i></p>	<p><b>RM04C: Temperature Compensated Oscillators</b> Room: 211AB Chair: Timothy Hancock, <i>MIT Lincoln Laboratory</i> Co-Chair: Donald Y.C. Lie, <i>Texas Tech University</i></p>	<p><b>RM04D: Silicon Millimeter-Wave Amplifiers</b> Room: 212AB Chair: Kevin Kobayashi, <i>RF Micro Devices</i> Co-Chair: Paul Blount, <i>Custom MMIC Design</i></p>	
<p><b>RM04A-1: A 120<math>\mu</math>W Fully-Integrated BPSK Receiver in 90nm CMOS</b> H. Yan, J. G. Macias-Montero, A. Akhnouk, L. C. N. de Vreede, J. R. Long, J. J. Pekarik*, J. N. Burghartz <i>ERL/DIMES, Delft University of Technology, Netherlands, *IBM Microelectronics, Essex Junction VT, USA</i></p>	<p><b>RM04B-1: A Differential 4-Path Highly Linear Widely Tunable On-Chip Band-Pass Filter</b> A. Ghaiffari, E.A.M. Klumperink, B. Nauta <i>University of Twente, CTIT Institute, IC Design group, Enschede, The Netherlands</i></p>	<p><b>RM04C-1: A 65nm CMOS DCXO System for Generating 38.4MHz and a Real Time Clock from a Single Crystal in 0.09mm<sup>2</sup></b> D. L. Griffith, F. Dulger, G. S. Feygin, A. N. Mohieldin, P. Vallur <i>Texas Instruments</i></p>	<p><b>RM04D-1: A 60GHz Transformer Coupled Amplifier in 65 nm Digital CMOS</b> Michael Boers <i>Broadcom Corp., Irvine, CA, 92617, USA</i></p>	15:30 - 15:50
<p><b>RM04A-2: A Fully Integrated 2.4-GHz CMOS Diversity Receiver with a Novel Antenna Selection</b> Yong-Il Kwon*, Sang-Ku Park*, T.J.Park*, and Hai-Young Lee** <i>*UC solution team, SAMSUNG Electro-Mechanics, Suwon, 443-743, Korea, **Department of Electronics Engineering, Ajou University, Suwon, 443-749, Korea</i></p>	<p><b>RM04B-2: A CMOS Wide-Bandwidth High-Power Linear-in-dB Variable Attenuator Using Body Voltage Distribution Method</b> Yan-Yu Huang, Wangmyong Woo, Chang-Ho Lee, Joy Laskar <i>Georgia Electronic Design Center, Georgia Institute of Technology, Samsung Design Center, USA</i></p>	<p><b>RM04C-2: A 50ppm 600MHz Frequency Reference Utilizing the Series Resonance of an FBAR</b> Julie Hu, Lori Callaghan*, Richard Ruby*, Brian Otis <i>University of Washington, *Avago Technologies, Inc.</i></p>	<p><b>RM04D-2: A Stage-Scaled Distributed Power Amplifier Achieving 110GHz Bandwidth and 17.5dBm Peak Output Power</b> J. Chen, A. M. Niknejad <i>University of California at Berkeley</i></p>	15:50 - 16:10
<p><b>RM04A-3: A 90<math>\mu</math>W MICS/ISM Band Transmitter with 22% Global Efficiency</b> J. Pandey, B. Otis <i>University of Washington, Seattle, WA, USA</i></p>	<p><b>RM04B-3: A 17 GHz Transformer-neutralized Current Re-use LNA and Its Application to a Low-power RF Front-end</b> S. Kundu, J. Parameesh <i>Carnegie Mellon University, USA</i></p>	<p><b>RM04C-3: An Electronically Temperature-Compensated 427MHz Low Phase-Noise AlN-on-Si Micromechanical Reference Oscillator</b> H. M. Lavasani, W. Pan, F. Ayazi <i>Georgia Institute of Technology</i></p>	<p><b>RM04D-3: DC Hot Carrier Stress Effect on CMOS 65nm 60 GHz Power Amplifiers</b> T. Quémerais***, L. Moquillon**, V. Huard**, J.-M. Fournier*, P. Benech*, N. Corrao* <i>*IMEP-LHAC, UMR INPG/UFV/US/CNRS, 3 parvis Louis Néel, BP 257, 38016 Grenoble Cedex, France, **STMicroelectronics, 850 rue Jean Monnet 38920 Crolles, France</i></p>	16:10 - 16:30
<p><b>RM04A-4: A 2mW CMOS MICS-Band BFSK Transceiver with Reconfigurable Antenna Interface</b> S. Min, S. Shashidharan, M. Stevens, T. Copani, S. Kiaei, B. Bakklaglou, S. Chakraborty* <i>Arizona State University, *Texas Instruments, USA</i></p>	<p><b>RM04B-4: A Self-Healing 2.4GHz LNA with On-Chip S11/S21 Measurement/Calibration for In-Situ PVT Compensation</b> Karthik Jayaraman, Qadeer Khan, *Baoyong Chi, William Beattie*, Zhuhua Wang, and Patrick Chiang <i>School Of Electrical Engineering and Computer Science, Oregon State University, Corvallis, OR, USA, *Institute of Microelectronics, Tsinghua University, China</i></p>	<p><b>RM04C-4: A Wide Tuning 1.3 GHz LC VCO with Fast Settling Noise Filtering Voltage Regulator in 0.18 <math>\mu</math>m CMOS Process</b> Hiroshi Akima, Aleksander Dec, and Ken Suyama <i>Epoch Microelectronics, Inc., Tarrytown, NY, USA</i></p>	<p><b>RM04D-4: A Layout-Based Optimal Neutralization Technique for mm-Wave Differential Amplifiers</b> Z. Deng, A. M. Niknejad <i>Berkeley Wireless Research Center</i></p>	16:30 - 16:50
<p><b>RM04A-5: A 1.8 to 2.4-GHz 20mW Digital-Intensive RF Sampling Receiver with a Noise-Canceling Bandpass Low-Noise Amplifier in 90nm CMOS</b> Joonhee Lee, Jaewook Kim and Seonghwan Cho <i>Department of Electrical Engineering, KAIST, Daejeon, Republic of Korea</i></p>	<p><b>RM04B-5: A Low Power LNA using Miniature 3D Inductor without Area Penalty of Passive Components</b> Akira Tanabe, Ken'ichiro Hijioka, Hirokazu Nagase, Yoshihiro Hayashi <i>NEC Electronics Corporation</i></p>	<p><b>RM04C-5: A Wide-Range VCO with Optimum Temperature Adaptive Tuning</b> Behzad Saeidi*, Joshua Cho** <i>*Marvell Semiconductor, Aliso Viejo, CA 92656; **Skyworks Solutions, Inc, Irvine, CA 92618</i></p>	<p><b>RM04D-5: A 100 GHz Transformer-Coupled Fully Differential Amplifier in 90 nm CMOS</b> N. Deferm, P. Reynaert <i>K. U. Leuven, ESAT/MICAS, Heverlee, Belgium</i></p>	16:50 - 17:10





## TUESDAY

## TECHNICAL SESSIONS

08:00-11:50

**RTU1B: CMOS Millimeter-Wave 60/24 GHz Radio****Room: 207AB**Chair: Frank Henkel, *IMST GmbH, Kamp-Lintfort, Germany*  
Co-Chair: Mark Ruberto, *Intel Corp.***RTU1C: CMOS PAs****Room: 211AB**Chair: Eddie Spears, *RFMD*  
Co-Chair: Freek van Straten, *NXP Semiconductors***RTU1D: Emerging Architectures in Digital Frequency Synthesis****Room: 212AB**Chair: Stefano Pellerano, *Intel Corporation*  
Co-Chair: Sanjay Raman, *Virginia Tech*

08:00-08:20

**RTU1B-1:A 68-82 GHz integrated wideband linear receiver using 0.18  $\mu$ m SiGe BiCMOS Technology**

A. Y.-K. Chen\*\*, Y. Baeyens\*, Y.-K. Chen\*, and J. Lin\*\*

\*Alcatel-Lucent/Bell Laboratories, 600 Mountain Ave. Murray Hill, NJ 07974 USA, \*\*Department of ECE, University of Florida, Gainesville, FL 32611 USA

**RTU1C-1:A Discrete Resizing and Concurrent Power Combining Structure for Linear CMOS Power Amplifier**

J. Kim\*, H. Kim\*, Y. Yoon\*, K. H. An\*, W. Kim\*, C.-H. Lee\*\*, K. T. Komegay\*, and J. Laskar\*

Georgia Electronic Design Center, Georgia Institute of Technology, Atlanta, GA 30308, USA\*, Samsung Design Center, Atlanta, GA 30308, USA\*\*

**RTU1D-1:A 700uA, 405MHz Fractional-N All Digital Frequency-Locked Loop for MICS Band Applications**

S. Shashidharan, W. Khalil\*, S. Chakraborty\*\*, S. Kiaei, T. Copani and B. Bakkaloglu

Arizona State University, Tempe, AZ., \*\*Ohio State University, Columbus, OH., \*\*\*Texas Instruments Inc., Dallas, TX, USA

08:20-08:40

**RTU1B-2:A 24-GHz Low-Power Fully Integrated Receiver with Image-Rejection using Rich-Transformer Direct-Stacked/Coupled Technique**N. Shiramizu, T. Nakamura, T. Masuda, K. Washio  
*Hitachi, Ltd.***RTU1C-2:A Single-Chip 2.4GHz Double Cascode Power Amplifier under Multiple Supply Voltages in 65nm CMOS for WLAN Application**Mingyuan Li, Ali Afsahi, Arya Behzad  
*Broadcom Corporation, San Diego***RTU1D-2:A 2-MHz Bandwidth  $\Delta$ - $\Sigma$  Fractional-N Synthesizer Based On a Frequency Divider with Digital Spur Suppression**

P.-E. Su and S. Pamarti

Department of Electrical Engineering, University of California at Los Angeles, U.S.A.

08:40-09:00

**RTU1B-3:A 60 GHz CMOS Receiver Front-End with Integrated 180-degree Out-of-Phase Wilkinson Power Divider**

C. C. Chen, J. H. Lee, Y. S. Lin

*National Chi Nan University, Taiwan***RTU1C-3:A 31-dBm, High Ruggedness Power Amplifier in 65-nm Standard CMOS with High-Efficiency Stacked-Cascode Stages**

S. Leuschner\*, S. Pinarello\*\*,\*\*\*, U. Hodel\*\*\*, J.-E. Mueller\*\*\*, H. Klar\*

\*Technical University of Berlin, \*\*Friedrich-Alexander-Universitaet Erlangen-Nuernberg, \*\*\*Infineon Technologies AG

**RTU1D-3: A 6fJ/step, 5.5ps Time-to-Digital Converter for a Digital PLL in 40nm Digital LP CMOS**

J. Borremans, K. Vengattaraman\*, J. Craninckx

*IMEC, Leuven, Belgium, \*KUL, Leuven, Belgium*

09:00-09:20

**RTU1B-4:Coherent Parametric RF Downconversion in CMOS**

Z.Zhao, J.F. Boudquet\*, S. Magierowski\*\*

*University of Calgary, Canada***RTU1C-4:Analysis and Design of a Wideband High Efficiency CMOS Outphasing Amplifier**

M.C.A. van Schie, M.P. van der Heijden\*, M. Acar\*, A.J.M. de Grauw\*, L.C.N. de Vreede

*Delft University of Technology, \*NXP Semiconductors, The Netherlands***RTU1D-4:A 6GHz Direct Digital Synthesizer MMIC with Nonlinear DAC and Wave Correction ROM**

D. Y. Wu, G. P. Chen, J. W. Chen, X. Y. Liu, L. X. Zhao, Z. Jin

*Institute of Microelectronics of Chinese Academy of Sciences, China*

09:20-09:40

**RTU1B-5:60 GHz Broadband Image Rejection Receiver using Varactor Tuning**

J. Kim, W. Choi, Y. Park, and Y. Kwon

*Seoul National University, Korea***RTU1C-5:A Highly Efficient 5.8 GHz CMOS Transmitter IC with Robustness over PVT Variations**

Eun-Hee Kim, Jeong-Ki Choi\*, Seok-Oh Yun\*, Jinho Ko\*, Kwiro Lee

*Korea Advanced Institute of Science and Technology, \*PHYCHIPS Inc.***RTU1D-5:A 10GHz 8-bit Direct Digital Synthesizer Implemented in GaAs HBT Technology**

G. P. Chen, D. Y. Wu, Z. Jin, X. Y. Liu

*Institute of Microelectronics, Chinese Academy of Sciences, Beijing, China*

TUESDAY

TECHNICAL SESSIONS

13:20-17:10

**RTU2A: WLAN Transceivers and Components****Room: 207AB**Chair: Albert Jerng, *Ralink Technology*Co-Chair: Srenik Mehta, *Atheros Communications***RTU2A-1: Dual-Band CMOS Transceiver with Highly Integrated Front-End for 450Mb/s 802.11n systems**S. Gross, T. Maimon, F. Cossoy, M. Ruberto, G. Normatov, A. Rivkind, N. Telzhensky, R. Banin, O. Ashkenazi, A. Ben-Bassat, S. Zaguri, G. Hara, M. Zajac, N. Shahar, S. Shahaf, A. Fridman, O. Degani  
*Intel Corporation, Mobile Wireless Group, Haifa, Israel***RTU2A-2: A CMOS Transceiver with internal PA and Digital Pre-distortion For WLAN 802.11a/b/g/n Applications**Chia-Jun Chang, Po-Chih Wang, Chih-Yu Tsai, Chin-Lung Li, Chiao-Ling Chang, Han-Jung Shih, Meng-Hsun Tsai, Wen-Shan Wang, Ka-Un Chan, and Ying-Hsi Lin  
*Realtek Semiconductor Corp., Hsinchu, 300, Taiwan***RTU2A-3: Highly Linear SOI Single-Pole 4-Throw Switch with an Integrated Dual-band LNA and Bypass Attenuators**Chun-Wen Paul Huang, Lui (Ray) Lam, Mark Doherty, and William Vaillancourt  
*SiGe Semiconductor, Andover, MA 01810, USA***RTU2A-4: A 6.1GS/s 52.8mW 43dB DR 80MHz Bandwidth 2.4GHz RF Bandpass  $\Delta\Sigma$  ADC in 40nm CMOS**J. Ryckaert, A. Geis\*, L. Bos\*, G. Van der Plas, J. Craninckx  
*IMEC, \*also at VUB***RTU2A-5: Single-chip WiFi bgn 1x2 SoC with Fully integrated Front end & PMU in 90nm digital CMOS technology**J.C. Jensen, R. Sathwani, A.A. Kidwai, B. Jann, A. Oster\*, M. Sharkansky\*, I. Ben-Bassat\*, O. Degani\*, S. Porat\*, A. Fridman\*, H. Shang, C. Chu, A. Ly, M. Smith  
*Intel Corporation, Hillsboro OR, \*Intel Corporation, Haifa Israel***RTU2C: Millimeter-Wave Arrays****Room: 211AB**Chair: Brian Floyd, *North Carolina State University*Co-Chair: C. Patrick Yue, *UC Santa Barbara***RTU2C-1: A 44-GHz 8-Element Phased-Array SiGe HBT Transmitter RFIC with an Injection-locked Quadrature Frequency Multiplier**Sungwhan Kim\*, Prasad S. Gudem\*\*, and Lawrence E. Larson\*  
*\*Center for Wireless Communication, University of California San Diego, CA, USA, \*\*Qualcomm Inc., San Diego, CA, USA***RTU2C-2: A thirty two element phased-array transceiver at 60GHz with RF-IF conversion block in 90nm flip chip CMOS process**Emanuel Cohen\*\*/\*, Claudio Jakobson\*, Shmuel Ravid\*, and Dan Ritter\*\*  
*\*Mobile Wireless Group, Intel Haifa, Israel, \*\*Electrical Engineering Technion, Haifa, Israel***RTU2C-3: A 16-Element Phased-Array Receiver IC for 60-GHz Communications in SiGe BiCMOS**S. Reynolds, A. Natarajan, M.-D. Tsai\*, S. Nicolson\*\*, J.-H. Zhan\*, D. Liu, D. Kam, O. Huang\*, A. Valdes-Garcia, B. Floyd  
*IBM T. J. Watson Research Center (Yorktown Heights, NY), \*MediaTek (HsinChu, Taiwan), \*\*MediaTek Inc. (San Jose, CA)***RTU2C-4: A 24-GHz Phased-Array Receiver in 0.13- $\mu$ m CMOS using an 8-GHz LO**S. Patnaik, R. Harjani  
*Department of Electrical and Computer Engineering, University of Minnesota, Minneapolis, MN 55455***RTU2C-5: Wafer-Scale W-Band Power Amplifiers Using on-chip Antennas**Y. A. Atesal, B. Cetinoneri, R. A. Alhalabi, G. M. Rebez  
*University of California at San Diego***RTU2D: RF Modeling for Switch and PA Applications****Room: 212AB**Chair: Francis Rotella, *Peregrine Semiconductor*Co-Chair: Yuhua Cheng, *Peking University***RTU2D-1: Application of BSIMSOI MOSFET Model to SOS**Technology: J. W. Roach, L.-W. Chen, P. G. Clarke, F. M. Rotella  
*Peregrine Semiconductor, San Diego, USA***RTU2D-2: Modeling of SOI FET for RF Switch Applications**T.-Y. Lee, S. Lee  
*Skyworks Solutions, Inc.***RTU2D-3: A High Power CMOS Differential T/R Switch using Multi-section Impedance Transformation Technique**H.-W. Kim, M. Ahn\*, O. Lee, C.-H. Lee\*, and J. Laskar  
*Georgia Institute of Technology, \*Samsung Design Center***RTU2D-4: Exploitation of Active Load-pull and DLUT Models in MMIC DesignA**D. M. FitzPatrick, T. Williams\*, J. Lees, J. Benedikt, S.C. Cripps and P.J. Tasker  
*Cardiff University, \*Selex-Galileo SAS Ltd.***RTU2D-5: A Mixed-signal Load-Pull System for Base-station Applications**Mauro Marchetti\*, Rob Heeres\*\*, Michele Squillante\*, Marco Pelk\*, Marco Spirito\*, and Leo C. N. de Vreede\*  
*\*Delft University of Technology, Mekelweg 4, 2628 CD, Delft, The Netherlands, \*\*NXP Semiconductors, Gerstweg 2, 6534 AE, Nijmegen, The Netherlands*

13:20 - 13:40

13:40 - 14:00

14:00 - 14:20

14:20 - 14:40

14:40 - 15:00



## TUESDAY

## INTERACTIVE FORUM

14:00-16:00

## RTUIF: RFIC Interactive Forum

Room: 208AB &amp; 209AB

Chair: David Ngo, RFMD

Co-Chair: Chris Rudell, University of Washington

**RTUIF-01: A 228 $\mu$ W Injection Locked Ring Oscillator based BPSK Demodulator in 65nm CMOS**

Q. Zhu, Y. Xu

Illinois Institute of Technology

**RTUIF-02: A 0.13- $\mu$ m CMOS Wireless Reflector for Phase Sweep Cooperative Diversity**

J.-F. Bousquet, S.C. Magierowski, G.G. Messier, Z. Zhao

Schulich School of Engineering, University of Calgary

**RTUIF-03: Design methodology and comparison of rectifiers for UHF-band RFID**

Francesco Mazzilli\*, Prakash E. Thoppay\*, Norbert Jöhl+, and Catherine Dehollain\*

\*Swiss Federal Institutes of Technology, Lausanne, 1015, Switzerland, +Advanced Silicon, Lausanne, 1004, Switzerland

**RTUIF-04: A CMOS Ultra-wideband Radar Transmitter with Pulsed Oscillator**

Sungeun Lee, Sanghoon Sim, Songcheol Hong

School of Electrical Engineering and Computer Science at KAIST, Korea

**RTUIF-05: 900MHz/1800MHz GSM Base Station LNA with Sub-1dB Noise Figure and +36dBm OIP3**

D. Leenaerts, J. Bergervoet, J.-W. Lobeek, M. Schmidt-Szalowski

NXP Semiconductors, Eindhoven, 5656AE, the Netherlands

**RTUIF-06: A 4.35-mW +22-dBm IIP3 Continuously Tunable Channel Select Filter for WLAN/WiMax Receivers in 90-nm CMOS**

Mostafa Savadi Oskooei\*\*, Nasser Masoumi\*\*, Mahmud Kamareh\*\*, and Henrik Sjöland\*

\*Department of Electrical and Information Technology, Lund University, Lund, Sweden, \*\*School of Electrical and Computer engineering, University of Tehran, Tehran, Iran

**RTUIF-07: Wideband Trans-Impedance Filter Low Noise Amplifier**

M. Kaitiokallio\*, A. Pärssinen\*\*, J. Rynänen\*

\*Aalto University, Finland, \*\*Nokia Research Center, Finland

**RTUIF-08: A Wideband High-Linearity Mixer in 0.5  $\mu$ m InP DHBT Technology**

M. Stuenkel, M. Feng

University of Illinois

**RTUIF-09: A High Gain Wideband 77GHz SiGe Power Amplifier**

IBM Haifa Research Lab

Roei Ben Yishay, Roi Carmon, Oded Katz and Danny Elad

**RTUIF-10: A Broadband Differential Cascode Power Amplifier in 45 nm CMOS for High-Speed 60 GHz System-on-Chip**

M. Abbasi\*, T. Kjellberg\*\*, A. de Graauw\*\*\*, E. V. Heijden\*\*\*, R. Roovers\*\*\*, H. Zirath\*

\*Chalmers University of Technology, \*\*Chalmers Industrial Technologies, Sweden, \*\*\*NXP Semiconductors, The Netherlands

**RTUIF-11: A CMOS LC VCO with Novel Negative Impedance Design for Wide-Band Operation**

Chang-Hsi Wu and Guan-Xiu Jian

Department of Electronic Engineering, Linghua University of Science and Technology, \*RF Integrated Circuits, Wireless Communication Systems Nonlinear System Theory\*, R.O.C.

**RTUIF-12: An 80GHz range Synchronized Push-push Oscillator For Automotive Radar Application**

C. Ameziane, T. Taris, Y. Deval, D. Belot\*, R. Plana\*\* and J.-B. Bégueret

IMS-Bordeaux, \*STMicroelectronics, \*\*LAAS, FRANCE

**RTUIF-13: Millimeter Wave CMOS VCO with a High Impedance LC tank**

S. Chai, J. Yang, B. Ku, S. Hong

Korea Advanced Institute of Science and Technology

**RTUIF-14: Controlled dither for effective fractional delay in 90 nm digital to time conversion based DDS for spur mitigation**

S. A. Talwalkar, T. Gradishar, B. Stengel, G. Cafaro and G. Nagaraj

Matorola, Inc., Plantation, FL

**RTUIF-15: 2-4 and 9-12 Gb/s CMOS Fully Integrated ILO-based CDR**

Q. Mazouffre\*, R. Toupet\*, M. Pignol\*\*, Y. Deval and J.B. Begueret\*

\*IMS Laboratory, University of Bordeaux, Talence, France, \*\*CNES (Centre National d'Etudes Spatiales), Toulouse, France

**RTUIF-16: A 22.5-dB Gain, 20.1-dBm Output Power K-band Power Amplifier in 0.18- $\mu$ m CMOS**

Chi-Cheng Hung, Jing-Lin Kuo, Kun-You Lin, and Hwei Wang

Dept. of Electrical Engineering and Graduate Institute of Communication Engineering, National Taiwan University

**RTUIF-17: A 40% PAE Linear CMOS Power Amplifier with Feedback Bias Technique for WCDMA Applications**

H. Jeon, K.-S. Lee, O. Lee, K. H. An, Y. Yoon, H. Kim, D. H. Lee\*, J. Lee\*\*, C.-H. Lee\*\*\*, J. Laskar

Georgia Electronic Design Center, USA, \*Skyworks, USA, \*\*Gwangju Institute of Science and Technology, Korea, \*\*\*Samsung Design Center, USA

**RTUIF-18: A Switching-Mode Amplifier for Class-S Transmitters for Clock Frequencies up to 7.5 GHz in 0.25 $\mu$ m SiGe-BiCMOS**

S. Heck, M. Schmidt, A. Bräckle, F. Schuller, M. Grözing, M. Berroth, H. Gustat\*, C. Scheytt\*

University of Stuttgart (Institute of Electrical and Optical Communications Engineering), \*IHP GmbH, Germany

**RTUIF-19: SiGe Power Amplifier ICs for 4G (WIMAX and LTE) Mobile and Nomadic Applications**

V. Krishnamurthy, K. Hershberger, J. Dekosky, H. Zhao, D. Poulin, R. Rood, E. Prince

VT Silicon, Inc., USA

**RTUIF-20: Self-Matched ESD Cell in CMOS Technology for 60-GHz Broadband RF Applications**

Chun-Yu Lin 1, Li-Wei Chu 1, Ming-Dou Ker 1,2, Tse-Hua Lu 3, Ping-Fang Hung 3, and Hsiao-Chun Li 3

1. National Chiao-Tung University, Hsinchu, Taiwan; 2. I-Shou University, Kaohsiung, Taiwan; 3. Taiwan Semiconductor Manufacturing Company

**RTUIF-21: The Impact of MOSFET Layout Dependent Stress on High Frequency Characteristics and Flicker Noise**

Kuo-Liang Yeh, Chih-You Ku, and Jyh-Chyurn Guo

Institute of Electronics Engineering, National Chiao Tung University, Hsinchu, Taiwan

**RTUIF-22: A Novel Low-Profile Low-Parasitic RF Package Using High-Density Build-Up Technology**

Chien-Cheng Wei, Ming-Chien Lin, Chin-Ta Fan, Ta-Hsiang Chiang,

Ming-Kuen Chiu, Shao-Pin Ru, and Albert Cardona\*

Tong Hsing Electronic Industries, LTD., 5S, Lane 365, Yingtao Road, Yinko, Taipei Hsien, Taiwan 239, Agile RF\*, Inc. 93 Castilian Drive, Santa Barbara, CA 93117

**RTUIF-23: A High Quality Factor Varactor Technology Evaluation**

R. DEBROUCKE\*, S. JAN\*, J.-F. LARCHANCHE\*, C. GAQUIERE

\*STMicroelectronics Crolles, FRANCE; IEMN University of Lille, FRANCE

**RTUIF-24: Power Improvement for 65nm nMOSFET with High-Tensile CESL and Fast Nonlinear Behavior Modeling**

C.S.Chiu, K.M.Chen, G.W.Huang, K.H.Liao, S.Y.Lin, C.C.Hung\*,

S.Y.Huang\*, C.W.Fan\*, C.Y.Tzeng\*, S.Chou\*

National Nano Device Lab., United Microelectronics Corporation\*, National Chiao Tung University\*\*, Taiwan

**RTUIF-25: RF Benchmark Tests for Compact MOS Models**

G.D.J.Smit, A.J.Scholten, D.B.M.Klaassen

NXP Semiconductors, The Netherlands

**RTUIF-26: A 1.8V 74mW UHF RFID Reader Receiver with 18.5dBm IIP3 and -77dBm Sensitivity in 0.18 $\mu$ m CMOS**

X. Sun, B. Chi, C. Zhang, Z. Wang,

Z. Wang Beijing, 100084, P. R. China

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# 75<sup>TH</sup> ARFTG MICROWAVE MEASUREMENT CONFERENCE



Welcome to the 75th Automatic RF Techniques Group (ARFTG) Microwave Measurement Conference Hilton Anaheim on Friday, 28 May 2010.

**From: Ken Wong, General Chair, 75th ARFTG Conference**  
**John Wood, Technical Program Chair, 75th ARFTG Conference**



The conference will include technical presentations, an interactive forum, and an exhibition; all to give you ample opportunity to interact with your colleagues in the automated RF and microwave measurement and test community. The conference theme is "Measurement of Modulated Signals for Communications" with papers focusing on vector signal measurements and complex waveform analysis, nonlinear measurement techniques in time domain and envelope domain, application of digital signal processing to communications signal measurements, on wafer measurements, measure-

ments in fixtures for high power applications, nonlinear modeling, linearization and predistortion techniques, and other areas of RF, microwave and millimeter wave measurements. Also, be sure to check out the joint ARFTG/IMS workshops on mm-wave waveguide measurements and signal integrity. An important part of any ARFTG Conference is the opportunity to interact one-on-one with colleagues, experts and vendors in the RF and microwave test and measurement community. Whether your interests include high-throughput production or one-of-a-kind metrology measurement, complex systems or simple circuit modeling, small to large signal measurements, phase noise or noise figure, dc to lightwave, you will find a kindred spirit or maybe even an expert. Starting with the continental breakfast in the exhibition area, continuing through the two exhibition/interactive forum sessions and the luncheon, there will be ample opportunity for discussion with others facing similar challenges. Attendees find that these interactions are often the best source of ideas and information for their current projects. So come and join us. You'll find that the atmosphere is informal and friendly.

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# ARFTG TECHNICAL SESSIONS

# PACIFIC A

08:00 – 09:20

**Session 1: Modulated Signals for Wireless Communications**

Chair: John Wood, Freescale Semiconductor Inc

10:20 – 12:00

**Session 2: Nonlinear Measurements**

Chair: Dominique Schreurs, KU Leuven

13:20 – 15:00

**Session 3: Calibration Techniques**

Chair: Dave Blackham, Agilent Technologies, Inc

15:40 – 16:40

**Session 4: Other Areas of Microwave and Millimetre-wave Measurements**

Chair: Jean-Pierre Teyssier, University of Limoges

<b>Session 1-1: Modern Cellular Wireless Signals</b> (Invited) 8:00 AM-8:40 AM E. McCune, RF Communications Consulting, Santa Clara, United States	<b>Session 2-1: A Simplified Extension of X-parameters to Describe Memory Effects for Wideband Modulated Signals</b> 10:20 AM-10:40 AM J. Verspecht1, D. E. Root2, J. Horn2, 1Jan Verspecht B.V.B.A., Opwijk, Belgium, 2Agilent Technologies, Santa Rosa, United States	<b>Session 3-1: A multi-step phase calibration procedure for closely spaced multi-tone signals</b> 1:20 PM-1:40 PM M. Mirra1, M. Marchetti1, F. Tessitore1, M. Spirito1, L. C. de Vreede1, L. Betts2, 1TU Delft, Delft, Netherlands, 2Agilent technology, Santa Rosa, United States	<b>Session 4-1: Impact of the Pulse-amplifier Slew-rate on the Pulsed-IV measurement of GaN HEMTs</b> 3:40 PM-4:00 PM S. A. Albahrani, A. E. Parker, Macquarie University, Sydney, Australia
<b>Session 1-2: Measurement and Correction of Residual Nonlinearities in a Digitally Predistorted Power Amplifier</b> 8:40 AM-9:00 AM R. N. Braithwaite, Powerwave Technologies, Santa Ana, United States	<b>Session 2-2: Multi-Harmonic Broadband Measurements using an Large Signal Network Analyzer</b> 10:40 AM-11:00 AM Y. Kot1, P. Roblin2, S. Myoung3, J. Strahler4, F. D. Grootes5, J. P. Teyssier6, 1The Ohio State University, Columbus, United States, 2The Ohio State University, Columbus, United States, 3Samsung Corporation, Suwon, Republic of Korea, 4Andrew Corporation, Westerville, United States, 5Verspecht-Teyssier-DeGrootes s.a.s., Brive-la-Gaillarde, France, 6XLIM Limoges University, Brive, France	<b>Session 3-2: Traceable calibration of Vector Signal Analyzers</b> 1:40 PM-2:00 PM D. A. Humphreys, M. R. Harper, M. Salter, National Physical Laboratory, Teddington, United Kingdom	<b>Session 4-2: A Novel Method for Direct Impedance Measurement in Microwave and mm-Wave Bands</b> 4:00 PM-4:20 PM M. Randus, K. Hoffmann, Czech Technical University in Prague, Prague, Czech Republic
<b>Session 1-3: Experimental Sensitivity Analysis of Multi-Standard Power Amplifiers Nonlinear Characterization under Modulated Signals</b> 9:00 AM-9:20 AM M. Ben Ayed, S. Boumaiza, University of Waterloo, Waterloo, Canada	<b>Session 2-3: A VNA based broadband loadpull for non-parametric 2-port Best Linear Approximation Modelling</b> 11:00 AM-11:20 AM Y. Rolain, J. Schoukens, R. Pintelon, L. Delocht, G. Vandersteen, Vrije Universiteit Brussel (VUB), Brussel, Belgium	<b>Session 3-3: A Novel Method for Measuring Phase and Group Delay of Mixers Without a Reference Mixer</b> 2:00 PM-2:20 PM J. P. Dunsmore, J. Ericsson, Agilent Technologies, Santa Rosa, United States	<b>Session 4-3: Inter-laboratory Comparison of Reflection and Transmission Measurements in WR-06 waveguide (110 GHz to 170 GHz)</b> 4:20 PM-4:40 PM M. Salter1, N. Ridler1, P. Goy2, S. Caropen2, J. Watts3, R. Clarke4, Y. Lau5, D. Linton6, R. Dickie6, P. Huggard7, M. Henry7, J. Hesler8, S. Barker9, J. Stanec9, 1NPL, Teddington, United Kingdom, 2AB Millimetre, Paris, France, 3Flann Microwave Ltd, Bodmin, United Kingdom, 4University of Leeds, Leeds, United Kingdom, 5OML Inc, Morgan Hill, United States, 6Queens University Belfast, Belfast, United Kingdom, 7Rutherford Appleton Laboratory, Didcot, United Kingdom, 8Virginia Diodes Inc, Charlottesville, United States, 9University of Virginia, Charlottesville, United States
	<b>Session 2-4: An Intelligence Driven Active Loadpull System</b> 11:20 AM-11:40 AM R. S. Saini, S. P. Woodington, J. Lees, J. Benedikt, P. J. Tasker, Cardiff University, Cardiff, United Kingdom	<b>Session 3-4: A new 75-110 GHz primary power standard with reduced thermal mass</b> 2:20 PM-2:40 PM D. Adamson, J. Miall, J. Howes, M. Harper, R. Thompson, National Physical Laboratory, Teddington, United Kingdom	
	<b>Session 2-5: Investigation of X-Parameters Measurements on a 100 W Doherty Power Amplifier</b> 11:40 AM-12:00 AM J. Wood, G. Collins, Freescale Semiconductor, Inc., Tempe, United States	<b>Session 3-5: Some effects of error term interpolation on network analyzer uncertainties</b> 2:40 PM-3:00 PM J. Martens, Anritsu Company, Morgan Hill, United States	

# ARFTG INTERACTIVE FORUM

# PACIFIC B

<b>Poster-1: Metrology standards for digital modulation error Based on CW combination</b> 9:30 AM-10:30 AM R. Zhang, F. Zhong, L.Q. Guo, China Academy of telecommunication Research of MIT, Beijing, China	<b>Poster-2: Harmonic Load Pull of High-Power Microwave Devices using Fundamental-Only Load Pull Tuners</b> 9:30 AM-10:30 AM J. Hoversten, M. Roberg, Z. Popovic, University of Colorado at Boulder, Boulder, United States	<b>Poster-3: S-functions behavioral model order reduction based on narrow-band modulated large-signal network analyzer measurements</b> 9:30 AM-10:30 AM M. Myslinski1, F. Verbeyst2, M. Vanden Bossche2, D. Schreurs1, 1K.U.Leuven, Leuven, Belgium, 2NMDG n.v., Bornem, Belgium	<b>Poster-4: X-Parameter Measurement Challenges for Unmatched Device Characterization</b> 9:30 AM-10:30 AM D. T. Bespalko, S. Boumaiza, University of Waterloo, Waterloo, Canada
<b>Poster-5: Time reference for measurements of arbitrarily shaped pulses.</b> 9:30 AM-10:30 AM M. Odyniec, NSTec, Livermore., United States	<b>Poster-6: Analysis of Phase Noise Effect On Microwave Attenuation Precision Measurement Using A Heterodyne Receiver</b> 9:30 AM-10:30 AM T. Y. Wu1, S. W. Chua1, Y. L. Lu2, 1A*STAR, Singapore, Singapore, 2Nanyang Technological University, Singapore, Singapore	<b>Poster-7: Automation of Absolute Phase/Power Calibrations Applied to Real Time Large Signal Systems</b> 9:30 AM-10:30 AM I. Volokhine, NXP Semiconductors, Nijmegen, Netherlands	<b>Poster-8: Uncertainties in Coplanar Waveguide and Microstrip Line Standards for On-Wafer Thru-Reflect-Line Calibrations</b> 9:30 AM-10:30 AM U. Arz, K. Kuhlmann, PTB, Braunschweig, Germany
<b>Poster-9: Multimode TRL Technique for De-embedding of Differential Devices</b> 9:30 AM-10:30 AM M. Wojnowski1, V. Issakov2, G. Sommer1, R. Weigel3, 1Infineon Technologies AG, Neubiberg, Germany, 2University of Paderborn, Paderborn, Germany, 3University of Erlangen-Nuremberg, Erlangen, Germany	<b>Poster-10: Comparison of noise figure calibration and measurement techniques using noise figure verification techniques</b> 9:30 AM-10:30 AM B. Shoulders, K. H. Wong, Agilent Technologies, Santa Rosa, United States	<b>Poster-11: An Improved Method to Extract the Parasitic Capacitances Cpg and Cpd of AlGaIn/GaN FETs</b> 9:30 AM-10:30 AM J. R. Loo-Yau1, J. A. Reynoso-Hernández2, 1Centro de Investigacion y Estudios Avanzados del I. P. N., Guadaluajara, Mexico, 2Centro de Investigacion Cientifica y Educacion Superior de Ensenada, Ensenada, Mexico	



# WORKSHOPS AND SHORT COURSES

Workshops and Short courses are offered on Sunday, Monday and Friday of Microwave week. Please see daily handout on Sunday, Monday, and Friday in the registration area and from volunteers through out the meeting floors to confirm room location.

## SUNDAY WORKSHOPS

### WSA (IMS)

Sunday, 08:00 - 12:00

#### Software Defined Radio for Microwave Applications

Reviewed by: MTT-9, MTT-20

#### Organizers:

Jeffrey Pawlan, *Pawlan Communications*  
Hermann Boss, *Rohde & Schwarz*

**Abstract:** Software Defined Radio (SDR) is the most significant innovation and change to radio communications since 1990. From HF to microwave frequencies, it allows the use of a fixed hardware platform to change bands, frequencies, and modulation types without any change in the hardware at all. This synergistic combination of analog and digital microwave hardware combined with software has significantly improved performance, allowed for great flexibility to ever-changing modulations and standards, shortened development time, and reduced cost. This workshop will make SDR understandable and applicable to microwave engineers. It will begin with a clear explanation of how SDR works and its evolution through several generations of refinements. You will see and hear SDR in action with several live demonstrations of operating hardware and software along with test equipment. Your future work as a microwave engineer will be put in perspective with the current and future radio requirements. Actual space communications SDR hardware and software will be demonstrated by the second speaker who is from JPL / NASA. Cognitive Radio, a new related field, will be presented by a third speaker. SDR makes it possible to dynamically assess spectrum activity and change the modulation format to allow multiple signals to co-exist on the same frequency without interference or jamming. This workshop will be practical and emphasize weak signal communications and commercial applications.

#### Speakers:

1. Jeffrey Pawlan, *Pawlan Communications*  
"Software Defined Radio for Weaksignal and Commercial Applications"
2. James Lux, *JPL*  
"The Adoption of SDR by NASA for Space Communications"
3. Vasu Chakravarthy, *Air Force Research Laboratory/Sensors Directorate*  
"An Introduction to Cognitive Radio and its Implementation"

### WSB (RFIC)

Sunday, 13:00 - 17:00

#### Advances in Filtering and Sampling for Integrated Transceivers

Reviewed by: RFIC, MTT-9, MTT-20

#### Organizer:

Tom Riley, *Kaben Wireless Silicon Inc.*

**Abstract:** Blocker and interference filtering is a key issue in highly integrated Software Defined Radio (SDR) Receivers. If blockers can be removed prior to the ADC and

conversion to the digital domain, power and area in the ADC can be greatly reduced. This workshop will show how Analog, sampled-time signal processing can be used to implement highly selective FIR, IIR and spatial FIR filters. N-path filtering can be used to design high bandwidth filters using low bandwidth analog components. Component mismatch, timing jitter and other sources of error that can affect receiver performance will be discussed. Linearity enhancement techniques for filters will be presented, as well as wideband RF front-end circuit techniques. For added blocker rejection, notched Delta-Sigma data converters are presented. Following each speaker's presentation, the floor will be opened for interactive discussion with the audience.

#### Speakers:

1. Tom Riley, *Kaben Wireless Silicon Inc.*  
"Advances in Discrete-Time Analog Filtering"
2. Bogdan Staszewski, *Technical University of Delft*  
"Discrete-Time Receiver"
3. Asad Abidi, *University of California, Los Angeles*  
"A Discrete-Time Wideband Receiver for Software-Defined Radio"
4. Martin Snelgrove, *Kapik Integration Inc.*  
"Interference Mitigation in Receivers"

### WSC (RFIC)

Sunday, 8:00 - 17:00

#### Interference, Noise and Coupling Effects in Modern SoC and SiP Products: Issues, Problems and Solutions

Reviewed by: RFIC, MTT-6, MTT-12

#### Organizers:

Jan Niehof, *NXP Semiconductors*  
Matthias Locher, *ST-Ericsson*; Oren Eliezer, *Xtendwave*

**Abstract:** The focus of this interactive workshop will be on resolving noise and self-interference problems: on-chip coupling effects, chip-package co-design, substrate issues, noise (inherent and external), coupling-aware RFIC floor planning, digitally assisted solutions for interference problems, EMC (chip and board level), design practices, and CAD/EDA modeling capabilities to effectively analyze and address these effects. Recognized companies and partnerships active in the semiconductor industry will present actual issues encountered in their designs and the solutions/design-practices used to address them, including key lessons learned. Interactive discussions will be facilitated to exchange valuable ideas for the benefit of participants and the industry at large.

#### Speakers:

1. Nikos Haralabidis, *Broadcom*  
"Self-Interference in Multi-Standard RF SoC Transceivers"
2. Dietolf Seippel, *Infineon*  
"Floor planning of complex Baseband-Radio SoCs in consideration of cross talk prevention"
3. Matthias Locher, *ST-Ericsson*

"A Bottom-Up Design and Verification Approach for Coexistence in Multi-System SoCs"

4. Ayman Fayed, *Iowa State University, Oren Eliezer, Xtendwave*  
"System-level methodology for the power management system design in complex SoCs: minimize the impact of interference through the supply"
5. Jonathan Jensen, *Intel*  
"Isolation and coexistence challenges – a single-chip Bluetooth/WiFi combo example"
6. Jan Niehof, *NXP Semiconductors*  
"Interference issues and coupling effects in RF products"
7. Ravi Subramanian, *Berkeley Design Automation*  
"Advances in CAD: Simulation & Analysis of RF SoCs"

## WSD (IMS)

Sunday, 8:00 - 17:00

### Ultra-Wideband (UWB) Technology: The State-of-the-Art and Applications

Reviewed by: MTT-15, MTT-16

#### Organizers:

Zhizhang (David) Chen, *Dalhousie University*  
Hong (Jeffery) Nie, *University of Northern Iowa*

**Abstract:** Since the FCC issued a Report and Order allowing license-free use of 0-960 MHz and 3.1-10.6GHz frequency bands in 2002, extensive research and development efforts have been made worldwide in utilizing these ultra-wide-band (UWB) frequency allocations for applications such as microwave imaging, high-speed short-range wireless communications, and wireless sensor networks. Despite a couple of setbacks in its commercialization, UWB technology and application continue to advance. More UWB algorithms and hardware design approaches are emerging. This workshop presents the latest developments of various UWB technologies, paving the way for ultimate realization of practical UWB systems. The workshop provides insight into (a) the operating principles and limitations of UWB systems, (b) design and test of UWB antennas, components, RF front-ends and transceivers, (c) the state-of-the-art in UWB signal processing algorithms, and (d) future trends in the UWB systems and their applications. This workshop will be beneficial to students, engineers and researchers who want to learn about the current status of UWB and related designs, tests and applications, and who want to follow and understand the recent developments and advanced applications of UWB.

#### Speakers:

1. Dave Michelson, *University of British Columbia*  
"Deployment of UWB Wireless Systems in Industrial Environments"
2. Zhining Chen, *Institute for Infocomm Research*  
"Miniaturization of Ultra-Wideband Antennas"
3. Ke Wu, Serge O. Tatu and Renato G. Bosisio, *École Polytechnique de Montréal*  
"Multi-Port Interferometers for UWB Transceiver Systems and Applications"
4. Natalia Nikolova, *McMaster University*  
"Direct Methods for Detection and Imaging with Microwave Measurements in the Ultra-wide Band"
5. Aly Fathy and Mohamed R. Mahfouz, et. al., *University of Tennessee*  
"Recent Trends and Advances in UWB Positioning"
6. Hong Nie, *University of Northern Iowa*  
"Code Shifted Reference UWB transceiver and Its Applications for Intra-Vehicle Control and Communication"
7. Zhizhang (David) Chen, *Dalhousie University*  
"UWB Reference-based Impulse Radio Systems and Hardware Design Issues"

## WSE (IMS)

Sunday, 8:00 - 17:00

### High Speed Signal Integrity Workshop

Reviewed by: MTT-11, MTT-12

#### Organizers:

Brett Grossman, *Intel Corporation*  
Mike Resso, *Agilent Technologies*

**Abstract:** The triple play of voice, video, and data continues to demand ever greater bandwidths from devices and interconnects. This requirement is driving the challenges faced by the signal integrity engineer into a realm which may seem somewhat familiar to the microwave engineer. However, the challenges associated with frequency content, coupled with the density of signals, and the need to fit into relatively low cost consumer products, are a unique set of constraints which drive these solutions. This signal integrity workshop will feature presentations which discuss practical case studies, as well as more fundamental and theoretical signal integrity research. You are welcome to attend and listen to industry and academic experts describe several of the latest developments in the field of high speed signal and power integrity.

#### Speakers:

1. Paul Huray, *University of South Carolina*  
"Bridging the Gap"
2. Michael Hill, *Intel Corporation*  
"Microprocessor Power Integrity – Metrologies and Future Challenges"
3. Heidi Barnes, *Verigy*  
"The Art of VNA Calibrations for Measuring Low Loss PCB Components"
4. Matthew Claudius, *Intel Corporation*  
"End Use Model Correlation"
5. Bob Schaefer, *Agilent Technologies*  
"Comparison of Fixture Removal Techniques for Connector and Cable Measurements"
6. Jim Rautio, *Sonnet Software*  
"Measurement and Analysis of Substrate Dielectric Constant Anisotropy"
7. Evan Fledell, *Intel Corporation*  
"Passive Interconnect Frequency Domain Characterization for Mixed-Medium and Vertical Interconnect Systems"
8. Leung Tsang, *University of Washington*  
"Electromagnetic Modeling of High Speed Vertical Interconnect on Chip-Package-Board"





## WSF (IMS)

Sunday, 8:00 - 17:00

**GaN for High Power, High Bandwidth Applications:  
Finally Fulfilling the Promise**

Reviewed by: MTT-5, MTT-6, MTT-7

**Organizers:**

Bill Vassilakis, *Empower RF Systems*  
David W. Runton, *RF Micro Devices*

**Abstract:** GaN circuits have, for a long time, promised to enable amplifier applications that have not been possible with GaAs or LDMOS such as higher temperatures of operation, large operating bandwidths, and higher operating power. Material quality problems have slowed the progress on the delivery of such applications leaving many wondering when GaN would displace incumbent technologies. GaN has also defied declining cost trends of semiconductors, due to higher processing costs, smaller wafers, and lower yields. In the commercial market, dollars per watt delivered has long dominated in the selection of technology. Other factors such as efficiency, the ability to pre-distort, and linearity have been secondary. GaN is at last emerging as a serious contender for both commercial and military applications, as we see more demand for power, efficiency and larger bandwidths of operation. As other technologies are reaching inherent limits, GaN is finally ready for prime time.

**Speakers:**

1. Norihiko Ui, *Sumitomo Electric Device Innovations*  
"Power and High Efficiency GaN-HEMTs for Cellular Base Station Applications"
2. Oualid Hammi and Fadhel M. Ghannouchi, *iRadio Lab, Department of Electrical and Computer Engineering, University of Calgary*  
"Power Amplifiers for Wireless Communication Infrastructure"
3. Dr. James J. Komiak, *BAE Systems Electronic Solutions*  
"Progress in High Power GaN HEMT Power Amplifiers for Wideband Applications"
4. Simon Wood, *Cree Inc.*  
"Trends in high power GaN transistors and MMICs"
5. Bumman Kim, *Pohang University of Science and Technology*  
"Highly Efficient Saturated Power Amplifier based on GaN – A class P amplifier"
6. David W. Runton, *RF Micro Devices*  
"Defining Application Spaces for High Power GaN"
7. Rik Jos, *NXP Semiconductors*  
"GaN HEMT and their commercial RF power applications"

## WSG (RFIC)

Sunday, 8:00 - 12:00

**MOSFET Modeling for RFIC Design Based On the Industry-Standard PSP Model**

Reviewed by: RFIC, MTT-6

**Organizers:**

Kevin McCarthy, *University College Cork*  
Weiman Wu, *Arizona State University*

**Abstract:** This workshop will present an overview of the state-of-the art in MOSFET modeling for the design of CMOS Radio Frequency ICs using modern nanometer-scale

CMOS. It focuses on the industry-standard PSP (MOSFET) and MOSVAR (varactor) models. The workshop will review the fundamentals of both models and demonstrate the highly-accurate RF simulation capabilities they provide for RFIC designs. The workshop will also show how the PSP model can be extended to SOI and Multi-Gate devices, which will become of increasing importance to RFIC design.

**Speakers:**

1. Gert-Jan Smit, *NXP Semiconductors*  
"The PSP Compact MOSFET Model: Physical Background and Benefits for RFIC Design"
2. Brandt Braswell, *Freescale Semiconductor*  
"Deployment of an Advanced MOSFET Model in an Industrial Context"
3. James Victory, *Sentinel IC Technologies*  
"MOSVAR – A PSP-Derived MOS Varactor Model"
4. Weimin Wu, *Arizona State University*  
"PSP-Based Modeling of SOI and Multi-Gate MOS Devices"

## WSH (RFIC) Sunday, 8:00 - 17:00

**Power Management for Integrated RF Circuits: Challenges and Solutions**

Reviewed by: RFIC, MTT-6

**Organizers:**

Ayman Fayed, *Iowa State University*  
Waleed Khalil, *Ohio State University*; Oren Eliezer: *Xtendwave*

**Abstract:** The recent expansion in the use of mobile communications and multi-media devices has fueled the demand for various wireless/RF transceivers to be integrated in a single SoC with the digital processing circuitry and power management functions. As battery life in mobile devices is critical, and with these transceivers typically not operating directly from the battery, regulating and delivering power to them in an efficient manner is becoming a bottleneck. Since power delivery efficiency and implementation cost on one hand, and noise and regulation quality on the other hand are two contradictory factors in traditional power management circuits, RF loads present a great challenge due to their high sensitivity to their power supply quality. This workshop will discuss the challenges and tradeoffs that power management designers have to make when designing for RF loads while maintaining high efficiency and cost-effectiveness.

**Speakers:**

1. Ayman Fayed, *Iowa State University*  
"Challenges in Integrated Power Management for Analog, RF, and mixed-signal SoCs"
2. Keith Kunz, *Texas Instruments*  
"Integrated DC-DC converters in nanometer CMOS RF SOCs"
3. Bertan Bakkaloglu, *Arizona State University*  
"Low-noise switched-mode and low-dropout linear regulators for RF applications"
4. Siamak Abedinpour, *Freescale*  
"An overview of Integrated Power Management Circuits for Portable RF applications"
5. Sam Palermo, *Texas A&M University*  
"Supply Regulation Techniques for Frequency Synthesizers"

6. David Allstot, Jeffery Walling, *University of Washington*  
"Supply Regulators in Class-E/G/H CMOS Power Amplifiers"
7. Ram Sathwani, *Intel*  
"Direct powering of RF and analog circuits from DC-DC converters"
8. Ahmed Emira, *Newport Media*  
"DC-DC converters noise considerations in RF SoCs"

## WSI (IMS)

Sunday, 8:00 - 17:00

### Substrate Integrated Circuits (SICs)

Reviewed by: MTT-8, MTT-12

#### Organizers:

Maurizio Bozzi, *University of Pavia*  
Ke Wu, *Ecole Polytechnique (Université de Montréal)*

**Abstract:** Substrate integrated circuits (SICs) are probably the most promising candidate for the design and implementation of low-cost and high-density millimeter-wave integrated circuits and systems in the next decades. SICs, which integrate planar and non-planar structures together, are able to offer a compact, low-loss, flexible, high integration density, and cost-effective solution for integrating active circuits, passive components and radiating elements on the same substrates including multilayered geometries regardless of technological platforms such as PCB, LTCC, MHMICs, MMICs and even CMOS processes. In this way, the concept of System-in-Package (SiP), widely adopted in the design of RF/microwave circuits, can be extended to System-on-Substrate (SoS) for up-higher frequency ranges. This technological concept can be extended to terahertz and optoelectronic domains. The aim of this workshop is to provide an overview of the current trends of research and development in the field of SICs, including modeling methods, innovative structures, design techniques and technological issues.

#### Speakers:

1. Ke Wu, *Ecole Polytechnique (Université de Montréal)*  
"State-of-the-art and Future Perspective of Substrate Integrated Circuits"
2. Tatsuo Itoh, *University of California*  
"Progress in Composite Right/Left Handed Structures based on Substrate Integrated Waveguide"
3. Vicente E. Boria-Esbert, *Polytechnic University of Valencia*  
"Computer-Aided Design Tools of Passive Circuits in Substrate Integrated Waveguide Technology"
4. Jens Bornemann, *University of Victoria*  
"Multilayered Substrate-Integrated Waveguide Couplers"
5. Maurizio Bozzi, *University of Pavia*  
"Full-Wave Analysis and Equivalent-Circuit Modeling of SIW Components"
6. Ruey-Beei Wu, *National Taiwan University*  
"Development of LTCC mm-wave Passive Components for SoP Wireless Applications"
7. Apostolos Georgiadis, *Centre Tecnològic de Telecomunicacions de Catalunya*  
"Oscillator and active antenna design in SIW technology"
8. Roberto Vincenti Gatti, *University of Perugia*  
"SIW components and solutions for large electronic beam steering arrays"
9. Stepan Lucyszyn, *Imperial College*  
"Substrate Integrated Metal-Pipe Rectangular Waveguides"

## WSJ (RFIC)

Sunday, 8:00 - 17:00

### Re-configurable Multi-Radios at the Nanoscale

Reviewed by: RFIC, MTT-6, MTT-20

#### Organizers:

Gernot Hueber, *DICE*  
Robert Bogdan Staszewski, *Delft University of Technology*  
Stefan Heinen, *RWTH Aachen University*

**Abstract:** Advances in CMOS fabrication technology have enabled the use of CMOS in today's RF transceivers for wireless communications. Multi-band and multi-mode radios covering the diversity of communication standards from 2G GSM, 3G UMTS, to 4G LTE impose unique challenges on the RF-transceiver design due to limitations of reconfigurable RF components that meet the demanding cellular performance criteria at costs that are attractive for mass market applications. Nanoscale CMOS on one hand features the possibility for implementing a significant computational power and complex functionality directly on a single IC, on the other hand it shows poor raw performance or RF circuits compared to other technologies. The focus of this workshop is on the challenges the cellular standards pose on future multi-radio integration in nanoscale CMOS, along with a thorough discussion of advanced techniques for receivers and transmitters towards integration in a multi-radio SoC or SiP. Approaches include novel architectures, highly configurable analog circuitry, digitally assisted and enhanced analog/RF modules and the integration of digital signal processing into the traditionally purely analog front-ends.

#### Speakers:

1. Gernot Hueber, *DICE*  
"Flexible RF Transceivers for 4G Systems"
2. Ali M. Niknejad, *UC Berkeley*  
"High Dynamic Range Wide Bandwidth Building Blocks for Multi-Mode CMOS"
3. Vito Giannini, *IMEC*  
"The Green-Scalable Revolution of Nanoscale Software-Defined Radios"
4. Jaques C. Rudell, *University of Washington*  
"Nanometer CMOS Transceiver Design Enters the Era of "Co-Existence" and the SDR"
5. Hooman Darabi, *Broadcom*  
"Radio architectures for 2/3/4G highly integrated cellular applications"
6. Francois Rivet, *IMS Lab, University of Bordeaux & Atlantic Innovation ES, France*  
"Towards Software Radio Receiver"
7. Ali Hajimiri, *Caltech*  
"Electromagnetically Reconfigurable Radios: Antenna Meets Digital"
8. Frank Op 't Eynde, *Audax-Technologies Ltd.*  
"Unsolved Issues in SDR RF Frontends"
9. Larry Larson, *University of California*  
"Low-Power Transmitters in Nanoscale CMOS"
10. Robert Bogdan Staszewski, *TU Delft*  
"Advances in Digital RF Architectures"



## WSK (RFIC)

Sunday, 8:00 - 17:00

**Multi-Mode Front End Design Challenges and Techniques**

Reviewed by: RFIC, MTT-6, MTT-20

**Organizers:**

Edward Spears, *RFMD*  
 Nick Chang, *Skyworks Solutions*

**Abstract:** With the proliferation of data services, mobile device original equipment manufacturers (OEMs) are presented with new, unprecedented challenges and demands from both mobile operators and consumers. Mobile operators require customized handsets and mobile devices to meet various consumer roaming needs, and the issue of rapid customization has fallen to OEMs who must configure these complex 3G devices to function in multiple frequency bands and operating modes (GSM, EDGE, WCDMA, HSPA+, with LTE on the horizon). As the number of bands and band combinations grow, frequency flexibility and signal routing at the platform level have increased in importance as critical parameters for 3G mobile device development. This sets up an unprecedented challenge for front end suppliers, who are challenged to design a broad portfolio of high-performance, multi-band, multimode front ends and components that offer frequency flexibility, ease of implementation, size reduction, and low current consumption. Presentations in this workshop will focus on the design challenges to meet these multi-mode front end requirements along with the required advancements in device technology and design techniques to meet the overall bandwidth and efficiency requirements. Design techniques of linearization, efficiency enhancement, power detection and controls will be covered in design examples utilizing various technologies such as GaAs HBT, CMOS, Silicon-on-Insulator and Silicon Germanium.

**Speakers:**

1. Ville Vintola, *Nokia*  
"OEM prospective for Multi-mode solutions"
2. Ray Arkiszewski, *RFMD*  
"GaAs HBT Multi Mode Amplifiers"
3. David Ripley, *Skyworks Solutions*  
"Multi-mode, Multiband Power Amplifiers and Serial Bus Interface Standards"
4. Larry Larson, *University of California at San Diego*  
"Design Techniques for Broadband Efficient Linear Power Amplifiers for Multi-Mode Wireless Applications"
5. Dan Nobbe, *Peregrine*  
"Multimode Antenna Switch Modules"
6. Nadim Khat, *RFMD*  
"Tunable Front Ends Performance Benefits"
7. Pasi Tikka, *Epcos*  
"Multimode Filter and Switch Modules"

## WSL (IMS/RFIC)

Sunday, 8:00 - 17:00

**Silicon-Based Technologies for Millimeter-Wave Applications**

Reviewed by: MTT-6, MTT-16, RFIC

**Organizers:**

Jitendra Goel, *Raytheon Company*;  
 Lance Wei-Min Kuo, *Raytheon Company*  
 Didier Belot, *STMicroelectronics*  
 Eric Kerhervé, *IMS Lab*  
 Georg Boeck, *TU Berlin*

**Abstract:** Traditionally, millimeter-wave (MMW) circuits utilizing only III-V technologies have been employed in low-volume, high-performance products. With the recent progress of highly scaled Si-based (SiGe and CMOS) technologies achieving  $f_i$  and  $f_{max}$  beyond 200 GHz, the application space of Si-based technologies has broadened from digital, analog, RF, and microwave domains to include MMW applications. The workshop will focus on MMW applications such as imaging (94 GHz and 140 GHz), automotive radar (LRR at 77 GHz and SRR at 79 GHz), and wireless high data rate communications (W-HDMI at 60 GHz). It gives an overview of recently developed architectures, circuit design techniques, and antenna configurations to meet the demanding performance specifications of MMW applications.

**Speakers:**

1. Ali Hajimiri, *California Institute of Technology*  
"Si Millimeter-Wave Systems"
2. Gabriel M. Rebeiz, *University of California at San Diego*  
"Ultra-Low Power Millimeter-Wave Phased Arrays and Gbps Communications Systems Using On-Chip Antennas"
3. M. C. Frank Chang, *University of California, Los Angeles*  
"60-1300 GHz Circuit/System Developments Based on Super-Scaled CMOS"
4. Tian-Wei Huang and Huei Wang, *National Taiwan University*  
"Millimeter Wave Broadband Multi-Gigabit CMOS Transceiver Design"
5. Scott K. Reynolds, *IBM T. J. Watson Research Center*  
"Millimeter-Wave Circuits and Systems Work at IBM Research"
6. Piet Wambacq, *IMEC*  
"CMOS Radio Integration for High-Datarate 60 GHz Applications"
7. Ali Niknejad, *UC Berkeley*  
"mm-Wave Medical Imaging Using a 94 GHz Time-Domain Ultrawide-band Synthetic Imager (TUSI)"
8. Ullrich Pfeiffer, *University of Wuppertal*  
"Silicon Process Technologies for Emerging Terahertz Applications"
9. Pierre Busson, *STMicroelectronics*  
"60 GHz W-HDMI Transceiver"
10. Joy Laskar, *Georgia Tech*  
"mmW Digital CMOS Radio Solutions for Ultra-Low Power, High Resolution Sensing and High Bandwidth Connectivity"
11. Katya Laskin, *University of Toronto*  
"140 GHz Imaging"

## WSM (IMS/RFIC)

Sunday, 8:00 - 17:00

**RF Packaging Solutions for Wireless Communication Platforms**

Reviewed by: MTT-12, MTT-20, RFIC

**Organizers:**Telesphor Kamgaing, *Intel Corporation*Vijay Nair, *Intel Corporation*Clemens Ruppel, *TDK-EPC*

**Abstract:** In order to satisfy the decreasing form factor and increasing functionality demand from novel devices such as netbooks and smartphones, it is imperative to create a platform, where different radios and digital logic have to co-exist. This ultimate goal can only be achieved by overcoming various significant challenges at the silicon, packaging and testing levels. This full day workshop will focus on recent research and development work that will enable future ultra-small form factor computing and communication devices that incorporate one or multiple radios on the same platform. Various technology ingredients and packaging solutions for 60GHz, WiFi, WiMAX, Bluetooth, GPS and 3G/4G radios among others will be addressed by leading industrial and academic experts in the field.

**Speakers:**

1. Vijay Nair, *Intel Corporation*  
"Multi-protocol Multi-radio Wireless Platform Integration Challenges"
2. Joy Laskar, *Georgia Institute of Technology*  
"Development of Millimeter-Wave QFN: CMOS, PCB and Phased Array"
3. Anh-Vu Pham, *University of California, Davis*  
"Development of Ultra-small Wireless Passive Modules Using 3-D Organic Metamaterials"
4. Telesphor Kamgaing, *Intel Corporation*  
"Package Level Realization of Passives for Multiradio Wireless Modules"
5. Clemens Ruppel, *TDK-EPC*  
"Front-End Integration for Multi-Band, Multi-Standard Mobile Phones Based on LTCC"
6. William Chappell, *Purdue University*  
"Silicon on Silicon Packaging Using Self-aligned Interconnects"
7. Walter De Raedt, *IMEC*  
"3D Heterogeneous Integration Techniques for Wireless Devices"
8. Kevin Slattery, *Intel Corporation*  
"RF Interference in Small Form Factor Devices"

## WSN (IMS)

Sunday, 8:00 - 17:00

**The State of Art of Microwave Filter Synthesis, Optimization and Realization**

Reviewed by: MTT-8, MTT-16

**Organizers:**Ming Yu, *COM DEV, Canada*John Bandler, *McMaster University*

**Abstract:** Today systems require increasingly sophisticated microwave filters and multiplexers. The designer often faces the challenges of compromising between several contrasting requirements. This workshop will present a comprehensive overview of the state of the art of microwave filter synthesis, optimization and realization. Recent advances in some of the most promising application areas of microwave filters; innovative solutions concerning both design approaches and technological achievements will also be presented.

**Speakers:**

1. Dick Snyder, *RS Microwave*  
"Phase Shift, Delay, Anomalous Dispersion, and Meta-Materials: Implications for Future Filter Designs"
2. John W. Bandler, *McMaster University*  
"Advanced Optimization Techniques for Modern Filter Design—From Newton to Space Mapping"
3. Smain Amari, *RMC, France*  
"New Development in the Synthesis and Design of Microwave Filters of Arbitrary Bandwidth"
4. K. Zaki, *University of Maryland*  
"Dielectric Resonator and LTCC Filters"
5. Jen-Tsai Kuo, *National Chiao Tung University*  
"Microwave Planar Filter Technologies"
6. G. Macchiarella, *Politecnico di Milano*  
"Advanced Filter Technologies for Wireless Base Stations"
7. Ming Yu, *COM DEV*  
"Advanced Filter/Multiplexer Technologies for Satellite Transponders"
8. Ian Hunter, *University of Leeds*  
"Advanced Tunable and Reconfigurable Filters"
9. Vicente E. Boria-Esbert, *University of Valencia*  
"Prediction Models of RF Breakdown Effects in Passive Components for Satellite Payloads"



## MONDAY WORKSHOPS AND SHORT COURSES

### WMA (IMS)

Monday, 08:00 - 17:00

#### SiGe HBTs towards THz Operation

Reviewed by: MTT-4, MTT-7, MTT-11

#### Organizers:

Paulius Sakalas, *TU Dresden and FPL Semiconductor Physics Institute*  
Michael Schroter, *RFnano Corporation and UC San Diego, USA*

**Abstract:** This workshop will overview state-of-the-art SiGe HBT technology and its perspectives, aiming at operation towards TeraHertz frequencies: (1) the technology aspects, (2) the most relevant physical effects and the concepts of analytical formulations for compact modeling and the (3) physical limits, explored by device simulation in the framework of semi-classical transport theory (doping profiles, dimensions, lattice stress effects), (4) high frequency noise trends and practical noise modeling, (5) cryogenic operation as a mean to assess the basic physical properties and transport physics of SiGe HBTs, (6) circuits for wireless applications with mm-wave front-end for short and long-range radar, phased-array transceivers, imaging and (7) circuits for fiber optical applications such as next generation data transport in 100 Gigabit Ethernet networks a range of components from 112 Gb/s for simple on-off-keying (OOK) to 30 or even 60 GS/s A/D and D/A converters for sophisticated modulation schemes like OFDM or CPDQPSK as well as (8) calibration, de-embedding techniques at mm-frequencies and beyond.

#### Speakers:

1. H. Rucker, *Innovations for High Performance (IHP)*  
"Technology aspects of high-speed SiGe HBTs"
2. M. Schroter, *RFnano Corporation*  
"Compact modeling of high speed SiGe HBTs"
3. C. Jungemann, *Bundeswehr Universität München*  
"Exploring high speed SiGe HBTs and their limits by physics based simulation"
4. P. Sakalas, *TU Dresden and FPL Semiconductor Physics Institute*  
"High frequency noise in SiGe HBTs, practical modeling, challenges"
5. J. Cressler, *Georgia Institute of Technology*  
"Using cryogenic temperatures to probe physics and scaling limits of SiGe HBTs"
6. J. Long, *Delft University*  
"SiGe HBTs in Wireless Applications"
7. M. Moeller, *Saarland University and Micram GmbH*  
"Circuit design with SiGe HBTs for future 100 Gb/s data transport network"
8. A. Rumiantsev, *Suss Microtec*  
"Measurement accuracy at mm-frequencies and beyond: on-wafer calibration vs. de-embedding techniques. Who wins for THz SiGe HBTs"

### WMB (IMS)

Monday, 08:00 - 17:00

#### Advances in Photovoltaic Solar Cell Technology and its Possible Applications in Microwave Communications Systems as an Energy Source

Reviewed by: MTT-4, MTT-10, MTT-16

#### Organizers:

Aly E Fathy, *University of Tennessee*  
Samir El-Ghazaly, *National Science Foundation*  
Fuad Abulfotuh, *University of Alexandria*

**Abstract:** This workshop will address the need to: create a revolution in existing PV systems, develop new technologies, increase efficiency, significantly reduce associated costs, and discuss ways to extend the limits of various enabling technologies such as: single-crystal solar, thin films, organic semiconductors, dye sensitization, and quantum dots. Recent advances in the fabrication of nanoscale architectures to develop low-cost material and device technologies will be presented with emphasis on developing THz components, nanotennas, and demonstrating various possible applications in microwave communications systems.

#### Speakers:

1. Samir El-Ghazaly, *NSF*  
"Novel Devices for capturing solar energy spectrum"
2. Steven Novack, *Idaho National Lab (INL)*  
"The Nanoantenna Prospect for Harvesting Energy"
3. Nathan Lewis, *Caltech*  
"Advances in Photovoltaics Enabled by Nanotechnology"
4. Hameed Naseem, *University of Arkansas*  
"Low Cost Plasmon Enhanced Thin Silicon Solar Cells using Aluminum Induced Crystallization of Amorphous Silicon at Low Temperatures"
5. Arthur Nozik, *NREL*  
"Third Generation Solar Photon Conversion to Electricity: Multiple Exciton Generation in Silicon and Group IV-VI Quantum Dots; Quantum Dot Arrays and Solar Cells"
6. Aimin Song, *University of Manchester*  
"Terahertz nano-Diodes for Energy"
7. Sandra Rosenthal, *Vanderbilt University*  
"CdSe Nanocrystal Sensitized TiO<sub>2</sub> Nanotube Arrays Incorporated in Solid-State, Ordered-heterojunction Solar Cells"
8. Tim Anderson, *University of Florida*  
"Synthesis Routes for CuInxGa1-xSe2 Thin Film Absorbers"
9. Fuad Abulfotuh, *University of Alexandria*  
"Concentrated Photovoltaics: Advanced Technology with economic Performance"

## WMC (IMS) Monday, 08:00 - 17:00

### Recent Advancements and Challenges in mm-Wave Applications and Systems

Reviewed by: MTT-6, MTT-12, MTT-16

#### Organizers:

Amin Rida, *Georgia Institute of Technology*  
 Manos Tentzeris, *Georgia Institute of Technology*  
 Seung Lee, *Toyota Research Institute North America*

**Abstract:** MM-Wave technology has been rapidly evolving and is characterized with a plethora of benefits for several applications such as: broadband communication, automotive radars, imaging, and radio astronomy systems. This workshop highlights recent advancements and discusses the challenges in mm-Wave applications and systems. Active as well as passive mm-wave systems will be covered. Topics include: mm-wave imaging arrays (from 30 to 94 GHz) with designs approaching RF-VLSI status, architectures of several recently produced highly integrated MMICs for military and space applications using GaAs and SiGe as well as CMOS sub-mm oscillators. Integration examples such as FMCW System on Chip will be demonstrated. The second part of the workshop will focus on the passive RF-Front Ends (packaging considerations, interconnections, antenna arrays, and scanning arrays employing phase shifters) as well as on some radio architectures that realize beamforming. In addition, a talk on mm-wave imaging system for radio astronomy will be given. A panel session with speakers and attendees will be held as a conclusion of this workshop.

#### Speakers:

1. S. Nicolson, *MediaTek USA*  
"Recent Advancements and Challenges in mm-Wave Applications and Systems"
2. Dave Saunders, *ViaSat Advanced Microwave Products*  
"Highly Integrated MMIC Design – Advantages and Pitfalls"
3. G. Rebeiz, *University of California San Diego*  
"Large Scale Phased Arrays for Millimeter-Wave Applications"
4. Q. Jane Gu, *University of California Los Angeles*  
"Terahertz Circuits in CMOS"
5. P. Wambacq, *IMEC*  
"Riding the mm-Waves, Destination Many Gbit/s"
6. L. Roselli, *University of Perugia*  
"MIOS: 90 GHz Space Based Radiometer for Observation of Sun Flares"
7. J. Volakis, *Ohio State University*  
"mm-Wave Front-end Modules for 60 GHz Wireless Systems"
8. A. Rida, *Georgia Institute of Technology*  
"Low Cost Integrated mm-Wave Automotive Systems"

## WMD (IMS) Monday, 08:00 - 17:00

### New Microwave Devices and Materials Based on Nanotechnology

Reviewed by: MTT-15, IMS2010

#### Organizers:

Luca Pierantoni, *Università Politecnica delle Marche*  
 Fabio Coccetti, *LAAS-CNRS*  
 Christophe Caloz, *École Polytechnique de Montréal*  
 George W. Hanson, *University of Wisconsin-Milwaukee*

**Abstract:** Nano-materials and nano-devices often exhibit their most interesting properties at microwave and millimeterwave frequencies. Therefore, the area of nanoelectronics is an enormous opportunity for the microwave community, which can utilize its established body of modelling, design and measurement techniques with the aim to bridge the gap between nano-science and a new generation of extremely integrated circuits. Our goal is to present a meaningful overview of new microwave materials and devices based on recent achievements of nanotechnology. We introduce nanoscale metamaterials, discuss the electromagnetic heating of nanoparticles and explore superconducting nanodevices. We show how the transport properties of carbon-based materials (graphene, GNR, CNT) lead to new device concepts, as ambipolar transistors and mixers, CNT-arrayed devices (antennas, resonators), nano-interconnects, nano-electro-mechanical switches. We compare the RF performances between graphene-based and conventional semiconductor materials (e.g. Si) FETs. A novel CNT-nanoradio transistor is introduced. We focus on the metrology of heterostructured nanodevices. We introduce a unified model for the electromagnetic/transport problem in nanodevices.

#### Speakers:

1. Christophe Caloz, *École Polytechnique de Montréal, Montréal, Canada*  
"Ferromagnetic Nanowire Metamaterial Structures for Microwave Applications"
2. George W. Hanson, *University of Wisconsin-Milwaukee, WI, USA*  
"RF dissipation and electromagnetic heating of nanoparticles for thermal therapies and thermoacoustic imaging"
3. Peter Russer, *Technische Universität München, Munich, Germany*  
"Superconducting Nanoelectronic Devices"
4. Mitch Wallis, *National Institute of Standards and Technology, Boulder, CO, USA*  
"Metrology of heterostructured nano-devices for microwave applications"
5. Tomas Palacios, *Massachusetts Institute of Technology, Cambridge, MA USA*, "Ambipolar Graphene Electronics for RF Applications"
6. Yu-Ming Lin, *IBM T.J. Watson Research Center, Yorktown Heights, NY, USA*  
"High Performance Graphene FETs for RF Applications"
7. Azad Naeemi, *Georgia Institute of Technology, GA, USA*  
"High-frequency circuit models for carbon nanotube and graphene nanoribbon interconnects"
8. Peter Burke, *University of California, Irvine CA, USA*  
"Arrays of SWNT devices for analog RF: overview of the field"
9. Stephen Purcell, *Laboratoire de Physique de la Matière Condensée et Nanostructures, Villeurbanne, Cedex, France*  
"Towards RF applications in Nanotubes and Nanowires: the Nanoradio and Self Oscillations"
10. Stephen M. Goodnick, *Arizona State University, AZ, USA*  
"Terahertz Nanoelectronics"
11. Luca Pierantoni, *Università Politecnica delle Marche, Ancona, Italy*  
"Advanced Frequency- and Time-Domain Multiphysics Techniques for the Electromagnetic/ Coherent-Transport Problem in Nanodevices"
12. Fabio Coccetti, *LAAS-CNRS Toulouse & National Institute for Research and Development in Micro and Nanotechnologies (IMT), Bucharest, Romania*  
"Exploring nanostructured materials for sensing and communication applications"



## WME (IMS)

Monday, 08:00 - 12:00

### High-Power-Density Packaging of Gallium Nitride

Reviewed by: MTT-5, MTT-6, MTT-12

#### Organizers:

Rüdiger Quay, *Fraunhofer Institute Applied Solid-State Physics, Freiburg*  
Bernie Geller, *Vadum Inc, North Carolina*  
Frank Sullivan, *Raytheon Company*

**Abstract:** GaN has long been praised to be -THE- solution on the high-power side of RF-electronics. Next to reliability, packaging technology is the prime bottleneck for efficient heat extraction; high-power transfer and combining; and bandwidth: The intention of this workshop is to give an overview on recent advances in the packaging technology suitable for III-N electronics based both on performance and cost issues. We have five speakers covering the following topics: cost-effective diamond as high-density-wafer substrate, packaging for space in the European project AGAPAC, and packaging aspects with focus on traditional packaging to keep the integration cost-effective. Further, the thermal modeling of GaN with liquid microchannel coolers and advanced amplifier modules including high-density switching, filters, broadband board design, and modulator integration are addressed.

#### Speakers:

1. Ed Piner, *Nitronex Corp.*  
"GaN/Diamond AlGaIn/GaN/AlGaIn HEMT – The Next Frontier"
2. O. Vendier, *Thales Alenia Space, Toulouse*  
"AGAPAC: A European View for Advanced High Power Amplifier Packaging"
3. Paul Garland, *Koycera America, San Diego*  
"Packaging Materials and Processes to Optimize Performance for GaN Devices"
4. Morag Garven, *Science Applications International Corporation (SAIC)/Naval Research Laboratory*  
"High Heat Flux Thermal Management and Packaging Techniques for GaN on-SiC Semiconductor Devices"
5. Martin Oppermann, *EADS Defense Electronics, Ulm*  
"Application-specific Packaging Solutions for GaN Based Amplifier Modules"

## WMF (IMS)

Monday, 13:00 - 17:00

### High Efficiency, High Power Microwave Amplifiers for High Data Rate Space Communications

Reviewed by: MTT-5, MTT-7, MTT-16

#### Organizers:

Kavita Goverdhanam, *U.S. Army – CERDEC*  
Rainee N. Simons, *NASA Glenn Research Center*

**Abstract:** In space and terrestrial communication systems, high power amplifiers are needed to boost signal amplitude for propagation over long distances. Hence, the high power amplifier determines the overall efficiency and linearity of the system. In this workshop state-of-the-art MMICs and TWTAs for Ka-Band and above will be reviewed. Failure rates of both types of amplifiers will be discussed. As the satellite ages to account for losses, the RF output power may need adjustment.

Therefore, on-orbit re-configurability of amplifiers will be discussed. Future space platforms, which have size, weight and power constraints may require amplifiers for dual-functions such as, communications and radar. Hence dual-band operation will be discussed. The non-linearity of the amplifier may affect the performance of the link depending on the type of modulation and these aspects will be discussed. Finally, the relationships between higher order modulation formats, higher-speed data rates, amplifier bandwidth and linearity parameters will be discussed.

#### Speakers:

1. Mansoor Siddiqui, *Northrop Grumman Aerospace Systems*  
"High Efficiency MMIC Power Amplifiers for Space and Satellite Communications Applications"
2. William L. Menninger, *L-3 Communications, Electronics Technologies Inc*  
"Recent Advances in High-Efficiency and High-Power Space Traveling-Wave Tube Amplifiers"
3. Eric Nicol, *The Boeing Company*  
"On-Orbit Reliability Data for Solid State Power Amplifiers (SSPAs) and Traveling-Wave Tube Amplifiers (TWTAs)"
4. Christopher P. Silva, *The Aerospace Corporation*  
"Characterization, Impact, and Mitigation of Distortion Effects in Solid-State and Traveling-Wave Tube Power Amplifiers"
5. Ramesh K. Gupta, *SkyTerra LP*  
"Efficient Modulation Schemes for High Data Rate Satellite Communications"

## WMG (IMS)

Monday, 08:00 - 12:00

### Ultra-high Speed Microwave and Photonic Devices and Systems: How Will They be Tested?

Reviewed by: MTT-3, MTT-11

#### Organizers:

Stavros Iezekiel, *University of Cyprus*  
Ron Reano, *Ohio State University*

**Abstract:** Despite the bursting of telecoms bubble in 2000/2001, bit rates have continued to rise inexorably in both wireless and optical communications. This is manifested by the development of multi-Gb/s 60 GHz systems and the interest in 100 GbE technology. This workshop addresses a number of state-of-the-art approaches to the time- and frequency-domain measurement and diagnostic testing of critical components in present and emerging broadband optical, mm-wave and THz systems.

#### Speakers:

1. Paul D. Hale and Dylan Williams, *NIST*  
"Electro-optic sampling for traceability of high-speed electrical measurements"
2. John Whitaker, *University of Michigan*  
"Electro-Optic Sensing of Microwave Fields via Photonic Heterodyne Down Mixing"
3. Miguel Drummond, *Instituto de Telecomunicações*  
"Photonic RF instantaneous frequency measurement system by means of a polarization domain interferometer"
4. Robert E. Miles, *University of Leeds*  
"Terahertz Electronics"

## WMH (IMS)

Monday, 08:00 - 17:00S

**3D Microwave and Millimeter-Wave Packaging**

Reviewed by: MTT-6, MTT-12

**Organizers:**

John A. Pierro, *Telephonics Corporation*  
Debabani Choudhury, *Intel Corporation*

**Abstract** System applications ranging from highly complex commercial wireless handsets to the most sophisticated active electronically steered arrays for radar, remote sensing, and communications are demanding more and more functionality in ever smaller footprints. Wireless devices must continually make room for circuitry to support the latest emerging wireless standards without any changes to the size of the device. The trend toward “tile” packaging in modern AESA’S to achieve the affordability needed to make active arrays practical is forcing packaging innovations to solve very difficult PA thermal management problems and solve the problems of integrating and interconnecting very heterogeneous technologies. An element (typically one of thousands!) in an AESA typically comprises the printed antenna, the T/R module electronics and the controller. All of this functionality must be packaged in a very size-constrained area “behind” the radiating element. The T/R module and controller may employ as many as five distinct semiconductor technologies to perform the required functions. The workshop will assemble experts from around the world who are working to find practical, relevant solutions to these problems. Experts knowledgeable in AESA, RFID tags and wireless sensor networks, hand-sets, and high speed wireless access systems will present their latest thinking on the perennial challenge of providing more and more capability to both the commercial and defense industries at ever lower cost.

**Speakers:**

1. Takana Kaho, *NTT*  
“Ultra Compact RFICs Using Three-dimensional MMIC Technology from Microwave to Millimeter Wave Band”
2. Katherine J. Herrick, *Raytheon USA*  
“Wafer Level 3D Integration and Packaging for T/R Modules”
3. Douglas J. Carlson, *M/A-COM Technology Solutions Inc.*  
“Low Cost Panel Based Phased Array Technology: Creating a Three Dimensional RF System in Low Cost PCB Technology”
4. Manos M. Tentzeris, *Georgia Tech*  
“Flexible 3D Organic, Ceramic and Paper-based Modules for Communication and Sensing Applications”
5. Tauno Vähä-Heikkilä, *VTT Technical Research Center*  
“LTCC - 3D Integration Platform from Handset to Millimeter Wave Modules”
6. Tzzy-Sheng Jason Horng, *National Sun Yat-Sen University, Taiwan*  
“Integrated/Embedded Passive Substrate Design Technology for Wireless System-in-Package Applications”
7. Jean-Marc Rollin, *Nuvotronics*  
“Poly-Strata Technology for 3D System Integration”
8. Yves Mancuso, *Thales Systèmes Aéroportés*  
“Microwave Developments for AESA Tile Antennas with 3D Modules”

## WMI (IMS)

Monday, 08:00 - 17:00

**Making Reliable Measurements at Millimeter and Submillimeter Wavelengths**

Reviewed by: MTT-4, MTT-11

**Organizers:**

Nick Ridler, *National Physical Laboratory (NPL)*  
Andrej Rumiantsev, *SUSS MicroTec Test Systems GmbH*

**Abstract:** At the present time, there is a great deal of support available for making reliable measurements at frequencies up to 110 GHz. However, above 110 GHz this situation changes dramatically: there are only a few suppliers of test equipment and virtually no traceability for these measurements. In recent years, there has been a dramatic increase in interest in using frequencies in the millimeter- and submillimeter-wave bands (30 GHz to 3 THz) and this is challenging the current state of play regarding available test equipment and measurement assurance mechanisms. This workshop will provide a review of the current state-of-the-art for making reliable measurements at frequencies above 110 GHz. This will concentrate on the various transmission media that are being used at these frequencies – metallic waveguide, on-wafer and alternative wave-guiding structures (e.g. dielectric-based waveguides). The workshop will conclude with a panel session aimed at identifying priority areas where reliable measurements are needed now, and in the coming few years.

**Speakers:**

1. Dylan Williams and Erich Grossman, *NIST*  
“Overview of Rectangular Metal Waveguide, Power, and On-Wafer Measurements at Millimeter and Submillimeter Wavelengths”
2. Nick Ridler, *NPL, UK*  
“Methods for Verifying VNA Measurements Above 100 GHz”
3. Bobby Weikle, *University of Virginia*  
“Waveguide-Based Measurements at Terahertz Frequencies”
4. Jon Hacker, *Teledyne*  
“Silicon Waveguide Design Above 300 GHz”
5. Shelley Begley, *Agilent Technologies*  
“Characterizing Electromagnetic Properties of Materials at 110 GHz and Beyond”
6. Martin Salter, *NPL*  
“Realizing Dielectric Waveguide Network Analyzers for Millimeter-Wave Frequencies”
7. Richard Wylde, *Thomas Keating Ltd*  
“Quasi-Optical Measurement Systems”
8. Francisco Falcone, *Public University of Navarra*  
“Measurement of Metamaterial Devices and Structures in Millimeter Wave and Sub-Terahertz Frequency Range”





## WMJ (IMS)

Monday, 08:00 - 17:00

**Recent Advances in Reconfigurable Filters”**

Reviewed by: MTT-8, MTT-21

**Organizers:**

Dimitrios Peroulis, *Purdue University*  
Raafat Mansour, *University of Waterloo*

**Abstract:** Tunable RF and microwave filters are critical components in reconfigurable radios, radars and sensors. Over the past several years, a number of different technologies have been proposed to address this challenge with distinct advantages, drawbacks, maturity levels and market potentials. This workshop will review the state of the art in several of these technologies. The first few talks will focus on system-level aspects. The workshop will address challenges and opportunities for employing tunable filters in wireless communication systems. Non-linearity and distortion issues will also be covered in detail. The remaining ones will discuss a variety of tuning approaches such as ferroelectric, BST, BAW devices and MEMS with an emphasis on 3-D architectures and power handling. In addition, the performance, requirements and market opportunities for very high-Q superconducting tunable filters will also be discussed. Techniques for temperature compensation and frequency tracking/control will be presented. Overall, there is approximately equal split among all technologies and a fair comparison is expected.

**Speakers:**

1. Kristi Pance, *M/A COM*  
“The benefits that reconfigurable filters will bring to base stations”
2. Christoph Ernst, *European Space Agency*  
“Tunable filters for flexible satellite payloads”
3. Gabriel Rebeiz, *University of California*  
“Distortion mitigation in tunable high-Q filters”
4. Balam Willemsen, *Superconductor Technologies Inc.*  
“Reconfigurable high temperature superconductor filters”
5. Robert York, *University of California*  
“Voltage-activated BAW devices”
6. John Papapolymerou, *Georgia Institute of Technology*  
“Electronically Tunable ferroelectric filters”
7. Pierre Blondy, *Université de Limoges*  
“High-Q tunable filters using RF-MEMS”
8. Dimitrios Peroulis, *Purdue University*  
“Power handling and monitoring issues in high-Q RF MEMS tunable filters”

## WMK (IMS)

Monday, 08:00 - 17:00

**RF MEMS for Antennas and Integrated RF Front End**

Reviewed by: MTT-14, MTT-16, MTT-21

**Organizers:**

John Papapolymerou, *Georgia Institute of Technology*  
Art Morris, *WiSpry*  
Hector De Los Santos, *NanoMEMS Research*  
James C. Hwang, *Lehigh University*

**Abstract:** RF MEMS technology has been under development for the last 15 years with primary emphasis on individual RF devices and circuits such as SPMT switches, tunable filters and phase shifters, as well as reliability and RF power handling issues. As the technology has matured and has started to be inserted in more complex and integrated RF systems, such as antenna arrays and RF front ends, there is increased interest in investigating new challenges that arise from MEMS integration into RF systems and antennas, including design, simulation and modeling. This workshop will highlight some of these issues to create awareness among circuit and system designers of the maturity and level of technology readiness of RF MEMS, as well as bridge the gap with a very important RF MEMS application area (antennas) that has never been presented as a stand-alone workshop at IMS.

**Speakers:**

1. J.C.M. Hwang, *Lehigh University*  
“Compact RF model for transient characteristics of MEMS capacitive switches”
2. Kartikeya Mayaram, *Oregon State University*  
“Accurate simulation of RF MEMS VCO performance including phase noise”
3. Raphael Mzyk, *University of Erlangen*  
“Modeling mechanical dynamics of MEMS self actuation and its application”
4. Andre van Bezooijen, *EPCOS*  
“Adaptively controlled RF-MEMS antenna tuners for hand-held applications”
5. John Maciel, *Radant MEMS*  
“RF MEMS Switches for Electronically Steerable Antenna Applications”
6. Aly Fathy, *The University of Tennessee*  
“Reconfigurable Antennas for Wireless Applications-examples, implementations, challenges”
7. Volker Ziegler, *EADS*  
“Reconfigurable antennas and RF-front ends on aeronautic and space platforms”
8. Nickolas Kingsley, *Auriga*  
“RF MEMS Antennas and Systems on Light Weight Organic Substrates”
9. Dimitri Peroulis, *Purdue University*  
“Real-time Reconfigurable Matching Networks for Miniaturized Antennas in Pulse-based Systems”
10. Art Morris, *WiSpry*  
“Integrated Tuning Technology for Antennas and Radio Front Ends”

**SC-1 Monday****08:00–17:00****Theory and Design of Phase Locked Loops****Instructors:**

L. Dayaratna, Lockheed Martin; Dean Banerjee, National Semiconductor; Cicero S. Vaucher, NXP Semiconductors; P. White, Applied Radio Labs; Ron Reedy, Peregrine Semiconductor

**Topics and Speakers:**

- Theory and Design of Phase Locked Loops, Lama Dayaratna, Ph.D., Lockheed Martin Commercial Space Systems, United States
- Phase locked loop Performance and Simulation, Dean Banerjee, Ph.D., National Semiconductor corporation, United States
- PLL System and Circuit Design for Microwave and mmWave Applications Cicero S. Vaucher, Ph.D., Edwin van der Heijden, and Juan Osorio, NXP Semiconductors, The Netherlands
- Modelling and Analysis of PLL Frequency Synthesizers, Peter White, Ph.D., Applied, Applied Radio Labs., Australia
- Recent Development in PLL Technologies, Ron Reedy, Ph.D., Peregrine Semiconductors corporations, United States

This one day design course, deals with the theory and design of phase locked loops for RF and microwave applications. The course provides an in-depth coverage of the design, analysis, simulation, and measurements of phase lock loop circuits. It is taught by several leading experts from industry

The course is developed as a laboratory hands-on course with live hardware and software demonstrations. The objective is to provide a state of the art review of phase locked loop design with special reference to low noise techniques. This PLL workshop is an intensive short course where the fundamentals of design, analysis, and modeling of phase lock loops will be covered. The following topics will be addressed in detail: Phase Locked loop design, Phase lock loop components, Voltage controlled Oscillators, Phase detector Circuits, Loop filter design, Loop characterization, Fractional- N synthesis, DDS, Multi Loop synthesis, Composite DDS/PLL solutions, Noise in Phase Locked loop circuits.

The phase locked loops have found widespread use in RF and Microwave applications. The dynamics of its operation, however, are quite complex and not surprisingly, the loops are too often incorrectly optimized. A badly designed loop can lock on wrong frequencies, not sufficiently reduce injected noise, can drop out of lock too easily. This workshop provides information on the design, simulation, applications, and product development of phase locked loops by several leading experts from industry. Many of the lectures rely on the use of live demonstrations involving test equipment and computer-based simulation tools to illustrate concepts. Attendees will have access to live 'hands-on' hardware and software demonstrations 'set-ups' during this one day session.

This course is an engineer's guide to planning, designing, and implementing phase locked loops for RF and microwave applications.

**SC-2 Monday****08:00–17:00****Low Phase Noise Oscillators: Lecture (theory and design) and Laboratory****Instructor:**

Jeremy K.A. Everard, BAE Systems/Royal Academy of Engineering Research Professor in Low Phase Noise Signal Generation, Department of Electronics, University of York, UK.

**Topics:**

- Oscillator phase noise theory
- Optimum operating conditions
- Flicker noise measurement and reduction
- Oscillator tuning and the effect on phase noise
- Generic design rules for low noise oscillators
- Oscillator designs: LC, Crystal, SAW, CRO, DRO
- Phase noise measurements: Phase detector and direct digital measurements
- Lab Class
  - Non contact measurement of Q0 and design of the resonator for correct QL/Q0
  - Simulate and measure the open loop resonator on PCB
  - Close Oscillator loop, measure phase noise and compare with theory

This full day course will present theory and design lectures in the morning and a lab class in the afternoon. The lectures will present the theory and design rules required to design low noise oscillators operating within 0 to 1dB of the theory. The course will include the latest state of the art techniques and results as well as the material required for a clear understanding of the underlying principles. Detailed design discussions will cover oscillators operating from 10MHz to 10GHz using, LC, Crystal, SAW, Ceramic (CR) and Dielectric (DR) resonators. A battery powered laboratory pack will be provided to enable the delegates to design, simulate, build and measure a 100MHz low noise oscillator. This pack will enable both fixed frequency and tuneable oscillators to be built. The delegates will be provided with a copy of the PowerPoint slides and a disk containing the specific Java Runtime software required for simulation of the resonator and the phase noise. Delegates should bring a laptop to the laboratory class. The latest test equipment will be provided by Agilent, Rohde & Schwarz and Symmetricom. Delegates can either attend this full day class including lab or just the morning theory/design class (see separate listing SC-2A); however, the number of delegates attending the full day class is limited.

Latest results using these techniques demonstrate -123dBc/Hz at 1Hz offset for a 10MHz SC cut crystal oscillator, -173dBc/Hz at 10kHz offset for a 1.25GHz DRO and -153dBc/Hz at 10kHz offset for a 4GHz DRO. This course was run at IMS 2009 for the first time last year and was very successful.

**SC-2A Monday****08:00–12:00****Low Phase Noise Oscillators: Lecture Only****Instructor:**

Jeremy K.A. Everard, BAE Systems/Royal Academy of Engineering Research Professor in Low Phase Noise Signal Generation, Department of Electronics, University of York, UK.

**Topics:**

- Oscillator phase noise theory
- Optimum operating conditions
- Flicker noise measurement and reduction
- Oscillator tuning and the effect on phase noise
- Generic design rules for low noise oscillators
- Oscillator designs: LC, Crystal, SAW, CRO, DRO
- Phase noise measurements: Phase detector and direct digital measurements

**Abstract:**

This half day course will present the theory and design rules required to design low noise oscillators operating within 0 to 1dB of the theory. The course will include the latest state of the art techniques and results as well as the material required for a clear understanding of the underlying principles. Detailed design discussions will cover oscillators operating from 10MHz to 10GHz using, LC, Crystal, SAW, Ceramic (CR) and Dielectric (DR) resonators. The delegates will be provided with a copy of the PowerPoint slides.

Dr. Jeremy K. A. Everard obtained his PhD from the University of Cambridge in 1983 and currently holds the BAE Systems/Royal Academy of Engineering Research Professorship in Low Phase Noise Signal Generation at the University of York, UK. He has been designing low noise oscillators for over 30 year at Marconi Research Laboratories, Philips Research, MA-COM, the Universities of London and York. A brief CV and recent publications are given on his Departmental web pages at: <http://www.elec.york.ac.uk/staff/jke1.html> . His personal web page is at: <http://www-users.york.ac.uk/~jke1/> . His group has now developed a number of designs offering the best performance available in the world. For example our: 10MHz SC cut crystal oscillators demonstrate -123dBc/Hz at 1Hz and -149dBc/Hz at 10Hz and our L band (1.25GHz) DR oscillators demonstrate -173dBc/Hz at 10kHz and -180dbc/Hz at 50kHz offset.

**SC-3 Monday****13:00–17:00****Microwave Packaging and Manufacturing 101****Organizer:**

Alan Lindner, L-3 Communications, Narda Microwave - West

**MTT Affiliation:** MTT-12**Topics and Speakers:**

- Accuracy of Package and Interconnect Simulation Models, HeeSoo Lee, Agilent
  - For microwave and millimeter-wave packaging and interconnects, there are many instances where distances are electrically short and that there are discontinuities. How to know when to rely on a linear model or when to perform a complete electromagnetic simulation will be discussed. The tradeoffs with speed and accuracy with such analysis will be explained.
- LTCC Substrates & Packaging Solutions, Paul Garland, Kyocera
  - Low temperature co-fired ceramic (LTCC) technology provides a unique solution for high interconnect density, compact networks and high frequency applications. Design guidelines will be presented on how to incorporate embedded passive components, route high density interconnects, define the thermal management requirements and assemble active devices.
- Multilayer High Frequency Laminates, Art Aguayo, Rogers Corporation
  - Use of high frequency laminates to construct microwave single and multilayer assemblies. The process in fabricating such material will be discussed explaining tradeoffs for electrical performance and assembly techniques.
- Materials and Metallization Schemes used in Thin Film Processing, David Adams, Applied Thin-Film Products
  - Thin Film technology provides a robust and highly accurate topology used in microwave products. The process steps will be discussed to help the design engineer better understand the construction. Design guidelines including materials and metallizations will be presented on how to have assemblies built to meet the electrical performance requirements and the cost objects.
- Accurate Testing and Calibration Techniques, Alan Lindner, L-3 Communications, Narda Microwave – West
  - An overview of the use of launches, probes and feedthrus. Also, how to choose the appropriate calibration and what accuracies can be achieved.

Packaging, assembly and test of most microwave and millimeter-wave devices are a challenging task. Issues arise with the material selection, modeling accuracy, assembly and testing. Most engineers are only aware of what techniques are implemented in their facility or rely on what the process engineer recommends. With a good understanding of the options, proper design choices can be made. This half day course will give the attendee an understanding of the construction processes and tradeoffs, and how best to model and test.

## FRIDAY WORKSHOPS

## WFA (IMS)

Friday, 08:00 - 12:00

**The Expanding Role of GaN in RF Systems**

Reviewed by: MTT-5, MTT-6, MTT-16

**Organizers:**

Jim Sowers, *Space Systems/Loral*  
Jay Banwait, *Northrop Grumman*

**Abstract:** Because of its unique properties, GaN is expanding into many different areas of an RF System. GaN's significant benefits of power density, efficiency, and bandwidth are well known with respect to power amplifier performance. A lesser known fact is the properties that enable these performance benefits for power amplifiers also provide advantages for other types of devices. As an example, control devices which manage signal flow or signal level in an RF system such as switches and limiters, as well as high dynamic range LNA's and oscillators, can benefit greatly from the high voltage breakdown property of GaN. The objective of this workshop is to help device, circuit, and system designers understand these benefits, the tradeoffs that come with them, and the status of these types of component developments. The workshop will conclude with a panel discussion in which the attendees will be asked to submit their questions and comments to the speakers.

**Speakers:**

1. James J. Komiak, *BAE Systems Electronic Solutions*  
"GaN HEMT Control, Termination, and LNA/Gain Block Components for Wideband Applications"
2. Shyh-Chiang Shen, *School of Electrical and Computer Engineering, Georgia Tech*  
"High-Voltage III-V Power Transistor Switches"
3. J.W. Milligan, *Cree, Inc.*  
"Commercial GaN Devices for Switching and Low Noise Applications"
4. Eli Reese, *TriQuint Semiconductor*  
"GaN MMICs for Control Components in RF Systems"
5. Rama Vetury, *RFMD*  
"GaN Applications Beyond the PA for RF Systems"

## WFB (IMS)

Friday, 08:00 - 12:00

**Wireless Power Transmission**

Reviewed by: MTT-5, MTT-16, IMS2010

**Organizers:**

Debabani Choudhury, *Intel Corporation*  
John A. Pierro, *Telephonics Corporation*

**Abstract:** While energy has become a hot topic nationally and internationally, wireless delivery of energy has also come into the spotlight in RF and wireless engineering. The dream of collecting a tiny percentage of the limitless energy emitted by the sun, converting it to electric power via low earth orbit collection/conversion stations and transmitting this energy to earth via very narrow high power microwave beams emanating from electrically large antenna arrays is something we all can appreciate and give credence to. In the consumer products market, several

academic and industrial organizations are investing in R&D of various wireless power technologies for fixed as well as portable devices in recent years. Examples include high-power resonant wireless energy link, wireless charging technologies and wireless powering of tiny sensors allowing remote battery-free powering and sensing. This workshop will bring together experts in the field who are exploring and refining techniques to transmit power without the use of wires.

**Speakers:**

1. Richard M. Dickinson, *Off Earth-WPT*  
"Wireless Power Transmission Retrospective of World's Record: Usefully Recovered Electric Power"
2. Shigeo Kawasaki, *Japan Aerospace Exploration Agency (JAXA)*  
"High Power Active Integrated Phased Array Antenna for Wireless Communication and Power Transmission"
3. Joshua Smith, *Intel Corporation*  
"Mapping the Space of Wirelessly Powered Systems"
4. Brian Otis, *Univ. of Washington*  
"Miniaturized Sensors Enabled by Wireless Power Transfer"
5. Jenshan Lin, *Univ. of Florida*  
"From Far-Field Wireless Power Transmission to Near-Field Wireless Charging"

## WFC (IMS)

Friday, 08:00 - 17:00

**Millimeter-Wave SiGe/CMOS and III-V Chips for Imaging Systems**

Reviewed by: MTT-4, MTT-6, MTT-16

**Organizers:**

Gabriel M. Rebeiz, *University of California, San Diego*  
Sorin Voinigescu, *University of Toronto; Vipul Jain, Sabertek*

**Abstract:** The workshop will present the latest advances in III-V, SiGe and CMOS chips for passive and active imaging systems. Recent advances in SiGe and CMOS designs have shown that it is possible to use silicon for millimeter-wave passive radiometers and active imaging systems. Several questions remain un-answered: what about the  $1/f$  noise in CMOS chips? Can SiGe and CMOS result in as low a NF as InP at 94 GHz? What about 45nm or 32nm CMOS? Does advanced digital functions placed on the same chip as the active imaging systems or passive radiometers result in improved performance? What is III-V doing to compete with this technology? The workshop will show the state of the art in Silicon and III-V passive and active chips and related imaging systems, and present an honest discussion on the pros and cons of silicon vs. III-V.

**Speakers:**

1. Erich Grossman, *NIST*  
"Imaging Systems at 100 GHz and Above for Security Applications"
2. Larry Yujiri, *Northrop Grumman Aerospace Systems*  
"An Introduction to Passive Millimeter-Wave Imaging"
3. Jonathan Lynch, *HRL Laboratories*  
"W-Band Sensors for Passive Millimeter-Wave Imaging"
4. Roger Appleby, *QinetiQ*  
"Passive Millimeter Wave Imaging Systems"



5. Michael Schlechtweg, *Fraunhofer Institute IAF*  
"Multifunctional ICs up to 350 GHz for Active and Passive Imaging Systems"
6. Gabriel Rebeiz, *University of California*  
"Millimeter-Wave SiGe ICs for Passive Imaging Systems"
7. Alexander Tomkins, *University of Toronto*  
"W and D-Band Passive Imagers in 65nm CMOS and SiGe HBT technology"
8. Toshihide Suzuki, *Fujitsu Laboratories*  
"W-band transceivers in InP HEMT and CMOS for Active/Passive Imaging Systems"
9. Payam Heydari, *University of California*  
"W-band passive imaging receiver ICs in (Bi)CMOS Technologies"
10. Ullrich Pfeiffer, *University of Wuppertal*  
"Terahertz Imaging with SiGe and CMOS Focal-Plane Arrays"
11. Koji Mizuno, *Tohoku University*  
"Millimeter-Wave Imaging through a Flame"

3. Zhizhang (David) Chen, *Dalhousie University*  
"Unification of Numerical Methods: Grid-based and Meshless"
4. Wolfgang J. R. Hoefer, *Institute of High Performance Computing*  
"Transient Wide-Band Modeling of Metamaterials and Cloaking Devices"
5. Wojciech Gwarek/Malgorzata Celuch, *Warsaw University of Technology*  
"Modeling and Simulation in Multi-physics Environments and Optics"
6. Natalia Nikolova, *McMaster University*  
"Electromagnetic Simulations Aiding Imaging and Detection with Microwaves"
7. Peter Thoma, *CST - Computer Simulation Technology AG*  
"Advanced Modeling of EM Problems by Using Coupled Simulations"
8. Poman So, *University of Victoria*  
"Computational Electromagnetics on Graphics Processors"

## WFF (IMS)

Friday, 08:00 - 17:00

### New Theories, Applications and Practices of Electromagnetic Field Simulators

Reviewed by: MTT-1, MTT-15

#### Organizers:

Zhizhang (David) Chen, *Dalhousie University, Canada*  
Poman So, *University of Victoria, Canada*

**Abstract:** Proliferation of electromagnetic simulators is having a profound effect on the way microwave engineers and researchers operate, as evidenced by the growing numbers of commercially available electromagnetic simulators and applications to a wide range of R&D areas such as microwave imaging and cloaking devices. Such new developments also create challenges for users and developers of electromagnetic simulators as well as researchers in computational electromagnetics in understanding and utilizing these developments. In this workshop, we will (a) provide insight into the operating principles and limitations of electromagnetic field simulators, (b) show how these principles are related to or translated into simulator parameters for practical applications, and (c) present recently developed theories, applications and practices pertaining to electromagnetic simulations: examples include the analysis of large complex problems using a combination of different approaches and techniques. This workshop be beneficial to (a) microwave engineers and researchers with circuit simulation experience who would also like to learn more about field-solvers, (b) students and beginners who would want to see what is involved in electromagnetic modeling and simulation, (c) users of electromagnetic simulators who seek a better understanding of theoretical and computational foundation, and (d) researchers and engineers who want to have more detailed knowledge of the recent developments and advanced applications of electromagnetic simulations. A discussion session is planned at the end of the workshop for interactions among all the participants.

#### Speakers:

1. Peter Russer, *Munich University of Technology*  
"Time-Domain Network Methods for Electromagnetic Field Modeling"
2. Costas Sarris, *University of Toronto*  
"Transformation Optics inspired Advances in Time-Domain Numerical Electromagnetics"

## WFG (IMS)

Friday, 08:00 - 17:00

### Emerging Optical Modulator Technologies for RF Photonics

Reviewed by: MTT-3, MTT-16, IMS2010

#### Organizers:

Ronald M. Reano, *Ohio State University*  
Dieter Jäger, *Universität Duisburg-Essen*

**Abstract:** The optical modulator is a central component for coupling RF signals with optical signals. A widely employed configuration involves coplanar waveguide RF electrodes proximity coupled to a guided wave Mach Zehnder optical interferometer incorporated on a substrate exhibiting 2nd order susceptibility (linear electro-optic effect). But what are emerging alternative methods to modulate an optical beam with a high-frequency signal? Specifically, what are alternatives to the linear electro-optic effect? Or, if linear electro-optic effect is used, what are alternative approaches to couple the RF signal to the optical signal. What performance metrics are enhanced, and which are degraded? Do these alternative approaches spawn ideas for new applications? This workshop will address these questions, focusing on novel concepts for optical modulators and the resulting application areas that emerge.

#### Speakers:

1. Ebrahim Mortazy and Ke Wu, *Ecole Polytechnique*  
"Substrate Integrated Waveguide Traveling-Wave Electro-Optical Modulators"
2. Lute Maleki, *OEwaves, Inc*  
"New directions in whispering gallery mode modulators"
3. Mani Hossein-Zadeh, *University of New Mexico*  
"Optical modulation using optomechanical interaction in high-Q microcavities"
4. Rod Waterhouse and Dalma Novak, *Pharad, LLC*  
"Photonically Integrated Antennas"
5. Hiroshi Murata, *Osaka University*  
"Electro-Optic Modulators Using Antenna-Coupled Electrodes and Polarization Reversed Structures"
6. Raluca Dinu, *GigOptix*  
"100 Gbps Electro-Optic Polymer Modulators"
7. Jaesang Oh and Anand Gopinath, *University of Minnesota*  
"Linearized Optical Directional Coupler Modulators"
8. Yifei Li, *University of Massachusetts*  
"Quadratic electro-optic phase modulator for frequency mixing"
9. Ronald M. Reano, *Ohio State University*  
"Dispersion engineering for RF-optical devices"

## WFH (IMS)

Friday, 08:00 - 12:00

**How to Start a Microwave Business**

Reviewed by: MTT-19, IMS2010

**Organizers:**

Fred Schindler, *RF Micro Devices*  
Mike Golio, *Golio Pubs*

**Abstract:** Much of the world is facing tough economic times producing turmoil in the ranks of microwave engineering professionals. This climate causes many engineers to consider taking on business risk that will be somewhat in their control as opposed to employment risk entirely in the hands of their employer. This workshop will examine the challenges several entrepreneurial working engineers have experienced in starting their own successful businesses and provide valuable advice to those just starting out or considering making that step. The workshop will also provide viewpoints from a venture capitalist describing requirements for a good business from their perspective.

**Speakers:**

1. Lamberto Raffaelli, *LNX Corp*  
"When you start a business it is all about cash flow: it is really true?"
2. Geoff Dawe, *BitWave*  
"The Venture Capital Path to Starting a RF/Microwave Company – An Entrepreneurs' Prospective"
3. Nitin Jain, *Anokiwave*  
"Anokiwave"
4. Wayne Boulais, *Apex Venture Partners*  
"Microwave Business – a VC perspective"

## WFI (IMS)

Friday, 08:00 - 12:00

**Practical Metamaterial RF and Antennas for Commercial Application**

Reviewed by: MTT-15, MTT-16, MTT-20

**Organizer:**

Maha Achour, *RAYSPAN Corporation*

**Abstract:** The air interface is an essential part of every radio and includes the antenna and the associated passive and active RF front-end components between the RFIC chip and air wireless access. But as standards have proliferated to include 3/4G cellular, WiFi MIMO, GPS, Bluetooth, WiMax and UWB, the air interface now presents some of the most challenging RF system integration problems facing the wireless industry. Because these standards require support of multiple radio bands, multiple signal modulation and multiple channels within bands, the size and spacing requirements make it challenging to meet specifications while maintaining adequate system performance. In the past two years, metamaterial-based solutions have been successfully adopted by the wireless industry and deployed in the market to meet stringent performance and size reduction requirements. This workshop will focus on practical passive and active metamaterial-based RF designs that address these emerging challenges facing the wireless industry.

**Speakers:**

1. George V. Eleftheriades, *University of Toronto*  
"The Transmission-Line Paradigm for Realizing Metamaterials: Fundamentals & Applications"
2. Tatsuo Itoh, *UCLA*  
"Applications of CRLH Structures for Active Microwave Circuits"
3. Christophe Caloz, *Polytechnique Montréal*  
"Recent Advances in Metamaterial Smart Antenna Concepts and Applications"
4. Richard W. Ziolkowski, *University of Arizona*  
"Multi-band Linear and Circular Polarized, Electrically Small, Metamaterial-inspired, Near Field Resonant Parasitic Antennas"
5. Carlos Camacho-Peñalosa, *Universidad de Málaga, Spain*  
"Active microwave distributed circuits inspired by Metamaterials"



Exhibit hours have been scheduled to provide maximum interaction between conference attendees and exhibitor personnel:

Tuesday, 25 May	09:00 to 17:00
Wednesday, 26 May	09:00 to 18:00
Thursday, 27 May	09:00 to 15:00

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Communications Equipment	C W Swift & Associates, Inc.	dBm	Ferro-Ceramic Grinding
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American Microwave Corp.	CAD Design Software	Design Workshop Technologies Inc.	Flexco Microwave Inc.
American Standard Circuits, Inc.	Cadence Design Systems, Inc.	Diablo Industries Thin Film	Florida RF Labs/EMC Technology
American Technical Ceramics	Cambridge University Press	Diamond Antenna & Microwave Corp.	Focus Microwaves Inc.
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 RH Laboratories Inc.  
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 Teledyne Microwave  
 Teledyne Relays  
 Teledyne Scientific Company  
 Teledyne Storm Products  
 Teledyne Technologies, Inc.  
 Telegartner, Inc.  
 Telnova Technology Co., Ltd.  
 Telogy LLC  
 Temp-Flex Cable Inc.  
 Temwell Corp.  
 TestEquity LLC  
 Thales Components Corp.  
 THINFILMS Inc.  
 Times Microwave Systems  
 TLC Precision Wafer Technology  
 Inc.  
 TMD Technologies Ltd.  
 Toshiba America Electronic Cmpts.  
 TowerJazz  
 TRAK Microwave Corp.  
 Trak Microwave Ltd./Farran Tech.  
 Transcom, Inc.  
 Trilithic Inc.  
 TriQuint Semiconductor  
 TRM Microwave  
 Tronser Inc.  
 TRU Corporation Inc.  
 TTE Inc.  
 Tyco Electronics Relay Products  
 Group  
 UltraSource Inc.  
 UMS (United Monolithic  
 Semiconductors)  
 University Booth  
 UTE Microwave Inc.  
 VACCO Industries  
 Valpey Fisher Corp.  
 Vectron International  
 Verspecht-Teyssier-Degroote  
 VIDA Products, Inc.  
 VidaRF  
 Virginia Diodes Inc.  
 Vishay Intertechnology  
 Voltronics Corp.  
 VTI Instruments Corp.  
 W.L. Gore & Associates  
 Wavenics, Inc.  
 Weinschel Associates  
 Wenzel Associates Inc.  
 Werlatone Inc.  
 West Bond Inc.  
 WEVERCOMM Co., Ltd.  
 Williams Advanced Materials  
 WIN Semiconductor Corp.  
 WIPL-D D.O.O.  
 Wireless Telecom Group  
 X5 Systems, Inc.  
 XMA Corp.  
 Ya Guang Electronics Co., Ltd.  
 Yantel Corp.  
 Ying Chuang  
   Microwave Electronics Co.,Ltd.  
 Z-Communications, Inc.  
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 Zeland Software, Inc.  
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# MICROAPPS

The MicroApps program features practical Application papers describing state-of-the-art products and processes of interest to the microwave community. This year's highlights include a keynote presentation by Dr. David Root of Agilent Technologies on nonlinear behavioral modeling Wednesday morning. There are also two tutorials on Wednesday evening, prior to the industry-hosted reception. MicroApps attendees will receive a free DVD of presentations sponsored by Agilent.

	Tuesday	Wednesday	Thursday
9:10	Design-Stage Thermal Analysis using Templates Shariar Motakef, Cape Sym, Inc.	High-Power Measurements using the Agilent Nonlinear Vector Network Analyzer Keith Anderson, Agilent Technologies	Practical Considerations in the Design and Implementation of RF and Microwave Signal Switching Solutions for ATE Walt Strickler, Giga-tronics Incorporated
9:30	Multi-chip Module Design Challenges Josh Moore, Dustin Hoekstra, AWR Corp.	An Introduction to Gallium Nitride (GaN) Device Characterization Steve Dudkiewicz, Maury Microwave Corp.	Test & Measurement Migration to Integrated Simulation, Test & Measurement for M&RF Design Christina Gessner, Sherry Hess, Rohde & Schwarz; AWR Corp.
9:50	How to Prevent MMIC/RFIC Packaging Integration Failures Hee-Soo Lee, Agilent Technologies	KEYNOTE: X-parameters: The Emerging Paradigm for Interoperable Characterization, Modeling, and Design of Nonlinear Microwave and RF Components and Systems David Root, Agilent Technologies	Fundamentals of Phase-Coherent RF Measurements David A. Hall, National Instruments
10:10	Nonlinear co-simulation with real-time channel measurements for PCB Signal Integrity Mike Heimlich, Khaled Nikro, Harry Momjian, Macquire University; AWR Corp.; Anritsu Corp.		Mobile Phone Testing using Impedance Tuner Roman Meierer, Steve Dudkiewicz, Maury Microwave Corp.
10:30	Causality Considerations for Multi-Gigabit StatEye Analysis Michael Heimlich, Scott Wedge, Ted Mido, AWR Corp.; Synopsys, Inc.		Improved Amplifier Testing Using Statistics BoB Muro, Wireless Telecom Group
10:50	Do Something Really Useful with VNA Time Domain Processing Don Metzger, Constant Wave	Redefine How You Measure & Simulate Nonlinear Devices Using X-Parameters™, Jack Sifri Agilent Technologies	Detailed comparison of dynamic range between a vector network analyzer and sampling oscilloscope based time domain reflectometer by normalizing measurement time Sho Okuyama, Agilent Technologies International Japan, Ltd
11:10	Unexpected Effects of Conductor Profile on the Propagation Constant in Rogers RO4000® LoPro™ High Frequency Laminates Allen F. Horn, III, Rogers Corp.	S-functions, the "S-parameters" for nonlinear devices Guillaume PAILLONCY, NMDG nv	Ultra-Fast Noise Parameter Measurements – 100x Faster and More Accurate Gary Simpson, Maury Microwave Corp.
11:30	Microwias for Microwave Applications in Cofired Ceramics Iris Labadie, Kyocera America, Inc.	A New Approach for Nonlinear Behavioral Modeling Darren McCarthy, Johannes Benedikt, Tektronix Inc.; Mesuro Limited	WinCal the Microwave Tool Leonard Hayden, Cascade Microtech, Inc.
11:50	Drop-on-demand Inkjet Printing of Functional Materials using the Dimatix Materials Printer DMP-3000 Jan Sumerel, FUJIFILM Dimatix, Inc.	Accurate Mixer Measurements Using Multi-tone X-parameter™ Models Mihai Marcu, Radek Biernacki, Agilent Technologies	Coaxial Measurements – Common Mistakes and Simple Solutions Sathya Padmanabhan, Rocky Teresa, Maury Microwave Corp.
12:10	Characterization Of Adhesive Films From kHz to GHz Dietmar Koether, Uwe Gollor, Joerg Berben, IMST GmbH		Application of second-tier VNA calibration with Cascade Microtech WinCal XE Craig Kirkpatrick, Cascade Microtech, Inc.
12:30	Advances in High Frequency Printed Circuit Board (PCB) materials used in Power Amplifier Applications John Coonrod, Rogers Corp.	A methodical approach to analyzing and understanding the performance of a LTE system Joel Kirshman, AWR Corp.	The challenges of the Nanoscale material and device characterization Hassan Tanbakuchi, Pavel Kabos, Agilent Technologies; NIST

Color Coding Key:

- High Power
- SW/signal processing
- Comp Modeling
- Materials CZ
- Phase Noise
- Wide bandwidth
- Test equipment/meas

# MICROAPPS

	Tuesday	Wednesday	Thursday
12:50	How to Save Money by Using Custom Designed GaAs MMICs Liam Devlin, Plextek Limited	Practical Digital Pre-Distortion Techniques for Linearization in 3GPP LTE Systems Jin-Biao Xu, Agilent Technologies	60 GHz Power Amplifier Design for Wireless HDMI (WPAN) Michael Thompson, Ken Mays, Agilent Technologies; TriQuint Semiconductor
13:10	System-Level Component Models for RF EDA Jiang Liu, Lawrence Dunleavy, Modelithics, Inc.	Wideband Linearization Allen Katz, Linearizer Technology, Inc	
13:30	Multi-Rate Harmonic Balance for Non-Linear Simulation Josh Moore, AWR Corp.	EMPIRE XCcel – Efficient solving of large scale EM problems Winfried Simon, A. Wien, IMST GmbH	
13:50	A Survey of Load-Pull Simulation Capabilities -- How Do They Help You Design Power Amplifiers? Andy Howard, Agilent Technologies	XFtdt 7 and Wireless InSite: Remcom's Multi-Physics Toolset Joseph J. Rokita, Remcom, Inc.	
14:10	PA Design Inclusive of Load-Pull Analysis Josh Moore, Dustin Hoekstra, AWR Corp.	When Should You Apply Planar EM Simulation? Andy Howard, Agilent Technologies	
14:30	Online Design Environment provide Interactive Datasheets for Small Signal RF Transistors – Allows Users to Generate Custom Datasheets for a Variety of Operating Conditions Sherry Hess, Uwe Knorr, Ronald Thissen, "AWR Corp.; Transim Technology Corp NXP Semiconductors"	Rapid 3-D Analysis of Multiple Design Configurations with HFWorks Hussam Maleh, Kousseil Ben Ahmed, ElectroMagnetic Works	
14:50	Using AWR's iFilter™ Mark Saffian, AWR Corp.	The Use of Computer Clusters and Spectral and Domain Decomposition in 3D FEM Analysis John DeFord, AWR Corp.	
15:10	Synthesis, design and high-power analysis of dual-mode filters with FEST3D Jordi Gil Raga, Carlos Vicente, Vicente Esbert Boria, Benito Gimeno, Aurora Software and Testing S. L.	Low Phase Noise Signal Generation and Measurement John S. Hansen, Agilent Technologies	
15:30	Creating and Tuning a Conformal Antenna with Remcom's XF 7 Software James F. Stack, Jr., Remcom, Inc.	Miniature low phase noise microwave opto-electronic oscillator (OEO) Danny Fung, Oewaves, Inc.	
15:50	Ultraminiature High Power RF Switch Werner Johler, Tyco Electronics	Pulse Generation and Analysis John S. Hansen, Agilent Technologies	
16:10	Silicon Technology Solutions for Wireless Front End Modules Alvin Joseph, Randy Wolf, Peter Rabbeni, Alan Botula, Dawn Wang, David Hareme, Jim Dunn, IBM Microelectronics	"Modern Methods for Fast And Accurate Frequency Converter Characterization" David Ballo, Agilent Technologies	
16:30	Single Chip LNA using high Q inductors on a Silicon-on-Sapphire process Duncan Widman, Andrew Greatbatch, AWR Corp.; Sapphicon Semiconductor	Down-Converting Ultra Wideband Track and Hold Circuits Mehran Mokhtari, Teledyne Scientific	
16:50		High Power Load Pull with X-Parameters – A New Paradigm for Modeling and Design Gary Simpson, Maury Microwave Corp.	
17:20		A Tutorial on Silicon Spiral Inductor Ground Return Effects on RFIC Design James Rautio, Sonnet Software, Inc.	

Color Coding Key:

High Power
SW/signal processing
Comp Modeling
Materials CZ
Phase Noise
Wide bandwidth
Test equipment/meas

## Historical Exhibit

While enjoying the latest technology and products in the exhibitor's hall, take a leisurely break and visit the Historical Exhibit in booth 3530. Here you will find some of the early groundbreaking inventions and microwave related items from the National Electronics Museum as well as contributions from companies in the Southern California area. As you reflect on the history of the items contained in this exhibit, you will be amazed how far technology has evolved from its humble beginnings and has revolutionized the microwave and communications industry into that which we know and enjoy today.



## SOCIAL EVENTS

### Sunday, May 23, 2010

#### **RFIC Reception — 19:00-21:00** **Anaheim Convention Center, Room 213BCD**

Immediately following the RFIC Plenary Session is the RFIC Reception to be held in adjacent ROOM 213BCD at the Anaheim Convention Center. This social event is a key component of the RFIC Symposium, providing an opportunity to connect with old friends, make new acquaintances, and catch up on the wireless industry. Admission is included with RFIC Symposium registration. Additional tickets can also be purchased separately at registration.

### Monday, May 24, 2010

#### **IMS 2010 Welcome Reception — 18:00-20:00** **Hilton Hotel, Sunset Deck**

All Microwave Week attendees and exhibitors are invited to attend a reception hosted by IMS 2010.

### Tuesday, May 25, 2010

#### **Special Luncheon for Chuck Swift — 12:00-14:00** **Anaheim Convention Center, Rooms AR1 & 2**

The IMS 2010 will hold a Special Luncheon on May 25, 2010, to celebrate Chuck Swift's 52 years of service in support of the Los Angeles Chapter of the Microwave Theory and Techniques Society. The chapter has sponsored monthly technical meetings since 1952 and periodic national/international 3-5 day meetings since 1970, such as the IMS meeting being held in Anaheim on May 23-28, 2010. Chuck formed his business, C. W. Swift & Associates, in July 1958. Since 1958, Chuck, his business and his family have supported 450 meetings and 7 IMS symposia. IMS 1989 stands out as the best performance, where Chuck put on a show of shows. The Luncheon will be held on Tuesday May 25 from 12:00 (noon) to 2:00 pm, in the Convention Center, in Rooms AR1 & 2 (near the Arena). The Luncheon is a full sit-down lunch. Admission is \$35.00 per person; sign-up is through the IMS 2010 Registration.

#### **Women in Microwave Engineering (WIM) Reception — 17:30-19:30** **Uva Bar, 1580 Disneyland Drive, Downtown Disney**

Meet with old friends as well as make new connections to the growing community of women who make a career in the field of high-technology. Enjoy good food, cool beverages and warm conversation at the WIM Social Event. Join us at the outside patio area of the Uva Bar in the center of the Downtown Disney entertainment district.

#### **Student Reception — 19:00-21:00** **Hilton Hotel, Room California B**

Mix and mingle with fellow students from across the globe!

#### **Ham Radio Social — 18:00-21:00** **Hilton Hotel, California A**

While enjoying a buffet and open bar, the attendees will have the opportunity to see the accomplishments of amateur radio operators who have skillfully designed and built transceivers for use from VHF to high millimeter wave bands. Some of these transceivers were made from surplus and commercially available components and some are state-of-the-art new designs including SDR. Several will be on display and their builders will be there to answer questions.

All conference attendees are welcome. You will find that amateur radio operators are utilizing their allocated frequency spectrum for very important uses and you may be interested in obtaining your license so you too can test your new designs and microwave propagation.

### Wednesday, 26 May 2010

#### **Industry Hosted Cocktail Reception — 17:00-18:00** **Anaheim Convention Center Exhibition Floor**

Symposium Exhibitors will host a cocktail reception.

#### **MTT-S Awards Banquet — 19:00-22:00** **Hilton Hotel, California Room**

The MTT-S Awards Banquet includes a fine dinner, major society awards presentation, and entertainment. This year's entertainment will be provided by String Theory. String Theory is an exceptional music performance drawing on the very space of the performance by transforming architecture into musical instruments and then playing the building. The result is a visually stunning landscape in which the performance unfolds. Tickets can be purchased at the time of registration.

### Thursday, 19 June 2010

#### **MTT-S Student Awards Luncheon — 12:00-14:00** **Hilton Hotel, California B**

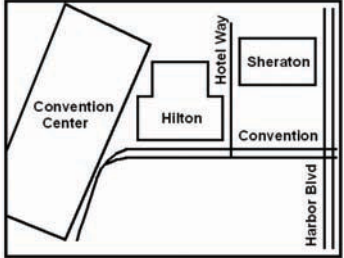
All students are invited to attend this luncheon which recognizes recipients of the MTT-S Undergraduate Scholarships, MTT-S Graduate Fellowships, IMS2010 Student Volunteers, IMS2010 Student Paper Awards, and the winners and participants of the IMS2010 Student Design Competitions.

#### **MTT-S Graduates of the Last Decade (GOLD) Reception — 17:30-19:00** **300 Anaheim**

The IEEE MTT Graduates of Last Decade (GOLD) Committee invites all MTT GOLD members to a complimentary reception at 300 Anaheim. This will be an excellent opportunity not only to relax and entertain, but also to interact and network with other GOLD members.

# HOSPITALITY SUITE

Enjoy Southern California hospitality by joining us in the Hospitality Suite in the Garden Room of the Sheraton Hotel. Grab your guest badge and come have breakfast in the morning or snacks later in the day. Meet friends, make friends, kick back and relax. There will be a special area for children with toys and games. Guest Tours will depart from the Hospitality Suite. Don't forget to bring your swim gear, as guests will have access to the pool at the Sheraton Park during the hours the Hospitality Suite is open.



Open Sunday, May 23 through Thursday, May 27 7:30am to 3:30pm

# RECREATIONAL ACTIVITIES

Registration for all the guest tours will be available on line at <http://www.pra-tours.com/IEEE> and in the Hospitality Suite at the Sheraton Park.

## LOS ANGELES COUNTY MUSEUM OF ART, PETERSEN AUTOMOTIVE MUSEUM & LA BREA TAR PITS Sunday, May 23, 2010



**Suggested Itinerary:**

- 10:00 AM Depart Sheraton Park Hotel
- 11:30 AM Arrive LACMA and Petersen – Free time to explore both museums
- 1:30 PM Lunch at LACMA
- 2:30 PM Arrive Page Museum and La Brea Tar Pits- guided tour
- 4:00 PM Depart Museum
- 5:30 PM Return to Sheraton Park Hotel

**Time:** 10:00 AM – 5:30 PM  
**Price:** \$125.00 per person

Explore a collection with more than 100,000 works of art at LA CMA, the largest encyclopedic museum west of Chicago. Through its far-reaching collections, the museum is both a resource to and a reflection of the many cultural communities and heritages

in Southern California. Highlights include European masterpieces, cutting-edge contemporary art, an extensive collection of American art from the United States and Latin America, a major Islamic art collection, one of the most comprehensive Korean art collections outside of Korea, and the stunning Pavilion for Japanese art.

Across the street is the Petersen Automotive Museum, where imagination drives guests from memory lane to the fast lane, and destinations beyond. The Petersen Automotive Museum is dedicated to collecting, preserving and interpreting the role of the automobile and its technology in shaping American culture. It is the largest and most innovative automotive museum in the world.

Concluding the tour guests are treated to views of one of the world's most famous Fossil sites found in the heart of Los Angeles, The La Brea Tar Pits. The tar pits were formed about 12,000 years ago by layers of soil that built up into sedimentary formations. Eventually, heat and pressure sent oil oozing through cracks in this sediment. As the water began to dry up, the oil turned into sticky asphalt, imprisoning animals which had come to drink or prey on those already stuck. The bones of all these animals were eventually covered by asphalt. Water brought more sediment, causing a buildup. All this was bad for the animals, but good for scientists who have dug up more than one-million fossils representing 4,000 mammals and 126 types of birds. Among the fossils discovered were the bones of a twenty-five to thirty-year-old woman, dubbed "La Brea Woman." Carbon-dating indicated the woman died about 9,000 years ago.

A visit to the George C. Page Museum of La Brea Discoveries gives a picture of the diversity of Ice Age life in Southern California. The Rancho La Brea fossils that are exhibited and stored in the museum are a unique natural resource . . . a window into the life of the past.





## RECREATIONAL ACTIVITIES

### NEWPORT HARBOR CRUISE Sunday, May 23, 2010



**Suggested Itinerary:**

- 1:30 PM Depart Sheraton Park Hotel
- 2:00 PM Newport Harbor Cruise
- 2:45 PM Free time to explore Balboa Island
- 4:00 PM Board coach and depart for hotel
- 4:30 PM Return to Sheraton Park Hotel

**Time:** 1:30 PM – 4:30 PM  
**Price:** \$64.00 per person

Welcome to the Newport Beach, one of Southern California’s most vibrant recreation and entertainment centers. Famous worldwide for its picturesque sandy beaches, majestic coastline, infinite recreational activities, award-winning dining and world-class shopping, Newport Beach is more than a sophisticated beach town - it’s a way of life.

Guests are treated to a cruise along Newport Harbor. Newport Harbor is home for yacht clubs, beachfront mansions, and sportfishing fleets. Film crews in the silent screen era used its beautiful coastline to double as a Caribbean pirate’s hidden cove. Today, Newport is one of California’s busiest harbors, filled with dozens of colorful sailboats and majestic yachts.

As an added enhancement, following the harbor cruise, free time has been allotted for guests to explore quaint Balboa Island with its one of a kind boutique shops, beautiful homes, and their infamous frozen banana!

### QUIET ON THE SET! Monday, May 24, 2010

**Suggested Itinerary:**

- 9:00 AM Depart Sheraton Park Hotel
- 9:45 AM Arrive Warner Bros. Studio
- 10:00 AM Watch film on the Studio’s history
- 10:30 AM Docent guided tram tour
- 12:45 PM Lunch at Warner Brothers cafeteria Commissary
- 1:45 PM Depart Warner Bros. Studio
- 2:30 PM Return to Sheraton Park Hotel

**Time:** 9:00 AM – 2:30 PM  
**Price:** \$138.00 per person

Built in 1919, Warner Bros. Studio was the first Hollywood studio to introduce sound. This event occurred in 1927 with its production of “The Jazz Singer,” starring Al Jolson.

The tour begins with a short film showcasing the movies and television shows created by Warner Bros. talent over the years. Guests are then escorted via tour carts to the Warner Bros. Museum - a true archive of filmed entertainment history. Exhibits include costumes, props, awards and actual scripts from some of their most renowned productions. From the Museum, guests will visit our backlot sets, sound stages and craft/production shops - routes change from day to day to accommodate production on the lot, so no two tours are exactly alike.

As guests tour the studio on the VIP tour cart, anything can happen - perhaps a celebrity sighting, or a shoot just wrapping on an exterior set! They may pull into New York Street - location for such television hits as ER, but originally constructed in the 1930s for the film noir classics. Or visit Midwest Street - Warner Bros.’ answer to “Any Town USA” - made famous in the musical A Music Man. If the timing is right, guides will take guests onto a sound stage to see the set of a current Warner Bros. show! Guests may also visit “The Mill”, home to craft shops since the 1930’s; the costume or prop warehouses; or maybe enter the Foley stage for a demonstration of how sounds are recreated for film.



## RECREATIONAL ACTIVITIES

### A PRESIDENTIAL PEEK Monday, May 24, 2010



#### Suggested Itinerary:

1:00 PM	Depart Sheraton Park Hotel
1:30 PM	Docent guided tour of the Nixon Library, based on (2) hours
3:30 PM	Free time on own at the Nixon Library
4:30 PM	Depart the Nixon Library
5:00 PM	Return to Sheraton Park Hotel

**Time:** 1:00 PM – 5:00 PM

**Price:** \$60.00 per person

The story of our times is told in unforgettable fashion at the Richard Nixon Library & Birthplace. The library opened its doors on July 19, 1990. This privately supported, non-profit institution is dedicated to educating the public about the life and times of the 37th President and encouraging interest in history, government and public affairs.

The nine acre Library & Birthplace is a three-dimensional walk-through memoir featuring a 52,000 square foot museum. Exhibits include the "Structure of Peace" exhibit, which highlights President Nixon's foreign policy breakthroughs and a piece of the Berlin Wall that serves as a stark reminder of the danger of totalitarianism. Another featured gallery is the "Hall of World Leaders", where 10 life-sized bronze figures of postwar titans, from Churchill to Mao are on display, with priceless gifts presented to President and Mrs. Nixon by heads of state and governments from around the world. The Watergate Gallery is the largest exhibit dedicated to a single subject. It describes Watergate as a political struggle between Nixon and a Democratic Congress which ad strongly opposed the Administration's policies in Vietnam during his first term. Visitor's can listen to key portions of the so-called "smoking gun" conversation from June 23, 1972, in which the President is first given John Dean's idea for covering up Watergate.

In addition to the Library site is the faithfully preserved boyhood home of the 37th President, built by President Nixon's father in 1912, decorated with original furniture, including the bed, in a closet-sized room, where Richard M. Nixon was born. Rounding out the Library & Birthplace site are nine flower-drenched acres including Orange County's largest public rose garden. The President and Mrs. Nixon's memorial is also located at the library. President Nixon's gravestone reads: "Even when people can't speak your language, they can tell if you have love in your heart."

### IN VINO VERITAS - WINE COUNTRY OF TEMECULA Date: Tuesday, May 25, 2010

#### Suggested Itinerary:

8:15 AM	Depart Sheraton Park Hotel
9:45 AM	Ponte Winery
11:45 AM	Free time in the Visitor's Center
12:15 PM	Depart Ponte Winery
12:30 PM	Lunch and tasting at Wilson Creek Winery & Vineyards
2:30 PM	Free time in Visitor's Center
3:00 PM	Depart Temecula
4:30 PM	Return to Sheraton Park Hotel

**Time:** 8:15 AM – 4:30 PM

**Price:** \$140.00 per person

The magic ingredients of soil, climate, and skill combined in an effort to make great wines are hard to find or duplicate. Just east of Orange County is one of America's most beautiful and bountiful wine countries . . . Temecula.

Guests sample this grand panorama and learn the history and legends that truly make California the Golden State while touring two of the most popular wineries and tasting the products of their labors.

The Ponte Family Estate Winery is one of Temecula's most appealing wineries. The Ponte family, who has been growing grapes in Temecula since 1984 opened the winery in May of 2003 right in the heart of Temecula Valley Wine Country. The journey began back in 1984 when the Ponte Family purchased over 500 acres of Cabernet, Merlot, Chardonnay, Zinfandel and Sauvignon Blanc vineyards. At first the Ponte Family sold the fruit to other California wineries but now they are proud to offer a full array of wines under the Ponte label. Guests will make their first stop here at Ponte Winery and will enjoy a private tour and have the chance to experience wine right from the barrel in the Barrel Room.







## RECREATIONAL ACTIVITIES

Wilson Creek Winery – Three generations of the Wilson family participate in running the winery, making it truly a family endeavor. Gerry and Rosie got their start in winemaking thirty years ago, making rhubarb and dandelion wines in tubs beside the sauna in their Minnesota basement. What was once a hobby is now their full-time passion. After retiring, the Wilson’s purchased the twenty-acre vineyard on winery row in Temecula in 1996. It truly was a diamond in the rough. A seasonal creek fronting the property was dubbed “Wilson Creek”. Today, visitors benefit from all their hard work by enjoying picnics surrounded by Rosie’s elegant flower gardens. Work on the winery building itself was completed in 1999. Gerry can usually be found behind the tasting bar, pouring wines, sharing stories, and making people feel welcome. If not behind the tasting bar herself, Rosie is usually hard at work in her beautiful flower gardens, which adorn the property.

The serenity and beauty of the Temecula region combined with a visit to these wineries make this a relaxing, informative and tasty day.

Today, acquire a very special insight into the world of art as guests explore some of the city’s premier galleries where they find art for sale to suit every taste, décor and budget.

One of Laguna’s foremost artists accompanies guests on their “art walk” giving them an insight into the world of art, which is the very heart of Laguna.

Following a gallery tour, guests have free time to explore the quaint specialty shops and seaside boutiques that offer bargain shopping with an ocean view, explaining why many feel Laguna Beach is a shopper’s paradise. Shopping is concentrated in a charming area along Pacific Coast Highway near Main Beach and Forest Avenue. Quaint shops, antique galleries, art studios and boutiques offering the latest in designer fashions abound. Browse and shop at your own pace, then take a few minutes to kick off your shoes and enjoy a leisurely stroll along the shore!

### BRUSHSTROKES OF LAGUNA Tuesday, May 25, 2010



**Itinerary:**

- 10:30 AM Depart Sheraton Park Hotel
- 11:00 AM Art walk with local artist, based on (1½) hours
- 12:30 PM Free time for browsing and shopping in Laguna Beach
- 2:00 PM Depart Laguna Beach
- 2:30 PM Return to Sheraton Park Hotel

**Time:** 10:30 AM – 2:30 PM  
**Price:** \$96.00 per person

### THE GLITZ AND GLAMOUR...AN INSIDE LOOK Wednesday, May 26, 2010



**Suggested Itinerary:**

- 10:00 AM Depart Sheraton Park Hotel
- 11:00 AM Arrive Hollywood, begin Historic Hollywood tour
- 12:15 PM Tour ends – free time in Hollywood
- 1:00 PM Depart Hollywood
- 1:15 PM Lunch at uWink
- 2:15 PM Free time on Rodeo Drive
- 3:30 PM Depart for Hotel
- 4:30 PM Return to Sheraton Park Hotel

**Time:** 10:00 AM – 4:30 PM  
**Price:** \$108.00 per person

The tour begins on the motorcoach ride into Hollywood, where a guide gives guests a brief history of Hollywood and an overview of the tour. Once in Hollywood, the one-hour walking tour includes inside looks at some of Hollywood’s most well known movie palaces, including Disney’s El Capitan Theater, Grauman’s Egyptian Theatre,

## RECREATIONAL ACTIVITIES

and Grauman's Chinese Theatre, as well as some lesser-known but equally important landmarks. Additionally, the "live audio" system allows guests to hear the tour over extreme city noise. Each guest wears an audio headset and the tour guide speaks into a microphone, so guests don't miss any information while looking around.

Lunch at uWink - Guests will enjoy lunch at the hippest and newest dining experience, uWink! This interactive restaurant will truly give your guests the ultimate unique diner is all about the latest in technology. Order from a touch screen, play games with those sitting around you and see your group feel special and welcomed with custom signage and screen boards.

Following lunch, guests have free time on Rodeo Drive in Beverly Hills. Few areas in the world can compete with Beverly Hills for luxurious, exclusive, and expensive shopping. Window displays drip with diamonds, evoke scenes of extravagant elegance, hint at lifestyles most people can only dream about. Rolls-Royces, Bentleys, Mercedes Benzes, and other luxury cars arrive at roadside valet-parking stations. The rich and famous, clad in attention-getting attire, stroll casually along. Even if you can't afford one thing that's on display in the fabulous shops (and that's unlikely, because even the most pricey boutiques carry reasonably priced gift items), a visit to Rodeo Drive is a must!

### WINDOWS OF DISCOVERY AT BOWERS MUSEUM Wednesday, May 26, 2010



#### Suggested Itinerary:

11:15 AM	Depart Sheraton Park Hotel
11:30 AM	Free time at Bowers Museum
1:30 PM	Depart the Bowers Museum
1:45 PM	Return to Sheraton Park Hotel

**Time:** 11:15 AM – 1:45 PM  
**Price:** \$60.00 per person

Step into a world of mystery, adventure, power, and magic. It's a world where Africans transform the harshest surroundings into the most graceful art, ancient mariners settle the wild islands of the Pacific with the aid of spirits and dreams, and the native peoples of our vast continent commune with nature to forbear the rise and fall of powerful empires. Discover the Bowers Museum of Cultural Art . . . a place where art can communicate both the diversity and the unity of human experience.



#### Temporary Exhibitions

Where Masks Still Dance  
December 26, 2009 - June 6, 2010

Masters of Adornment: The Miao People of China  
November 15, 2008 – ongoing

#### Permanent Collections at Bowers Museum

#### ART OF ADORNMENT: TRIBAL BEAUTY

Tribal art represents the art of the world's indigenous people. In many of these indigenous cultures, there isn't a word for "art." Instead, there is an inherent aesthetic incorporated into the people's daily life. This can be seen in all aspects of their life from preparation of food, hunting and warfare, ceremony and religion, and in the way they enhance their appearance in body adornment. "Art of Adornment: Tribal Beauty" will feature 70 rare and spectacular treasures and will focus on the tribal aesthetic of body adornment from indigenous peoples around the world.

Relive the adventures, hardships, and triumphs of early California settlers from the days when Native Americans lived in harmony with the land, to the fierce Spanish conquest and the frenzy of the great California Gold Rush. As part of the permanent collections, California Legacies takes a fascinating look at the people and events that helped shape today's Orange County and the Southwest.



## RECREATIONAL ACTIVITIES

Following on the heels of Treasures From Shanghai: 5000 Years of Chinese Art and Culture, the Bowers is drawing on its own collections, and the curatorial expertise of the world renowned Shanghai Museum, to maintain the Shanghai theme in this now permanent exhibition called, Arts of Ancient China.

### LANDMARKS OF LONG BEACH Thursday, May 27, 2010



**Suggested Itinerary:**

- 8:45 AM Depart from Sheraton Park Hotel
- 9:15 AM Arrive Aquarium of the Pacific Self Guided Tour
- 10:45 AM Depart for Queen Mary
- 11:00 AM Arrive Queen Mary Self Guided Tour
- 12:00 PM Lunch at Promenade Cafe
- 1:30 PM Ghost and Legends Show
- 2:15 PM Board coach and depart for hotel
- 2:45 PM Return to Sheraton Park Hotel

**Time:** 8:45 AM – 2:45 PM

**Price:** \$135.00 per person

The Aquarium of the Pacific tells the story of the Pacific Rim and the vast and populous sea that covers nearly half of the planet. Over 17 major exhibit tanks, 30 smaller focus tanks, one million gallons of sea water, and more than 10,000 denizens of the Pacific Ocean, representing over 550 different species are showcased.

The endless wonders of the world’s largest, deepest and most astonishing ocean come to life at the Aquarium of the Pacific.

Come aboard the legendary Queen Mary, the most elegant ocean liner afloat. Built with all the pride of Great Britain’s seafaring tradition and presented to the world as

a standard of luxury and craftsmanship unequalled in shipbuilding history, she is as beautiful today as when she first set sail in 1936.

Guests have the opportunity to explore this majestic ship and discover her rich past from engine room to wheelhouse. A tour of the R.M.S Queen Mary includes newly restored areas that have been under wraps since the final voyage in 1967 and examines her life as both a World War II troopship and luxury liner. They also experience “Ghosts and Legends of the Queen Mary”, an interactive, state of the art, special effects attraction that blurs the line between what’s real and what isn’t.

### SECRETS OF THE SEA Thursday, May 27, 2010



**Itinerary:**

- 9:00 AM Depart Sheraton Park Hotel
- 9:30 AM Arrive at Crystal Cove

- Beach Walk
- 11:30 AM Board coach and depart for hotel
- 12:00 PM Return to Sheraton Park Hotel

**Time:** 9:00 AM – 12:00 PM

**Price:** \$97.00 per person

Crystal Cove State Park offers three and a half miles of unobstructed pristine beach and remains the most natural beach in Orange County. Miles of beautiful coastal bluffs support healthy strands of coastal sage scrub habitat along with blooming seasonal native flowers and shrubs. Trails meander along the bluffs and lead down to the beach. A strong wildlife population includes coyotes, squirrels, raccoons, rabbits, deer, bobcats, opossum, hawks and a variety of inland and coastal birds.

Walking along coastal bluffs through a mosaic of native plants, guests enjoy a panoramic overview of the sparkling Pacific Ocean. As guests descend the trails onto the beach, they are amazed to learn about the sophistication of dolphin societies, whose members are often seen playing in the waves. Guests learn how dolphin schools operate, how they call each other by name, the elaborate games they play and the advanced echolocation system that allows dolphins to picture their world in virtual reality even in the dark. Guests also learn about the birth and death of a wave, whose “life” may have begun continents away.

On the beach, guests explore what a forty-ton gray whale has in common with a two-ounce hummingbird and what the difference is about their annual 2,000 to 10,000 mile migrations.

A unique Southern California experience!

**THE GETTY CENTER**  
**Friday, May 28, 2010**

**Suggested Itinerary:**



- 9:30 AM Depart Sheraton Park Hotel
- 10:30 AM Self-guided tour at the Getty Center, based on (3) hours Lunch on Getty Center lawn
- 1:30 PM Depart the Getty Center
- 2:30 PM Return to Sheraton Park Hotel

**Time:** 9:30 AM – 2:30 PM  
**Price:** \$81.00 per person

As the crowning jewel of the J. Paul Getty Trust, the original museum was created entirely for the benefit of the public, and is devoted to the visual arts. The Getty Museum began as a Romanesque villa in the secluded mountains of Malibu, displaying its permanent, ornate collection of Greek and Roman antiquities, pre-twentieth century European paintings, drawings and sculpture, as well as decorative arts.

The Getty Museum was transformed into the much-anticipated J. Paul Getty Center, a 110-acre, six-building comprehensive art complex situated in the Santa Monica Mountains. The exhibits have expanded from its European roots to reflect the creative and cultural dynamics of art around the world, incorporating ancient and modern works of Latin America, Africa and the Far East in captivating, constantly changing exhibits. The Getty Center has also become an interactive, state-of-the-art research and educational facility for art students and enthusiasts of all ages. The grounds consist of elaborate gardens and sweeping

views, such as the Central Garden, which is an ever-changing work of art filled with the color, sound and light of nature.





## GOLF COURSE DESCRIPTIONS

To those who wish to enjoy the links of Southern California, the Anaheim / Orange County area offers something to fit any golfer's skill. While a formal golf outing is not part of the official recreation schedule, we can certainly assist those interested in finding a course to suit their needs. There are plenty of choices within a ten mile radius; Anaheim Hills, Dad Miller, Tustin Ranch, Coyote Hills, and Black Gold just to name a few.

If you have the time & inclination to test your swing while attending IMS2010 please let us know. Contact Philip Arnold, philip\_arnold@ieeee.org, cell 818-808-8315. He will be delighted to assist in getting you headed in the right direction. If there's enough interest in heading out early morning (before 9:00 a.m.) on Monday the 24th it might be possible he can set up a group outing to one of the local courses. Each individual would be on their own for green fees, clubs, transportation, etc. but he can assist in making the logistics less cumbersome. For a complete listing of the local courses check out the URL <http://www.playocgolf.com/>

Enjoy IMS2010 and your stay in So Cal.

### Anaheim Hills

Anaheim Hills is located just 20 minutes from Disneyland and rests in enchanting, old California terrain, featuring incredible vistas and cool valleys, with a natural stream flowing past stands of oaks and sycamores. Richard Bigler designed the 6200 yard par 71 layout. Combine all this with very affordable green fees and you have the best golf value in Orange County.

Call the golf shop up to seven days in advance for reservations 714-998-3041.

Well maintained and price friendly, Dad Miller Golf Course in Anaheim has become a popular destination for players of all ages and abilities. The par 71, 5900 yard course features a lake, with lovely trees surrounding the fairways, and can be easily walked. Tiger Woods used to play the course while he was in high-school.

Reservations can be made up to seven days in advance by calling 714-765-3481.

### Tustin Ranch Golf Club

Tustin Ranch Golf Club is a championship course designed by famed architect Ted Robinson. The par 72, 6800 yard layout offers breathtaking scenery, sparkling lakes and cascading falls. It was recently voted the "Best Orange County Golf Course 2009" by the readers of the Orange County Register. In addition, Tustin Ranch is a multiple-year, 4-Star recipient of Golf Digest Magazine's "Places To Play".

For reservations up to seven days in advance call 714-730-1611.

### Mile Square Golf Course

Mile Square Golf Course in Fountain Valley has been one of the top rated public courses in Orange County since it opened in 1969. Both the Players and Classic Courses, designed by David Rainville, have the reputation for outstanding greens that are consistently ranked among the best in the county and have become a "must play" for anyone in the area.

For reservations up to seven days in advance call 714-968-4556 or 714-545-7106.

### Coyote Hills

Coyote Hills in Fullerton was designed by Cal Olsen and golf legend Payne Stewart. The par 70, 6500 yard layout is tucked away in the foothills of Orange County amongst 250 acres filled with streams and gnatcatchers and coyotes. The scenic terrain will challenge even the most experienced players.

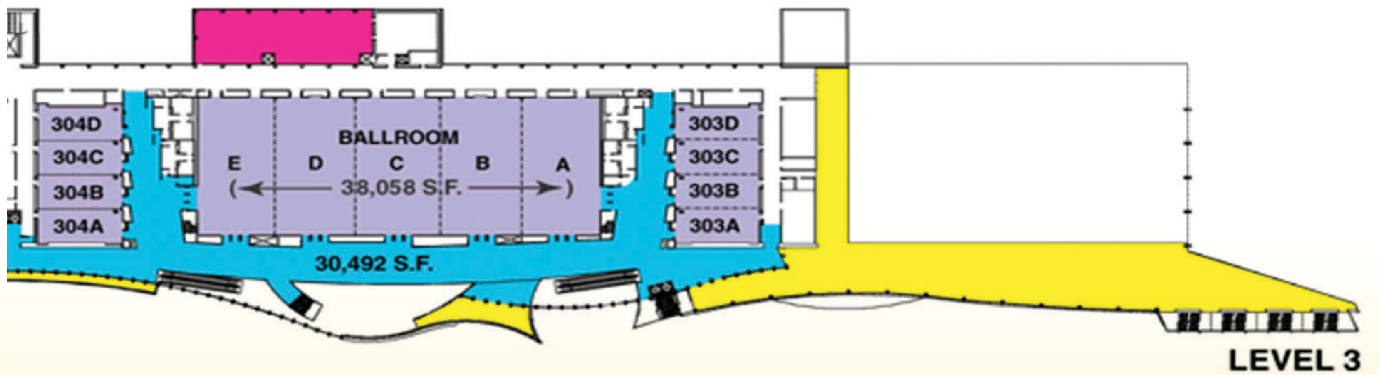
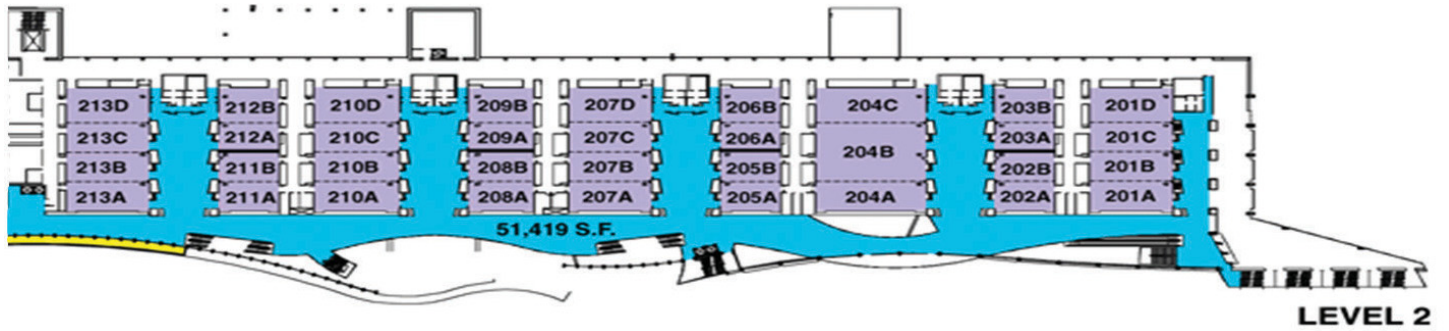
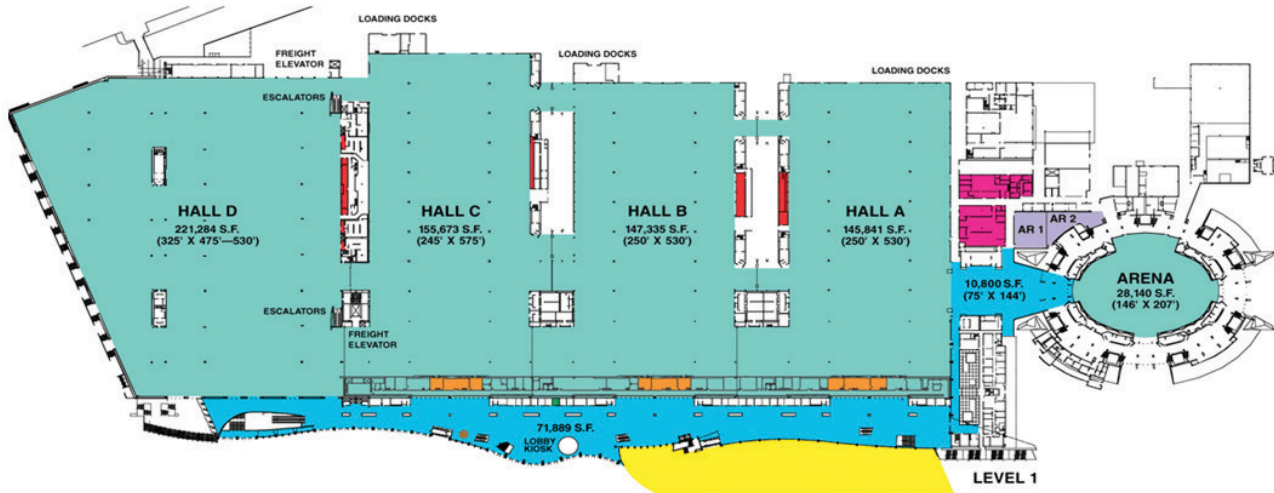
For reservations up to seven days in advance call 714-672-6800.

### Black Gold Golf Club

Black Gold Golf Club in Yorba Linda is a favorite of Orange County Golfers. Arthur Hills designed this par 72 layout which stretches up to 6756 challenging yards. Incorporating several design features which include a stunning waterfall off the 18th green, slight elevation changes, rolling hills, strategic bunkering and the incredible vistas overlooking coastal Orange & Los Angeles Counties. Recently rated 4.5 stars by Golf Digest.

Call 714-961-0060 to reserve a tee time up to seven days in advance.

# CONVENTION CENTER MAPS





**ANAHEIM**  
 ORANGE COUNTY  
 VISITOR & CONVENTION BUREAU

**Restaurants**

- 1 18 Fifty Bar and Grill
- 2 Agio Ristorante
- 3 Baja Fresh/Mix Restaurant
- 4 Sbarro/Frozen Assets Yogurt
- 5 Café Del Sol
- 6 Coyo's Bakery Restaurant
- 7 Disney's PCH Grill
- 8 Garden Court Bistro
- 9 Goofy's Kitchen
- 10 Hook's Pointe & Wine Cellar
- 11 IHOP
- 12 JW's Steakhouse
- 13 K'ya Anaheim
- 14 McDonald's
- 15 Mimi's Cafe
- 16 Molly's Kitchen
- 17 Morton's The Steakhouse
- 18 Napa Rose
- 19 Overland Stage Southwestern Grill & BBQ Company

- 20 Ruth's Chris Steak House
- 21 Steakhouse 55
- 22 Storyteller's Cafe
- 23 Tangerine Grill & Patio
- 24 The Mexicana Cafe & Cantina
- 25 The Sandbox Bar & Grille
- 26 Tivoli Gardens Café
- 27 Tony Roma's

**Downtown Disney**

- 28 AMC Theatre
- 29 Catal Restaurant & Uva Bar
- 30 ESPN Zone
- 31 House of Blues
- 32 Naples Ristorante e Pizzeria
- 33 Rainforest Cafe
- 34 Ralph Brennan's Jazz Kitchen
- 35 Tortilla Jo's

**THE SHOPS AT ANAHEIM GARDENWALK**

30 Bar Louie	37 P.F. Chang's China Bistro
31 Bubba Gump Shrimp Co.	38 Pop the Cork Wine Bar
32 California Pizza Kitchen	39 Roy's Hawaiian Fusion Cuisine
33 FIRE + ICE Grill + Bar	40 The Cheesecake Factory
34 Heat Ultra Lounge	41 Cinemafusion 14/IMAX
35 Johnny Rockets	42 24 Hour Fitness
36 McCormick & Schmick's Grille	43 300 Anaheim Bowling & Entertainment Center

**GardenWalk Retail Stores**

Harley-Davidson of Anaheim • Lux/Aveda Salon & Spa  
 O'Neill • White House/Black Market  
 ...and more!

**ATTACHMENT D**



<http://www.ims2010.org:80/about.html>

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INTERNATIONAL  
MICROWAVE SYMPOSIUM

IEEE MTT-S • MAY 23-28, 2010 • ANAHEIM, CALIFORNIA

THE GOLDEN STATE OF MICROWAVES

## About the Symposium

### IMS 2010

The IEEE MTT International Microwave Symposium, held in **Anaheim, California, May 23-28, 2010**, is the premier annual international meeting for technologists involved in all aspects of microwave theory and practice. It consists of a full week of events, including technical paper presentations, workshops, and tutorials, as well as a full set of social events. The symposium also hosts a huge commercial exhibition, organized by [MP Associates](#).

The MTT IMS is held concurrently with two other symposia, the [RFIC Symposium](#) and the summer [ARFTG](#) meeting. These meetings are organized separately from the IMS; please see their respective websites for further information.

This year the symposium will be held in Anaheim, California, at the [Anaheim Convention Center](#). The headquarters hotel is the [Anaheim Hilton](#), just a short walk from the convention center. The convention center is well located, convenient to many hotels and restaurants. The closest airports are Los Angeles International Airport and Orange County John Wayne Airport. These are connected to Anaheim by busses, taxis, and shared-ride vans.

For further information about attending or participating in the symposium, please use the links in the menu to the left.

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